# **Electronics**

Faster r-f device testing: page 94 Special report on gallium arsenide: page 105 A suitcase-sized computer memory: page 138 November 13, 1967 \$1.00 A McGraw-Hill Publication

Below: Crystal of gallium arsenide opens new horizons in electronics, page 105



NEW SERIES ULTRAMINIATURE TRANSISTOR TYPE AUDIO TRANSFORMERS



This DO-T200 series of transistor transformers and inductors has been newly added to the UTC lines of stock items available for immediate de-livery. These transformers provide the unprecedented power handling capa-bilities and the inherent reliability found only in the basic structural design of the UTC DO-T Family of miniature transformers. This reliability has been

dramatically proven in the field. Leads are 7%" long, .016 Dumet wire, gold plated, and may be either welded or soldered. They are uninsulated and are spaced on à .1" radius circle, conforming to the termination pattern of the "TO-5" cased semicon-

ductors and micrologic elements. D0-T200 series of transformers are designed for Class R application. On special order they may be designed to Class S Specifications. No additional life expectancy is gained by using Class S insulation systems at Class R temperatures.

In pulse coupling impedance matching applications, (when measured with a 30 microsecond input pulse voltage wave), typical values for these transformers are: 5% or less droop, zero overshoot, and less than 10% backswing.

Special unit modifications, such as additions and deletions of leads, changed lead lengths, different impedance ratios and incorporation of electrostatic shields, etc., are available in these constructions.

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MINIATURIZATION

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- Hermetically Sealed
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- Excellent Response
- High Efficiency
- Low Distortion

Type No.	MIL Type	Pri. Imp.	D. C. ma‡ in Pri.	Sec. Imp.	Pri. Res.	Mw Level	Application
DO-T255	TF4RX13YY	1K/1.2K CT	3	50/60	115	100	Output or matching
DO-T275	TF4RX13YY	10K/12K CT	1	1.5K/1.8K CT	780	100	Interstage
DO-T277	TF4RX13YY	10K/12K CT	1	2K/2.4K split	560	100	Interstage
DO-T278	TF4RX13YY	10K/12.5K	1	2K/2.5K CT	780	100	Driver
DO-T283	TF4RX13YY	10K/12K CT	1	10K/12K CT	975	100	Isol. or Interstage or Puls
DO-T288	TF4RX13YY	20K/30K CT	.5	.8K/1.2K CT	830	50	Interstage
DO-T297	TF4RX16YY	200,000 CT	0	1000 CT	8500	25	Input and Chopper

Drawn Hipermalloy shield provides 15 to 20 db shielding through side of case DO-T200SH

‡DCma shown is for single ended useage. For push pull, DCma can be any balanced value taken by .5W transistors. Where windings are listed as split, ¼ of the listed impedance is available by paralleling the winding.

PIP

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DI-T Flexible leads. Freq range 400 CPS—10KC & up. Power up to ½ W. Size 1/16 dia x ¼" h. Wt approx 1/15 oz. DO-T200 Series. See above

D0-1200 Series Straight pin gold plated. Dumet leads. Freq range 400 CPS-100KC. Power up to 500 mw. Size  $\frac{4}{16}$  d x  $\frac{3}{4}$ <sup>m</sup> h. Wt approx  $\frac{1}{15}$  oz. PIL Inductors range from .025 hy to .8 hy .D C 0 to 10 ma. Transformers from 500 ohms to 10,000 ohms impedance. Freq range 800 cps-250 KC; power up to 100 MW. Size  $\frac{4}{16}$  dia x  $\frac{3}{16}$ <sup>m</sup> h. Wt  $\frac{1}{20}$  oz.

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04 21

band and CW tests because of its low residual FM and high-resolution frequency dial. Then too, the 8690A main unit accepts 17 other sweeper units covering 1 to 40 GHz in octave and waveguide bands.

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The new Hewlett-Packard 7850 Series Rectilinear Fluid-Process Recorder produces ultra-clear traces on Z-fold paper or rolls. The numbered Z-fold pages offer more convenient access to recorded data. Contactless pen tip sensing and a low-pressure ink system produce traces of constant width throughout the recorder's variable speed ranges of .025 to 200 mm. per second. Designed with modular, solid-state electronics, the 7850 Series Recorder provides high-resolution, permanent, rectilinear recording of up to eight variables from dc to 160 Hz.

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For complete information on the 7850 system, optional and related equipment, contact your local HP Field Office or write Hewlett-Packard Company, 175 Wyman St., Waltham, Mass. 02154.





Circle 2 on reader service card

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#### **Readers Comment**

#### No exceptions

To the Editor:

I would like to correct one statement made in the article "Strengthening a link . . . or replacing it" [Aug. 21, p. 39] to the effect that everyone except Amphenol would be forced to requalify as suppliers of MIL-C-26500C. This is not the case. Amphenol, as well as all other potential suppliers of a connector qualified to MIL-C-26500C, will have to qualify by running the required tests in the manner specified. As a matter of fact, we have already asked permission to start such qualification testing at Amphenol.

J.E. Atkinson

Vice president Amphenol Connector Division Chicago, Ill.

#### New light

To the Editor:

"Is Einstein wrong?" was the heading you gave to a letter from Pascal M. Rapier [July 10, p. 4] discussing the article "Settling on the moon" [May 15, p. 110].

Rapier had suggested that either Einstein's theory "that the phase of a light signal is independent of velocity . . ." is wrong or that "the lunar soft landings whose velocity and rauge data were obtained from radar doppler techniques . . . impossible under Einstein's theory" were fakes.

C. J. Badewitz, the author of the article, replied that Einsteinian doppler shifts encountered in the Surveyor approach velocities differ from such shifts calculated by means of classical theory by a completely negligible amount.

Neither of these gentlemen appears to have read "Light Velocity and Relativity," by Arthur S. Otis. This 130-page booklet presents some half-dozen disproofs of the postulate questioned by Rapier. One of them concerns the doppler shift.

The postulate is: the velocity of light is constant in all inertial systems.

Dr. Otis argues thusly: since light velocity  $v = \lambda f$ , and since  $\lambda$ 

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does not change but the spectroscope shows various amounts of red shift for distant receding stars, meaning that f decreases accordingly, then v must decrease accordingly. A similar spectroscopic shift toward violet occurs for approaching stars, indicating an increase in the observed "invariant" velocity of light.

One can conclude from this that Einstein's postulate is invalid, and that any error in the techniques of the Badewitz article is negligible even if it is valid.

Howard S. Balsam, P.E. Support engineer Sanders Associates Inc. Nashua, N.H.

#### Protection channels

To the Editor:

The statement in Electronics Newsletter [Sept. 18, p. 25] that, "Essentially all of the Bell System's fault-location and switching, to sidestep an out-of-commission line or microwave transmitter, is currently done manually," is inaccurate. All of our broadband eable and radio systems are under constant check by automatic systems that switch to protection facilities on the same route rapidly and automatically.

It is the availability of these protection channels that permit the restoration system that the news item describes. Total failures, such as those caused by destruction of a microwave tower, occur only rarcly but are, of course, very serious when they do occur. The protection channels on other routes are now used to restore service manually from a route (microwave or cable) experiencing a total failure. We are now in the process of automating this procedure to restore service.

C.H. Elmendorf

Asst. vice president American Telephone & Telegraph Co. New York

But telephone systems engineers told Electronics reporters that the equipment in use is inadequate to meet the needs of today's heavy traffic and that a modern system is needed to replace the present automatic checkout gear and the repairmen who must still manually search through a maze of wires to find a fault.

#### Premature

To the Editor:

Under the heading, "Around the World" [Sept. 4, p. 209] you reported that Jules Leger, currently ambassador to France, will succeed the retiring Alphonse Ouimet as head of the Canadian Broadcasting Corp.

Although Ouimet announced his intention of retiring about a year ago, a successor has not been named as of this date. However, the Prime Minister has indicated that new legislation pertaining to broadcasting in Canada is about to be introduced in the House of Commons, and that the appointment of a successor to Ouimet would be made this fall.

David H. Orr

Corporate Supervisor Information Services—CBC Ottawa, Ontario

Reader Orr is right. So would Electronics have been had we said that Leger will most likely be named to succeed Ouimet.

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Our precision resistors are aged to improve reliability, and we guard the process like a vintage champagne maker. Ageing is just one of many extra steps that make our precision components the most reliable you can specify. A few of our components are described briefly below.

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3. Dekapot<sup>®</sup> Resistive Voltage Dividers These rapid-setting potentiometers have a terminal linearity up to 0.002%. Kelvin-Varley circuitry provides constant input impedance.



4. Dekatran Transformer Voltage Divider The patented coaxial dial is easy to read and adjust. Accuracy of 0.001% and long-term stability are achieved through gapless toroidal cores of very high permeability.





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Voltage Range.	1 mv to 300 volts full scale
Phase Dial Range	0° to 90° with 0.1° resolution (plus 4 quadrants)
Phase Accuracy	0.25°, 31.6Hz to 31.6KHz (derating to .6° at 10Hz, 1° at 100KHz)
Input Impedance	10 megohms, 30μμf for all ranges (signal and reference inputs)
Reference Level Range	
Harmonic Rejection	
Nulling Sensitivity	less than 2 microvolts
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Price	\$2790.00 plus \$160.00 per set of filters

North Atlantic's sales representative in your area can tell you all about this unit as well as other Phase Angle Voltmeters\* for both production test



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#### People

Intersil Inc.'s appointment of **Ward Gebhardt** as marketing director without a product reflects the op-

timism that prevails at the fledgling semiconductor firm started by Jean Hoerni, developer of the planar process, f o u n d e r o f Ameleo Semi-



Ward Gebhardt

conductor, and guiding spirit behind the entry of the Union Carbide Corp. into semiconductors. Though Intersil has only 15,000 square feet of plant facilities and some \$2 million in backing, Gebhardt left a comfortable spot as marketing manager for discrete components at the semiconductor division of the Fairchild Camera and Instrument Corp.

"We already have some proposals out, trying to find out who wants what," Gebhardt explains. "Our present plant is strictly for research and development and prototype fabrication. But we are geared for fast expansion. The n&D is not so far beyond the market that we can dispense with a marketing man. You need one for long-term planning, to help in the language and pricing for bidding on specific circuits."

Gebhardt has known Hoerni since 1963, when both did some consulting work for Union Carbide. The chance to work with Hoerni at Intersil—where the financial rewards for success could be enormous—may have dictated the decision to leave Fairchild.

To **Theodor F. Hueter**, the field of ocean engineering appears to be "at the Sputnik 1 hour," poised for

exciting thrusts, but s a d d l e d with the omnipresent brake on funding imposed by the war in Vietnam. The 50-year-old Hueter, an acoustics ex-



Theodor F. Hueter

Circle 8 on reader service card



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#### LOCAL AVAILABILITY

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New high density collindrical connectors with  $0.085^\circ$  pin spacing meeting all requirements of MLL C-81511 (Navy

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- Silicon-base hybrid microcircuits in hermetically-sealed flat packs.
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- Packaged for compatibility with monolithic circuits.

For complete technical data on D-to-A microcircuits, write to Technical Literature Service, Sprague Electric Company, 35 Marshall St., North Adams, Mass. 01247.

#### SPRAGUE COMPONENTS

THIN-FILM MICROCIRCUITS INTEGRATED CIRCUITS TRANSISTORS CAPACITORS RESISTORS PULSE TRANSFORMERS 455-7141 INTERFERENCE FILTERS PACKAGED COMPONENT ASSEMBLIES FUNCTIONAL DIGITAL CIRCUITS MAGNETIC COMPONENTS CERAMIC-BASE PRINTEO NETWORKS PULSE-FORMING NETWORKS



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pert, was recently chosen to head Honeywell Inc.'s Marine Systems Center.

The Center consists of two facilities-the West Covina, Calif., headquarters and a site in Seattle. Total employment for the two installations has grown from about 750 two years ago to some 1,300, and Hueter looks for it to reach 2.000 once the Vietnam conflict subsides. He expects to get a good share of military business. For example, there are the Navy's DX destroyer program in which Honeywell would probably compete for antisubmarine warfare hardware development, and an improved version of the Navy's Asroc antisubmarine rocket, which was developed by the Marine Systems Center.

One of Lee Rice's first moves as senior vice president of the Ogden Corp. of New York will be to get

the company into the electronics business. "We plan to acquire several electronics companies by mid-1968 and exceed \$250 million in electronics sales



Lee Rice

by the early '70's,' says the Washington-based executive.

Rice says he plans to "create a broad technology base as a viable business and to serve Ogden's other activities," which include shipbuilding, metals and food processing, biomedicine, water treatment, chemicals, and demolition. Ogden now has technical laboratories in Los Angeles and Sunnyvale, Calif., and Long Island, N.Y., which provide environmental and functional testing for aerospace and oceanographic equipment.

The electronics companies Rice has in mind will include a mixture of "those concerned with advanced development and those dealing in a product line, mainly in the areas of pollution control and for the chemical industry."



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# RCL miniature 1/2" rotary switches



#### INDUSTRY'S MOST COMPLETE SELECTION

- Shorting AND non-shorting poles may be grouped on one deck in any combination.
- Up to 12 positions per deck shorting or non-shorting.
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#### Meetings

Computer Conference, American Federation of Information Processing Societies; Convention Center, Anaheim, Calif. Nov. 14-16.

Meeting of the Anti-Missile Research Advisory Council, Advanced Research Projects Agency; U.S. Naval Postgraduate School, Monterey, Calif., Nov. 14-16.

International Exhibition of Industrial Electronics, Swiss Industries Fair, Basle, Switzerland, Nov. 14-18.

Missile System Meeting, American Institute of Aeronautics and Astronautics; Monterey, Calif., Dec. 4-6.

Symposium on Theory and Measurement of Atmospheric Turbulence and Diffusion in the Planetary Boundary Layer, Atmospheric Sciences Laboratory of the Army Electronics Command; Sandia Base, Albuquerque, N.M., Dec. 5-7.

Vehicular Conference, IEEE; New York Hilton, New York, Dec. 5-7.\*

Symposium on Reliability, IEEE; Sheraton-Boston Hotel, Boston, Jan. 16-18.

Power Meeting, IEEE; Statler-Hilton Hotel, New York, Jan. 28-Feb. 2.

Aerospace and Electronic Systems Convention, IEEE; International Hotel, Los Angeles, Feb. 13-15.

International Solid-State Circuits Conference, IEEE; Sheraton Hotel, Philadelphia, Feb. 14-16.

Scintillation and Semiconductor Counter Symposium, IEEE; Shoreham Hotel, Washington, Feb. 28-March 1.

International Convention and Exhibition, IEEE; New York Coliseum and New York Hilton Hotel, New York, March 18-21. Symposium on Microwave Power, International Microwave Power Institute, Statler Hilton Hotel, New York, March 21-23.

Joint Railroad Conference, IEEE; Conrad Hilton Hotel, Chicago, March 27-28.

International Magnetics Conference, IEEE; Sheraton Park Hotel, Washington, April 3-5.

Business Aircraft Meeting and Engineering Display, Society of Automotive Engineers, Broadview Hotel, Wichita, Kan., April 3-5.

#### Short Courses

Low Frequency Standards, U.S. Dept. of Commerce, National Bureau of Standards, Washington, Dec. 11-13; \$90 fee.

Process Control, University of Wisconsin's Department of Engineering, Madison, Wis., Dec. 13-15; \$70 fee.

Automation and Publishing, The American University's Center for Technology and Administration, Washington, Jan. 15-18; \$175 fee.

#### Call for papers

Colloquium on Information Retrieval, University of Pennsylvania's School of Electrical Engineering; University of Pennsylvania, Philadelphia, May 3-4, 1968. Dec. 1 is deadline for papers to David Lefkowitz, Moore School of Electrical Engineering, University of Pennsylvania, Philadelphia, Pa., 19104.

Power Meeting, IEEE; Sherman House, Chicago, June 23-28, 1968. Feb. 9 is deadline for submission of papers. Authors should advise the technical conference services office of IEEE if they expect to submit a paper.

Conference on Precision Electromagnetic Measurements, IEEE; National Bureau of Standards Laboratories, Boulder, Colo., June 25-28, 1968. Feb. 12 is deadline for submission of summaries and abstracts to Donald King, Aerospace Corp., Box 95085, Los Angeles, Calif. 90045.

\* Meeting preview on page 16.

# THE Connector THING

A periodical periodical designed to further the sales of Microdot Inc. connectors and cables. Published entirely in the interest of profit.

#### Everybody wins Play Pricrodot voolf, it's time pastime, you g of history Pistorical

In the words of Virginia Woolf, it's time for fun and games.

For this new national pastime, you simply need a smattering of history, mythology and current events. And some information about Microdot's cable products. We'll supply you with the latter. For the rest, go listen to Walter Cronkite.

We got started on this activity while we were sitting around one evening with a bottle of Slivovitz (we ran out of Scotch), trying to think of memorable ways to remind you of the various unique features of Microdot cables. Like –

Like our Mini-Noise cable – reduces noise voltage from shock and vibration by a factor of more than 100 to 1 compared to untreated cable. This makes possible the transmission of extremely faint signals through coax cable without audio frequency noise. Off-the-shelf.

Like our microminiature coax cable uses a fine silver-plated copper steelcovered wire. You get 50 ohm impedance, and even with the addition of dielectric, outer shield and protective jacket, the nominal O.D. does not exceed .080". And we can get that O.D. down to .025" in a range of hundreds of different cables.

Like our new complete in-house capability to produce precision quality multiconductor cables, which includes twisting, extruding, shielding and jacketing—the whole deal. All under one roof. And we can cable hundreds of conductors into one unit.

Like we're the only one to produce a high temperature, low weight, low capacitance coax cable through the use of a *cellular Teflon* dielectric. Especially suited to the requirements of video tape recorders. Like Microdot's Twinaxial cable —to be used when you need to send two signals from a single source which must both terminate at the same point. No need to use two coax cables; therefore lower cost and greater flexibility.

Now when you think of cables, you think of cablegrams. And when you drink a lot of Slivovitz, it sort of takes you back through time and you come up with stuff like this : Low noise Spaghetti-Gram: "You lose. Signed, Calvin Coolidge?"

High temperature Spaghetti-Gram: "Julius, honey, ain't nobody home tonight but me. Signed, Cleopatra."

Miniature size Spaghetti-Gram: "Cancel that order for bras. Signed, Twiggy."

**Dual shield Spaghetti-Gram:** *"I can lick any guy in the joint. Signed, Brunhilde:"* 

Large size multiconductor Spaghetti-Gram:

"Send more elephants. Signed, Hannibal."

Get the idea. You can use any of the features of any of our cable products, such as low noise (Mini-Noise), special requirements (Multiconductors), high temperature, low weight, and, of course, small size. You don't really need the Slivovitz. It works well even with Sanka.

#### About the fork

**DO** 

WIN

YOUR

OWN

CABLE

FORK

No, Melvin, we won't explain the relationship between cable and spaghetti. We call

• it a cable fork, and if you don't want to use it for cating cables that's your prob-

lem. The manufacturer describes this

handy gadget as a "revolutionary breakthrough that leaps for-

ward from antiquated hand labor to the modern machine age!" We won't try to top that. We'll just explain that you stick it into the pasta and then turn the little handle to save getting spaghetti all over your celluloid collar.

Want one for your very own? Okay. Just send us a Microdot Spaghetti-Gram scribbled on company stationery and taking off from any of the product features we've discussed. We'll send you a beautiful cable fork along with more literature on our cable products than we care to mention.

But hurry. We've already run out of Slivovitz. It won't be long before we run out of cable forks. (That means offer is limited.)



Electronics | November 13, 1967

#### **Meeting preview**

## **PLOTAMATIC** x-y recorders offer more performance, features, value

### just compare the specs



BBN/DE 600	HP
1 megohm, constant all ranges	100K on four most sensitive ranges
Vacuum: b <mark>e</mark> tter holddown, easier line-up, quiet	Electrostatic: attracts dust particles
Sealed follow-up pots (no slide wire cleaning kits)	Open slide wires (require frequent cleaning)
Push-button zero check on control panel	Must remove X-Y input signals
No shift from zero calibrate position regardless of full scale input range selected	Shifts from zero calibrate position when attenuator input range is adjusted for proper full scale setting
\$2 <mark>5 les</mark> s	
	BBN/DE 600 1 megohm, constant all ranges Vacuum: better holddown, easier line-up, quiet Sealed follow-up pots (no slide wire cleaning kits) Push-button zero check on control panel No shift from zero calibrate position regardless of full scale input range selected \$25 less

Plotamatic is a clear winner on these and other basic important features. You'll want to test all features right in your own lab. We have 30 models of X-Y recorders to choose from. Call us, and we'll bring the particular Plotamatic best suited for you to compare and evaluate. Or write for our complete Plotamatic brochure.



**Crowded spectrum** 

As is becoming usual when land mobile radio users gather, frequency congestion will be a major topic of discussion at this year's annual IEEE Vehicular Conference, Dec. 6 to 8. At the New York meeting, W.L. North of the Federal Communications Commission will report on a study of the problem in a 34-mile-square area including metropolitan New York.

North recommends the use of computers to plan frequency assignments, two-frequency systems to ease intermodulation problems, and cooperative base stations. With all this, however, he warns that additional frequencies will be needed in the New York area by around 1975-77.

Equipment scored. At the same session, R.C. Eldridge of the British Columbia Telephone Co. will blame the height and power of many base-station transmitters and the sensitivity of receivers for much of the traffic interference and, in the long run, for reducing the number of available channels.

To extend the range of highway and railroad communication systems with fixed transmitters, a solid state repeater with a stable gain of 140 decibels at 450 megahertz can amplify attenuated signals. J.G. Churcher will describe the device, which was developed in England at Pye Telecommunications Ltd.

Also on the agenda are reports on two mass-transportation radio communications systems that will operate in the 150-Mhz band. C.E. Paul of Bell Telephone Laboratories will outline the projected radio telephone service on a high-speed train planned for runs between Washington, D.C., and New York. And Seymour Dornfield of the New York City Transit Authority and G.H. Kamerer of the Radio Corp. of America will describe a radio system to be installed in New York's 4,000 buses.

**Plaudits.** At a session on reliability, Otmar Schreiber of the General Instrument Corp. will praise the contributions of thermoelectric generators to very-high-frequency communications.



#### Push for Automatic Measurements



An automatic capacitor-test system produced by General Radio.

These are the basic building blocks for a variety of automatic capacitance-measuring systems that can test capacitors at rates as high as 120 per minute. Such systems are used for production testing and sorting, incoming inspection, zero-defects qualityassurance programs, and environmentaltest runs for design evaluation. Cost analyses by owners of 1680 systems indicate savings of up to 80% or more on the per-unit cost of component inspection over manual methods.

The heart of each system is GR's 1680 Automatic Capacitance Bridge, which automatically selects C and D (or G) range, balances, and displays measurements in digital form. Measurement range is 0.01 pF to 1000  $\mu$ F and basic accuracy is 0.1% of reading for C and G, 1% of reading  $\pm$ 0.001 for D. Price is \$4975 in U.S.A.

Other system components designed around the 1680 bridge are shown below:



Three of these instruments are new:

*Type 1770 Scanner System*, for sequential connection of many capacitors to the bridge; modular construction permits up to 100 input channels; guarded connection; six operating modes; visual display and BCD output of channel number. Price dependent upon requirements; about \$3500 for a guarded, 50-channel model.

*Type 1781 Digital Limit Comparator*, makes possible fully automatic capacitor sorting; compares BCD output of the 1680 bridge with limits of C and D (or G), preset on the 1781 front panel; GO/NO-GO visual indication and relay-contact output. Price, \$1625 in U.S.A.

*Type 1791 Card-Punch Coupler,* a parallelto-serial converter for driving an IBM 526 Card Punch from the BCD output of the 1680 bridge and other digital instruments; 22-digit capacity. Price on request.

For additional information, write General Radio Company, W. Concord, Massachusetts 01781; telephone (617) 369-4400; TWX (710) 347-1051.

#### **GENERAL RADIO**

Circle 17 on reader service card





# Off-the-shelf PMT from Amphenol

PMT means Precious Metal Tip, a wrought gold dot welded to printed circuit connector contacts. PMT is 100 times thicker than ordinary contact plating. We have 22 different PMT connectors that will work for 20 years, and they're all standard production items. Pre-tensioned contacts spring back to position insertion after insertion -without damaging P.C. boards. You'll pack about twice as many contacts in the same space, too: 56 in a

No. 28 connector, 36 in a No. 18. PMT could be your best printed circuit connector buy. Call your nearest Amphenol Sales Engineer or write to Amphenol Connector Division, 1830 S. 54th Avenue, Chicago, Illinois 60650



Cut-away Amphenol PMT connector shows welded gold dots on contacts





# **Build with** 3 more linear IC innovations rom RCA

#### New Versatility for Commercial, Industrial, and Military Use



For Automatic Fine Tuning in VHF

- Dual phase detector with differential.
- Compensated reference voltage sup-
- Operating temperature range –55°C
- Total current drain 9 mA (type) @
- Output offset voltages between terminals #4 and #5 1.5V max. @ Vcc=



RCA CA3034V1 with preformed leads. Price \$1.75 (1000+)

## 3-in-1 wide-band amplifier array— 132 dB (typ) Gain!



Low noise performance and outstanding wide-band response make this three-in-one unit general purpose amplifier array ideal for TV remote control.

• Three separate amplifiers; gain and bandwidth for each adjustable by external circuitry

• Can operate as individual units—or in cascade for 132 dB gain (typ) @ 40 KHz

Voltage gain-	-Ampl. #1	44dB typ
	Ampl. #2	46dB typ
	Ampl. #3	42dB typ
Bandwidth @	-3 dB poir	nt—Ampl. #1

Ŭ	Ampl. #2 Ampl. #3	2.5 MHz 2.5 MHz

● Operating temperature range -55°C to +125°C

• All three amplifiers single-ended, only one power supply needed

• Typical applications: TV remote control; IF systems; instrumentation amplifiers; chopper amplifiers





500 KHz

RCA CA3035 wide-band highgain ampl. in T0-5 package. Price \$1.50 (1,000+)

RCA CA3035V1 with preformed leads. Price \$1.50 (1,000+)

## **Dual Darlington amplifier array**





Block diagram of application as stereo phono pre-amp. Cartridges designed around the CA3036 can provide enhanced fidelity, low hum pick-up without shielding. Response flat to 1MHz @ $R_L=1K\Omega$ 

- Voltage gain for either pair 26 dB (typ)
- Power gain for either pair 47 dB (typ) @ f= 1 KHz
- Gain-bandwidth product for either pair 200 MHz
- hre for either pair 4540 typ. @  $l_{c1} + l_{c2} = 1mA$
- Operating temperature range -55°C to +125°C
- VCEO = 15V max.
- Усво = 30V max.
- $V_{EBO} = 5V \text{ max.}$
- Ic (each transistor) = 50 mA max.
- Emitter-follower output

 Typical applications: stereo phono amplifiers; differential ampls; op amp driver; mixer



RCA CA3036 Dual Darlington Array in 10-lead T0-5 package. Price 98⊄ (1,000+)

#### Ask your RCA Distributor for his price and delivery.

For Technical Data write to RCA Commercial Engineering Section ICN11-1, Harrison, N.J. 07029.

## RCA ELECTRONIC COMPONENTS & DEVICES

in Electronics

The new AO StereoStar/ZOOM Microscope gives you high resolution, new convenience, superior optics and wide magnification range.

Here are a few of the outstanding advantages that make the new AO<sup>®</sup> StereoStar/ZOOM Microscope the finest instrument of this type available today:

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 3.5-210X ■ High resolution to meet the most exacting needs ■ The most convenient zoom control available
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TM Reg., American Optical Co.





#### **Editorial**

#### **Special-interest** education

Despite the turmoil on college campuses these days, more students are staying on after graduation to earn graduate degrees instead of plunging into the worlds of industry or business. One reason has been the exemption from the draft and the Vietnam war. But almost as important has been a growing recognition among students that a bachelor's degree is just not enough in today's complex industrial environment. In no area has the interest in graduate study been heavier than in electronics and electrical engineering. Unfortunately, the increase in quantity of advanced degrees has meant a sharp drop in the quality of the education administered.

Business has encouraged the move to more education by its prospective employees. Many engineering managers get a feeling of confidence if an applicant owns a graduate degree. At the very least, it shows an inclination for scholarship. At the most, it could mean broad knowledge, an exposure to research techniques, and a mastery of new complex technology.

This feeling shows up dramatically in the salary differentials that are now being paid for advanced degrees. Twenty years ago, an engineer with a master's degree would find it was worth \$300 to \$500 more a year in starting salary. Today that same master's degree can be worth as much as \$2,000 to \$4,000 a year. On the West Coast, graduates with a Ph.D. degree, and a specialization in semiconductor technology for example, start at over \$16,000 a year, without a day's industrial experience.

Despite all this, there is a nagging suspicion among some engineering managers that the advanced degree candidates in engineering are not worth all this extra pay. They believe that technical graduate education has deteriorated over the past 10 years so that the bearer of a master's degree in engineering is more a technician versed in some narrow specialty than a fullfledged engineer trained in advanced techniques, the connotation formerly associated with advanced degrees. And this applies equally to those who take advanced degrees in part-time study while they work at engineering jobs.

At fault for this decline in stature of the advanced degree are both business and colleges. Traditionally, colleges must serve the economy by producing the kind of graduates industry wants or needs. Over the past 10 years the electronics industry, particularly, has wanted specialists who would work in a specified narrow area, rather than the broad expert trained in fundamentals. Such apparent expertise has looked good on proposals made to the Government for defense and space projects.

As part of the academic proclivity to service the economy, universities have rushed to tailor graduate curricula to the product and interest mixes of nearby companies. On the West Coast you find electrical engineering curriculum heavily endowed with semiconductor, computer, and radar technology—reflecting the aerospace-oriented activities of western firms. Courses and curriculum at eastern and midwestern colleges reflect the local interests of their industries and companies.

Even if a company or government facility sets up shop far in the wilderness, if it's big enough a local college is likely to follow with an extension service geared to the facility's special interests. Its graduates come out with masters' degrees and specialized training limited to such narrow disciplines as wind tunnel instrumentation, or missile range data gathering.

Looking closely you can turn up some extreme—almost absurd—examples of this loosening of academic standards in advanced degrees. For example, one new graduate with a master's degree in the new specialization of bioinstrumentation engineering has never had a single course in transistor circuit design or semiconductor technology. His undergraduate curriculum clung to tube technology (in the mistaken belief that the receiving tube may someday make a comeback); at graduate school, he took life science courses instead of the searching kind of engineering course that would teach him how and why phenomena happen.

Industry used to complain, sometimes bitterly, that colleges were not responsive to their needs for graduates. But that was 30 years ago when liberal arts training predominated. Today, the opposite criticism has to be leveled. The colleges are so responsive to what industry says it wants that a university does the job of a company's training department instead of being an academic institution of higher learning.

Some colleges brag that their engineering professors are in close contact with industry because the academicians consult for local companies. Consulting has become so lucrative that professors vie feverishly with each other for these plums and are anxious to please the industrial paymasters who augment their university salaries so lavishly. Under such circumstances, it is easy to see why courses tend to follow some companies' specific interests so closely.

If advanced degrees are to regain their former stature and meaning of training well above the bachelor level, the academicians have to regain control of the curriculum. More emphasis has to be placed on intellectual effort and less on workbench practice. U.S. colleges are turning out too many engineers who are technicians and not enough who are trained to advance technology by thinking through problems and putting new phenomena to work. Engineers who have learned to live with the flutter problem in hysteresis synchronous motors will find that living comes easier now. Especially in voice/data recording applications.

Indiana General's unique inverted stator design provides up to six times the rotor inertia of conventional designs. Flutter characteristics are so low as to be practically negligible.

And the price is not so high that it

restricts the use of our inverted stator motor solely to recording devices. It is so economical to manufacture that it's priced competitively with induction type motors, making the Indiana General hysteresis motor economically practical for units like fans and blowers. And, the inverted stator design significantly reduces start-up input power-surge and combines very high operating efficiency with low slip characteristics. Indiana General inverted stator motors are smaller and lighter than conventional synchronous motors and are available in a wide range of sizes, mountings, power ratings and torques. You can get full details by writing Mr. R. D. Wright, Manager of Sales, Indiana General Corporation, Electro-Mechanical Division, Oglesby, Illinois.

INDIANA GENERAL 🖘

# New inverted hysteresis motor design drives the flutter out of recording equipment.



## **Electronics Newsletter**

#### November 13, 1967

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Raytheon will push bipolar FET op amp	The Raytheon Co.'s semiconductor operation, which cut sharply into Fairchild Semiconductor's 709 sales when that company ran into produc- tion difficulties last spring, isn't going to wait for Fairchild to falter again. Like Fairchild [Electronics, Oct. 2, p. 25], Raytheon is in the early development stage of a fully compensated operational amplifier that uses field-effect transistors in the input stage. The interior of the chip will contain bipolar elements. Raytheon has confidently promised one customer sample circuits by December. The company is working with both junction and metal-oxide- semiconductor FET's for the input stage. The high impedance of FET's is said to give the op amp more potential applications. The MOS impedance is inherently higher, but that of a junction FET may be high enough, and junction devices are easier to make than MOS.
Siegel may buy laser center	It appears that Lear Siegler Inc. has found a buyer for its unprofitable laser-systems center in Ann Arbor, Mich. Likely purchaser: either a group of the center's engineers or Keeve M. Siegel's fast-growing KMS Indus- tries Inc. of Ann Arbor.
Spy satellite runs into delay	Although Air Force officials will say nothing publicly about the super- secret program 949—the integrated reconnaissance satellite—they're privately admitting that the project is five months behind schedule. TRW Systems group is building the satellite and Aerojet-General Corp. its sensors under a contract awarded last year [Electronics, Dec. 26, 1966, p. 49]. Indications are that the delay has been caused by technical diffi- culties not, as rumored, by a stretchout of funding.
GE will market a set-it-yourself unijunction device	A "programable" unijunction transistor (UJT) that permits the user to set firing voltage and sensitivity levels has been developed at General Electric's Semiconductor division. GE, which invented the UJT, hopes the new device will help restore the sales lead it formerly enjoyed. Conventional devices have nonadjustable instrinsic standoff ratios that establish the firing point; the new unit's triggering level can be varied by adding two external resistors. The programable unit, a p-n-p-n struc- ture similar to a silicon-controlled switch, is compatible with monolithic integrated-circuit fabrication. It can be used for firing thyristors or as an oscillator. Other likely applications: in timing, sensing, and control networks. The new units will be marketed before year's end.
Lockheed improving rotor antenna radar	An improved model of its radar using a rotor-blade antenna is being readied for tests by Lockheed Electronics. The higher power integrated circuit version, to be tested aboard a five-place Fairchild-Hiller FH-1100 copter delivered early this month, will weigh 130 pounds and deliver 30 kilowatts. The earlier model, tested on a two-passenger Enstrom F-28, put out only 2 kw. Lockheed is developing a phased-array antenna to be placed into the nose of the helicopter, replacing the mechanical scanning unit and

## **Electronics Newsletter**

its dome. The company plans a sales push for its multifunction radar, good for mapping and navigation, terminal landing, weapons delivery, and limited station keeping.

#### Motorola readying 3rd generation ECL

A third-generation emitter-coupled-logic line will be introduced next year by Motorola Semiconductor. The company is aiming the MECL-3 integrated circuits at the ultrahigh-speed computers expected to be introduced in 1970 or 1971.

Motorola seeks a 1-nanosecond typical propagation time; switching speed of the MECL family now on the market is 5 nanoseconds. Jim Burns, manager of IC marketing, says the current-mode line will include flip-flops that operate at frequencies between 200 and 400 megahertz.

By the skin or the teeth A hearing aid that uses the teeth and the skin to conduct sound is being developed by a small New York City electronics company, Intelectron Corp. The development is significant because it could result in a hearing aid considerably smaller than those currently in use.

In the Intelectron model sound is not produced by the motion of air as it is in conventional hearing aids which use loudspeakers—but through bone conduction. Consequently, the hearing aid has smaller parts.

In one model, a radio-frequency receiver is placed in a patient's tooth; the "sound" is then conducted through the tooth to the ears' nerves. And in an earlier model, which was used for rehabilitating the hard of hearing, an electrode is attached to the patient's skin.

**Due for mailing** President Johnson's spending freeze so far has held back the Post Office from issuing contracts from its \$18 million R&D budget this year, but department officials are hopeful that they can start letting the first of some 100 to 150 awards by the end of the year. The Post Office also promised the 300 industry representatives attending a briefing earlier this month a list of R&D contracts it will put out for bids.

**Addenda** 

A sweeper plug-in, developed at Hewlett-Packard Co.'s Loveland, Colo., division, contains the first integrated circuit turned out by the new IC facility there. Construction of the facility began only last spring. The IC is a diode chain used to give a logarithmic shape to the dynamic response of the instrument. . . . Interior Secretary Stewart L. Udall is trying to interest Westinghouse and General Electric in establishing electronics plants in "new towns" that might be built on Indian lands in New Mexico and Arizona. He's citing as precedent the dozen electronics firms attracted to another new town, two-year-old Reston, Va. . . . Happy days are here again at Autonetics where officials, winding up development tests on four programs, are anticipating orders for more than 2,000 airborne computers. The computers, all members of the D26J family, will go on the Condor and short-range attack missile (Sram), both air-tosurface weapons, and the FB-111 and the RF-111 aircraft. . . . Litton Industries has won a hot contest to build the Army's Tacfire (tactical fire direction system). Under an award that could reach an estimated \$50 million, the firm will build a system to provide automatic data processing for all elements of information needed by an artillery officer. Burroughs and IBM were the losers.

# TTL TENDS from Texas Instruments



# Why Bunker-Ramo chose TTL complex functions for new NC systems



These low-cost numerical control systems offer as standard most of the functions normally found in far more expensive equipment. They are the first such systems to employ ICs for all non-power functions. Shown with Dean W. Freed, General

Manager of the NC Division, the Bunker-Ramo 2100 (right) is a two-axis positioning and straight-cut control, while the 2200 (left) is a three-axis positioning and straight-cut control, with optional two-axis incremental slope and arc capability.

Series 74 complex-function TTL integrated circuits from Texas Instruments have enabled Bunker-Ramo to further improve reliability and performance, while reducing size and cost of the numerical control systems shown above.

Series 74 TTL offered many performance as well as cost advantages. These included higher noise immunity and faster speed, plus the economies made possible by complex-function circuits.

#### High noise immunity

Since numerical control systems usually operate in an electrically noisy environment, the high noise tolerance (typically one volt) and the low input impedance (70 to 150 ohms) of Series 74 circuits are big advantages. Bunker-Ramo engineers found that this reduced shielding and line-filtering requirements, while simplifying many associated design problems.

#### High speed

TTL's high speed gives important design advantages, even though today's NC systems often do not

# Do ICs really cut costs?



#### Please send the following:

- 200 🗌 6-page case history brochure
- 201 
  48-page complex-function IC data book
  202 
  48-page TTL brochure
- 203 🗆 84-page IC plastic package reliability report
- 204 🗆 24-page plastic S-C brochure
- 205 🔲 16-page "Total Reliability at TI"

NAME TITLE COMPANY ADDRESS \_\_\_\_ CITY \_ \_\_\_\_\_ STATE \_\_\_\_\_ ZIP \_\_\_\_

The answer is an emphatic yes! That's no promise. It's a fact... with proof to back it up.

We've gathered some of the proof in the folder pictured at the left. This 6-page brochure describes how other industrial manufacturers have achieved revolutionary product advances with ICs. Like these OEMs, you too can significantly reduce equipment size and weight . . . make major performance improvements... achieve new systems capability... dramatically reduce costs! For your copy, check No. 200 on the TI information service card.

But that's not all! Check number 202 for the 48-page brochure that contains performance, application, and catalog information on all 180 Series 54/74 TTL ICs.

An 84-page report provides results of TI's "Tougher-than-military" testing program. It's yours for the asking. Check number 203.

A new 24-page color brochure that gives information on all plastic-encapsulated semiconductors – including Series 54/74 ICs – is also available. Check No. 204.



To get the literature you want, check the appropriate numbers, fill out the card, and drop it in the mail. If you prefer, circle the same numbers on the magazine Reader Service card.

Ε

SN7482 is a two-bit binary adder that has a typical carry time of only 8 nsec per bit. The logic diagram shows the complexity of an SN7482.

SN7483 is a four-bit binary adder that is equivalent to 34 gates in a single package.

### BCD-to-decimal decoder/driver

Here is a real cost saver! The SN7441 replaces conventional decoding consisting of one dual fourinput gate, two triple three-input gates and a dual two-input gate, plus four inverters and ten transistors. Output is sufficient to directly drive gas-filled readout



tubes, miniature lamps, and many small relays. The logic diagram (above) shows the complexity of an SN7441.

#### Quadruple latch



A single SN7475 quadruple latch replaces eight AND-OR-INVERT gates...greatly reducing package count and costs.

This monolithic quadruple bistable latch offers complementary Q and  $\overline{Q}$  outputs. The device is ideally suited for such applications as temporary storage of binary information between processing units and input/output or indicator units.



#### Shift register

SN7491A is a monolithic serial-in, serial-out eight-bit shift register that is composed of eight R-S master/slave flip-flops. It includes both input gating and clock driver, and is capable of storing and transferring information at clock rates up to 18 MHz.

Want to know more about how you can upgrade your new designs with Series 54/74 TTL from Texas Instruments? Start by sending for the comprehensive literature offered on the Information Service Card . . . or call your nearest TI sales engineer or authorized TI distributor.

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require all the speed available. While clock rates of 4 MHz are common today, 20 MHz and up are possible with TTL. To the user, this reserve speed gives an extra measure of performance insurance ... and longer productivity before obsolescence.

In addition, B-R found that the extra speed of TTL also made possible simpler circuitry. For example, a function that would have had to be performed in parallel fashion with lower speed logic can now be performed in serial fashion with Series 74 TTL. This results in fewer circuits and a simpler, less expensive, more reliable system.

#### 20 percent fewer ICs

The complex-function circuits available in the Series 74 line also made possible a 20 percent reduction in package (and circuit board) count. Since the cost of any system is largely proportional to the number of elements used, Bunker-Ramo designers were able to realize important economies.

For example, a decade counter is often made up from four J-K flip flops and a gate...perhaps three packages. Bunker-Ramo used a single SN7490N instead. Since about 40 decade counters are used in a typical NC system, the savings in integrated circuit and circuit board costs are substantial.

#### Improved reliability

By using Series 54/74 ICs in the new 2100 and 2200 NC systems, Bunker-Ramo engineers found that they were able to surpass reliability standards established by existing discrete-component designs, since the number of soldered connections were substantially reduced. Also, B-R engineers could place more functions on each circuit board...reducing the number of circuit boards by about 20 percent and further improving reliability.

#### You get a broader choice of complex-function circuits in Series 54/74 from TI

Complex-function circuits to add, count, store, decode, and perform many other jobs are available in TI's Series 54/74 TTL line...industry's most complete logic family. These complex-function ICs can help you achieve the same kinds of performance and economic advantages realized by Bunker-Ramo.

For a comprehensive data book describing all Series 54/74 complex-function ICs, just check 201 on the TI information service card.

#### Counters



TI offers counters capable of dividing by 2, 3, 4, 5, 6, 8, 10, 12, and 16 at typical rates of 18 MHz. When used singly or in combination, they can perform most division or counting functions that might be required. Furthermore, they afford tremendous reductions in package count, soldered connections, and costs. In addition to the SN7490Ns used by B-R, SN7492 divide-bytwelve counters and SN7493 fourbit binary counters are available. As may be required by the application, each of these devices offers the flexibility of several alternative interconnection arrangements in the system circuitry.

#### Adders

If you need adders, TI offers a broad selection. SN7480 is a highspeed, single-bit binary full adder with complementary inputs, complementary sum outputs, and inverted carry output.



TEXAS INSTRUMENTS

# Quality analysis... TI reliability starts here!



Any really successful reliability program must start with correcting the causes of failure *before they occur in the field*, and TI's Reliability Analysis Laboratory... established in 1962...has been examining the "where, what, when, how and why" aspects of IC failures for more than five years.

This lab has facilities to analyze each individual element within even the most complex integrated circuit and can duplicate failure mechanisms under precisely controlled conditions.

Typical of these quality-analysis studies is the X-ray video monitoring facility shown at the left. This important analytical tool permits full 360° observations in both vertical and horizontal planes. It reveals failure mechanisms that might otherwise escape detection.

Following identification of failures, the analysis is forwarded to a corrective-action group. Here, TI's in-depth technical resources – including physicists, chemists, and metallurgists, as well as research, design, and manufacturing engineers – are focused on the problem. After evaluation of all data and reports, necessary corrective actions are undertaken.

Quality analysis is only one of many steps taken by TI to ensure reliability of integrated circuits. Other important steps are described in a new 16-page brochure

in full color...Total Reliability at TI. Check number 205 on the TI information service card for your copy.



# TEXAS INSTRUMENTS

## For a clear picture of Centralab...

## ... keep an eye on our ripples

In our years of manufacturing miniature and subminiature components, we've made many ripples, and a few splashes, in the electronics industry:

**Centralab designed** and produced the world's first carbon composition potentiometer and for more than 40 years has been an industry leader. In 1936 we introduced the first temperature-compensating ceramic capacitor in America. We were first to offer dual controls and to add integral line switches to variable resistors. Our exclusive **PEC** integrated circuits have been key elements in the miniaturization of electronic equipment. During World War II days Centralab developed the ceramic disc capacitor design for military requirements. And our Ultra-Kap<sup>©</sup> ceramic disc capacitor has replaced millions of larger, more costly devices.

**Centralab sales** have increased substantially every year and our services have grown proportionately. Our products are sold, by separate sales groups and from separate warehouses, to original equipment and distributor markets.

**Centralab's tested and proven** products include capacitors, packaged circuits, rotary switches, potentiometers and technical ceramics. In October, 1966, we erected a push button switch manufacturing plant and in May, 1967, we acquired solar devices and semiconductor facilities.

Innovation, growth and stirring the waters are nothing new at Centralab; and we don't intend to stop. As technology advances and components become smaller, more complex and more sophisticated, we'll keep our feet wet.

To help keep abreast of Centralab developments, we'll be happy to send you complete product literature.



CENTRALAB 6 pro D on GLORE L D C 5757 NORTH GREEN BAY AVENUE NEWS OF COMPANY

# talk about systems...


Television. Show Business. To Belden it's all a world of wire. Belden plays a leading role in many complex systems of sight and sound communication. By delving into design, processing, packaging and a host of factors, Belden's team of wire specialists have helped many people wring out hidden costs. Success takes a supplier that is really <u>perceptive</u> – one who makes all kinds of wire for all kinds of systems. Want to join us in wringing out values and costs? Just call us in...Belden Corporation P.O. Box 5070-A, Chicago, Illinois 60680.





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# You don't have to have someone re-invent the wheel

The answer to your latest switching problem may already have been developed. And, if there's any place in the world where you can get it right off-the-shelf, it's MICRO SWITCH.

Many of our switches would be considered specials by some people. But at MICRO SWITCH they are available without special engineering costs. They are available now. And they are application-proved reliables.

Main reason for this extra service is that we've specialized in nothing but switches for over 30 years. And in the process have come up with the world's largest selection of switches.

Engineering and application help is also available from MICRO SWITCH. Our field engineers are thoroughly experienced in solving switching problems. You will find them a cost-saving addition to your design team.

Call a local MICRO SWITCH Branch Office (See Yellow Pages, "Switches, Electric"). Or write . . .



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Give us your signal, and we'll show you better results on EAI X-Y plotters than any comparable machine on the market... often at lower cost.

We state emphatically: EAI has the finest machines available. And a superior service reputation that backs them to the hilt.

We developed the first commercially produced X-Y plotters to tie in with our analog computers, and we've been building them at the computer-quality level ever since.

There is a whole family available: different features, different prices . . . one for your needs. Here are a few of the extras you can count on in every EAI plotter. Single Loop Direct Drive — eliminates complex string

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Tell us what you're looking for in a X-Y plotter. We'll set up a test date. Don't pass it up.







# It pays to pick the fastest... in the computer race, it's SUHL/TTL.

We became deeply involved in TTL before anyone. That's why in TTL we're way ahead with SUHL<sup>TM</sup> ICs, the fastest IC line in the industry.

Our SUHL line keeps breaking speed recordsnow down to 5 nsec-without compromising noise immunity and power dissipation. That's why we're the prime source for TTL and why Sylvania Universal High-level Logic ICs are being secondsourced. In fact, several of the largest electronic manufacturers standardized on SUHL ICs, even though Sylvania was their only source.

We have the most modern manufacturing facilities in the industry. All our ICs are made with one optimum process to maximize performance characteristics of every unit. Automated test equipment insures the ultimate in production monitoring, final testing, and quality control. So get SUHL's speed and reliability.

Sylvania Semiconductor Division, Electronic Components Group, Woburn, Massachusetts 01801.



Circle 40 on reader service card →

# ASA turned to Airco for helium and....

**reliability.** To pre-cool Centaur rocket engines, irco delivered 5,500 gallons of liquid helium. The argest single commercial delivery of helium ever hade. & it took only 42 hours, in one of Airco's 0,000 gallon trailers, from Kansas to Cape Kennedy.

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That's the way Airco works. & from 25 points spotte across the country. We're the number one helius supplier & we perform for all our customers – larc & small. For more information write us at 150 Ea 42nd Street, New York, N. Y. 10017.



## A TECHNICAL DIGEST FOR INNOVATORS OF INDUSTRIAL EQUIPMENT



Here's industry's most complete offering of reed switch relays GE reed switch relays give you both the small size and high response you need for multi-relay applications. Each GE reed switch relay you buy provides extremely long electrical and me-chanical life. Units are available in a wide variety of forms including standard, small, and miniature for open printed circuits, enclosed printed cir-cuits, tube plug-ins, and bracket-, channel- or stud-mounting. **Circle Number 90**.



GE reed switch relays are particularly applicable for latching, timing, and voltage- or current-sensing

#### 8 microwave tube exhibits in one



the General Tube Van 

This traveling exhibit shows you just some of the reasons General Electric is one of the world's leading microwave tube producers! The van features "live" demonstrations of:

- Distance Measuring Equipment (DME).
- Radar Altimeter. •
- Spectrum Analyzer.
- Unit Oscillator. .
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And many other tube and solid state attractions. Write about a possible GE microwave van visit to your plant. Circle Number 91.

**High-performance** computer-grade capacitors

General Electric 86F aluminum electrolytic capacitors, with improved volumetric lytic capacitors, with improved volumetric efficiency, provide extra high volt-micro-farad capacity for power supplies, in-dustrial control equipment, and energy storage applications. Units are available to 370,000  $\mu$ f (at 5WVDC) and at voltages to 450WVDC. Ripple current ratings are as much as 100% higher for a given case size than are earlier models designed for similar uses. **Circle Number 92.** 



Fuel Cells----What's available from GE today?

While off-the-shelf hardware cannot yet be offered, prototypes of packaged fuel cell power sources—for communication or sensing equipment or for battery charg-ing—are now being tested. These units weigh as little as one quarter pound per watt and deliver upward of 80 watt-hours per ounce of special fuel. Completely self-contained fuel cell power packages have contained fuel cell power packages have been developed for long unattended operation in remote or underwater environ-ment. (Example: 44-kilowatt-hours at 175 watt-hours per pound, 5 watt continuous with hourly 500-watt peak.) Inquiries for experimental application

are invited.

Circle Number 93.





A TECHNICAL DIGEST FOR INNOVATORS OF INDUSTRIAL EQUIPMENT

Lower cost—yet higher sensitivity with the new L14B photo transistor Priced at  $97\phi$  in lots of 100-999, General Electric L14B photo transistors feature high sensitivity. Light current (typically) =7mA at 10v when irradiance is 5mW/cm<sup>2</sup>. Typical applications include card and tape readers, door openers, counters, and contactless potentiometers. Circle Number 94.



Shown actual size

**Bias your** reed relay with Lodex® permanent magnets



Reedswitch with Lodex magnet

This revolutionary new permanent magnet ma-terial—the result of years of extensive General Electric research—offers reed switch and reed relay users high piece-to-piece magnetic uni-formity. Lodex permanent magnets provide ex-tremely close physical tolerances . . . can either be pressed to the precise intricate shape you require (reducing your overall package size) or extruded for greater physical strength. **Circle Number 95.** 

**GE** panel meter relays available in 2 styles



Type 195 BIG LOOK

GE meter relays are ideal for temperature precise control. over-temperature protection, hazardous atmosphere control, hyardous atmosphere control, ny-draulic pressure consistency-wherever control of auxiliary equipment is needed. Contact-less action and "piggyback" plug-in design provide excep-tional reliability and easy instal-lation. Choose BIG LOOK® or new HORIZON LINE® meter re-lays in a variety of sizes lays in a variety of sizes. Circle Number 96.



Type 196 HORIZON LINE

New full line of highperformance, regulated d-c power supplies GE d-c power supplies are available in a wide selection of 50 Hz and 60 Hz models with output voltages ranging from 10 to 200 VDC. Each unit features static-magnetic circuitry for long-life reliability and holds d-c output voltage to within  $\pm 1\%$  despite incoming line-voltage fluctuations over the rated range of 97 to 130 volts. Other advantages include:

- operation from —10 to 40C ambient.
  total ripple content: 1% rms or less.
  plus or minus grounded installation.
- . overload protection to 200% of rated
- load.

Circle Number 97.



Typical power supply, model 9T66Y989

New cooling fan assemblies for electronic equipment cabinets



100 CFM assembly

New 100 CFM (and similar 90 CFM) fan assemblies are powered by reliable GE shadedpole motors and measure slightly under 4¾-inches square. 500 CFM assemblies are pow-ered by GE unit-bearing, 4-pole, shaded pole motors and measure less than 6¼ inches deep with a 10-inch diameter fan venturi. Both units require only simple ON-OFF switches for operation and are designed for years of quiet, dependable continuous-duty operation without maintenance. Circle Number 98.



500 CFM assembly

WE MAY NOT OFFER EVERYTHING YOU WANT FROM ONE COMPONENTS SUPPLIER. BUT WE DO COME A LITTLE CLOSER THAN ANYONE ELSE. 285-30





250v

400v

500v

600v 700v High Voltage NPN Silicon Power Transistors *in 3 Packages!* 

UNARA	$I_c = 1.0A$	$I_c = 2.0A$	$I_{\rm C} = 3.0$ A		
V <sub>CEX</sub>	$h_{FE} = 15 \text{ Min}$ $V_{CE}(\text{sat}) = 0.5\text{V}$ $V_{BE}(\text{sat}) = 1.0\text{V}$	$h_{FE} = 10-50$ $V_{CE}(sat) = 0.5V$ $V_{BE}(sat) = 1.5V$	$\begin{array}{l} h_{FE} = 10 \ \text{Min} \\ V_{CE}(\text{sat}) = 0.5 \text{V} \\ V_{BE}(\text{sat}) = 1.5 \text{V} \end{array}$		
250V	SDT1050 SDT1150 SDT1250	SDT1055 SDT1155 SDT1255	SDT1060 SDT1160 SDT1260		
400∨	SDT1051 SDT1151 SDT1251	SDT1056 SDT1156 SDT1256	SDT1061 SDT1161 SDT1261		
500V	SDT1052 SDT1152 SDT1252	SDT1057 SDT1157 SDT1257	SDT1062 SDT1162 SDT1262		
600V	SDT1053 SDT1153 SDT1253	SDT1058 SDT1158 SDT1258	SDT1063 SDT1163 SDT1263		
700∨	SDT1054 SDT1154 SDT1254	SDT1059 SDT1159 SDT1259	SDT1064 SDT1164 SDT1264		
SDT1050 - SDT1064	SDT1150	- SDT1164	SDT1250 - SDT1264		
B			H.J.S.		
T0-3	ТО				

T0·3 100W @ 75°C

TO-61 100W @ 75°C

**S**olitron now offers silicon power transistors, with  $V_{CEX}$  up to 700 Volts, in three different packages: T0-3, T0-61 and T0-66. These high reliability devices, priced low, have many applications including vertical and horizontal TV circuits, audio amplifiers, inverters, converters and relay drivers. They replace similar higher priced units now on the market.

50W @ 75°C

To obtain additional information on these devices, Dial 1-800-327-3243 for a no charge telephone call.



When you think of semiconductors... think Solitron!

## **New PAR Lock-In Amplifier Measures Signals** in the Presence of Noise by Crosscorrelation



Transistorized Lock-In Amplifier --- Model HR-8

The PAR Model HR-8 Lock-In Amplifier represents a significant advance in signal processing equipment for experimentalists who must measure low-level signal intensities in the presence of noise. It employs the theoretically optimum technique for signal recovery, and can be incorporated into a large class of experiments in which the signal of interest is, or can be made periodic, and in which a reference voltage related in frequency and phase to the signal can be obtained. The Model HR-8 first amplifics and bandlimits the input signal and then crosscorrelates it with the reference signal, suitably phase shifted and shaped. The crosscorrelation of input and reference signals yields a DC output voltage proportional to the signal of interest, while the crosscorrelation of the reference and noise results in no net DC voltage. The system can also be described as a continuously integrating, highly sensitive, phase conscious voltmeter, the response of which is "locked" to that particular frequency and phase at which the signal information has been made to appear.

#### Technical Features:

Frequency Range: 1.5 cps to 150 KC continuously tunable in 5 ranges. Time Constants: 11 values in 1-3 sequence extending from 0.001 to 100 seconds. Single or double section RC filtering.

Pre-Amplifiers: Interchangeable lownoise pre-amplifiers, operable either within the HR-8 or remotely, are used.

- Type A: Differential 10 megohm input. Type B: Low impedance transformer
- input for low source impedances.

Sensitivity: 21 calibrated full scale ranges in 1-2-5 sequence.

With Type A Pre-Amplifier: 100 nanovolts to 500 millivolts rms.

With Type B Pre-Amplifier: 1 nanovolt to 5 millivolts rms.

Output: ± 10 volts full scale, singleended with respect to ground. Will drive galvanometric and servo recorders.

Frequency Selective Amplifiers: Notch network in negative feedback loop used in both signal and reference channel tuned amplifiers. Reference channel Q of 10. Signal channel Q adjustable from 5 to 25 with calibrated dial (no gain change with Q adjustment).

Phase Adjustment: Calibrated 360° phase shifter, providing continuous rotation as well as a four position quadrant switch which shifts phase in 90° increments.

Price: \$2,250 with either Type A or Type B Pre-Amplifier.



Contours of constant noise figure for a typical PAR Type A preamplifier plotted to show dependence on frequency and source resistance at 300° K. Amplifier operated single-ended.

Write for bulletin No. 120 on the HR-8 or ask for information on PAR's complete line of Lock-In Amplifiers and accessories.



# **Electronics Review**

Volum<mark>e 40</mark> Number 23

#### Computers

#### **Unwarped memories**

Woven plated wire memories have a half dozen advantages over other types of memories. They provide both nondestructive and destructive readout; high speed (100 nanoseconds undestructive or 250 nanoseconds destructive, full cycle); high bit density; low power consumption; a temperature range of  $-54^{\circ}$  to  $+125^{\circ}$ C; and light weight. Take those advantages, lower the price 20% while improving reliability, and you have a good part of the reason for \$1 million in new contracts received by the Librascope group of General Precision Inc. for various airborne applications.

Librascope has made the improvements by dramatically reducing the number of soldered wire joints from 704 on one side of a 64x64 (4,096-word) memory to only 256.

To and fro. Plated wire memories are made by weaving magnetically plated wires (digit wires) at right angles to insulated copper wires (word wires) the way cloth is woven. With the old system used by Librascope, the word wires came off a warp and the digit wires came from a spool mounted on one side of the loom. Alternate



Solder . . . With the old system, a woven plated wire memory had nine solder points to link a four-turn word coil to the outside world.



More for less. New Librascope loom produces memories, rolling onto drum, that cost 20% less while offering improved reliability.

strands of word wire were raised and the digit wires were pulled between them. The digit wires were then cut off, the position of the strands was reversed, and the process was repeated. Each word wire in a matrix was discrete and many solder connections were needed to complete the circuit in a word winding.

Now the positions of the wires have been reversed. The word wires come in from the side and are threaded between the digit wires. The warps are replaced by spools, each carrying a digit wire. The digit wires come through two stations, meaning that the loom can weave two arrays at the same time, from 2 to 5.8 in. wide. Four shuttles at each station carry the



... saver. The new continuous filament method developed by Librascope accomplishes the hookup with only two solder points.

word wires back and forth between the digit wires. Of the four, one carries the word coil wires, another is for dummy lines (spacers), a third is for magnetic keeper wires that help shape the magnetic field and cut down noise ratios, and the fourth is a spare.

Plus. What this boils down to is that the word wires, woven as continuous filaments throughout the matrix, are cut off only at the end of a word. Only two joints have to be soldered for each word. With the old system 13 joints had to be soldered on a five-turn word coil and nine on a four-turn because the loom used a broadcloth pattern-no continuous thread in either direction. Also, the new technique is much more flexible because word lengths can be changed within two or three minutes merely by adding or eliminating digit wires from the spools behind the loom.

Gordon Osborne, Librascope's product marketing manager for woven plated wire memory systems, estimates the total 1968 market for aerospace computer memories at about \$40 million. He says the company's contracts, many of them classified, include:

• A buffer for telemetry data on a space probe. The original contract called for power consumption of less than 10 watts. Librascope has demonstrated operation at <sup>1</sup>/<sub>2</sub>watt including peripheral electronics. Flight hardware is scheduled for delivery by August or September of 1968.

•A 4,096-word, 36-bit nondestructive readout memory module as the main internal memory for a variety of space computers. Dimensions will be 6x6x4 inches, including all electronics and an auxiliary power converter. The contract calls for six flight hardware units to be delivered by April 1968.

• A contract for 200-memory element arrays of 4,320 nine-bit words for a missile program. The memory will be loaded before launching and continuously read during flight as the program memory for a space-borne telemetry system. Power consumption requirement is less than 3 watts.

• A contract for a memory for an airborne computer. Basically it will be a permanently woven, read-only memory, although parts of it will have both read only and nondestructive readout on the same plane. Requirements include operation at one-microsecond rate, average total power dissipation of less than ½-watt, density of 2,500 bits per sq. in., and absolutely fixed and nonvolatile data storage. A prototype will have an 8,192-bit capacity.

• A contract for several hundred 60,000-bit memory stacks for an orbiting satellite that will have to operate on less than two watts for up to three years. Flight hardware is scheduled for qualification later this year. The system will be used as a sequencer or programmer for telemetry transmission.



Electronics production in September rose for the fifth consecutive month, climbing 1.1 points from August and 12.5 points from the September 1966 level. Consumer production, which had spurted 27.2 points in August, advanced only 1.1 points in September. However, that was enough to put this index at its highest level since February's 109.8. Defense electronics output also went up in September, but the 1.7 point gain was the smallest month-to-month increase since May. Industrial-commercial volume slipped 0.3 point from August and 2 points from the year-earlier pace to a level 4.8 points off its record high of 123.4 in December 1966.

Indexes chart pace of production volume for total industry and each segment. The base period, equal to 100, is the average of 1965 monthly output for each of the three parts of the industry. Index numbers are expressed as a percentage of the base period. Data is seasonally adjusted. \* Revised.

#### Solid state

#### Hot dice

There are now two ways to slice a silicon wafer — the conventional way and the new Air Force way. The new way promises to boost yields to 100% from the present 60% to 90%.

Traditionally, integrated circuit manufacturers dice the wafer by scribing it with a diamond-tipped needle and then applying bending stresses. Although engineers have long been trying to perfect a thermal slicing technique, they've been unsuccessful. Spokesmen at Radio Corp. of America, Bell Laboratories, Texas Instruments, and International Business Machines Corp. agree that they're no closer to thermal slicing than they were a year and a half ago.

Now it turns out that an engineer at Tinker Air Force Base, Okla., has overcome thermal-slicing hazards-such as alteration of wafer geometry and silicon contamination-by conducting the process in an inert nitrogen atmosphere, using an 0.0005-inch-wide tungsten ribbon. The flat, homogeneous ribbon is stretched across the wafer in a lattice conforming to the desired slicing configuration and a-c current is applied to the wire. The wafer, hot on one side and cold on the other, then breaks along the wire lines. The Air Force engineer, Edwin B. Lyons, says that the thermal method is just as rapid as the diamond scribe.

#### Space electronics

#### New twist

Having gained a lead in the communications-satellite field with a simple design that stabilizes a craft by spinning it, the Hughes Aircraft Co. has come up with an approach that can result in the first spin-stabilized satellites with solar paddles, and in more accurately aimed antennas with sharply increased effective radiated power. So promising is the technique, called Gyrostat, that Hughes plans to apply it to proposed designs for the Intelsat 4 communications satellite, NASA'S Applications Technology Satellite models F and G, and the domestic communications craft.

The Gyrostat method spins the satellite about its minor axes of inertia to produce a spin-stabilized spacecraft with a despun platform. This stationary platform would carry the solar paddles and parabolic antennas, which could be fixed on the sun and the earth, respectively, according to Anthony J. Iorillo, assistant manager of advanced design at the Hughes Satellite Systems Laboratories and the developer of the Gyrostat technique.

Scatter guns. Early Hughes spinstabilized communications craft such as Syncom 1 carried omnidirectional antennas that wasted radiated power in signals that didn't hit the earth. Later models such as the ATS-1 had electronically despun, phased-array antennas, but these were limited in size, and the power generated by the satellite was restricted by the diameter of the launch vehicle. Also, the fact that all these satellites spun about their axis of maximum inertia limited their height, which, in turn, limited the number of solar cells that could be attached to them

"We like the spin-stabilized satellites because they have lasted longer in orbit than other kinds," says the 29-year-old Iorillo. "They have simplicity and reliability. So we've built on the spin-stabilization technology and extended it to handle a broad class of new missions.

"We're providing a space platform that can be very accurately and reliably oriented in space. Application of the Gyrostat principle yields a stable base that allows us to talk about antenna-pointing accuracies to within a half-mile of where we want the beam on the ground, and this is achieved with simple sensors." Iorillo adds that this is the equivalent of accuracies of 5 to 10 arc seconds. The National Aeronautics and Space Administration is interested in such accuracies, he explains, because it plans to relay communications on laser beams from planetary distances to earth



More and better. Gyrostat principle enables communications satellite to have solar paddles, more accurately aimed antennas, and permit greatly increased effective radiated power.

via an earth-orbiting repeater.

NASA is also interested in using the Gyrostat concept in the second generation of ATS satellites, Iorillo says. ATS program officials at Goddard Space Flight Center have already proposed a Gyrostat satellite to NASA headquarters, he adds, but the fate of the follow-on ATS series is now uncertain because of the pinch on space agency funds.

**Comsat too.** The Communications Satellite Corp. has shown interest in Gyrostat satellites to the tune of \$500,000. The money represents the Hughes share of a study of multipurpose synchronous communications satellites for Comsat.

Iorillo says the Gyrostat concept could produce a domestic communications satellite radiating power 45 to 50 decibels above a watt; the satellite's capacity would be 12 television channels. This compares with a figure of 25 dbw for communications satellites now under development, such as TRW Inc.'s Intelsat 3.

The addition of solar paddles oriented toward the sun can boost effective radiated power to levels of 70 to 80 dbw, Iorillo goes on. Levels that high would be compatible with the small-diameter earth antennas envisioned for use with satellites broadcasting directly to the home.

#### Looking sharp

Pity the earthbound astronomer. He can observe only about five of the 21 decades in the electromagnetic spectrum because of atmospheric distortion. (The atmosphere severely attenuates emanations from extraterrestrial sources.) To get beyond the distortion area and observe the entire spectrum, he hopes to put telescopes in orbit around the earth—and the National Aeronautics and Space Administration agrees that this should be done.

The first such telescope will be mounted in an Apollo to concentrate on solar observations, as part of the Apollo Applications Program, despite a fiscal cutback because NASA Administrator James Webb thinks it's a high-priority project.

After Congress cut \$300 million from NASA's fiscal 1968 Apollo Applications Program request late last month, Webb said the agency would still build four uprated Saturn I launch vehicles, beyond those needed for the Apollo manned lunar landing effort. This, he said, would allow at least one attempt to conduct the two highest priority items in the applications program—the orbital workshop and the Apollo Telescope Mount.

Farsighted. But researchers at Douglas Aircraft Co. are looking beyond the Apollo Telescope Mount toward the period 1970-1980, and trying to come up with an evolutionary orbiting observatory plan to fit the spacecraft that will be available then. The space agency's Marshall Space Flight Center has provided \$475,000 for Douglas, a component of McDonnell Douglas Corp., to analyze the needs of a manned orbital support facility for future astronomical research from space. The three-phase study began last December and is to be completed next February.

Although none of the three phases is complete, the effort is far enough along for its director at Douglas to comment on results to date. Harry L. Wolbers, program manager for space station subsystem analysis at the Douglas Space Systems division, Huntington Beach, Calif., says the study has three phases. Task A is to define the astronomers' research objectives; Task B is to recommend instrumentation to implement those objectives; Task C is to develop a flexible plan that accommodates the outputs of Tasks A and B in the space vehicles that will be available from 1970 to 1980.

Task A is no mean one. Wolbers says his team has conferred with as many astronomers as possible to determine the objectives of greatest scientific significance to be pursued from outside the atmosphere. So far, 92 observation requirements have been suggested.

The output from Task B will be the establishment and evaluation of instrument groups needed to carry out Task A's observation requirements. "We'll conduct a commonality analysis and come up with possibly 10 equipment groups that cover this range of requirements," says Wolbers. Kollsman Instrument Corp. is principle subcontractor to Douglas for this portion of the study.

Cross your H. Of the four antennas being considered for radio-frequency observations-terminated loop types, orthogonal terminated loops, a combination tethered orthogonal loop and terminated loop, and crossed H types—the crossed H is one that looks feasible, says Wolbers. A tethered pair of crossed H antennas, with directivity of 5.9 to 8 decibels and a frequency range from 0.5 megahertz to 10 Mhz, may be as far apart as six miles. An exotic version of the terminated loop shows promise for low-frequency studies down to 0.05 Mhz. The two loops could be as far apart as 25 miles at each end of the supporting structure, and electronically linked to give interferometric data.

#### **Medical electronics**

#### The good old ways

When a hospital administrator installs a computer to help him control soaring operation costs he often finds he's taken on two new financial headaches: the price of purchasing or leasing the equipment with its complex input terminals and the expense of teaching nurses to operate them. But by using old-fashioned punch-card readers instead of those terminals, Medelco Inc., a subsidiary of Scam Instrument Corp., thinks it has a way to avoid those headaches.

The system consists of punch card units for data transmission, a magnetic drum memory for data storage, and an electronic arithmetic unit for data manipulation. It functions as a message center that substitutes written for oral messages and, at the same time, maintains an inventory of material within the hospital, records patient charges, keeps a bed census, and can be used for employee time-card data.

**Price is light.** Capable of handling all the data requirements for a 432-bed hospital (up to 5,000 transactions a day), the Medelco system will lease for about \$5,000, roughly one-third the monthly rental fee of a computer with compa-

rable capacity. It will sell outright for about \$200,000. Even hospitals with as few as 50 beds can find Medelco's system an attractively priced answer to many problems. And, although the first system has only recently been placed in operation, Medelco's approach already has advocates. According to Lou Philipps, Medelco's president, the company has a \$1 million order backlog for the system.

Dubbed THIS, for total hospital information system, it combines the punch card system and magnetic drum memory to transmit instantaneously information to and from hospital departments. Each order, whether for drugs, hospital services, or special equipment, is acknowledged and stored in the memory to be reported to the accounting department.

Operation is simple. A punched card, made up for the patient when he is admitted, carries information such as name, date, address, doctor, and method of payment—specifying his insurance plan—in typewritten form and in punch-card code. In addition, each nurses' station has a rack of prepunched order information cards covering every service and medication. Similar cards are kept in such areas as X ray and the pharmacy, for all services performed there.

**Push, print.** When the nurse receives the patient information card and the physician's instructions, she selects the proper order cards from the rack and inserts them along with the patient card into the card reader. Instructions are printed out immediately in all concerned departments, including accounting, and the nurses' station for confirmation and for the patient's chart. If medication is ordered from the pharmacy, the teletypewriter there even prepares labels for the prescription items.

One of the attractive features of THIS, according to Gene Stanos, Medelco's chief engineer, is the fact that the system can be used by personnel who have no prior training. Another plus for the small hospital is that all components are interchangeable, minimizing service requirements.

Not only does the system offer



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hospital administrators a means of acquiring budgetary control information, but it reduces clerical work and insures quick, accurate transmission of orders. And with the additional paper work demanded by government medical programs such as Medicare and Medicaid, that's vital.

#### Advanced technology

#### Hot spot storage

Optical memories for computers promise to deliver enormous capacity, high density, and dazzling speed. Their potential has attracted the attention of several companies, some of whose attempts to develop such memories have been in vain. One that has succeeded is Honeywell Inc.

Scientists at the company's research center in Hopkins, Minn., have worked out a way to store binary information in a manganesebismuth film, using a laser capable of operating at two power levels one for writing in and a lower one for reading out data. The technique works at room temperature and can repeatedly read and rewrite information in the same place indefinitely.

Room-temperature operation is an inherent advantage for the technique over the cryogenic requirements of a europium oxide memory under study at International Busi-

ness Machines Corp. [Electronics, Sept. 18, p. 45], even though at those low temperatures EuO does work better. And Honeywell has thus far escaped the fate of Itek Corp., which tried to develop a read-only photographic memory but failed [Electronics, March 20, p. 47].

Film property. Both Honeywell and IBM have exploited the magneto-optic properties of their film. The film has a natural ferromagnetic axis that can be oriented perpendicularly, pointing either up or down. If the film is heated beyond its Curie temperature—+360° C for MnBi, and -176° C for EuOits magnetization plunges. If it then cools in a magnetic field, its intrinsic magnetic vector aligns itself with this external field. And if a beam of linearly polarized light is directed on the film, its plane of polarization is rotated to the right or left depending on whether the magnetization of the film is up or down.

Both MnBi and EuO are capable of rotating the plane several degrees as it passes through a film only 1,000 angstroms (10<sup>-4</sup> millimeter) thick.

A laser pulse focused on a small area of the film for a microsecond is enough to heat that spot above the Curie point. But a microsecond later, the film has cooled off almost to its initial temperature and is remagnetized. Binary data can thus be written by a laser beam having a few milliwatts continuous power focused down to many kilowatts per square inch. The same beam, throttled back by a modulator, does not heat the film appreciably, but its angle of polarization is rotated so that the recorded data is read out, theoretically at a speed of up to 100 million bits per second.

Stick to a spot. A film of EuO is much more transparent than one of MnBi of similar thickness, and is therefore more easily read-but at cryogenic temperatures. But MnBi's opacity-95% for a reddish light—improves its absorption of the energy in the laser beam. Thus, a small spot heats up quickly without spreading outside the beam area. "In this respect, manganese bismuth is unique," says M. Donald Blue, who heads the project. "We know of no other material that rotates polarized light so well and still has such a high absorption coefficient-and all at room temperature."

A practical limit now appears to be a spot 3 microns in diameter; theoretically, this could be reduced to 1 micron if problems caused by heat diffusion and lens aberrations can be overcome. Three-micron spots 10 microns apart lead to a packing density of 6.25 million bits per square inch.

These figures point to the eventual development of mass memory units with 30 times as much data per unit volume as conventional magnetic disk units, and also to relatively small—but extremely fast —memories in a small volume subsystem.



Tool. End-point sensor can be used for resistor trimming in General Instrument's hybrid IC's after they're packaged.

#### Integrated electronics

#### Neat trim

When users of hybrid integrated circuits want premium characteristics they have two alternatives. They can ask the manufacturer to trim component values (for a price) or cut into available space by adding external trimmer potentiometers and precision resistors (also for a price).

Now General Instrument Corp.'s Hybrid Microcircuit department is marketing hybrid 1c's—such as reg-



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The measurement system illustrated consists of the Type RM561A with the Type 3B4 Time-Base Plug-in and the Type 3A6 Dual-Trace Amplifier. The Type 3B4 provides versatile triggering and calibrated sweep speeds from 5 s/div to 50 ns/div. A direct-reading magnifier provides up to X50 magnification about the center of the CRT. The Type 3A6 Dual-Trace Amplifier has DC-to-10 MHz bandwidth and 35-ns risetime over its 10 mV/div to 10 V/div deflection range.

Type RM561A Oscilloscope			,	\$ 580
Type RM561A MOD 171A (Includes slide-out tracks)				\$ 630
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The plug-ins shown in the Type RM564 are the Type 2B67 Time-Base Unit that has calibrated sweep speeds from 5 s/div to 1  $\mu$ s/div extending to 200 ns/div with the X5 magnifier, and the Type 3A74 Four-Channel Amplifier that provides DC-to-2 MHz bandwidth over its 20 mV/div to 10 V/div calibrated deflection range.

Type	RM564 Storage Oscilloscope	1025
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#### **Electronics Review**

ulators and amplifiers—that can be trimmed by the user after the package is sealed.

The company makes the free ends of appropriate cermet resistors available to the user by putting extra leads on the package. Application of high-voltage pulses across the resistors trims the component to desired levels. To prevent harm to other devices in the package that have lower breakdown points, key resistors on the substrate are formed with one end free. Thus the trimming signals aren't coupled to associated circuitry. After application of the pulses, the free end is connected to the remainder of the circuit simply by adding an external wire.

#### Manufacturing

#### IC overseer

Has integrated circuit manufacturing grown enough to justify the use of digital computers for controlling test, inspection, and process operations? It's a question some IC makers are starting to ask, and at least one is trying to answer.

In Florida, the ITT Semiconductor division of the International Telephone & Telegraph Corp. started a two-month study last week which could result in the largest commitment so far for computercontrolled IC manufacturing and testing. "If our concept proves feasible, ITT will spend about \$10 million for extensive centralized computer IC test equipment in the next five years," says Irwin A. Horowitz, ITT Semiconductors' director of information systems.

Putting control computers into a plant is not a lightly-made decision, such manufacturing plants as refineries and steel mills have discovered. A control computer project takes about two to three years of study, engineering, programing, installation, and—not the least important—a large investment before it becomes fully operative.

**Specialists.** Now, like most IC makers, ITT uses dedicated test stations, each one doing fixed tasks

and directed by a special-purpose computer. In the future, it hopes to direct all of its test stations from two large central computers.

When Horowitz took over his new assignment last June, he made a quick assessment of information needs of the West Palm Beach plant and noted three factors worthy of deeper study:

• The steep growth pattern of IC sales—and more complex IC's in the future—warrants large expenditures for test equipment.

• One-third of the cost of present IC testers goes for special purpose computer-directors, two-thirds for programed power supplies.

• Less than 50% of labor cost is for 1C production, the rest for testing and inspection.

Until recently, ITT has been playing catch-up in the IC business, serving as second source for Fairchilddesigned devices. This year ITT expects to sell more than 3 million IC's, including diode-transistor logic, transistor-transistor logic, complementary-transistor logic, and linear packages. Next year, volume should rise to 15 million units—including devices of ITT's own design—which will amount to about 7% of total estimated IC sales of \$360 million.

**Peas in a pod.** What Horowitz hopes to do first is consolidate IC testing strategy into two central computers and interface them with numerous satellite test stations, all essentially alike. Flexibility for testing a variety of IC's will thus be accomplished by programing rather than by individual adjustment of electrical and environmental parameters for each type of IC at each station.

Horowitz' study team includes two ITT engineers with hands-on experience in IC testing, two corporate staffers knowledgeable in programing and communication, and two fulltime men and other specialists as needed from the Burroughs Corp. who will aid in specifying computer size and configuration.

Horowitz selected Burroughs after interviewing five computer makers—all of whom offered their men to the team free of charge. He emphasized Burroughs has no assurance it will get the computer order. If and when equipment is



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## Electronics Review

bought, vendors will bid to specs developed by the team.

During its study the team will specify computer, interface, and test station sizes and configurations; will consider such related factors as lease or purchase, programing, communications, service, and expandability; and will set up project schedules and manpower needs.

Voila. Irr hopes the system will produce data at each test point which can be fed back for on-line process control, diagnostics to test the test equipment, go/no-go signals, production and labor efficiency data which can also be used to simulate and forecast product throughput, and timely inventory information for its marketing department.

Although it's up to the study team to establish specifics, Horowitz estimates now the job will use, for reliability reasons, two somewhat redundant large computers— "like IBM 360 Model 40's or 50's" —and multi-interface gear under control of supervisory programs.

If the study says yes to computers, ITT will take a fresh look at test stations.

#### **Consumer electronics**

#### Music in IC major

Motorola's Semiconductor division has a major foothold in the lucrative electronic organ market as a result of having produced the first integrated circuits designed expressly for organs—a frequency divider and a dual-gate keyer [Electronics, July 24, p. 96]. But other major IC producers, with the incentive of \$200 million worth of electronic organs to be sold this year, have entered the lists.

The first challenge to Motorola came from Philco-Ford [Electronics, Oct. 30, p. 26] in the form of a seven flip-flop, dual in-line frequency divider package priced at 30 cents a flip-flop, compared to Motorola's 50 cents.

Here comes GE. Now the General Electric Co. is sampling a

metal-oxide semiconductor IC designed for organs, designated the PA448. It's a six-stage frequency divider available in two configurations: one with each stage cascaded in series, the other with inputs in a 1-2-3 cascaded combination.

Frequency division is accomplished by synchronous sequential logic in which all conditions that could lead to a false output have been eliminated. Divided outputs are fed to a push-pull amplifier that also acts as a buffer. The PA448 will be offered in a dual inline plastic package. GE says it will be priced competitively with Motorola's MC 1124A per flip-flop but is noncommital about being able to compete with the Philco-Ford price.

Since most of the 125,000 electronic organs made each year use more than 100 flip-flops per organ, ic makers hope to find an outlet for 10 million divider circuits a year.

#### Short circuited

Earlier this year integrated circuit makers began a big push for the potentially huge tv set and entertainment equipment market [Electronics, June 12, p. 38]. There was plenty of talk about big orders around the corner. Today, six months later, not only are they still around the corner, but Texas Instruments is scrapping its hybrid monolithic series and Fairchild Semiconductor, with inventories of its  $\mu$ a717 sound i-f amplifier built up, has stopped producing it, at least temporarily.

Tr developed and manufactured a line of multifunction hybrid IC's for i-f and audio stages in tv sets, radios, and phonographs. The products were sound, and the hybrid approach appeared better than the monolithic construction chosen by its rivals. TI chose hybrids for its pilot HIC1000 IC line for good reasons:

• The circuits were offshoots of units being made for IBM's 360 computer.

• Development costs were lower than for monolithics.

• Manufacturing costs for the

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#### **Electronics Review**

low-volume evaluation period were less than for monolithics.

• Diverse semiconductor elements, required to minimize customer redesign efforts but not amenable to monolithic fabrication, could be combined in hybrids.

**Failure.** The thick-film IC's were priced in the same range as competitive monolithics also aimed at displacing tubes and transistors in tv sockets. Despite this, the products didn't catch on. A TI marketing official admits "the IC's have not satisfactorily met the economic requirements of the consumer electronics industry." The company has dropped the entire hybrid line and is revising its approach to the consumer market.

Realizing it has fallen behind its competitors, TI hopes to get back in contention by developing integrated electronic components providing even more functions in the IC package, such as an entire i-f strip. The integrated electronic components being worked on make greater use of monolithic content and also contain thin- and thickfilm circuitry.

Meanwhile, none of the six or more major set makers who sampled Fairehild's  $\mu$ a717 sound i-f amplifier, supplied on a breadboard mockup last spring, has given Fairchild any indication that it will design the 717 into a ty set.

The 717 has also been sampled by the high-fidelity components industry but so far there are no takers. As one leading audio engineer points out, the 717 "does not provide adequate limiting for use as an i-f amplifier in our f-m receivers." Fairchild will only say that it will announce an equivalent 10 that is "more flexible" sometime this month.

#### **Avionics**

#### All ahead slow

Competing fiercely for an R&D award that would give the winning firm a running start on another large receiver market to come out of the Navy's Omega program, de-

sign teams are rushing to wrap up their bid packages before the Nov. 16 deadline.

The award calls for two computer-equipped engineering models of airborne receivers to be used in the very-low-frequency navigation system. Delivery date will be one year after the contract is signed. The second phase of the contract calls for two prototype receivers for flight tests. The timing depends on when the Navy can get the money to pay for them.

Budget squeeze. Getting enough money for the entire Omega program has been a problem. But Navy officials believe the \$2 million presently budgeted for research and development of the airborne receiver will be released despite the spending squeeze caused by the Vietnam war. They concede, however, that both building the airborne prototypes and expandground-transmit-Omega's ing ter network into a worldwide system will probably have to wait until spending for the war eases [Electronics, Oct. 16, p. 69].

Although no one knows how many sets the Navy and other military services will buy, one company believes total sales will top 5,000 over the next five years.

Estimates of the airborne-receiver price range from \$25,000 to \$40,000 once production lines are operating, a far cry from the shipboard receiver's hoped-for price of \$2,500. The primary difference between the two sets is that the airborne version will be tied to a computer for automatic operation. The Navy hopes Omega will be used in small planes, so is specifying a top weight of 75 lbs., including 30 to 40 lbs. for the computer.

The computer will convert the Omega coordinates it gets from the receiver to latitude and longitude data—something that can be done manually on ships but not by busy pilots. The Navy also wants a receiver that can be plugged into an aircraft's central computer or work alone with minor changes.

**Cost secondary.** The proposals due this week will be evaluated by the Navy on the basis of technology, not cost. Although the winner will have to compete for produc-



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#### **Electronics Review**

tion-model awards, it most likely will be selected if past procurement practices prevail.

The Northrop Corp.'s Nortronics division, which is developing the shipboard receiver, the AN/SRN-12, under a contract awarded last summer [Electronics, July 10, p. 48], is believed to have an edge on the airborne unit award. Another company making a strong bid for the work is Pickard & Burns Electronics, a division of the Gorham Corp., teamed with the Kearfott division of General Precision Inc. Other top contenders are ITT, Ryan, and Litton.



#### Stock taker

Getting quotes on stock prices to brokers quickly with electronic devices has been a significant factor in the booming sales of stocks around the country. Now the next logical step, which might help spur sales still more, is being taken.

With a desk-top display developed by Bunker-Ramo Corp., Stamford, Conn., a broker not only can ask for the latest stock prices but he can key in a buy or sell order as well. The order will then be automatically switched through the broker's teletype communications system to the floor of the exchange where it is to be executed.

Windows. The display, part of Bunker-Ramo's new Telequote 70 market information system, consists of two six-inch cathode ray tubes placed side by side. On the screens a broker will be able to look at several market services such as the stock tickers from the New York and American Stock Exchanges, Bunker-Ramo's own stock market quote and trend services, and wire service reports of financial news.

In addition, the display can select information from the brokerage house's own computer-based information system, including re-search reports and records of a customer's portfolio. Graphs of the behavior of the entire market or a



Market. Bunker-Ramo stock data system.

single stock can be displayed as well as alphanumeric characters.

#### Communications

#### Out of one, many

The search continues for effective ways of getting many frequencies from a single coherent light source. Researchers at Bell Telephone Laboratories think they're on the right road. Their reason: an electrooptic crystal has been used to shift the frequencies of a continuous helium-neon laser over a range of  $\pm 45$ gigahertz. Previously, electro-optic techniques have only been able to shift laser frequencies 2 kilohertz.

Unlike parametric techniques, which can shift frequencies over a wider range, electro-optic techniques don't require claborate instrumentation for precise tuning. And parametric techniques can't tune continuous-wave lasers.

Versatile. M. A. Dugay, who refined the electro-optic tuning technique with J. W. Hansen, points out that it can be used in laser communication systems and in multiple resonance studies of the atomic and molecular structure of materials.

In the Bell technique, a modelocked helium-neon laser emits a wide band of frequencies continuously, locking the phases of these frequencies 10 million times a second. During this time, the frequencies add constructively and destructively, forming narrow light pulses.

The rest of the time, the pulses are emitted haphazardly and output is low. The light pulses travel through a lithium-niobate crystal, a material whose index of refraction changes in an electric field. At the instant a pulse forms, a 10-megahertz radio frequency signal is applied to the crystal, changing its index of refraction and therefore shifting the phases of the light frequencies. This phase change shifts the frequencies of the laser pulses. Amount of shift depends upon the amplitude and frequency of the r-f signal, the crystal's length, and the number of times pulses travel through the crystal.

**Loaded.** C-w lasers that produce pulses in this manner may carry large amounts of information in future optical pulse-code-modulation communications systems.

In pem systems, many high-speed pulse streams could be frequency multiplexed to increase the transmitted bandwidth. The electro-optic technique makes it possible to tune these narrow pulse streams.

#### Government

#### Voyage to nowhere

A year ago, the Voyager program to land an unmanned craft on Mars loomed as one of the more interesting and expensive new projects on the U.S. space agenda. Last week. an official at NASA's Office of Space Sciences and Applications in Washington said: "There's no such thing as a Voyager office anymore. Within a few weeks you won't even be able to find anyone tied in with the program. As far as we're concerned, the project can't go in 1973 as originally planned-and if you ask us if it can go in 1975, we'd just have to say we don't know."

Surgery. The closing of the Voyager office and the halting of the program for the time being was predictable in the light of Congressional cuts in NASA's fiscal 1968 budget. Hope for Voyager still existed late last month as the Senate tried to get \$36 million to keep the program alive. But it was



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#### **Flectronics Review**

dropped when both Houses agreed on a space agency appropriation of \$4.6 billion—\$502 million less than the requested \$5.1 billion. Besides postponing Voyager and some other embryo programs, the reduction in the space appropriation to a level \$370 million below last year's funding has already had the following effects:

Plans are being completed for a lavoff of 1,454 NASA employees. Hardest hit of the agency's facilities will be the Marshall Space Flight Center in Huntsville, Ala., where 700 will be scratched from the payroll. And reports from recent industrial aerospace meetings indicate the absence of those once ubiquitous recruiting teams.

 NASA officials are now engaged in a series of meetings to review the direction of the space effort and revise spending plans. A spokesman at NASA headquarters says the administrators will be considering new operating plans for every program except Apollo.

This is traditionally the time of year when work starts on the next budget. Says an official: "We're in a difficult spot; we should be working on the fiscal 1969 budget right now but won't be able to get to it until we can settle on the effect the 1968 appropriation will have."

#### For the record

Crystal ball. While American manufacturers as a whole anticipate an 8% increase in 1968 sales over this year, electronics manufacturers look to a 6% rise, a Mc-Graw-Hill survey finds. The fall survey of preliminary plans for capital spending reveals that electronics firms plan to hike their capital spending for new plants and equipment 4% in 1968, against a 5% increase by all of American business. The electronics industry anticipates a 4% increase in the prices it will have to pay for new plants and equipment next yearone point less than industry as a whole. But spending for new plants and equipment would be cut back the same 0.4% in the event of a tax increase or surcharge as for other industries. Some reasons for electronies' relatively less optimistic expectations than other industries: the belief that the Government will reduce spending in general and NASA programs in particular, and the feeling of some executives that they had better be prepared to pay for overexpansion in 1966 and 1967. That overexpansion was due to the anticipation of booming color television sales which failed to materialize.

Hot gem. Sapphire crystals grown in a molten solution now can be pulled out looking as if they have been extruded, says Tyco Laboratories Inc. The Waltham, Mass., company, using a proprietary process, apparently can control temperature at specific points in the molten solution. The new technique, developed by A.I. Mlavsky, Tyco vice president, and Harold E. LaBelle, staff scientist, apparently controls the temperature in the melt so closely that crystals emerge in almost any simple shape. Sapphires coming out of Tyco's furnace in early production are nearly flat enough for use as an integrated circuit substrate-and, unlike standard substrates, wouldn't require lapping and polishing. Funding Tyco's research is the Air Force Materials Laboratory at Wright-Patterson Air Force Base, Davton, Ohio.

Laser group. The Electronic Industries Association's board of governors has approved the establishment of a group serving laser manufacturers [Electronics, Oct. 16, p. 26]. The EIA earlier had been uncertain about whether to form a full subdivision on lasers or a committee on laser engineering -and while it deliberated, 31 laser manufacturers formed their own Laser Industry Association. Now that the EIA also has a laser group, it's planning to appoint a committee made up of laser manufacturer representatives who will work out the scope and structure of the group. James Secrest, executive vice president of EIA, says he foresees no competition between the two groups and expects "a certain amount of cooperation and exchange of information."

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Fig. 3 Standard Class 77 Relay in Socket with printed circuit

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Fig. 4 Standard Class 77 Relay mounted in a panel for solder connected wiring.

Fig. 5 Special Class 77 Relay with printed circuit terminals Fig. 6 Standard Class 77 Relay with special mounting bracket

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Electronics | November 13, 1967

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Do you have a tough cleaning problem that FREON can solve? Write Du Pont, Room 5623, Wilmington, Del. 19898. (In Europe, write Du Pont de Nemours International S.A., FREON Products Div., 81 route de l'Aire, CH 1211 Geneva 24, Switzerland.)

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BETTER THINGS FOR BETTER LIVING ... THROUGH CHEMISTRY

# **Washington Newsletter**

## November 13, 1967

College dropout: classified research	Dismayed by the mounting opposition of faculty and students to on- campus secret research for the military, the Pentagon plans to henceforth assign only unclassified projects to universities. Of the approximately \$300 million of defense research being conducted at universities, only about 8% is classified. It's expected that this work will either be declassi- fied or transferred to private industry or Government labs. However, John Foster, director of defense research and engineering, wants to retain some top university scientists as individual consultants on secret projects.
Cox takes new line on CATV's role	The wall of FCC opposition to CATV continues to crumble. Federal Communications Commissioner Kenneth Cox appears to be switching sides, making majority opinions favoring CATV petitions more of a likelihood. Softening his position in recent speeches before CATV regional meetings, Cox acknowledged that technological advances are outmoding the five-channel ceiling he once strongly backed. He asked the cablemen to consider offering programs without commercials—his solution to the copyright problem. Cox suggested that CATV operators charge additional fees for nonbroadcast services such as telemetering and opinion polling.
Bioengineering plan is dropped by NIH	National Institutes of Health director James A. Shannon is being realistic. Because the White House is cutting back nonmilitary spending he won't request extra funds for biomedical engineering next year, despite earlier plans for a new bioengineering division [Electronics, July 24, p. 50]. Shannon hopes that industry—particularly electronics and aerospace —will take the initiative and develop new medical equipment.
High-speed modem goal of five firms	Five firms have contracts to develop prototype 9,600-bits-per-second modems (modulator-demodulators) for competitive testing by the Defense Communications Agency as early as next spring. Standard mili- tary modems now operate at 2,400 bits per second, though several 4,800- bits-per-second systems have been developed. The military services want capacity boosted to cut the error rate, speed communications, and reduce costs: some leased lines cost the Pentagon \$30,000 a month. The high- speed modems would be used primarily for digitized voice communica- tions. At work on prototypes are Lincoln Laboratory and IBM for the Air Force; Bell Labs and Honeywell for DCA; and the Codex Corp. for the National Security Agency. Several other companies are working on the high-speed modems on an in-house basis.
McNamara approach to outlast him	No matter when Defense Secretary Robert S. McNamara leaves his post —and there's a growing conviction that he wants to get out some time next year—there'll be no significant change in the McNamara approach to budgeting and contracting. In the seven years he's held office, longer than any other Secretary of Defense, McNamara made systems analysis

## Washington Newsletter

and cost-effectiveness keystones of his policy in budgetary and contracting matters.

It's understood that McNamara would like to resign soon after the new defense budget is completed and submitted to Congress next January. But President Johnson is expected to persuade him to stay on until the critically important November, 1968 election. A Washington newspaper quoted McNamara directly as saying he does plan to quit "some time" next year.

The White House is putting out feelers on the idea of a Department of Communications. It would include the Department of Transportation, the Federal Communications Commission, and key communications groups within the Department of Defense, the Office of Emergency Planning and the General Services Administration.

Insiders say Transportation Secretary Alan S. Boyd, raised to cabinet level status only this year, wants to expand his domain and cover broader areas, making his department similar to communications ministries in other nations.

ARM guidance unit set for production

**Cabinet status** 

for communications?

Martin unit to build Rada test hardware

#### December date set for total package bids on destroyer

Mounting aircraft losses due to North Vietnamese antiaircraft fire—both conventional and missile—have moved the Pentagon to put the air-toground Standard ARM, a radar-homing missile, on the top-priority list. A go-ahead has been given IBM for a production run of the target identification and acquisition system (Tias), the ARM's guidance unit.

The order comes less than a year after General Dynamics received the ARM prime contract and only a month after the completion of flight tests [Electronics, Sept. 4, p. 54]. The ARM will replace the Shrike as the prime Air Force and Navy air-to-ground missile. The Tias, to be carried aboard the aircraft, is built around the IBM 4 pi computer.

Martin-Orlando will get an okay from the Army within the next month to start producing the first test hardware for the Random Access Discrete Address (Rada) system, an automatic dial radio network for tactical communications. Under a new contract covering third-phase development of the secure gear, Martin will build three user-to-user Rada sets for local area calls, plus a retransmission unit for calls within the system but beyond the range of the basic unit.

Request for proposals will go out to industry early in December for the first combat ship to be designed by industry rather than the Navy. The new class of highly automated destroyers, known as DX for destroyer experimental, will be procured as a total package, an approach that combines design, development, production and maintenance of a ship in one contract. Primary function of the DX will be as an antisubmarine craft, but antiaircraft missiles may be added later. A large number of ships will be built, enough to warrant setting up an automated shipyard for series production.

The Navy doesn't plan to develop any new weapons or electronics systems for the DX, but will incorporate systems under development that will be ready for the fleet by 1974. The contractor will select and integrate all systems and will be named by May, 1969.


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A-B Type J hot molded variable resistor rated 2.25 watts @ 70°C. Available in single, dual, and triple units. Standard total resistance values from 50 ohms to 5 megohms. Special resistance values and tapers can be supplied. Widely used throughout the process industries, the Foxboro Model 62H Universal Controller is a highly dependable precision instrument. During the years of painstaking development, Allen-Bradley engineers worked closely with Foxboro to provide a potentiometer having unusually high resistance values, which would provide the precise performance required.

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ations inherent in wirewound controls. Furthermore, Allen-Bradley Type J potentiometers are—for all practical purposes—noninductive, permitting their use throughout the frequency spectrum.

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#### **Burroughs Corporation**

#### November 13, 1967 | Highlights of this issue

# **Technical Articles**

#### Delay line speeds r-f testing page 94

A simple system electrically lengthens one path of a heterodyning test set to produce a different frequency. The unit reduces the time required for device tests while maintaining the same accuracy, range and sensitivity of the single-frequency heterodyne setup normally used for such tests.

Special report: The technology of gallium arsenide page 105

#### Electronics



Because of its better characteristics at high frequency and high temperature, gallium arsenide is the most promising compound semiconductor material around. Even more important than its use in such conventional devices as transistors and integrated circuits is its application in light-emitting diodes or in bulk-effect devices such as the Gunn-effect oscillator or the limited space

charge accumulation device. In this 32-page special report, 18 experts have prepared 17 articles that describe the state of the technology of gallium arsenide. The subject is divided into three major areas: materials, devices, and advanced technology. For the cover, photomicrographers at Texas Instruments Incorporated have magnified a slice of gallium arsenide, symbolic because some of the major work that still remains to be done is in the purification of crystalline material.

Suitcase-size memory for longer space trips page 138

A portable memory that dissipates only 3.5 watts has been developed for the Air Force. It is the first of what could be a whole family of digital equipment, each member of which dissipates so little power it can be battery-powered easily. To reduce power consumption, the new memory uses pulse techniques and metal oxide semiconductor transistors. Potential applications range from space travel to education.

#### Coming November 27

- Designing a transmission line by computer
- Using integrated operational amplifiers
- Avionics goes digital with a new VOR system
- Chirp improves communications

### **Delay line speeds r-f testing**

It electrically lengthens one path of a heterodyning test set to produce a difference frequency; the system is basically simple and reduces the time needed to measure transmission characteristics

By Frederick F. Rogers Western Electric Co., North Andover, Mass.

Measuring transmission characteristics of radiofrequency devices, traditionally a time-consuming task, can be speeded with a broadband, high-loss measurement test set developed by the Western Electric Co.

The unit has the range, accuracy, and sensitivity of a single-frequency heterodyne system, but without that system's complexity. And, unlike conventional swept systems, it doesn't need two signal sources. A delay line creates the difference frequency necessary for heterodyning, and thereby eliminates the need for the complex synchronizing circuits and mechanisms normally employed to keep the difference frequency constant.

Called the Incremental Heterodyne Frequency (IHF) test system, the set is capable of measuring insertion losses, return losses, and voltage standing wave ratio.

#### Against the tide

As a general rule, increases in the range and accuracy of r-f devices have demanded increases in the complexity of the systems used to test them. The application here of delay-line techniques, long used for making phase measurements, bucks this trend. The resulting instrument is simple and cuts the time needed to test an r-f device with wide dynamic and broad frequency ranges. In one trial,

#### The author



Frederick Rogers is an engineering associate at the Merrimac Valley Works of the Western Electric Co. He joined the company, the manufacturing arm of the Bell System, in 1957, and has since worked on microwave communications systems. a developmental model of the IIIF system operated over bandwidths of 0.5 and 1 gigahertz at test frequencies of 6 and 11 Ghz; the system's dynamic range was 35 decibels.

The set's test signal is derived from a single, swept-frequency source. The signal is split into two paths, one ( $\Lambda$ ) connected to a mixer by a delay line, the other (B) coupled directly to the mixer. The path with the delay line is therefore electrically longer, as in diagram at top of page 95.

An attenuator is used to drop the signal in test path B at least 20 db below the level in the other path. In a heterodyning system, it should be noted, the amplitude of the mixer output is directly proportional to the magnitude of the weaker signal. In this case, test results are carried via path B.

A second attenuator in the same path establishes a reference level on a readout device—usually an oscilloscope. Once the reference level is set, the r-f device to be tested is substituted for the attenuators. The mixer's output, a pulse-modulated signal, contains the test results.

At any instant in time, the swept signal can be regarded as a single frequency. Since the source is a linearly swept frequency generator, it produces, in effect, a series of instantaneous frequencies.

#### Delays make a difference

If a single set of instantaneous frequencies in the two paths is represented by  $f_1$  and  $f_2$ , respectively, and the mixer output frequency by  $f_3$ , the values of  $f_1$  and  $f_2$  arriving at the mixer at any time are a function of the sweep rate, r (the rate of change of frequency in hertz/second). If  $d_1$  and  $d_2$  represent the delays in paths A and B, respectively, and  $d_1 > d_2$  and  $f_1 < f_2$  when r is positive, then  $f_2 = r(d_1 - d_2) + f_1$ 

The desired mixer output  $(f_3)$  is the difference frequency  $f_2 - f_1$ . If the delay and sweep rate are

constants, then  $f_3$  is also a constant and can be expressed as  $r(d_1 - d_2)$ .

This equation is easier to use if it's stated in terms that represent the variables controlling the mixer output frequency. Letting D equal the difference in delay  $(d_1 - d_2)$ , W/T the sweep rate r (where W equals the sweep bandwidth and T the sweep time), and F the mixer output frequency  $f_3$ , yields the equation F = DW/T.

The graph at the right shows some F versus T curves for various values of D with W constant; both computed and measured values are given. Difference errors-about 10% in this case-can be attributed to: imprecision in the tuned-frequency voltmeter used to measure the mixer output frequency; the linearity of the ramp generator operating the swept-signal source; the flyback time required for static discharge of the glass envelope on the swept-signal source tube (backward wave oscillator); dispersions caused by the components of path A; frequency modulation caused by any or all of these factors; and the operator's inability to accurately measure the sweep times. Any improvement in these areas would, of course, improve the quality of the test data, though a 10% error isn't objectionable in production-line testing-the system's intended application.

#### **Proof positive**

The incremental heterodyne approach is essentially a time-domain, frequency-domain concept. In the simplified test circuit shown in the diagram above, detectors x and y represent the mixer input. The peaks at the centers of the photograph on page 98 are wavemeter pips that are caused by frequency modulation of the swept source and that originate before the signal reaches the beginning of paths A and B. But the scope presentation indicates that the pips traveling through the paths arrive at the Continued on Page 98

ATT <sub>2</sub> setting (r-f) (db)	ATT <sub>3</sub> setting (i-f) (db)	Scope sensitivity (mv)	Readout (mv)					
8	50	20	66					
10	48	20	66					
12	46	20	68					
15	43	20	68					
20	38	20	68					
25	33	20	68					
30	28	20	68					
35	23	20	68					
40	18	20	68					
45	13	20	68					
<b>46</b>	12	20	68					
47	11	20	68					
48	10	20	70					
50	8	20	70					
Dynamic range 12-47 or 35 db								
r-f power at ports A and B								
A: @ 11.27 Ghz, power = $-5.4$ dbm								
B: (a) 11.27 Ghz, power = $-21.4$ dbm (ATT <sub>2</sub> set at 31 db) B: (a) 11.27 Ghz, power = $-10.6$ dbm (ATT <sub>2</sub> set at 10 db)								



Signal delay. Intermediate frequency is established by electrically lengthening one signal path with a delay line.



Predictable i-f. Two parameters can be controlled to establish the intermediate-frequency output from the mixer. In this graph, the i-f was calculated over a range of sweep times at various fixed values for the delay. Actual measurements differed from computed values by only 10%.



Test setup. In an arrangement to determine the system's dynamic range, attenuators  $ATT_2$  and  $ATT_3$  are changed by identical amounts and the output is read on an oscilloscope. As indicated in the table, the scope's output remains constant with input signals ranging from 12 to 47 db.

#### The competition

There are a variety of conventional circuits that can be used to measure the insertion loss, return loss, and vswr of r-f devices. The simplest, the single-frequency, singledetection measuring circuit, A at right, uses a point-by-point technique in which the frequency of the signal source is manually switched each time a measurement at a new frequency is required. Insertion and return losses are measured with a square-law detector. The configuration A measures insertion losses; the second circuit, B, measures voltage standing wave ratios and return losses.

The simpler circuit has a signal source, a variable r-f attenuator, an r-f detector, and readout device. In the other circuit, a slotted line, a precision termination, and a shorting plate are added.

Combo. Another popular configuration, the modulated single-frequency, single-detection measuring circuit, C at right, also employs point-by-point, square-law-detection techniques. As it combines both of the previous circuits-plus a modulator and a demodulatorit can measure all three characteristics.

The single-frequency heterodyne measuring circuit, diagram D, is useful for extended range measurements. But two signal sources are needed, and they have to be adjusted for every frequency change. The circuit has three sections, of which one-the beat frequency oscillator section-resembles the first circuit discussed here minus the detector and presentation device. The second section-the test signal oscillator-resembles a combination of the first and second circuits, and the third consists of a mixer, an intermediate-frequency preamplifier, an i-f attenuator, an i-f amplifier, a detector, and a presentation device.

The signal strength levels at the mixer of this system must be maintained throughout all measurements, and the difference frequency between the TSO and BFO sections must be kept constant.

The difference frequency between the TSO and BFO is called the i-f and is usually much lower than either of the oscillator frequencies. Amplification of the i-f increases sensitivity and extends the measurement range.

Modifications. In all of these approaches, the need to switch frequencies wastes time. The signal source can be replaced in any of these circuits with a sweeper-an oscillator whose output frequency is systematically varied many times per second from a start to a stop frequency through a band of frequencies. But severe frequency modulation of the i-f and misalignment of the i-f with respect to the narrow pass band of the i-f amplifiers can occur if the sweepers aren't synchronized.

The circuits can be further modified with hybrid junctions to eliminate the slotted line for return loss and vswn measurements. Adding these junctions boosts the circuits measurement capabilities, but makes for greater complexity.

Technique		easu	ires	Measure- ment		Data accumulation		Comments
	IL	RL	vswr	Range (db)	Toler- ance (db)	Point- by-point	Con- tinuous (swept source)	
Incremental heterodyne frequency	×	x	x	70	±0.2	_	x	Needs only one source for he- terodyning; simple presenta- tion device such as scope can be used.
Single-frequency, single detec- tion	x	x (a)	x (a)	30	±0.2	×	(b)	Limited range but simplest cir- cuit. Require manual fre- quency adjustment.
Modulated single-frequency, single-detection	x	x	x	50	±0.2	x	(b)	Amplification of modulating fre- quency increases system's sen- sitivity and extends useful range
Single-frequency heterodyning	x	x	x	70	±0.2	x	(c)	Most complex but most ver- satile of these systems. Two sources and synchronizing are essential.

(a) Slotted line must be added to measure vswr and RL(b) Signal source can be swept to reduce test time and eliminate point-by-point measurements.

There are no serious implementation problems. (c) Sweeping of signal sources provides time-saving benefits, but complex synchronizing circuits and mechanisms are needed to keep frequency difference constant.





Time lag. Pips created by frequencymodulating signal sources and introduced into test system at the start of the two signal paths arrive at the mixer at different times.



Typical output. Test results are confined to the envelope of the oscilloscope display. Shown here is the mixer output signal after the i-f has been filtered and amplified.



**Final form.** Test set modified for laboratory use contains both an automatic calibrating path and a phase shift control. The signal through the path with attenuators  $ATT_2$  and  $ATT_3$  is alternately compared with the signal in the test path and the one in the electrically lengthened path. The scope's reference point is thus always available for comparison.

#### continued from page 95

detectors at different times, the actual time difference being equivalent to the delay difference between paths A and B, less about a 10-nanosecond delay caused by the scope's dual trace preamplifiers.

The displacement between two identical frequencies proves that two different frequencies originating at the swept-signal source are present at the detectors at the same time.

The number of points sampled by the test set depends on the mixer output frequency, and the only useful information in the output is contained at the peaks and valleys of the modulated signal's envelope. While this is satisfactory for a production-line instrument, a laboratory system should be able to measure abrupt losses occurring between the sample points.

The IHF system gains this capability when a 360-

degree phase shifter, shown above, is added to the measuring circuit. The phase shifter enables the operator to move any point on the envelope through as much as a one-cycle change and to investigate the test results at that discrete sample point.

Measurements made with the new circuit have been correlated to within a tenth of a decibel with a conventional sweeper test set. Losses of more than 50 db have been observed with sensitivities of 1 to 2 db per centimeter on an oscilloscope.

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#### Circuit design

# **Designer's casebook**

# Integrated circuit drives neons directly

#### By G.V. Wintriss

Tyco Labs, Waltham, Mass.

Neon glow-lamp indicators can be turned on and off by low-voltage integrated circuits, even though the circuits cannot handle the relatively high voltages needed to drive the lamps. The voltage incompatibility, an old problem, is simply and inexpensively sidestepped by not applying neon voltages directly to the 1c's.

Assume the neon lamps,  $N_1$  and  $N_2$ , have a breakdown voltage of 71 volts and require a maintaining voltage of 60 volts at  $V_1$ . The indicator supply voltage at  $V_2$  is a pulsating direct current that can turn the lamps on and off with each cycle of line power.

Now consider the instantaneous voltages applied to  $N_1$  and  $N_2$  with the 1 output of the 1c flip-flop high—say 4 volts. When  $V_2$  rises to 70 volts,  $N_1$  has 70 volts applied to it while  $N_2$  sees only 66 volts, the difference between  $V_2$  and the voltage at the 1 output.

As  $V_2$  continues rising to 71 volts,  $N_1$  fires,  $N_2$  remains off, at 67 volts. As soon as  $N_1$  fires, it begins drawing current and  $V_1$  drops to the maintaining voltage of 60 volts. Now,  $N_1$  is on, but  $N_2$  cannot turn on since 60 volts is below that needed for breakdown.

When the supply voltage cycle causes  $V_2$  to drop below 60 volts,  $N_1$  extinguishes; it turns on and off with each cycle of  $V_2$  as long as the IC's 1 output is



**Driver circuit.** Since  $N_1$  and  $N_2$  are connected in parallel, only one lamp can fire at a time.

Designer's casebook is a regular feature in Electronics. Readers are invited to submit novel circuit ideas, packaging schemes, or other unusual solutions to design problems. Descriptions should be short. We'll pay \$50 for each item published.

high. Likewise, if the 0 output is made high,  $N_2$  fires each cycle and  $N_1$  remains off.

The breakdown voltages of  $N_1$  and  $N_2$  do not have to be precisely matched. The circuit operates properly when the difference between the firing voltages of  $N_1$  and  $N_2$  is less than the difference between the IC's high and low output voltages. This requirement is met with conventional lamps, such as the NE-23. The operating life over which they continue to meet the requirement is predictable.

# Ring radiator succeeds in mobile vhf radios

#### By G.W. Horn

Industria Radio-Elettrica Telecomunicazioni, Trieste, Italy

A hula-hoop antenna performs well at very high frequencies if the loop is made resonant and if the open waveguide, formed between the loop and its ground plane, is adequately dimensioned. In contrast, the conventional configuration of this type of antenna—a directional discontinuity ring radiator (DDRR)—has very poor radiation efficiency at vhf but is usually good at medium and high frequencies.

The open waveguide of the standard design [Electronics, Jan. 11, 1963, p. 44] becomes so small at frequencies above 50 megahertz that the electromagnetic field cannot be launched into space efficiently. Also, the high-impedance and grounded ends of the loop are close together, inducing outof-phase r-f voltages in the feed point. Bandwidth is reduced and the voltage standing-wave ratio deteriorates seriously at vhf.

It was found that the DDRR becomes efficient at vhf when the loop is 56 electrical degrees in diameter. The open waveguide becomes perfectly symmetrical and the cross-section of the radiating slot is made twice as large as in the conventional design.

For best results, a half-wave loop is made to resonate at the operating frequency by connecting a small, well-insulated trimmer capacitor between ground and the point of highest impedance in the loop. To compensate for the reactive loading effect



New ring. Efficiency of radiator antenna (left), is improved at very high frequencies by adding capacitor, eliminating the discontinuity gaps (center), and making ground-plane diameter, D', twice loop diameter D (right).

of the capacitor, the loop's diameter is reduced to about 52 electrical degrees. The correct termination is found by moving the feed point through a distance shown as X in the first sketch.

The bandwidth is determined by the diameter, d, and the height above the ground plane of the rod used to form the loop.

Field intensity measurements of such half-wave DDRR's show that they are not only superior to the conventional DDRR, but have 1-decibel better gain than the standard quarter-wave verticle dipole. Radiation directivity was as good as the theoretical omnidirectional pattern given in the 1963 report. A 3-db jump in the directivity pattern is caused by the discontinuity at Y. The length of Y is not critical, and the jump in field intensity can be eliminated by reducing Y to zero, as in the second sketch, closing the loop.

Several half-wave DDRR's have been made for

# Relay actuator produces one-hour pulses

By David L. Pippen

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Long pulses at slow repetition rates for timing applications are generated by a free-running pulser consisting of solid state components and a relay. Pulse widths and rates from 20 milliseconds to several minutes can be obtained by changing the values of the resistors and capacitors that govern time constants.

The component values allow pulse width to be adjusted from approximately 50 to 150 msec, at a nominal repetition rate of one pulse per second. Stability of the repetition rate is within 2% over normal operating temperatures. mobile radio applications. The dimensions for the 156 to 17-Mhz band are: D = 10 inches

$$D = 10$$
 inches  $d = \frac{13}{13}$  inch

$$u = \frac{1}{32} mcn$$

h = 1% inch  $X = \frac{1}{3}$  inch, for 50 ohms impedance

This antenna's ground-plane diameter is approximately 2D.

The antenna is well-suited to vhf/f-m use, acting as a sharp bandpass filter centering on the operating frequency. It rejects adjacent-channel interference much better than conventional dipoles. Receiver signal-to-noise ratio is also better when the loop is grounded through the vehicle frame, to drain off static charges.

The low profile of the antenna, when mounted on an automobile roof, makes for low wind resistance and therefore less signal flutter, and inconspicuous appearance.

When a direct current is applied to the circuit, capacitor  $C_1$  charges through resistors  $R_3$  and  $R_4$ until the firing point of the unijunction transistor,  $Q_1$ , is reached. This time delay, adjustable with  $R_3$ , establishes the repetition rate.

After  $Q_1$  is triggered, the silicon controlled rectifier, scr<sub>1</sub>, fires and energizes relay K<sub>1</sub>, closing the normally open contact K<sub>1D</sub>. Now, power is applied through R<sub>2</sub> and R<sub>5</sub>, charging C<sub>2</sub>; this time delays the pulse width and is adjusted with R<sub>2</sub>. The charging of C<sub>2</sub> fires the second unijunction transistor, Q<sub>2</sub>, and scr<sub>2</sub>.

The low impedance of  $scn_2$  in its on state shunts  $scn_1$  so it returns to its off state. At the same time,  $K_1$  returns to its de-energized position. The pulsewidth-determining circuit is now fully recovered and waits for the next triggering signal from  $Q_1$ . Several low-priced, high-sensitivity scn's tried in this circuit did not function adequately, since they sustained conduction with less than 5 microamperes anode current. The on-state resistance in the  $scn_2$  must be low enough to assure  $scn_1's$  turning



off when it is shunted.

The two 20-volt zener diodes,  $D_1$  and  $D_3$ , keep the voltage in the timing circuitry constant. Diode  $D_2$  suppresses the relay coil's inductive kick, preventing erratic double-pulsing. Resistor  $R_1$  limits the anode current of  $scn_2$  to a safe value. As noted in the diagram, a double-pole, doublethrow relay results in two complementary outputs. If output rise and fall times of less than approximately 20 msec are required, reed relays can be used. A reed relay's response time is less than 2 msec and has a longer life than a relay.

#### Push-pull capacitors multiply input voltage

#### By Charles D. Brock and Leslie E. Johnston

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**Supply-voltage drops** can be kept to a minimum, as required in some solid-state systems, when the back-biasing voltage for switching transistors is supplied by a circuit that functions as a d-c to d-c noninductive autotransformer.

The circuit's design principle can also be extended to full-wave transformation, from the halfwave configuration shown. Stages can be cascaded to provide voltage multiplication with higher efficiency than other noninductive d-c to d-c converters. And if voltage regulation is needed in an otherwise unregulated system, the direct-current autotransformer can do the job.

The principle is best explained by visualizing the circuit as based on a double-pole, double-throw switch. When the switch is in position 1, capacitor  $C_1$  is charged to the input voltage. Moving the switch to position 2 discharges  $C_1$  into capacitor  $C_2$ . Since the negative terminal of  $C_2$  is at the positive input potential,  $C_2$ 's positive terminal is raised to a higher potential. Therefore, the output voltage is higher than the input voltage. The rise in potential at  $C_2$  depends upon its capacitance with respect to  $C_1$ . Returning the switch to position 1 initiates another cycle.

In the actual circuit, the cycles are initiated continuously by the relaxation oscillator formed by unijunction transistor,  $Q_1$ . Its output triggers flipflop  $Q_2$  and  $Q_3$ , whose outputs in turn are amplified



Charge-discharge. Two capacitors are switched so that the first discharges into the second, raising the potential of the second at its positive terminal.



Autotransformer. In actual circuit, the switching is controlled by a unijunction transistor,  $Q_1$ , and transistors  $Q_8$  and  $Q_9$  replace the switch contacts.

by  $Q_4$  and  $Q_7$  and  $Q_5$  and  $Q_6$ .

The two remaining transistors,  $Q_8$  and  $Q_9$  take the place of the switches  $S_C$  and  $S_D$  in the explanatory circuit. They are turned on alternately so that  $C_1$  repeatedly charges and then discharges into  $C_2$ , producing the high-voltage output. The circuit shown was assembled to test the concept. With a 20-volt input, the output was 35.5 volts at 80 milliamperes and the efficiency was 60%. The output can be efficiently regulated by providing feedback from the output to control the amplifiers in either the charge or discharge circuit.

#### Transistor replaces supply in CRT amplifier

#### By Phil Salomon

Pasadena City College, Pasadena, Calif.

Adding a transistor to a conventional paraphase amplifier eliminates the need for a negative power supply and improves the balance of the outputsignal amplitudes.

Paraphase amplifiers are widely used as balanced deflection devices for electrostatic cathode-ray tubes. They provide outputs of opposite polarity and equal gain when signal currents of equal magnitude flow in the two tubes,  $V_1$  and  $V_2$ , shown in the conventional circuit. Quiescent current for each tube is supplied from the cathode resistor,  $R_{K}$ .

Ideally,  $R_{\kappa}$  acts as a current source—it holds the quiescent current steady when operating conditions vary. Therefore,  $R_{\kappa}$  is returned to a negative power supply,  $-E_{cc}$ , so that the potentials of the



Hybrid amplifier. Transistor and bias resistor network prevent voltage variations from affecting current balance.

tubes' cathodes are held near ground. An analysis of the equivalent circuit shows that  $R_{\rm K}$  must be large, since

$$R_{k} = \frac{100}{P} \left[ \frac{r_{p} + R_{L}}{\mu + 1} \right]$$

where P is the percent of unbalance between the

# The many facets of gallium arsenide

Already the stuff of varactors, light emitters, injection lasers, and microwave diodes, GaAs is reaching a point of development where it can win a place in almost all electronic applications

Introduction by Stephen E. Scrupski, senior associate editor

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- III. Vapor-phase growth by James J. Tietjen and Leonard R. Weisberg
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#### Devices

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- V. Integrated circuits by Edward M. Mehal

# Gallium arsenide begins to keep some promises

Always just around the corner, this versatile compound semiconductor is finally challenging silicon and germanium in a host of uses, and is tackling some special applications all its own

By Stephen E. Scrupski

Senior associate editor

As multifaceted in application as it is in its erystal structure, gallium arsenide is on the verge of challenging germanium and silicon for the over-all championship of the semiconductor field. But the challenger has been brought along slowly, and rather than immediately risking a direct confrontation with its rivals in the transistor field, it may begin by outflanking them in light-emitting and bulk-effect applications.

New developments in the use of germanium and silicon as semiconducting materials are trailing off; it would not be an oversimplification to say that most of the work with these materials is now directed toward finding new ways to arrange devices, deposit insulation, and form photomasks. But materials research in the field of gallium arsenide is on the upswing. The conferences covering basic materials—electrochemical and metallurgical society meetings, for instance—are being inundated with papers on compound semiconductors.

Of these compound semiconductors, gallium arsenide is receiving the lion's share of attention. In terms of processing refinements, it's far ahead of the others. In the same terms, it's still far behind silicon, but silicon can't do all that GaAs does.

GaAs is today the most versatile of all semiconducting materials; the articles following will emphasize this. Varactors, transistors, microwave diodes, light-emitting diodes, injection lasers, bulk microwave power sources, negative resistance, amplifiers, and bulk-effect integrated circuits—all are possible with gallium arsenide.

Of these, only varactors, Schottky-barrier microwave diodes, light-emitting diodes, and injection lasers are being made in quantities that even approach conventional "production" levels. But advanced gallium-arsenide devices are waiting in the wings—in fact, they're being demonstrated in laboratory models.

#### Lifting the lid

And when the bulk-effect devices finally hit the market, a new world will open up, one in which functional integrated circuits are designed by shaping the material and by chemical processing. With such circuits, now being built at Bell Telephone Laboratories by Masazuku Shoji and at Standard Telecommunication Laboratories, Harlow, England, by C. P. Sandbank, we can forget about such individual components as transistors.

The key factor in gallium arsenide's success up to now is a single property—a higher electron mobility than either silicon or germanium. Gallium arsenide also has a wider band gap, a feature suggesting high-temperature uses. But Arthur Uhlir of Microwave Associates, author of the section on varactors in this report, sums up the present situation: "High-temperature characteristics, though they were once given as the main reason for research in gallium arsenide, have not been a very significant factor in the application of any galliumarsenide device."

In fact, as Uhlir notes in his article, the one GaAs application that has anything to do with temperature involves cryogenic freezing just a few degrees above absolute zero. This is the cooled parametric amplifier, which uses a gallium-arsenide varactor in a low-noise receiver.

The main obstacle to fuller exploitation of GaAs is its relative impurity compared with germanium and silicon. These elemental semiconductor mate-



**Conventional amplifier.** Output balance of a conventional paraphase amplifier requires a large cathode resistor,  $R_k$ , and a negative power supply. At the right is the equivalent circuit.

signal outputs  $e_{o1}$  and  $e_{o2}$ ,  $\mu$  is the amplification factor of each tube,  $r_p$  is the tube's plate resistance, and  $R_I$ , is the load.

A silicon npn transistor is more efficient as a current source in the cathode circuit than a resistor. It requires relatively low voltage, and the current supplied does not vary when the voltage across the transistor varies. Therefore, current balance is better and  $-E_{cc}$  is not needed. The difference in output signals is less than 1% when load resistors,  $R_{I,a}$  are well matched. Resistors  $R_1$  and  $R_3$  form a bias-resistance network that can easily be redesigned, using conventional transistor circuit design methods, to suit similar applications.

# Oscillator waits for switch to quiet down

#### By Peter T. Rux

Corvallis, Ore.

**Slight delays** in turn-on and turn-off times, built into a low-speed oscillator in the form of an extra transistor, enables digital circuits to be checked at a rate of only 2 hertz. The operator can watch the logic operate a visual indicator, confident that outputs will not be false because of contact bounce in the control switch or because he switched off the oscillator in the middle of a cycle.

The circuit is at rest with the switch,  $S_1$ , in the stop position. Transistors  $Q_1$  and  $Q_3$  are on and

the output is at  $V_{CE(SAT)}$ . The base of the extra transistor,  $Q_2$ , is also at  $V_{CE(SAT)}$ , so it is off. When  $S_1$  is moved to the run position,  $Q_2$  remains off until capacitor  $C_2$  is sufficiently charged through resistors  $R_1$  and  $R_2$  to turn on  $Q_2$ 's base. The delay, indicated in the waveform diagram, blocks any spikes caused by contact bounce.

When  $Q_2$  turns on, it acts with  $Q_3$  as an astable multivibrator. Diode  $D_1$  and  $R_3$  let the output rise sharply. The oscillator rate is controlled by the time constants of  $(R_1 + R_2)C_2$  and  $R_4C_1$ .

Returning  $S_1$  to the stop position stops the oscillator immediately if  $Q_2$  is in the off position. Transistor  $Q_2$  cannot turn back on, since  $Q_1$  is on and the oscillator remains in the rest condition. Alternatively, if  $Q_2$  is on when  $S_1$  is switched to stop,  $Q_1$  is off and the oscillator completes the cycle without being affected by switch contact bounce. At the end of the cycle,  $Q_2$  turns off and  $Q_1$  keeps it off.





#### GAF x-ray film assures quality welds in Sun Shipbuilding's revolutionary high-performance gas-turbine freighter

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The speed and accuracy of GAF radiography has actually helped improve welding techniques, making for



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greater construction efficiency. This has enabled Sun to launch its precedent-making ship in record time. Designed for long-term charter to MSTS, the vessel's combination of high speed (in excess of 25 knots) and large deck area, could well set a trend for use of gas-turbine power.

The need for quality welds, in thicknesses ranging up to several inches, virtually necessitates GAF radiography for unusual construction problems. For this job, Industrial "A" film was selected.

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rials can be zone-refined in a vacuum after growth, but there's no second step in GaAs purification.

This problem of impurities means, for example, that GaAs transistors can't be built with a spread between the doping in the emitter and the doping in the collector, though a wide spread would mean a better device. Silicon starts out with a lower impurity level and it achieves the spread, but designers of gallium arsenide devices cannot begin with a high impurity level and get the spread by heavily doping the emitter because there is a solubility limit on dopants. P-type impurities have higher solubilities, but the engineers want an n-type emitter for an npn transistor because the electron's mobility is about 20 times that of the mobility of the hole.

#### **Invasion routes**

Light-emitting diodes are just now beginning to find their way into optical encoders, where their solid state reliability offsets their high initial cost.

One of the next big areas to be invaded by GaAs devices will be that of displays—numerical readouts. Gallium arsenide diodes emit light in a direction perpendicular to the junction, so the longer the device, the wider the light beam. This contrasts with the injection laser, which emits light in the plane of the junction in a narrow, flat beam. To produce visible outputs, gallium arsenidegallium phosphide diodes must be used, since gallium arsenide diodes emit light in the infrared at about 9,000 angstroms, just outside the visible spectrum.

Once the visible wavelength is obtained, it's a simple matter to arrange the diodes in the form of a segmented readout and to form various numerals by pulsing different diodes. No such readouts are on the market yet, but it's only a matter of time before they find use in small instrumentpanel displays.

Injection lasers, too, seem to be on the verge of fulfilling their early promise. Gallium-arsenide coherent emitters are slated for use in sensing obstructions on railroad tracks [Electronics, Oct. 30, 1967, p. 25], and in an Air Force short-range communications link and an intrusion alarm system that may be used in Vietnam [Electronics, Oct. 30, pp. 44].

#### Sandwich

Still another use for gallium arsenide is being studied by researchers at Carnegie-Mellon University. A heterojunction transistor with a germanium base and collector and a gallium arsenide emitter is being developed there for microwave operation.

The two materials are compatible in basic crystal lattice dimensions and in thermal coefficients of expansion, and the researchers are using the wide band gap of GaAs as a high potential barrier at the emitter-base junction to reduce the injection of carriers from the base back into the emitter. This reduction allows much heavier doping in the base; with resistance lowered, the frequency response is boosted.

#### GaAs works

Like silicon and germanium, gallium arsenide owes its semiconducting properties to the structure of its energy bands—the conduction band, where electrons flow, the valence band, where holes flow, and the gap between the two bands.

At room temperature, not many electrons have enough energy to jump the gap and thus contribute to current flow. But if the material is doped with certain impurity atoms, electrons can be added at energy levels just below the conduction band, where it takes little energy to boost them up.

These impurities are called donors because each atom donates an electron, making the material n-type. Similarly, the material can be made p-type by introducing acceptor impurities that insert empty energy levels just above the top of the valence band, where electrons can be boosted out of the valence band into them, leaving holes behind.

Once free in their bands, electrons and holes can move under the influence of an electric field. Current depends on the mobility of each type charge carrier, and this mobility, the ratio of carrier velocity to electric field, has the dimensions of centimeters per second divided by volts per centimeter, or  $cm^2/volt$ -sec.

The electrons are normally more mobile than the holes. The material's conductivity, the reciprocal of its resistivity, is the product of three factors: the carrier concentration, usually stated in carriers/ cm<sup>3</sup>; the mobility; and the elementary electron charge.

In the valleys. As will be described in the first of these articles, the gallium-arsenide conduction band has two valleys separated by a small energy gap. Electrons in the lower-energy valley have a higher mobility than those in the upper-energy valley, and when the voltage across a sample of gallium arsenide is raised, an increasing number of electrons are excited into the upper, lowermobility, valley. Resistivity, therefore, increases as voltage increases.

When the electrons in the upper valley outnumber those in the lower, the material takes on a differential negative resistance. This effect, however, is unstable, and an accumulation of charges, or domains, starts to form.

Layers. Any deviation in charge concentration in the material will cause the formation of a charge accumulation layer and a depletion layer. At a point where the electron density suddenly decreases because of, say, nonuniform doping, the field will increase and the electrons will move more slowly. (On the negative resistance portion of the characteristic, increased field produces decreased current.)

At the edge of the depletion layer nearest the negative electrode, electrons traveling toward the positive electrode will tend to accumulate and the accumulation layer will grow; at the edge nearest the positive electrode, electrons will tend to move away from the depletion layer faster than they move into it and the depletion layer will grow.

The layers move across the sample at the average electron drift velocity, about  $10^7$  cm/sec, until they reach the positive electrode, where they disappear. New accumulation and depletion layers then appear, and the process repeats itself.

#### Materials I

# Some special features make the difference

#### By David Richman

RCA Laboratories, Princeton, N.J.

The similarities between gallium arsenide and the elemental semiconductors, germanium and silicon, are important but hardly surprising—all three have the same basic crystal structure, zinc-blende and diamond, that accounts for their semiconducting properties. But gallium arsenide's place as potentially one of the most important semiconductor materials rests on the differences.

A gallium-arsenide p-n junction, for example, is an efficient light emitter; germanium and silicon diodes are not.

For germanium and silicon, the conduction-band minimum occurs at a momentum different from that of the maximum of the valence band. But in GaAs, the minimum and the maximum occur at the same momentum—a feature that's the basis for the injection laser and the light-emitting diode.

Gallium arsenide thus is a direct-gap material; an electron can make the transition directly from the conduction band to the valence band without changing momentum and can give up its energy in the form of a quantum of light.

In germanium and silicon, indirect-gap materials; electrons cannot move from one band to the other with the same momentum and they must give up most of their energy to the lattice in the form of lattice vibrations, or phonons.

#### Mobility

Two other significant differences—gallium arsenide's greater energy-band gap and the greater mobility of electrons in its conduction band minima give the material its higher temperature and higher frequency capabilities.

Electron concentration and mobility are often used to judge the purity of a sample of GaAs. Pure material has about  $1 \times 10^{15}$  electrons/cm<sup>3</sup> and a mobility greater than 8,000 cm<sup>2</sup>/volt-sec. Less pure material has higher electron concentration and mobilities in the 5,000 cm<sup>2</sup>/volt-sec. range. In pure material, the mobility increases as temperature decreases; mobilities of over 100,000 cm<sup>2</sup>/volt-sec have been measured at temperatures of about 77°K.

GaAs is the basic material of Gunn-effect devices because there are two valleys in its conduction band, one of which is at a slightly higher energy level-about 0.36 electron-volt-than the other. Electrons in the lower-energy valley have much greater mobility than those in the other valley, though the energy difference between the two levels is so small that strong electric fields give the electrons enough energy to move from one minimum to the other. When the upperhigher energy-valley is more densely populated than the lower, the material exhibits a differential negative resistance; as the voltage is increased, more electrons move up to the lower-mobility band and the current decreases, causing bulk instabilities such as the Gunn effect.

#### Impurity

The maximum purity attainable with present GaAs crystal-growing methods is about  $10^{15}$  impurity atoms per cubic centimeter. Since GaAs has about 4.4 x  $10^{22}$  atoms/cm<sup>3</sup>, this limit corre-

Energy-band properties						
Property	Ge	Si	GaAs			
Band gap (ev)	.67	1.106	1.40			
Type of band gap	Indirect	Indirect	Direct			
Calculated maximum electron mobility at 15° C (cm <sup>2</sup> /v-sec)	3,950	1,900	11,000			
Calculated maximum hole Mobility at 25° C (cm <sup>2</sup> /v-sec)	1,900	425	450			
Electron effective mass	.55	i.1	.043071			
Intrinsic electrons at 25° C (cm <sup>-3</sup> )	2.4x1013	1.5x10 <sup>10</sup>	1.4x106			
Intrinsic resistivity at 25° C (ohm-cm)	46	2.3x10 <sup>5</sup>	3.7×10 <sup>s</sup>			



**Crystal** structure. Gallium arsenide crystallizes in a zinc-blende structure, where each atom bonds with its four neighbors. Major crystal plane designations are at left.

sponds to about 2 parts in  $10^8$ , or 0.02 parts per million. Stated in another way, the best GaAs is about 99.999998% pure when it leaves the crystal-growth apparatus, or, as often designated, it has seven 9's purity.

Germanium and silicon, the purest elements made today, have one or two 9's higher purity than GaAs because they can be zone refined. The purest GaAs is made by vapor deposition.

Gallium arsenide can be made either n or p by adding impurity atoms during crystal growth or by diffusion. An element from group II—zinc, for instance—will substitute for gallium in the lattice and, since it has one less electron than gallium, will create holes in the valence band and make the crystal p type. An element from group VI such as selenium will substitute for arsenic and contribute one additional electron to the conduction band, thus making the crystal n-type.

The group IV atoms are amphoteric dopants-

that is, they may act either as donors or acceptors. At low concentrations, they occupy only one gallium or arsenic—of the lattice sites, but as their concentration increases, they begin to occupy the other type of lattice site. Silicon in GaAs, for example, is a donor at low concentrations, displacing arsenic, but becomes an acceptor, displacing gallium, in heavily doped n-type material.

The ease with which the impurities release their extra electrons or holes to the conduction or valence bands depends on the position of the impurity energy level in the band gap. So-called shallow dopants lie close to the conduction or valence bands, and it takes little energy to ionize them. Deep donors or acceptors lie near the middle of the gap and aren't fully ionized at room temperature.

#### Latticework

Gallium arsenide owes its basic semiconducting properties to its crystal structure—a zinc-blende-



Energy bands. Comparison of gallium-arsenide and germanium structures shows differences that account for GaAs light-emission and bulk effect properties.

Matchups			
Property	Germanium	Silicon	Gallium arsenide
Melting point (°C)	936	1,420	1,238
Solid density (gr/cm <sup>3</sup> )	5,328	2.329	5.316
Lattice constant (Å)	5.658	5.430	5.654
Distance between nearest neighbors (Å)	2.45	2.35	2.45
Atoms per cm <sup>3</sup>	4.42 x 10 <sup>22</sup>	5.0 x 10 <sup>22</sup>	4.43 x 10 <sup>22</sup>
Vapor pressure at melting point (atm)	10-9	10-7	1
Specific heat (cal/gm)	.074	0.167	.086
Dielectric constant	15.7	12	11.1
Thermal coefficient of expansion (°C <sup>-1</sup> )	6.1 x 10 <sup>-6</sup>	2.33 x 10 <sup>-6</sup>	5.93 x 10-6

type lattice. Each gallium atom is surrounded by four arsenic atoms at the corners of a tetrahedron, and each arsenic atom is surrounded in the same way by four gallium atoms. Germanium and silicon crystalize in a diamond lattice with all sites occupied by the same type—germanium or silicon —atoms.

With germanium or silicon, all 111 faces of the crystal have the same chemical reactivity, since the atoms are the same when viewed from any direction. But in the zinc-blende structure, all 111 faces present alternating layers of gallium and arsenic atoms, and opposite planes have different surface atoms—gallium in one direction and arsenic in the other. As might be expected, the two surfaces react differently to chemical treatment.

The near equality of the lattice constants—the spacing of the unit cells in the crystal—and the thermal coefficients of expansion are the features that permit the epitaxial growth of germanium on gallium arsenide, a useful method in forming heterojunction transistors.

#### Materials II

## Crystal holds key to the future

#### By J.M. Woodall

International Business Machines Corp., Yorktown Heights, N.Y.

**"To achieve better,** more uniform results, it is clear that better materials are needed." This comment, found all too often at the conclusion of an article about gallium-arsenide devices, emphasizes the increasing importance of crystal growth techniques.

Epitaxy—the atom-by-atom growth of a layer of GaAs on bulk crystal—has proved a success, but the attainment of more reliable, more uniform, and longer-lived devices requires improved methods of bulk crystal growing. The future of epitaxial devices depends on the quality of the bulkgrown substrates.

Device-quality GaAs is grown by freezing the molten material at 1,242°C into a single crystal structure free of chemical contamination and structural defects. Besides producing high temperatures and promoting single-crystal growth, the apparatus used must prevent the melt from dissociating. The arsenic in the melt has a dissociation pressure of one atmosphere, and without this external vapor pressure it would leave the melt, thereby chemically unbalancing the crystal structure. Either this pressure must be provided, or as in a newer method, the melt can be encapsulated, and an inert gas used to block the escape of the arsenic.

#### Two paths to growth

Two methods of crystal growth are now popular, the Czochralski and the horizontal Bridgman (the vertical Bridgman method is not as convenient for use with semiconductor materials). In the first method, a seed crystal is inserted in the melt and then slowly withdrawn so that the melt forms a meniscus and solidifies as it's raised above the molten surface, repeating the same single-crystal structure as the seed. Typical high-purity results of



Bridgman crystal. The shape taken is that of the fabrication boat.

the Czochralski method are about 4 x 1015 electrons per cubic centimeter and an electron mobility of about 7,000 cm<sup>2</sup>/volt-sec.

In the horizontal Bridgman technique, the melt is slowly passed through a temperature gradient spanning the melting point, causing the melt to progressively solidify into a single-crystal structure. Although the melt need not be seeded to produce a single crystal, growth in a preferred crystal-plane direction requires seeding. The Bridgman method yields GaAs with about  $5 \ge 10^{14}$  electrons/cm<sup>3</sup> and a mobility of 8,000 cm<sup>2</sup>/volt-sec.

#### Seals and capsules

There are two versions of the Czochralski method. The first employs a sealed system to contain the arsenic vapor, while the other, more recently developed, form encapsulates the melt in a viscous material.



Czochralski crystal. Cylindrical shape results from twisting as crystal is lifted from the melt.

In the first version, the system must be held above 614°C to maintain the proper arsenic pressure, and all parts except the melt must be made of materials that don't react with arsenic vapor.

Nonreactive high-temperature seals and feedthroughs are sometimes used to raise the seed crystal from the melt. In a more popular method, the seed is held and lifted by iron parts that are encapsulated in quartz and magnetically coupled to an external lifting mechanism. The melt is usually heated with a radio-frequency coil, while the rest of the sealed quartz system is heated by a resistance furnace to maintain the arsenic pressure.

With the Czochralski method, one can observe the crystal during growth and immediately verify whether single-crystal growth has begun. But this advantage the technique has over the Bridgman is offset by the problem of uniformly lifting the seed out of the melt with magnetic coupling or



Seed lifting. Three basic methods of Czochralski single-crystal growth mechanisms: sealed system with magnetic lifting (left); nonreactive feedthrough seals and mechanical lifting (center); boric-oxide encapsulant (right).



Passing through. In the horizontal Bridgman method, the GaAs melt is passed through a temperature gradient and single-crystal material forms on the cooler end.

special seals and feedthroughs. Because the motordriven apparatus working through magnetic coupling or special seals may have small speed variations, the crystal cannot be grown at a microscopically uniform rate and the dopants tend to collect, often in periodic striations. In the Bridgman method, the motor-driven apparatus runs at a more uniform speed because it's simpler and operates at room temperature.

In the other version of the Czochralski method, the need for arsenic vapor is eliminated altogether by ensapsulating the melt in a viscous nonreactive material such as boric oxide,  $B_2O_3$ . Little arsenic escapes from the melt when an inert gas such as argon is applied outside with a pressure of one atmosphere.

The crystal is grown by dipping the seed through the  $B_2O_3$  and then withdrawing it at a uniform rate. As the grown crystal passes through the seal into the inert atmosphere, it picks up a thin layer of  $B_2O_3$ . This method thus allows the use of more stable seed-lifting mechanisms and should result in the growth of more perfect crystals.

#### **Boatloads**

The horizontal Bridgman method generally produces higher-purity material and a more uniform crystal. As with the Czochralski, the system is sealed and contains one atmosphere of arsenic vapor. A boatload of molten GaAs traveling through a temperature gradient forms a single crystal in the shape of the boat.

Neither the melt nor the solid crystal should adhere to or be constrained by the boat. This puts some restrictions on the choice of boat material—a factor of no importance in the Czochralski method.

One advantage of the Czochralski method is that it affords a wide choice of crucible materials; the major concern is the chemical reactivity, not, as in the Bridgman method, whether the melt wets the crucible. Aluminum-nitride, boron-nitride, and aluminum-oxide crucibles have all been successfully employed in growing high-purity GaAs.

Also, a special graphite crucible for Czochralski growth offering a desirable temperature gradient and good r-f coupling for heating has recently been used to grow dislocation-free GaAs—the substrate required for epitaxial growth of dislocation-free material.

With a recent development, the horizontal Bridgman method is also capable of producing dislocation-free material. This material, seeded crystals grown near the 310 direction in sand-blasted quartz boats and doped with  $2 \times 10^{18}$  tin atoms/cm<sup>3</sup>, has yielded the best room-temperature laser devices made so far, even though GaAs crystals grown in quartz are generally contaminated with silicon from the quartz at a concentration of 1 part per nillion or  $10^{17}$  atoms per cm<sup>3</sup>—a high impurity level by semiconductor standards.

Although 1 part in  $10^6$  silicon content doesn't affect laser devices, most other applications couldn't tolerate that level of impurity. But with modifications in the growth apparatus and additions of Ga<sub>2</sub>O<sub>2</sub> to the melt—to suppress the reaction of silicon with the melt—this contamination can be reduced to about 1 part in  $10^8$ .

Crystals grown this way are generally semiinsulating—having resistivities near 10<sup>8</sup> ohm-cm —but heat treatment produces high-mobility GaAs with resistivities between 1 and 1,000 ohm-cm depending on the temperature and length of heat treatment.

#### For more on . .

Crystal growth: L.G. Bailey, Transactions of Metallurgical Society of AIME, March 1967, p. 310.

## An all-in-one process for building junctions

#### By James J. Tietjen and Leonard R. Weisberg

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A hard fact of life is that the production of a good crystal of bulk gallium arsenide takes us only one step towards achieving a practical GaAs device. The p-n junctions must also be formed, and this is often the most difficult part of the task.

Alloying and diffusion methods used successfully with germanium and silicon often aren't good enough for GaAs devices. The high temperatures required can bring contamination, movement of defects in the crystal, or a decrease in carrier lifetimes.

With vapor-phase epitaxy, the device can be prepared in one continuous process. In this method, dopants are introduced as a single-crystal material is being epitaxially grown so that the p-n junctions are formed as the device takes shape, eliminating high-temperature processing after growth. Since the dopants are in a gaseous state, they can be introduced or removed at nearly any desired rate.

#### Gases for GaAs

The vapor-phase growth technique (for details, see the following article) is novel in that it uses gaseous reagents, such as arsine (AsH<sub>3</sub>) and, if a gallium-arsenide phosphide diode is being made, phosphine (PH<sub>3</sub>) for the supply of gaseous phosphorus. The independent introduction of these elements involves only a simple cracking of the gases. This eliminates the time delays of such epitaxial systems as the AsCl<sub>3</sub>, in which the reagents must slowly reach equilibrium before full control is possible.

Precise control of doping is shown in the photo of the varactor diode. Here a GaAs  $n^+$ - $n^-$ - $p^+$ structure is epitaxially grown in one continuous process on a GaAs substrate. Each layer is only 10 microns thick, yet junction planarity and uniformity is evident—no smearing of the junction boundaries can be seen. In the finished structure, the n-region has an electron concentration in the low  $10^{15}$ /cm<sup>3</sup> range and a mobility of about 6,000 cm<sup>2</sup>/volt-sec despite the presence of heavily doped layers on either side. Thus there was little problem with autodoping—the undesired diffusion of dopants from one portion of the device to another.

This technology has already produced several GaAs and  $GaAs_{1-x}P_x$  devices with properties never achieved before—varactors, injection lasers, light-emitting diodes, and Gunn diodes.

More than a thousand GaAs varactors have been prepared with vapor-phase techniques, and they exhibit the best combination of breakdown voltage (greater than 50 volts) and cutoff frequency (greater than 150 Ghz at -6 v bias) yet reported. Furthermore, the diodes are extremely uniform, with little variation in electrical characteristics in different regions of the wafer. The junctions are quite abrupt, with an n-factor equal to 0.49 (the theoretical value of n for an abrupt junction is 0.5).

By vapor-phase growing  $GaAs_{1-x}P_x$  alloys with



**Planar junction.** Varactor fabricated by vapor-phase method has narrow uniform junction.

 $p^+$ -n<sup>+</sup> junctions, several hundred injection lasers emitting visible light at room temperature have been fabricated, the only such devices yet reported. One laser operating at 4.2°K is the brightest electro-luminescent source ever prepared. Others emitting visible light in a continuous-wave mode at 77°K have also been built.

#### Multilayer

A major problem with GaAs and GaAs<sub>1-x</sub>P<sub>x</sub> lightemitting diodes is that much of the light given off is reabsorbed by the diode itself. To minimize this, a phosphorous-rich layer is placed above the p-n junction to act as a window for the light to pass through. This multilayer structure would be difficult to build with ordinary fabrication procedures, but is easily prepared with vapor-phase technology. Such a diode has provided a brightness of 135 foot-lamberts at a current density of 10 amps/cm<sup>2</sup>. For a Gunn diode,  $n^+ \cdot n^- n^+$  layers are vaporgrown in one continuous process with the  $n^-$  region as thin as 1 micron. This again demonstrates the absence of autodoping effects. Using such a structure with a 2.5-micron-thick  $n^-$  region, a Gunn oscillator has operated in the transit-time mode at 40 Ghz, the highest frequency reported for this kind of operation.

The same type structure with an  $n^-$ -layer 100 microns thick has provided 143 watts of pulsed power at 2.2 Ghz.

#### For more on . . .

Vapor phase growth: J.J. Tietjen, J.A. Amick, Journal of the Electrochemical Society, July 1966, p. 724. Epitaxial varactor diodes: J.J. Tietjen, G. Kupsky, H. Gossenberger, Solid State Electronics, 1966, p. 1049. Epitaxial Gunn devices: R.E. Enstrom, C.C. Peterson, Transactions of the Metallurgical Society of AIME, March 1967, p. 413.

#### Materials IV

# Film-making: a delicate job performed under pressure

#### By Kenneth L. Lawley

Bell Telephone Laboratories, Murray Hill, N.J.

The growth of a single-crystal material on a substrate of a similar material is the key step in fabricating many semiconductor devices. The epitaxial process produces material not attainable with bulk crystal or diffusion processes. Because of the low temperature of these processes, pure crystals can be grown, allowing the full realization of the high electron mobility possible with gallium arsenide.

Gallium-arsenide films are harder to grow than elemental semiconductors because there are no suit-



Water carrier. In the water-vapor epitaxial method, bulk gallium arsenide is used as the source.

able gallium compounds that are gaseous at room temperature and atmospheric pressure. Both the arsenic and gallium gaseous compounds must therefore be supplied to the reactant system under closely controlled conditions.

The three deposition methods generally applied use:

• bulk GaAs as a source and water vapor or a chloride as a transport medium;

• pure gallium as a source for the gaseous gallium compound and arsine or arsenic trichloride for the arsenic;

condensed GaAs in liquid gallium.

#### Pure and simple

The simplest of these methods is the first. The bulk material is exposed to an oxidizing gas, and the products of this reaction serve as the gaseous source from which gallium arsenide is deposited. Water vapor, hydrogen chloride, or chlorine diluted in hydrogen are usually used as the oxidizing gas, though other halides have been tried. Water vapor reacts with the GaAs crystal at about 1,050°C to form hydrogen, arsenic vapor and the volatile suboxide—or vapor form—of gallium. This reaction is reversed at a lower temperature about 1,000°C—in another part of the reactor, where a GaAs film is deposited on the GaAs substrate.

Mainly because of impurities transferred from the source crystal and contamination caused by the high temperatures necessary for deposition, the minimum donor impurity attainable so far is 2 to  $5 \times 10^{15}$ /cm<sup>3</sup> with mobilities exceeding 7,000 cm<sup>2</sup>/ volt-sec.

Doped films can be grown from source crystals doped with selenium and tellurium. However, silicon and the p-type dopants, zinc and cadmium, aren't transferred. Films can be grown at rates of 10 to 60 microns per hours on the preferred 111 plane.

When chlorides are used, the reactions at the GaAs source take place at 800° to 850°C—the temperature at which the chlorine or chloride reacts to form gallium trichloride and arsenic vapor. At the substrate temperature—about 750°—mono-chloride, formed from trichloride, combines with the arsenic vapors to form a GaAs film.

Chloride-produced films are less pure than watervapor-grown material, probably because most impurities in the feed gas and source crystal are too easily transferred to the film as chlorides. Common donors and acceptors are readily transported from source to film in this system. Growth rates are comparable to those attainable with water vapor, but the preferred growth plane is 100.

#### Purer

In the second major epitaxial method, the vaporphase, a gaseous gallium compound is formed and mixed with an arsenic compound. Gaseous gallium trichloride is generated by passing hydrogen chloride or chlorine over gallium in the reactor system. The chlorine can come from a tank or from the decomposition of arsenic trichloride.

The arsenic and gaseous gallium compounds are mixed in the reaction chamber and passed over the GaAs substrate at from 750° to 800°. Deposition occurs when the gaseous mixture is thermodynamically unstable with respect to the substrate—a condition believed attributable to the gallium monochloride-arsenic gas reaction.

This technique can yield high-purity films (donor impurities about  $10^{15}$ /cm<sup>3</sup>, mobility about 6,000 to 7,000 cm<sup>2</sup>/volt-sec) on semi-insulating or highly doped substrates. Hydrogen sulfide and selenide have been used to prepare n-type layers, and dimethyl zinc or zinc metal to prepare p-type on a variety of planes.

#### Purest

The purest films produced by chemical vapor deposition have been grown with the technique that uses a condensed source of GaAs in liquid gallium. The source mixture is presynthesized



Gaseous gallium. Vapor-phase gallium is obtained by passing hydrogen chloride over it; arsine is used for the arsenic.



Skin effect. A GaAs skin is formed on the pure gallium source to serve, in turn, as the source of gallium arsenide.

before deposition by exposing liquid gallium to arsenic trichloride. If the arsenic vapor pressure exceeds the decomposition pressure of the GaAsin-gallium solution at the operating temperature (about 850°C), a GaAs skin forms on the gallium and serves as the source of GaAs. After this skin is formed, a substrate is exposed to the source reaction products at about 750°C.

This method has been used by British researchers to grow films with donor impurity concentrations of less than  $10^{15}$ /cm<sup>3</sup> and room-temperature mobilities of about 9,000 cm<sup>2</sup>/volt-sec. The maximum electron mobility at the low temperature of about 56°K is about 140,000 cm<sup>2</sup>/volt-sec, and growth rates are about 10 to 20 microns per hour.

Other methods haven't received the attention given chemical vapor techniques, but the coevaporation of arsenic and gallium and liquid regrowth are currently being reinvestigated.

#### For more on . . .

Water vapor method: K.L. Lawley, Journal of Electrochemical Society, March 1966, p. 240.

Arsine vapor phase method: J.J. Tietjen, J.A. Amick, ibid., July 1966, p. 724.

GaAs in gallium: D. Effer, ibid., October 1965, p. 1020.

# Getting dopants on the beam is a long-term project

#### By Kenneth E. Manchester

Sprague Electric Corp., North Adams, Mass.

The technique of implanting dopants in crystals of gallium arsenide with a high-energy beam of ions is still at an early stage of development. Holding out the promise of alternative methods for building devices requiring limited processing temperatures and a precisely shaped doping profile, ion implantation can eventually complement existing diffusion method for doping semiconductors.

In the field of light-emitting gallium-arsenide devices, the technique would make it relatively easy to build the junctions close to the surface; this would enhance light-emitting properties by reducing absorption before the light leaves the surface. Diodes made with implanted dopants in the laboratory have emitted about the same levels of light as diffused diodes.

There are two major obstacles to practical ionimplanted GaAs devices: our ignorance of the details of the implantation process and impurities in



Implanted outputs. Ion-implanted diode with 80 kev zinc ions delivers sharp pulse (lower trace) in response to input (upper trace).

the GaAs substrates. However, the considerable efforts being made to understand ion implantation in silicon should carry over into the area of gallium arsenide.

#### Experimental diodes

At the Sprague Electric Corp., zinc has been implanted in n-type GaAs, and tellurium in p-type GaAs; ions have been accelerated to 40 and 80 kiloelectron-volts, a relatively low energy level, to produce shallow junctions.

Two types of diodes were formed by this process, each doped with 80-key zinc ions. One was annealed in an argon atmosphere for 20 to 30 minutes at 650°C, the temperature above which arsenic tends to leave the GaAs surface—a thermal etching effect. The other was annealed for 10 to 15 hours at the same temperature in argon. The diode surfaces were protected with a layer of silicon dioxide to further prevent thermal etching.

The first diode had an essentially abrupt junction and a sharp reverse breakdown. A good thermally diffused diode with a similar background carrier concentration would have a similar junction but a more gradual reverse breakdown.

The second diode had a graded junction, a higher referse breakdown voltage, and a relatively high forward resistance. The rate at which the impurity concentration decreased away from the junction was about  $10^{20}/\text{cm}^3$  per centimeter—about 1/100th the grading coefficient of a typical diffused graded-junction device.

The low grading coefficient indicates a long tail on the implanted distribution due to deeply penerating ions. This tail may be the result of either a channeling phenomenon occurring during implantation—where ions travel down open channels in the GaAs lattice—or a diffusion process during the long annealing period.

#### Comparisons

Both diodes emitted light at 9.2 microns when forward biased, but the abrupt-junction diode showed the higher power output and efficiency. The best implanted diodes have exhibited power outputs of about 2 milliwatts per ampere forward current. Good diffused-junction GaAs diodes also produce about 6 mw/amp output.

Researchers at the Ion Physics Corp., Burlington, Mass., report that sulfur implantations in ptype GaAs with ion energies of 400 to 800 kev through a sputtered quartz film produce junctions 0.25 and 0.50 microns deep. Diodes made this way have characteristics similar to those of diffused structures. GaAs implanted at low substrate temperatures— 100°C or less—must be annealed to heal the damage caused by the impact of the high-energy ions and also to enable the injected atoms to move into the positions of active acceptors or donors. Not only isn't this annealing process fully understood, but the results of GaAs annealing don't appear to be as consistent as those achieved with silicon.

#### For more on . . .

Implants in GaAs: P.E. Roughan, K.E. Manchester, Bulletin of American Physical Society, 1967, p. 140.

Materials VI

### An almost ideal substrate

#### By C.P. Sandbank

Standard Telecommunication Laboratories, Harlow, England

With all its potential for generating microwave power, emitting light, or multiplying frequencies, one of gallium arsenide's most important jobs may be one in which it does nothing. In its semiinsulating form, it merely isolates GaAs devices from one another in a monolithic integrated circuit, or isolates a single GaAs device from a heat sink to raise power.

The material has already played this passive role in experimental IC's, high-power devices, and domain-originated functional IC's—dofic's, but there is still room for improvement in the properties of the semi-insulating substrates.

Semi-insulating gallium arsenide has dielectric properties that provide excellent isolation from d-c to microwave frequencies while retaining a crystal structure that is an ideal substrate for the epitaxial growth of semiconducting GaAs. In fact, some of the best semiconducting GaAs has been deposited on GaAs substrates.

Semi-insulating gallium arsenide was first characterized at the Services Research Laboratory in Baldock, England, by C.H. Gooch, C. Hilsum, and B.R. Holeman. The first ingots actually appeared accidentally during a procedure that normally produces the semiconducting form.

Resistivity of intrinsic GaAs at room temperature is about 10<sup>8</sup> ohm-centimeters, corresponding to an intrinsic carrier density of about 10<sup>7</sup> carriers/cm<sup>3</sup>. The best epitaxial growth methods produce donor impurity levels of about 10<sup>14</sup> atoms/cm<sup>3</sup>—representing a resistivity of about 10 ohm-cm. To make higher-resistivity material, the donors must in some way be balanced by compensating acceptor atoms, a difficult task.

Several impurities—notably oxygen and copper can produce semi-insulating properties, but the best way to grow semi-insulating material was introduced by two Texas Instruments researchers, A.R. Cronin and R.W. Haisty. They found that when chromium was used to dope GaAs, the material behaved in a manner consistent with the mechanism that J.W. Allen of the Baldock facility originally suggested to explain the semi-insulating phenomena.

Allen realized that it was highly unlikely that the donor and acceptor impurities present in the ingot balanced exactly. He therefore postulated that shallow donor levels are compensated for by an access impurity that gives rise to a deep acceptor level near the center of the band gap. The acceptors contribute relatively few ionized carriers —holes with low mobility—at room temperature, Allen suggested.

Recently, D.R. Heath, P.R. Selway, and C.C. Took at Standard Telecommunication Laboratory, Harlow, England, identified this level in some chromium-doped ingots grown by the horizontal Bridgman process. They used measurements of photoconductivity to show that the acceptor level associated with chromium at room temperature is 0.79 electron volts from the conduction band and 0.64 ev from the valence band. It thus stands almost in the middle of the band gap.

Semi-insulating crystals with resistivities greater than the 10<sup>8</sup> ohm-cm level can now be consistently produced. This resistivity stems from the high density of traps, and from the fact that mobilities are normally much lower than those in the semiconducting n-type crystals. Typical electron-mobility values for the semi-insulating material lie between 200 and 2,000 cm<sup>2</sup>/volt-sec. Because the electrons are more mobile than the holes, they account for most of the small current flow.

#### Lab results

Semi-insulating GaAs has been deposited epitaxially by Haisty and P.L. Hoyt of TI, who obtained resistivities of up to 10<sup>5</sup> ohm-cm by doping with iron. And J. Franks and P.R. Selway of Standard Telecommunication Laboratory have made p-i-n diodes in which the intrinsic region was formed by the diffusion of chromium into n-type slices having an initial carrier concentration of more than 10<sup>16</sup> per cm<sup>3</sup>. Resistivities at the surface of the intrinsic layer were measured at 10<sup>8</sup> ohm-cm.

These results demonstrate the feasibility of integrated circuits in which the semi-insulating properties of the substrate are brought to the surface by a local diffusion of chromium to produce isolating channels in the semiconducting layer.

Devices I

### Off to a good start

#### By Arthur Uhlir Jr.

Microwave Associates Inc., Burlington, Mass.

For its first use in a practical device—the varactor diode—gallium arsenide was in the right place at the right time. In the late 1950's, makers of microwave systems needed low-noise parametric amplifiers and frequency multipliers that couldn't be built with other semiconductor materials.

The use of gallium arsenide for varactors in microwave systems is a reflection principally of quantitative features such as high electron mobility and retention of conductivity at 4.2°K liquid helium temperatures—a must for cooled, low-noise parametric amplifiers. In this respect, the varactor differs from more recent GaAs devices such as light-emitting diodes, lasers, and piezoelectric transducers, where the emphasis is on properties that are qualitatively different from those of silicon and germanium.

GaAs varactors have scored their biggest success in low-noise parametric amplifiers. Here they compete with silicon devices in uncooled appli-

Peak mobilities of 100,000 cm<sup>2</sup>/volt-sec have been achieved at the Standard Telecommunication Laboratory with semiconducting n-type GaAs vapor-deposited on semi-insulating GaAs by the arsenic trichloride-gallium process. Researchers at srL also report mobilities of 8,000 at room temperature (56,000 at 78°K) with n-type layers deposited from the liquid phase on semi-insulating substrates. The fact that n-type layers of GaAs can be grown on semi-insulating substrates simplifies the evaluation of the epitaxial process.

#### For more on . . .

First characterization: C.H. Gooch, C. Hilsum, B.R. Holeman, Journal of Applied Physics Supplement, 1961, p. 2069. First fabrication: F.A. Cunnell, J.T. Edmond, W.R. Harding, Solid State Electronics, 1960, p. 97.

Chromium doping: G.R. Cronin, R.W. Haisty, Journal of Electrochemical Society, 1964, p. 874.

Compensation effects: J.W. Allen, Nature, 1960, p. 403.

Epitaxial semi-insulating PaAs: P. Hoyt, R.W. Haisty, Journal of Electrochemical Society, 1966, p. 296.

Epitaxial semiconducting layers: J. Whittaker, D.E. Bolger, Solid State Communications, 1966, p. 181.

Domain-originated functional IC's: C.P. Sandbank, Solid State Electronics, 1967, p. 369.

cations and have the cooled field to themselves.

At room temperature, the higher electron mobility of GaAs yields a series resistance lower than that of silicon, and cutoff frequencies three or four times higher. This, however, doesn't result in a comparable drop in amplifier noise. For one thing, losses stemming from the relatively low mobility of holes in the p-type regions of the GaAs diode and from the finite conductivity of the cartridge metal reduce the cutoff-frequency advantage to a factor of about two—600 gigahertz against silicon's 300 Ghz. For another, high pumping frequencies are needed at room temperature to take full advantage of varactors with high cutoff frequencies.

When cost is no object, however, refrigeration will make parametric-amplifier noise negligible in comparison with noise from antenna feeds. It's far easier to design such an amplifier with a GaAs varactor than with silicon or germanium because only a few silicon or germanium devices will function at liquid helium temperatures, and those that will work have low-temperature electrical characteristics different from those at room temperature.

Gallium arsenide's low-temperature behavior has just one flaw: thermal conductivity—no bargain at any temperature—becomes even worse. This doesn't mean that the diodes are in any danger of burnout by pump power, but merely that they will heat up to some temperature, say 20°K, where the thermal conductivity is better but the noise worse.

For all this, the attainable noise temperatures are still remarkably low; in fact, the noise temperature of a parametric amplifier is often lower than that of a varactor.

#### Frequency multipliers

GaAs varactors haven't substantially penetrated the multiplier field. They are used to some advantage for output powers of 1 to 100 milliwatts at output frequencies above 20 gigahertz, where the high cutoff frequency dominates other considerations, but silicon is the universal choice at lower frequencies and higher powers. Among the reasons for this preference for silicon are higher yield for relatively large junction areas, better thermal conductivity, longer life, and lower cost.

An even more fundamental reason may be silicon's substantially longer minority carrier lifetime, a feature that, in a forward-biased p-i-n diode structure, permits the storage of a large amount of charge in the form of hole-electron plasma. This charge can be released rapidly across the depleted regions that form on either side of the plasma as bias is reversed. The degree to which this action can take place in GaAs varactors has never been thoroughly evaluated, but it is certainly much less than in silicon. Any hole-electron plasma in GaAs tends to decay through light emission, and perhaps even faster because of material imperfections.

In one circuit study, multiplier efficiency was directly related to carrier lifetimes in GaAs varactors having otherwise similar characteristics. (Short carrier lifetimes can be estimated from the ratio of capacitance to conductance for varied forward bias.)

Carrier lifetime is also a significant factor in parametric amplifiers, where the longer lifetimes of silicon diodes give wider bandwidth.

#### Tuning in

In tuning applications, however, lifetime appears to be a negligible factor. Yet GaAs varactors aren't widely used for electronic tuning of receivers, primarily because of the insufficient yields of highcapacitance diodes with junction areas substantially larger than those of parametric-amplifier varactors. However, material studies will almost certainly provide answers to the problems of low yield and high initial costs.

A factor of two in cutoff frequency, though important in a given circuit, can only add an octave of frequency to varactor-tuned receivers. This hypothetical octave band (which might today be 1-2 Ghz) would be at frequencies too high for silicon varactors but not for GaAs. Still higher frequencies will require digital tuning by p-i-n diodes.

An octave band in the ultrahigh-frequency or microwave regions points toward important future tuning applications for gallium-arsenide varactors. And GaAs varactors are the only devices for tuning circuits operating at any frequency at liquid helium temperatures.

#### Devices II

## Narrow field for bipolars

#### **By Hans Strack**

Texas Instruments Incorporated, Dallas

Any material that tries to invade silicon's home grounds—the transistor field—is in for a battle. Gallium arsenide stands alone in the Gunn-effect and light-emitting-diode areas, but present bipolar GaAs transistors don't measure up—either in price or performance—to comparable germanium and

silicon devices. However, they do have a chance to win a few encounters in the high-temperature field, where germanium and silicon won't work.

The major hurdle, as in other applications, is the starting material. A low solubility of impurities bars a wide range of doping concentrations from



Temperature effects. Common-emitter characteristics of GaAs bipolar transistor at -196°C, left, and at room temperature, right. Vertical calibration is 1 milliampere/division, horizontal is 1 volt/division; base current increases 0.1 milliamp with each step.

emitter to collector, and thus limits emitter efficiency and base spreading resistance.

In addition, it's difficult to measure the other material properties bearing on transistor operation, and difficult, with present processing methods, to do anything about changing them.

Although they have only partly fulfilled expectations, GaAs transistors have been a major factor in the development of other GaAs devices. Because of their dependency on material quality and fabrication processes, GaAs bipolar transistors are sensitive tools for the study of GaAs material and device technology.

#### Performance forecast

About 10 years ago, it was commonly predicted that GaAs transistors would bypass silicon and germanium devices in temperature and frequency performance because of gallium arsenide's wider band gap and higher electron mobility. Based on a maximum operating temperature of 100°C for germanium, engineers projected silicon transistors operating at up to 250°C and GaAs transistors at up to 450°C.

The highest operating frequency is related to the product of electron and hole mobility in the case of bipolar transistors, and to the majority carrier mobility with unipolar (field effect) transistors. Bipolar GaAs and germanium transistors lead silicon devices in this mobility factor; the two are equals at higher frequencies because the higher electron mobility of GaAs is offset by germanium's higher hole mobility and somewhat higher dielectric constant.

GaAs unipolar transistors should operate at frequencies roughly twice as high as the top levels for germanium unipolar transistors, which, in turn, should surpass those of silicon devices by about the same factor. The first GaAs transistors were fabricated from Czochralski-grown material. Reproducibility was very poor and current gains were low. Boat-growing led to better devices, but high current gain could only be achieved consistently after the introduction of vapor-phase epitaxial methods.

But the problems of relating material properties to device performance still remain; it isn't yet possible to define "good" transistor material, or even to influence critical parameters by changing growth conditions. The conveniently measurable properties of the material, such as dislocation density, mobility, and doping level, don't relate to transistor performance, although they are useful for basic material.

However, the recently applied cathodoluminescence technique may provide a means of selecting suitable GaAs material for device fabrication. In this technique. GaAs is bombarded with electrons that penetrate deep. From deep inside, the GaAs emits light related to such parameters as diffusion length and lifetime.

The influence of particular dopant elements on device performance is small compared with the effect of the starting material. Almost all transistors have been of the npn type because of the wide ratio of electron to hole mobilities—about 20:1 in GaAs.

The general difficulty in making GaAs transistors is that only two to three orders of magnitude concentration difference can be achieved between emitter and collector; with silicon transistors, the concentration difference runs to four or five orders of magnitude. In GaAs, the collector concentration is typically about 10<sup>16</sup>/cm<sup>3</sup>. At lower concentrations, thermal conversion of n-type to p-type material occurs, sometimes caused by fast diffusing acceptors such as copper. The solubility of electrically active donors in GaAs (the maximum



300°C 400°C High temperature. Common-emitter characteristics at 300°C, left, and 400°C, right. Calibration is the same as for curves at left.

doping concentration possible for the emitter) is about 2 to 3 x  $10^{18}$ /cm<sup>3</sup>. The base concentration consequently has to be kept between, say, 2 to 3 x  $10^{17}$ /cm<sup>3</sup> at the surface of the p-type base region. In contrast to donor solubility, the acceptor solubility is high, about  $10^{21}$ /cm<sup>3</sup>; this could allow high emitter doping, but pnp transistors are undesirable because of the low mobility of holes.

#### Base making

The techniques developed to fabricate base regions with the desired doping profile fall in three categories:

• Deep diffusion with subsequent etch-back of the p-layer to the required thickness of about 1 to 1.5 microns.

Diffusion through a mask such as silicon oxide, to reduce surface concentration and diffusion depth.

Epitaxial deposition of a uniformly doped p-type layer.

Because of the relatively high vapor pressure of arsenic over GaAs at the diffusion, temperature, special techniques have been developed for diffusions performed above 700°C. The GaAs slice is sealed in an evacuated quartz ampul together with the proper amount of dopant, and arsenic is added to reduce arsenic loss from the surface. Another way of preventing arsenic evaporation is to seal off the surface with a layer of either reactively sputtered silicon dioxide or silicon dioxide deposited by thermal oxidation of tetraethylorthosilicate (TEOS). Unlike silicon, which has its silicon dioxide, gallium arsenide doesn't have a natural oxide to protect it.

The TEOS method produces a better film in terms of density and leakage than sputtering does. When the TEOS, heated in the presence of an oxygen-rich atmosphere, breaks down, the silicon links with the oxygen and deposits on the GaAs wafer. Since the operational temperature is 450°C, there is no problem of arsenic leaving the GaAs surface.

#### Performance

The most striking characteristic of GaAs bipolar transistors is that actual cutoff frequencies are always below the values calculated from mobility and device geometry. Transistors with high d-e current gains generally have low cutoff frequencies, and vice versa. Also high d-e gains appear strongly dependent on temperature, while low d-e gains do not.

For example, transistors with common-emitter current gains of about 200 don't operate above 50 megahertz, devices with intermediate current gains of 20 have cutoff frequencies at about 500 Mhz, and devices with cutoff frequencies near 1 Ghz don't exhibit d-c gains higher than 10. Thus, the product of common-emitter d-c current gain and current-gain cutoff frequency seems to be about 10<sup>4</sup> Mhz.

However, transistors with intermediate current gain and intermediate cutoff frequency can be used over a wide temperature range. Devices with a d-e current gain of about 10 have been operated in a liquid helium environment (4.2°K) and at temperatures up to 500°C without the gain varying by more than  $\pm 20\%$ .

The explanation for this discrepancy between theroetical and observed frequency performance is the presence in GaAs of traps that limit electron mobility. The nature of these traps is only partially understood. While deep donors such as oxygen are known to lurt transistor performance, deep acceptors such as iron have been known to improve it.

Applications for high-temperature transistors are limited to those environments in which cooling systems for silicon devices are impractical or unfeasible. Possible jobs would be in test equipment for deep oil wells and in gear for space probes near the sun.

#### Stability

Before GaAs can be considered for high-temperature circuits though, serious stability problems must be solved. All GaAs transistors suffer from instability when operated over long periods of time, even at room temperature. At temperatures of 400°C to 500°C, the possibility of a rediffusion of emitter and base regions must be considered. Although individual transistors have been operated over periods of several thousand hours in a 300°C ambient environment with little degradation, these results are not reproducible with all transistors.

#### Devices III

## Fast-moving FETs can outpace rivals

#### By Hans Becke

RCA Electronic Components and Devices Division, Somerville, N.J.

**Gallium-arsenide** bipolar transistors may have a hard time trying to replace their silicon counterparts, but the story may be different in the case of field effect transistors. Gallium arsenide enters the race with at least one big plus—a far higher electron mobility than silicon's. This feature can mean more gain at higher frequencies to go along with gallium arsenide's higher temperature performance.

The frequency response of a field effect transistor is primarily determined by the mobility of the majority carriers—electrons in an n-channel device and GaAs has a 5:1 edge over silicon on this score. Two recent developments, a very-high-frequency device using silicon nitride as a gate insulator, and a microwave device using a Schottky barrier as the gate, demonstrate the potential of GaAs FETS. Since both depend on channel carrier mobility for high-frequency performance, they have the same frequency response limits.

Both are made in planar form and can be easily incorporated into integrated circuits. Such transistors, working with other new gallium-arsenide devices, could herald a new era in IC's.

The silicon-nitride, insulated-gate FET, developed at the Radio Corp. of America, has provided 22 decibels gain at 200 megahertz though it wasn't Studies of the stability of GaAs have produced a better understanding of the degradation of transistors, light-emitting diodes, and microwave devices. But failure-mechanism studies of GaAs devices have just scratched the surface of the problem.

#### For more on. . .

Comparisons with Ge, Si: D.A. Jenny, Proceedings of the IRE, June, 1958, p. 959.

Cathodoluminescence studies: D.B. Wittry, D.F. Kyser, Journal of Applied Physics, 1967, p. 375.

Iron doped transistors: H. Strack, Gallium arsenide—Institute of Physics and Physical Society Conference Series No. 3, p. 206.

designed with a high-frequency geometry. Silicon devices with the same geometry give only 16 db gain at the same frequency [Electronics, June 12, 1967, p. 82].

The device channel was made with the hydride vapor technique of J. J. Tietjen and J. A. Amick of RCA Laboratories [details on p. 115]. A thin layer of lightly doped n-type GaAs was epitaxially grown over a p-type substrate and covered with a layer of silicon nitride. After the  $Si_3N_4$  was masked and the source and drain sites were etched, tin was diffused into the source and drain sites to provide heavily doped n-type material for use with the contacts, which were then applied over the gate channel region and also over the source and drain sites.

#### Fewer surface states

Silicon nitride has a big advantage over silicon dioxide here in that it allows the electric field produced by the gate to penetrate deeper into the GaAs because it produces fewer surface states to terminate the gate field near the surface. This affords greater control of the channel current and a higher transconductance—typically, about 10 to 25 millimhos against silicon's 8 to 10 millimhos. The transconductance rises with increases in frequency because the surface states have less effect at higher frequencies—they can't follow the high-frequency signals.

The Schottky-barrier transistor, developed at the Fairchild Semiconductor division by a group including W. W. Hooper, P. L. Hower, and W. T. Lehrer, gave a maximum oscillation frequency of about 3 Ghz, and a gain of 10 db at 1 gigahertz. Its designers say the device, described in detail at the International Electron Devices Meeting in Washington last month, promises a useful gain at frequencies above 10 Ghz. Though easier to make than the insulated-gate FET, the Schottky-barrier unit can only be operated in the depletion mode because it uses a reversebiased junction for the gate. Enhancement mode operation—no standby power—is not possible since the gate junction would become forward biased, short-circuiting the input.

#### For more on...

Silicon-nitride insulator FETs: H. Becke, J. White, Electronics, June 12, 1967, p. 82. Schottky-barrier gate FETs: W.W. Hooper, W.I. Lehrer,

Proceedings of the IEEE, July 1967, p. 1237.

Devices IV

## Microwave mixing and detecting

#### By Charles M. Howell

Microwave Associates Inc., Burlington, Mass.

**Point-contact** microwave diodes, after 25 years of faithful service, may soon go into forced retirement. In the frequency range below 5 gigahertz, Schottkybarrier microwave diodes with better noise figures, better resistance to burnout, and higher reliability are now commercially available. And, except for burnout resistance, these advantages persist all the way up to 100 Ghz.

Gallium-arsenide Schottky-barrier mixer diodes can be made with noise figures so closely approaching a mixer diode's ideal 4.5 decibels that any difference between the devices lies in the calibration of the instruments used to measure them. GaAs Schottky-barrier detector diodes, which have requirements different from mixer diodes, have sensitivities that also approach an ideal level.

A Schottky diode made of silicon gives about the same noise figure through X band as a GaAs device, and both approach the limit of an ideal rectifier. Above X band, however, GaAs appears to have a small but significant edge in noise figure, although silicon diodes still cost less, are more uniform, and require less local oscillator power. However, improvements in the quality of epitaxial GaAs are narrowing this gap.

#### Working wall

A rectifying junction can be made between an n-type semiconductor and a metal contact by choosing a metal whose work function is higher than the semiconductor's. With lower capacitance and less carrier storage, this rectifying junction can operate at far higher frequencies than can conventional junctions.

A video receiver that uses a diode to detect microwave energy is simple and broadband, but has a top sensitivity of -50 dbm over a signal range of d-c to about 12 Ghz; a heterodyne receiver would be 50 to 60 db more sensitive.

The sensitivity of an ideal video detector is determined by the video impedance of the diode and the noise contributed by the video amplifier. High sensitivity can thus be achieved only with high impedances. But getting a good broadband match to



Noise figure. Operational characteristics of Schottky-barrier mixer diodes made with silicon and GaAs.

these high impedances over large bandwidths is a formidable task, and most designers resort to biasing the diode to reduce its impedance, or to padding the unit; both measures decrease sensitivity.

For high video impedances, the capacitance of the diode junction must be very small—less than 0.2 picofarad for S-band detectors and less than 0.05 pf for X-band.

The Schottky diode detector then must have as small a junction capacitance as possible; a large video impedance; low series resistance; and a Q between 10 and 20 at the operating frequency.

Therefore, the material chosen should have high electron mobility and small dielectric constant, and the diode should be made with a thin, high-resistivity epitaxial layer designed so the space charge of the junction can punch through into the substrate at or near the operating bias.

Epitaxial GaAs is thus an excellent choice. It offers a higher mobility of n-type material than does silicon, and is grown at lower temperatures, an incidental factor that can enhance control of doping in the epitaxial layer and reduce grading of the substrate-epitaxial interface. Too much grading gives a narrower-than-optimum diode space charge and boosts junction capacitance.

Generally, the larger the junction, the better the burnout resistance, but GaAs has less than a quarter of the thermal conductivity of silicon, and these factors tend to offset each other.

Gallium-arsenide Schottky detector diodes are made by depositing one of many possible metals on a clean epitaxial wafer. Nickel and gold are easily deposited, but nickel has a higher cutectic temperature with GaAs (500°C) and therefore a greater resistance to burnout.

The knee of the forward conductance curve depends on the work function of the metal used and on the crystal orientation of the gallium arsenide. The table gives a list of various metals and their barrier heights on planes 111 and 100 in GaAs and silicon; the height doesn't appear to affect sensitivity. All GaAs Schottky detector diodes require bias because the variable conductance doesn't occur near zero bias.

For a typical X-band diode, an n-type epitaxial GaAs layer 0.5 to 1 micron thick with doping of less



Pinheads. Array of Schottky-barrier metal contacts on batch-fabricated GaAs slice.

#### **Barrier heights of metals**

Elemental metal	n-type, GaAs Orientation		n-type Silicon Orientation		
	(111)	(100)	(111)		
Nickel	0.83	0.70	0.58		
Gold	0.99	0.90	0.79		
Silver	0.94	0.85	0.62		
Tungsten		0.73	0.67		
Aluminum	0.80	0.71	0.63		
Tin	0.70	0.68	0.60		
Copper	0.80	0.73	0.58		
Note: All heights measured to $\pm 0.02 v$					

than 10<sup>16</sup> electrons/cm<sup>3</sup> is first coated with a layer of aluminum borosilicate glass 2 to 5 microns thick. This glass has a dielectric constant of 3.8 and also matches the thermal expansion of the GaAs well.

After the dielectric layer has been deposited, ohmic contacts are applied to the substrate; sintered gold-tin contacts give low ohmic resistance.

The Schottky diodes are formed by photoetching holes through the dielectric layer to expose the GaAs. The metal is deposited either by vacuum evaporation through a mask or by electrodeposition from a proper solution; there appears to be no difference between diodes made with either process. After the metal-semiconductor junction has been formed, the hole is filled with metal.

Because it's difficult to make the necessary low parasitic capacitance contacts—which should be less than 0.02 pf—a small plated whisker is bonded to the junction. But a junction only 1 micron thick is difficult to contact, so many small junctions are formed and contact is made to one randomly.

#### Microwave mixers

The ideal microwave mixer is a multiport device with large-signal and small-signal parameters determined by the variable conductance set up by the local oscillator and the terminations of each port.

The mixer diode's important electrical characteristics are conversion loss, the noise ratio at the intermediate frequency, and the impedances at each of the four ports. The conversion loss depends not only on the impedances presented at each port but on the termination presented to the harmonics of both the signal and local oscillator. However, if the mixer circuit is taken to be ideal, the image is resistively terminated, no signal power is lost in the higher-order harmonics, and the diode's conversion loss depends on signal match and resistive losses.

An ideal mixer diode presents to the signal a timevarying conductance whose average value can fall within a wide range without hurting performance (in contrast to the detector situation). In a typical Schottky diode, the corresponding impedances will be 100 to 300 ohms, depending on the local oscillator drive. The capacitance of the junction tends to shunt this variable conductance. Because its barrier impedance is far lower than a detector's, the mixer diode can use larger capacitance junctions, but more attention must be paid to the series resistance.

Another mixer-diode design consideration is the minimizing of the local oscillator power requirement. Silicon diodes need less of this power than GaAs devices do. Local oscillator power is often limited, especially at high frequencies or where a solid state source is used. The power requirement for minimum noise figure in an unbiased mixer diode depends directly on the barrier voltage of the junction, so the junction should have as low a barrier height as possible.

Yet another consideration is dynamic range. In a typical mixer, signal compression occurs when the signal power is less than 20 db below the local oscillator. One can boost the local oscillator power to increase dynamic range, but as the field across the junction increases it starts field-induced minority carrier injection. This injection rapidly increases the shot noise and conversion loss of the diode. The onset of injection limits the maximum usable local oscillator power.

In general, the injection begins at current densities inversely proportional to barrier height. Thus, larger local oscillator powers can be used with low barrier junctions if the r-f bias doesn't exceed the breakdown of the diode; normally, however, this isn't the case.

A GaAs Schottky mixer diode's junction capacity must therefore be less than 0.4 pf for S band and 0.20 pf for X band, its series resistances should be no more than 3 to 5 ohms, and its barrier should be low. The metals with the lowest barrier potentials are tin and nickel, but tin is susceptible to burnout because it forms a low melting eutectic with GaAs.



Metal barrier. Schottky-barrier diode formed with nickel contact on semiconducting GaAs layer.

The 100 crystal face has a low barrier for all metals and seems good for thin epitaxial layers.

The starting material for fabrication is 100-oriented epitaxial GaAs with the same doping level used for the detector diode. However, because the bias set up by the local oscillator extends the space charge, the mixer diode's epitaxial layer can be as thick as 1.5 microns.

Junction diameters are much larger than those for detectors—5 to 10 microns in X band and as large as 12 to 20 microns in S band. These larger junctions permit the forming of a bilithic diode. The glass can be deposited over the edge of the junction and thermocompression contacts made.

**Devices** V

# Beating the heat in injection lasers

#### Hans Rupprecht

International Business Machines Corp., Yorktown Heights, N.Y.

Since that day in 1962 when IBM and GE almost simultaneously announced the development of injection lasers, gallium arsenide has been the material most often chosen for these devices.

The GaAs injection laser is only a few thousandths of an inch long and produces a beam of coherent light that can be directly modulated with nanosecond pulsing of input current. Because of these features, applications are envisioned in portable communications and ranging systems and in optical coupling of high-speed circuits.

However, if the advantage of small size is to be



Flat beam. Gallium-arsenide injection laser produces coherent light in plane of junction.

fully realized the laser must be operated at the environment's temperature. Today's goal is high pulsed power and continuous operation at 300°K, or at least at temperatures above 100°K, where simple cooling equipment can be used. Limitations on the duty cycle and ambient temperature primarily stem from heating effects within the laser.

Researchers reported, back in 1962, that when a GaAs diode is forward biased, electrons are injected from the n side into the p side, and that—in a region about 1 micron wide—the conduction-band electrons recombine with holes in the valence band and give up their energy as radiated light. The emitted photons have an energy close to the energy separation of the conduction and valence bands—the so-called band gap, which is about 1.4 electron-volts for GaAs at 77°K.

The recombination can occur spontaneously, where individual events are completely uncorrelated, or by a mechanism first proposed by Einstein in 1918—an emission induced by another photon. It's this process of induced emission that leads to the phenomenon of lasing.



Laser power. Stimulated emission region (in color) shows high-power output above threshold.

#### Getting in the mode

In a Fabry-Perot structure, a resonant cavity with two parallel reflecting surfaces, the photons that propagate perpendicular to the reflecting sides multiply fastest. When a certain threshold current is reached, they outnumber the photons propagating in other directions. The gain then becomes equal to the losses from absorption inside the cavity and at the partially reflecting end faces, and the diode enters a lasing mode of operation.

During operation, the junction temperature rises because of ohmic power losses within the diode and because much of the stimulated radiation is internally absorbed. The rise in junction temperature increases the threshold current density needed for laser action and thus cuts power output. When this temperature hits a level that boosts the threshold current above the applied diode current, lasing stops.

Much effort is being made to reduce threshold current density—normally about 100,000 amperes per square centimeter—and to make it as independent of temperature as possible. Geometric configurations that reduce ohmic losses and allow effective heat transfer from the junction to the heat sink are being sought.

Progress is reported toward both major goals. By forming the p-n junction with either a doublediffusion process or liquid-phase epitaxial process, the threshold can be lowered by a factor of 4 or 5 at 300°K. Values as low as 26,000 amp/cm<sup>2</sup> have been observed in diodes with a cavity length of 0.38 millimeter.

Despite the progress in high-power technology, continuous operation hasn't been extended much beyond liquid-nitrogen temperatures; typical values are about 3 watts continuous power at 77°K. When pulse operated at room temperature, improved diodes have delivered about 10 watts.

#### **Declining powers**

Laser diodes tend to degrade during operation. There appears to be an irreversible decrease in power output if a certain current density is exceeded, a situation frequently accompanied by a physical chipping of the reflecting surface along the junction line. The cause isn't fully understood.

It was determined early in the laser's history that near-perfect substrates are needed as a starting material. Periodic fluctuations in the doping level due to unstable growth conditions increase threshold current and decrease power output because the losses tend to become larger. Local inhomogeneities due to clusters of defects have a similar effect and are probably responsible for the oft-observed filamentary lasing mode, where only narrow "stripes" in the junction are lasing.

#### For more on . . .

Injection lasers: G. Burns, M.I. Nathan, Proceedings of the IEEE, July 1964, p. 770.

### GaAs light era on the way

#### By J. R. Biard and Hans Strack

Texas Instruments Incorporated, Dallas

**Conventional miniature** incandescent lamps may soon be in for some competition from galliumarsenide light emitters. Prices for the GaAs devices have dropped from the \$100 level of the recent past to \$10 today, and will soon be down around \$1. With that kind of price tag and with solid state efficiency and reliability, GaAs emitters may be just the devices to put light to work in electronic circuits.

These light emitters have been made with nearly 100% internal quantum efficiences—where each injected carrier emits one photon. The problem is to find a way for the light generated in the crystal to exit through the surface.

Light in most electroluminescent diodes is produced on the p-side of the junction when electrons recombine with holes that are bound to an acceptor or with free holes in the valence band. The bandgap energy in GaAs is about 1.4 electron-volts at  $25^{\circ}$ C, meaning that light is emitted in the near infrared at about 8,900 angstroms. To get visible light, a compound of GaAs and gallium phosphide must be used. With a mixture about 33% GaP and 67% GaAs, red light is emitted at a wavelength of 6,700 angstroms.

#### **Knifing through**

Light generated near the junction is emitted in all directions, but only light striking the exit surface at an angle smaller than the angle of total reflection ( $16^{\circ}$  in GaAs) can leave the crystal.

Because the radiative transitions are random, the devices are called spontaneous emitters; in contrast, the recombination processes in injection lasers are stimulated by photons.

The p-n junction in spontaneous GaAs light emitters can be formed either by diffusion or epitaxy, but quantum efficiency will be affected by the properties of the starting material and the fabrication process. Starting material for diffusedjunction light emitters is usually bulk n-type GaAs doped with tellurium, tin, or silicon; typical electron concentrations run between 5 x  $10^{17}$ /cm<sup>3</sup> and 3 x  $10^{18}$ /cm<sup>3</sup>.

The best of the present light-emitting diodes use crystals doped with such group IV elements as tin or silicon. The p-region is formed by diffusing zinc into the n-type substrate.

Studies of the electro-optical properties of the p-region, in which nearly all the light is generated, show that emission efficiency is highest where there is a graded, rather than abrupt, impurity distribution at the junction. Another factor is the doping level in the active p-region extending several electron-diffusion lengths away from the junction. High zinc concentration can cause nonradiative recombination centers to form, and these reduce the quantum efficiency. A heavily doped p-region at the surface of the zinc-diffused region will reduce the contact spreading resistance.

#### Three-step diffusion

One way to form the graded junction is a threestep diffusion; a zinc diffusion is followed by rediffusion without a zinc source in order to grade the junction and reduce the zinc concentration, and the process is capped by a shallow  $p^+$  diffusion.

Zinc diffusions are performed in sealed ampuls with either elemental zinc, binary compounds such as  $ZnAs_2$ , or ternary compounds such as  $GaZn_x$  $As_{1-x}$  as the source.

Typical diffusion temperatures are in the 800°Cto-900°C range and junction depths are on the order of 8 microns. Contacts to both the p- and n-type regions are made by evaporating a gold-



Well-rounded. Light-emitting diode made with hemispherical dome to improve light emission properties.

antimony alloy.

Recently, light emitters with improved efficiency and stability have been made by vapor-phase or solution epitaxy on bulk-grown substrates. The vapor-phase epitaxial technique [see p. 113] has been used to achieve a controlled degree of compensation and to approximate a graded diffused junction.

Light emitters built of bulk or vapor-phase epitaxial GaAs are processed in an arsenic-rich environment. Different properties are created when the material is grown in a gallium-rich environment by solution epitaxy; more stable and efficient light emitters have been produced in the laboratory with this technique.

A reactor used to fabricate high-purity and heavily doped solution-grown GaAs is on page 129 above. A substrate slice is inserted into a gallium melt saturated at around 900°C with doped or undoped GaAs, depending on the electrical properties desired. Upon cooling, a deposit is formed on the substrate. When group II elements are used for doping the melt, p-type deposits result; n-type deposits are obtained with group VI impurities. Group IV impurities are amphoteric; they lead to either n- or p-type deposits depending on the growth temperature.

The loss mechanisms of spontaneous emitters are different from those of lasers. Laser light exits in the junction plane through surfaces perpendicular to the junction, and light loss occurs because of free carrier absorption, cavity leakage, and transmission through the exit surface. Spontaneous light emission is isotropic and most of the light exits through planes parallel to the junction; losses are caused by bulk absorption, total reflection, and transmission.

Since the optical absorption losses in the bulk are about 10 times greater than the effective losses in the cavity, and since most of the emitted light is reflected back into the material, spontaneous emitter structures are generally less effective than lasers.



Light dome. Hemispherical shape of emitter assures that light falls within angle of transmission.

To offset total reflection losses, spontaneous light emitters have been built with a light-emitting junction embedded into a GaAs hemisphere. If the ratio of the sphere diameter to the junction diameter is equal to the dielectric constant of GaAs—about 12—no total reflection losses occur. Although absorption losses increase because of the longer light path in the crystal, the dome structure improves efficiency by about an order of magnitude.

Another way to improve external efficiency is to reduce the absorption losses. Because n-type GaAs doesn't absorb light originating at the p-side of the junction as much as p-type GaAs does, the n-type material is used for the dome structure. Solution-grown junctions doped amphoterically with silicon emit light at 1.33 ev, about 0.1 ev below the band-gap energy. In this energy range, the absorption is considerably reduced.

The average efficiency of a planar light emitter in bulk-grown GaAs is about 0.2% at room temperature. The efficiency of a dome-structure device of the same material would be about 2% and that of the best solution-grown diode with a hemispherical exit surface is 20%.

The light emitter's efficiency can also be increased by an antireflection coating with a dielectric such as silicon monoxide to increase the transmissivity of the GaAs-air interface. If the losses due to total reflection bulk absorption are cut, the external efficiencies of lasers and spontaneous emitters should be about comparable. Laser differential quantum efficiencies of up to 40% have been reported for pulse operation.

The fact that efficiency generally increases at lower temperatures has never been completely explained, but contributing factors are reduced absorption, increased injection efficiency, and deereased radiative lifetime. Efficiencies of 45% at 77°C have been reported for dome structures in bulk-grown GaAs.

Laser efficiency isn't linked to temperature to any pronounced degree. Differential laser efficiencies of 50% at 77°K have been measured. The threshold current for lasing, however, depends to a large extent on temperature. Typical values are  $10,000 \text{ amp/cm}^2$  at 25°C, 1,000 amp/cm<sup>2</sup> at 77°K, and 100 amp/cm<sup>2</sup> at 4°K.

#### Applications

Spontaneous emitters will probably be the first volume-produced GaAs devices. The two areas where these light sources are most likely to have an impact are data processing and, with GaAs-GaP alloys, indicator lamps. In both fields, solid state light emitters are superior to conventional units in both efficiency and reliability.

Miniature card-reader light sources have delivered 30 milliwatts per ampere total output in a 20° solid angle, and about 15 microwatts of radiant power into a 2.5° solid angle for a diode current of 50 milliamperes. To focus the light, the domeshaped GaAs emitter is placed in a reflector package. The dimensions of the package, 120 mils diameter and 175 mils length, allows a high package density.

Considerable progress has been made toward developing light emitters that are stable over long periods of time. Test data on planar units with expanded gold-titanium contacts indicate a 20,000hour useful life. The expanded contacts are believed to prevent surface deterioration, the main cause of device degradation. Light emitters fabricated in solution-grown GaAs exhibit more stability than those built in bulk GaAs, a fact that may be due to the higher surface stability inherent in solution-grown material.

High-power light sources might be used for communication systems and large-area illumination. Solution-grown diodes doped amphoterically with silicon have produced 200 mw/amp light. Semiconductor light sources have been used in voice-modulated communications systems operated in daylight over several miles, and video signals have been transmitted successfully over a distance of several hundred feet.

A wide variety of applications can be forecast for linear arrays of light emitters in areas such as film annotation and information storage. And monolithic arrays of up to 60 elements have been fabricated with minimum outputs of 1 to 2 mw/amp.



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Advanced technology I

## Two Gunn holdups slow microwave oscillators

#### By Daniel G. Dow

Varian Associates, Palo Alto, Calif.

Two barriers, neither of them insurmountable, are delaying the development of practical microwave Gunn-effect oscillators. One is the difficulty of getting the right quality, reproducible galliumarsenide material and the second—almost a corollary of the first—is to get a good yield.

Once over these hurdles, the material costs per device will be negligible and, because the device fabrication itself is straightforward, the ultimate device cost will be low. As they near this tempting goal, researchers are stepping up their efforts.

To make a practical microwave Gunn oscillator, the still-to-be-perfected Gunn diode must be embedded in a resonant circuit. By matching the circuit to the diode it will be possible to achieve: • Tunability of 1.5 to 1 at high efficiency, and 3 or 4 to 1 at reduced efficiency

Efficiency as high as 25%

 Peak power-frequency-squared product of approximately 1,000 watts-Ghz<sup>2</sup>

• Highly stable oscillations, with noise properties comparable to good klystrons.

#### View from the labs

Although results are still short of these predictions, progress is being made in the research laboratories. The highest reported continuous-wave power is 340 milliwatts at Nippon Electric in Japan; researchers at Bell Laboratories have reported 140 mw, and a number of other U.S. com-



High power. Parallel assembly of Gunn-effect diodes boosts power output.

panies are claiming powers up to 200 mw.

In pulsed research, experiments at Varian have produced 615 watts at 1,100 Mhz. However, the oscillator was restricted to a very low duty cycle because it used crystals grown from the melt by the horizontal Bridgman, or boat-grown, process. Although this technique produces good crystals, they have too much carrier compensation for practical applications.

The highest pulsed powers using epitaxial material are those reported by Radio Corp. of America—143 watts peak at 2,200 Mhz. Also reported by RCA was a device showing 24% efficiency at 112 watts, 1,900 Mhz. This high efficiency was attributed to a controlled doping profile. The RCA investigators also reported stability of both power and frequency against wide temperature excursions.

Commercial devices, however, are still rare. Although several companies are actively developing experimental Gunn diodes, the only ones being offered for sale are by Mullard (5 mw at X band) and Texas Instruments (10 mw at X band).

#### No compensation

The desired doping level for Gunn effect is about  $10^{15}$  atoms/cm<sup>3</sup>. This is less than one part in  $10^7$ , and cannot be achieved in boat-grown material. Thus, the needed high-resistivity n-type GaAs (anything lower than about 5 x  $10^{15}$ /cm<sup>3</sup> in doping density) must be made by compensating the shallow donors, close to the conduction band with acceptors, and allowing the deep donor levels to provide the active electrons. But—because the deep donors are not fully ionized at room temperature—the semiconductor carrier density is sensitive to temperature and can be effectively used only in research applications.

A practical device must be able to operate over a wide ambient temperature range; this alone would rule out compensated material. Even more critical is the fact that compensated material, whose conductivity increases as temperatures increase, will cause thermal runaway and device destruction under modest thermal stress. For example, the impressive data on pulsed LSA devices

of boat-grown material applies only to pulse lengths of 100 nanoseconds. Microsecond pulses would probably tell a different story—thermal runaway and a short-circuiting conductive channel.

#### Keeping pure

More success has been achieved with epitaxial GaAs where the crystal grows in a pure environment at temperatures from 650° to 850°C and the required purity can be held. Purity cannot be held at the melting temperature of GaAs (1,242°C) needed in the boat-growing procedure.

Vapor epitaxy, in which the gallium and arsenic are transported independently to a GaAs substrate, has been used with success for thin layers for several years, but the process is being worked at its limits to achieve the needed purity for Gunn diodes. More recently, there has been renewed interest in growth from a liquid (usually gallium) solution which may offer better control of purity.

A typical Gunn-effect oscillator designed to deliver 20 mw at X band requires a layer of GaAs, grown epitaxially on a highly doped substrate, which is about 10 microns thick, homogeneous in doping level to perhaps 20%, and with an average doping level between 0.5 and 2 times  $10^{15}$  carriers/ cm<sup>3</sup>.

Many wafers of material with these specifications have been fabricated in a large number of laboratories, yet the yield and controlling process variables are but slightly understood. The saving factor is that the active device is only 0.1 mm across, and it is conceivable that one square centimeter of good material could make 10,000 useful 20-mw oscillators.

The homogeneity problem is even worse with pulsed devices. Pulsed devices require larger areas of gallium arsenide than c-w devices to withstand the higher voltages. For example, an oscillator to deliver 1,000 watts peak at 1,000 Mhz would ideally use about 0.2 cm<sup>2</sup> of material homogeneously doped to  $2 \times 10^{14}$  donors/cm<sup>3</sup>. It may take another two years to refine the processes enough to do this.

#### Making contact

Most good ohmic contacts to GaAs fall into two general classes—alloy and epitaxy. Much of the early work with Guun effect was done with alloyed tin contacts. These seem to give good performance, but are not suitable for operation at elevated temperature, and under some conditions they show fairly rapid degradation. More recently, alloy combinations such as gold-tin, gold-germanium, silverindium-germanium, tin-nickel, and many others have been reported.

The liquid epitaxy process for growing contacts consists of saturating a pool of liquid tin with GaAs, allowing the mixture to envelop the GaAs wafer and cool a few degrees before removing it. The result is that a thin layer of GaAs, heavily doped with tin, grows on the surface of the wafer. This heavily n-type surface layer may then be easily contacted by almost any metal.

### LSA can come to mean large-size advantages

#### By John A. Copeland

Bell Telephone Laboratories, Murray Hill, N.J.

**Power and frequency** limits of solid state devices are extended when a wafer of gallium arsenide is operated as a microwave oscillator in the limited space charge accumulation mode. The diode can be thicker and longer than a Gunn device, and the greater size provides higher power, higher impedance, and easier heat dissipation.

The LSA mode exploits the negative resistance of GaAs while preventing the material from breaking into Gunn-type oscillations. The material is biased at a point where the oscillating microwave-frequency electric field can swing down into the positive resistance region for a brief interval during each cycle to quench the Gunn domain.

In operation, the frequency of oscillation depends on the tuning of the resonant cavity rather than on the basic property of the LSA diode; however, the frequency must fall within certain limits to accomplish the Gunn-squelching action. Domains form faster in GaAs that has a high carrier concentration —a sample doped at  $10^{-15}$ /cm<sup>3</sup> will form a domain in about 0.1 nanosecond, the period of a 10-gigahertz wave. If the sample is more heavily doped, it



Outputs. Comparison of power-frequency characteristics of various microwave solid state sources.



**Resonant stub.** Limited space charge accumulation diode has half-wave stub in its package for operation at 150 Gz.

has to be operated at a higher frequency to switch the electric field back into the positive resistance region quickly to prevent domain formation.

The limit is set by the ratio of doping to frequency, n/f, which must be between 2 x 10<sup>4</sup> and 2 x 10<sup>5</sup>. Maximum efficiency, about 17%, occurs at a ratio of 6 x 10<sup>4</sup>. Thus, for operation at a millimeterwave frequency of 50 Ghz, the optimum doping level is about 3 x 10<sup>15</sup>/cm<sup>3</sup>.

The most recent reported results are 20 milliwatts continuous power between 44 and 88 Ghz, achieved at the Bell Telephone Laboratories, and 630 watts peak pulse power in X band ,at Cornell University. Other diodes have been operated with detectable power up to 150 Ghz.

#### **Doping hangup**

A big problem is that doping must be uniform throughout the sample. If it varies by  $\pm 30\%$ , the maximum efficiency drops from the theoretical 17% to about 10%. The best efficiency yet observed, in fact, has been 9%.

The scene of most activity in this field, therefore, is the materials lab rather than the microwave-circuits facility. Researchers are satisfied that once uniform doping is achieved, LSA devices will be a practical source of microwave or millimeter-wave power.

### **Bulk-effect boosting**

By Hartwig W. Thim

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**Solid-state amplifiers** have been catapulted into the millimeter-wave range by gallium arsenide's negative resistance properties. Studies on these new bulk-effect amplifiers, are too recent to say with certainty how practical and widely used they may become. But the signs are good; bulk-effect amplifiers, like bulk-effect oscillators, offer the promise of simple, low-cost devices, competitive with transistor amplifiers which have had tough going at microwave frequencies. Tunnel diodes, the only other solid-state microwave amplifier, could be easily outclassed since they can produce only about a hundredth of a percent of the power available from bulk-effect amplifiers.

Bulk-effect amplifiers can be considered as three basic types:

• The stable amplifier, which has been operated up to 50 gigahertz.

• The traveling-domain amplifier, which has delivered 100 milliwatts at 6 Ghz.

• The unilateral traveling-wave amplifier, which has been operated at 0.1 mw at 1 Ghz.

#### Stable amplifier

Developed in 1965 at Bell Telephone Laboratories, the stable amplifier—also called a subcritically doped amplifier—uses a GaAs wafer whose product of doping–and length,  $n_oL$ , is less than  $10^{12}$  cm<sup>-2</sup>. This restriction is necessary to prevent Gunn-type oscillations, since the crystal is too short and too lightly doped for the domains to form.

A bias field of several thousand volts per centimeter is applied across the short wafer with only about 20 volts needed to set up this high field. The result is that electrons injected from the eathode are decelerated on their way toward the anode because of the differential negative mobility. A nonuniform field—low at the cathode and increasing across the device toward the anode builds up and becomes stable after one transit time. The differential d-c resistance is positive, but an applied a-c signal will see a negative resistance at frequencies corresponding to the integral multiples of the transit time. For the 50-micron wafer, the transit time is 0.5 nsec, and the frequencies for negative resistance are 2 gigahertz, 4 Ghz and so

forth, up to the millimeter-wave region.

For a three-terminal amplifier circuit, the wafer is mounted in a conventional reflection-type circuit that has a broadband eirculator. The incident signal enters port 1 of the circulator, exits at port 2 to the GaAs wafer, is amplified and then reflected back to the circulator and into the load resistance connected at port 3.

For a typical wafer, about 50 microns thick, the gain peaks at 10 decibels at 4 Ghz, the second harmonic of the fundamental transit-time frequency. Gain can be increased by adjusting the characteristic impedance of the transmission line to a value close to the negative resistance of the diode. However, the maximum output power per unit cross section is restricted by the limitation on the  $n_0L$  product. These subcritically doped amplifiers have achieved saturation levels in the order of 1 milliwatt and efficiencies of about 0.1%.

#### **Traveling domain**

The traveling-domain amplifier uses the negative resistance property of traveling high-field domains in Gunn oscillators. Such domains exist only in wafers with  $n_0L$  products greater than  $10^{12}$ cm<sup>-2</sup>. Because of the cyclic formation and disappearance of the domains at the contacts, this amplifier, in contrast to the stable amplifier, oscillates at the transit-time frequency while amplifying at some other frequency.

The only difference between the circuits of the stable amplifier and the traveling-domain amplifier is that in the latter a resonant cavity is connected to the coaxial line close to the GaAs wafer to act as a short circuit for the Gunn oscillations. The length of the cavity is thus an integral number of wave-lengths at the transit-time frequency of the Gunn oscillations, and the signal circuit is decoupled from the oscillator circuit, reducing parametric effects.

The traveling-domain amplifier is linear until the output power approaches the power available from the same device when operated as a Gunn oscillator. The maximum output power obtained from a traveling-domain amplifier was 0.1 watt, the efficiency 1%. The upper frequency limit was 11 Ghz, slightly higher than the transit-time fre-



Amplifier. A gallium-arsenide wafer displays a negative resistance in this reflection-type amplifier.

quency. The noise figure measured on the stable and traveling-domain amplifiers was about 20 decibels, suggesting that both will be used as high power amplifiers rather than low-noise devices.

#### Unilateral traveling-wave

Researchers at Stanford University recently proposed a two-port unilateral traveling wave type, several space-charge wavelengths long, in which a signal is injected at a contact placed near the cathode contact in order to excite space charge waves. Such a wave grows along the length of the diode and excites a larger signal at a contact placed near the anode. It is thus similar to a two-cavity klystron amplifier, where the signal is injected in one cavity, coupled to the electron beam, and extracted at a second cavity.

As in the subcritically doped amplifier, the  $n_0L$  product must be smaller than  $10^{12}cm^{-2}$  to avoid formation of high-field domains (spurious oscillations). Little gain has been obtained around 1 Ghz, and gain compression occurred when the output power reached 0.1 mw. If coupling can be improved, amplification should occur over broad frequency bands.

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Advanced Technology IV

### Pulsating passages

#### By Masakazu Shoji

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The discovery of the Gunn effect, besides opening new possibilities for solid state microwave power sources, could be a significant step towards realizing a concept that has intrigued designers for years —the bulk-effect functional integrated circuit. Here there would no p-n junctions or individual components; the device would perform a function simply because of its shape and material properties.

With a specially shaped chip of gallium arsenide, for example, moving Gunn domains might be used to generate current pulses of almost any waveform. Since the domain has a constant current density as it sweeps through the material, all that's needed to increase the current to the outside circuit at any point in the cycle is a larger cross-sectional area at the corresponding part of wafer. When the domain reaches this point, the total current changes.

#### **Tailored shapes**

The current waveform takes the shape of the device. If a triangular waveform were desired, the device would be shaped like a rooftop; if a dip in the waveform were desired, a notch would be cut in the device. The usual Gunn-effect current spikes also appear in the waveform when the domain reaches the anode, but they can be used as synchronizing pulses, or, if they might upset circuit operation, can be subtracted out by a uniformly shaped device connected in parallel.

Samples have been made with electron concentrations of 4 to 7 x  $10^{14}$ /cm<sup>3</sup>. The material was cut into pieces 40 by 40 mils square and 10 to 20 mils



Current generator. Peaked shape of gallium-arsenide sample is reproduced in the output current waveform.

thick, and ground carefully to desired shapes. The pieces then were cleaned, etched, and alloyed with pure indium contacts.

Another basic type of bulk-effect pulse generator employs contacts placed along the path of the domain to produce extra pulses at any point in the cycle. The contact is separated from the bulk material by a layer of high-resistivity material, an oxide formed by exposing the surface to air for several days. The oxide allows extra current to flow around the domain as the domain passes under it, and this shunt current appears in the output at a point corresponding to the position of the contact. When the domain reaches the anode, it delivers its normal current pulse to the output circuit.

#### Controlled pulses

The extra current pulse in the high-resistivity region can be switched in and out of the cycle with a switch connecting the contact to ground. The cur-



Current wave. Pulses, shown on sampling scope, were produced by a GaAs bulk generator of the type at left.

rent can then be shunted to ground and won't appear in the output.

Samples operating in this way were made of n-type GaAs with concentrations of 4 to 7 x  $10^{14}$ / cm<sup>3</sup>. A typical size was 40 mils long, 20 mils wide, and 20 mils thick. Pure indium contacts were alloyed to the ends, and the samples were exposed to air for from two to 60 days to oxidize the surface. Silver paint contacts then were applied to the surface to form the control electrodes.

Many applications are possible. For one, a multicontact device could perform logic, and, if the switches on the external current paths were replaced with photoconductive material, could be used as an image scanner.

#### For more on ...

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Advanced technology V

# Over the horizon: gallium arsenide IC's

By Edward M. Mehal

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Indicative of today's fast-paced technology is the fact that gallium-arsenide integrated circuits are being developed right along with the discrete devices. Although the additional fact that these IC's cost more than their silicon counterparts and are harder to fabricate will generally limit them to a few special jobs, they do have a clear field in two areas—the microwave and the optoelectronic. The microwave GaAs IC may be with us soon; the optoelectronic IC is farther off.

The key to monolithic gallium-arsenide circuits is the semi-insulating form of GaAs. This material

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Liblin



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facility. Copeland, a Ph.D. from Geor-

techniques and solid state bulk effects at Standard Telecommunication Laboratories Ltd., Harlow, England, did much early work on bulk-effect devices and coined the term "dofic"-domain originated functional integrated circuits-to describe them,

gia Institute of Technol-

ogy was the first to pre-

dict the possibility of LSA

oscillations. Shoji, with a



Biard

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Dow



Becke



Gunn oscillator. Planar device designed for use in 94 Ghz microwave-receiver integrated circuit.

provides a single-crystal matrix for the epitaxial growth of GaAs devices and affords excellent electrical isolation between components.

The basic building process sounds simple: pockets are etched in a wafer of semi-insulating GaAs to accommodate active devices, semiconducting GaAs is epitaxially grown in these pockets, and a layer of metalization is added to interconnect the devices with microstrip transmission lines. Of course, there are practical problems—how to get the semi-insulating GaAs, etch clean-cut holes, and grow pure epitaxial layers.

#### Fabrication

The first step in the process is to orient the GaAs semi-insulating substrate to a 111 surface and then to chemically polish the surface to remove any defects. As a mask, a silicon dioxide film about 0.3 microns thick is applied externally by sputtering or chemical deposition methods; the best method found at Texas Instruments is the thermal oxidation of tetraethylorthosilicate (TEOS).

Next, the pockets delineated by the  $SiO_2$  mask are etched out. Most of the common etching techniques produce holes with irregularly shaped bottoms, due to greater etching around the periphery of the hole. But this effect has been eliminated with a hydrogen peroxide-sodium hydroxide solution that's reaction-rate limited rather than diffusionrate limited and yields an etched hole with a planar bottom.

Care must be taken when semiconducting GaAs is deposited in the pockets; if these depositions project above the surface, masking will be upset. Pockets of different dimensions must therefore be filled separately to minimize overgrowth in the smaller ones. Regions with overgrowth of less than 1 micron have been achieved on 111-oriented substrates. The semiconducting GaAs used has a fairly low impurity content—around 1 x  $10^{15}/\text{cm}^3$ —and can be controllably doped with sulfur or tin to produce the required n-type carrier concentration for the devices.

#### Possible components

Planar bipolar transistors that could possibly be used in integrated circuits have been fabricated by Wilhelm von Muench of the International Business Machines Corp. lab in Boeblingen, Germany. He used one selective deposition of n-type GaAs into semi-insulating GaAs, and formed base and emitter regions by planar diffusions. Field effect transistors also have been fabricated on semiinsulating GaAs substrates, and these too might find employment in integrated circuits.

Microwave circuitry has been the principal area of application. Gunn oscillators and Schottky-barrier diodes made in planar form with selective deposition techniques are now being combined into microwave IC's.

The planar Gunn oscillators, which have operated at up to 28 Ghz, require three selective depositions of GaAs—two  $n^+$  regions for contacts, and an  $n^$ area as the active region.

An IC for the front end of a 94-gigahertz microwave receiver is being built at TI under a contract from the Air Force Avionics Laboratory, Wright-Patterson Air Force Base, Dayton, Ohio. It consists of a Gunn oscillator in a resonant circuit operating at about 31 Ghz; a tripler circuit that converts the 31-Ghz Gunn oscillator signal to 94 Ghz to serve as the local oscillator source; and a balanced mixer using two Schottky-barrier mixer diodes.

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## Suitcase-size memory for longer space trips

Employment of pulse techniques and MOS transistors results in a portable computer storage that dissipates only 3.5 watts, reducing power requirements and stretching mission times

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Just as a businessman steps off a plane with attaché case in hand, so may an astronaut someday step out of a spaceship, onto the moon or Mars, carrying a computer. The idea isn't far-fetched. A portable memory dissipating only 3.5 watts and designed to fit into a 21-inch suitcase is now being evaluated by the Air Force for various classified applications.

The memory is the first of what is expected to be a whole family of complex digital equipment, each unit of which will dissipate only a small amount of power—provided perhaps by a self-contained battery—and will be portable.

Development of integrated-circuit technology from gate to function to system levels has reduced the cost of such assemblies, and the amount of power they require. A production run of memory systems based on the prototype design would perhaps cost as little as 10 cents per bit in 1972, and might dissipate even less power if individual transistor tolerances were tightened. The 10-cents-a-bit level is about the price of present conventional magnetic memories.

At such costs, semiconductor memories would be competitive with conventional types made of ferrite cores or thin films, particularly in such sophisticated applications as associative memories, scratchpads, input-output buffers, and index registers. And low power dissipation would give semiconductor circuits the edge in aerospace applications, where the weight of power sources is always a problem. Ferrite cores need high driving power, and the thin films' small output signals demand complex sense amplifiers that also require high power.

#### **Cutting power**

Power reduction was at least as important a consideration as size in the development of the memory. Designers concentrated on the memory rather than on an entire computer, because the memory subsystem dissipates 40% to 60% of the total power in present aerospace computers. Paring memory power requirements could, therefore, significantly reduce over-all power requirements and the weight of power supplies, thereby extending mission times. Low power dissipation was emphasized at the expense, where necessary, of other parameters such as size and weight; a little extra weight devoted to power conservation, it was reasoned, can save many times more weight in power supplies.

The prototype model in the suitcase is a randomaccess memory suitable for production at reasonable cost. It has 1,024 words of 30 bits each, built with metal oxide semiconductor transistor arrays for storage, and bipolar transistors for the peripheral accessing circuits. It provides nondestructive readout with an access time of 0.7 microsecond, and a full read or write cycle of 1 microsecond.

The designers chose these integrated circuits because pulsing permits mos flip-flops to be operated at a very low power level, and because mos is well suited to low-cost large-scale integration. The bipolar devices used in address decoders,



**Prototype.** This experimental system, which operates on only 3.5 watts exclusive of the exerciser (top), is the forerunner of a family of low-power, portable, complex digital devices.

write drivers, sense amplifiers, and control circuits are commercially available integrated circuits. Interface circuits between Mos array and bipolar peripherals were built with discrete components, because at the time the design was frozen, levelshifting circuits weren't commercially available.

The peripheral circuits are also operated with pulse techniques to reduce power consumption. Special nonlinear switching circuits with inductive source impedances afford further savings in power, when driving large capacitive loads in the Mos array and distribution lines.

#### Cell block

The basic memory cell has a nominal threshold voltage of 5 volts. In the diagram at the right transistors  $Q_1$  and  $Q_2$  form the bistable storage elements of the cell; their loads are  $Q_3$  and  $Q_4$  respectively. Transistors  $Q_5$  and  $Q_6$  are biased off except when data is being written into the cell or read out.

If  $Q_1$  is conducting, the voltage at its gate is negative, driving electrons out of the adjacent ntype material and establishing a p-channel between

the p-type source and drain. The conduction establishes a voltage of +12 at the drain of  $Q_1$  and the gate of  $Q_2$ , holding  $Q_2$  in its normal, nonconducting state. Conversely, the drain of  $Q_2$  is near ground, and this level at the gate of  $Q_1$  keeps that transistor conducting.

However, capacitance exists between the  $Q_2$  drain and the substrate, and leakage current from the drains of  $Q_2$  and  $Q_6$ , plus the source of  $Q_4$ , charges the capacitance slowly toward 12 volts. If this voltage buildup were permitted to continue,  $Q_2$  would eventually turn on and the data stored in the flip-flop would be lost.

To eliminate the accumulated charge, the "restore" pulse periodically turns on  $Q_3$  and  $Q_4$ , opening a path to ground. With  $Q_2$  cut off, its transconductance is nearly zero, and the path transmits only the small amount of charge on the parasitic capacitance. But  $Q_1$  is conducting; the sum of the two transconductances of  $Q_1$  and  $Q_3$  is only slightly greater than that of  $Q_1$  alone, so the turn-on of  $Q_3$ has no appreciable effect on the current through  $Q_1$ .

#### Repulsing charges

The restore pulse must be frequent enough to assure that the drain of the cutoff transistor never accumulates enough charge to cause trouble even under worst-case conditions. In the low-power memory, the restore pulse has an amplitude of 18 volts, a duration of 1.5 microseconds, and a repetition rate of about 10 kilohertz (duty cycle of 1.5%). The memory cell would work if the restore input were kept "on" all the time; in fact, its switching time would be considerably faster. But the power dissipation would also be much higher.

The gating transistors,  $Q_5$  and  $Q_6$ , and the current source transistor,  $Q_7$ , are used when data is transferred into or out of the cell. A particular



**Basic cell.** Sixty-four of these cells are deposited on a single 80-by-100-mil chip. The key to low power dissipation is the restore pulse.



Memory chip. The 64 individual cells are easily discernible in this microphotograph.

x-address line is common to all the cells in a single row of a chip, and one y-address line is common to all the cells in a column. Therefore, one x-address and one y-address pulse select a single cell on the chip. The y-address opens the gate of  $Q_7$ , applying the negative level of the x-address to the gates of  $Q_5$  and  $Q_6$  and turning both transistors on.

To read data from the cell, both digit lines are kept at or near ground. Assume that  $Q_1$  is conducting and  $Q_2$  is off. When  $Q_5$  and  $Q_6$  turn on, current from  $Q_1$  flows into the corresponding digit line through  $Q_5$ ; no current flows through  $Q_6$  because the drain of  $Q_2$  is already at ground. A differential amplifier of them is receiving the current, and thereby connected to the digit lines senses which senses the state of the addressed cell.

To write data in the cell, a positive-going pulse is applied to one of the two digit lines while the other remains at ground and while  $Q_5$  and  $Q_6$  are on. If, for example, this positive pulse appears at the source of  $Q_6$ , it is transmitted to the drain of  $Q_2$  and thence to the gate of  $Q_1$ , which, if previously conducting, turns off. The drain of  $Q_1$  discharges to ground through  $Q_5$  and the other digit line, and this ground level then turns on  $Q_2$ , reversing the states of the bistable elements.

The monolithic chip shown in the microphotograph at left measures 80 by 100 mils and contains 64 memory cells. These cells contain one bit in each of 64 different words. Thus 30 of the chips can store 64 full 30-bit words, and 16 sets of 30— 480 chips altogether—give the 1,024-word capacity of the memory. Each chip is mounted in an individual 22-lead flatpack.

#### Pro and con

The addressing method employed is similar to the coincident-current technique common in magnetic memories except that the Mos array uses coincident voltages. The Mos memory has a number of advantages over magnetic memories; for one, it requires simpler peripheral circuitry because its inherently non-destructive readout makes it unnecessary to regenerate stored data after reading it out. The relatively high-amplitude read-out signals from the array and high signal-to-noise ratio of the output also simplify the peripheral circuits. Neverthcless, the memory's power dissipation is mostly in the peripheral circuits, not in the storage elements, as in magnetic memories.

Volatility is the principal disadvantage of the MOS memory, as compared with magnetic memories. Even momentary loss of power invariably causes loss of data. This difficulty is somewhat offset by the low power consumption, which makes an auxiliary battery source practicable to prevent data loss.

Also, the mos memory cannot be used at temperatures over  $60^{\circ}$ C., nor unshielded in the presence of nuclear radiation.

#### Mad but methodical

The 1,024 words in the memory are addressed by 32 x-address lines and 32 y-address lines; one of each can locate any single word. However, each bit of the word is on a separate chip, so that each address line must be connected to 30 different chips. This leads to a rather complicated routing of the address lines.

The casiest way to visualize the routing is by analogy with a conventional three-dimensional memory. Such an organization contains 30 planes, stacked vertically, with 1,024 bits—one bit of each



**Rearrangement for routing.** The array of low-power monolithic chips can be handled conceptually by dividing the conventional 3-D array into 16 parts, lining them up and spreading them out on one plane.



Array. The 480 MOS chips, each in its own flatpack, are indicated in color. The address decoders and other peripheral circuits are also integrated, but use bipolar transistors.

word—in each plane. Each plane is an array of 32 by 32 bits, and is accessed by 32 address lines in each direction. One x-address line and one yaddress line intersect at one bit position on each plane; corresponding lines on all planes are interconnected so that one x-address line and one yaddress line intersect at 30 bit positions on the 30 planes.

The array of 32 by 32 bits on each plane can be realized by a square group of 4 by 4 chips stacked 30 deep with 8 by 8 bits on each chip. Eight address lines provide access to each side of every chip, and are connected across the gap between chips to provide continuity through each square group of 16 chips in the same way as in the basic 32-by-32 array.

But packaging chips in a 3-D stack isn't feasible. Somehow the 30 groups of 16 chips have to be rearranged into a two-dimensional layout, retaining the access in each direction by 32 address lines. This is where the complication in address line routing comes in.

If the 16 chips in each planar group are rearranged in a 1-by-16 row instead of a 4-by-4 square, and if the 30 rows, each 1-by-16, are laid side by side instead of being stacked on top of one another, the two-dimensional layout is achieved.

The first eight y-address lines are connected to all the chips in the first four rows of the final 16by-30 layout, the second eight y-address lines to the second four rows, and so on. The first eight x-address lines are connected to the chips in rows 1, 5, 9, and 13, the second eight to rows 2, 6, 10, and 14, and so on. As Shakespeare's Polonius said, "though this be madness, yet there is method in't."

The memory chips are shown in color in the block diagram above; the peripheral circuits, not colored, include the address decoders, write



Address decoder. A matrix arrangement translates five bits from the memory exerciser into 32 address lines that locate a specific word in the memory. A new inductive line driver circuit reduces the power dissipation [see detailed schematic diagram on page 145].

drivers, sense amplifiers, and timing circuits. The feasibility model also contains a memory exerciser (in the same suitcase!), which supplies write data and checks read data for errors.

The 1,024-word capacity requires a 10-bit address, which is divided into two five-bit parts, one for x and one for y. A common pair of digit lines connects all 1,024 memory cells corresponding to a specific bit in each word. One or the other digit line is pulsed by the write driver when data is being written, and current on one or the other digit line is picked up by the sense amplifier during a read operation. Write and read strobe signals activate the corresponding circuits during the respective operations, so that data being written does not pass through into the sense amplifiers.

#### On the periphery

Two identical address decoders generate the x and y signals for addressing the memory. The memory exerciser transmits 10 bits and their complements to the decoders—five bits to each decoder. In the decoder, eight NAND gates—standard commercially available integrated circuits—decode three of the five bits, and four other NAND gates decode the other two. A given address actuates one high-level and one low-level matrix driver, which together select a single address driver out of a 4by-8 matrix of address drivers; the low-level driver is actually only a ground return for the high-level driver. The address driver generates a signal on one of the 32 address lines.

The memory exerciser transmits the data to be written into the memory, each bit with its complement, on 60 lines to the write drivers, and the write command signal activates those drivers that have binary 1 inputs, placing the signal on the corresponding digit lines.

In the driver's quiescent state, transistor  $Q_4$  is conducting, as in the schematic opposite, ground-
ing the digit line. The write command signal and a binary 1 on the data line turn off  $Q_4$  and turn on  $Q_2$ , so that the 12-volt signal appears on the digit line. The disappearance of the write command pulse turns off  $Q_2$  and turns on  $Q_3$ , opening a fast discharge path for the digit line;  $Q_4$  turns on again, to hold the digit line at ground.

Each digit line is also connected to a sense amplifier. When a read command signal is received, the memory cells of the address word supply current to the digit lines. The sense amplifiers pick up the difference between the currents in the two complementary digit lines and generate an output accordingly.

In the sense amplifier, shown on the next page, transistors  $Q_5$  and  $Q_6$  form a differential amplifier that biases the flip-flop  $Q_1$  and  $Q_2$ . The strobe read signal sets the flip-flop to the state toward which the differential amplifier previously biased it. Buffer transistors  $Q_3$  and  $Q_4$  isolate the circuit from the output loading, which might be unbalanced and therefore more sensitive. In the absence of a signal from the differential amplifier, both transistors in the flip-flop turn off at the trailing edge of the strobe signal.

To avoid the large surge of current that would







Write driver. A 12-volt positive signal appears on the digit line through  $Q_2$  and discharges quickly through  $Q_3$ . The heavy line capacitance makes the inductor and switch combination of the address driver impractical here, but the circuit's low duty cycle keeps power dissipation down.



Sense amplifier. In the absence of a strobe pulse, this circuit is completely "off." A current differential on the two digit lines biases the flip-flop in the center, and the strobe sets the flip-flop in one of its two stable states, establishing the two complementary outputs.

occur if a restore pulse were applied simultaneously to the entire memory, the memory is divided into eight sections that receive a pulse one at a time in rotation. A self-contained restore clock, asynchronous to the rest of the system, steps a three-stage counter and, following each count, delivers a pulse to one of the eight drivers in an order determined by a decoder. The restore pulse driver circuits are quite similar to the address drivers.

Timing control is done entirely by integrated monostable multivibrators.

#### Pack it in

The MOS storage elements are packaged on both sides of two multilayer printed-circuit boards, each 12 by 14½ inches; a third board carries the xaddress decoder and the restore generator, and a fourth carries the y-address decoder and control circuits. All these boards are mounted in one end of the bottom of a Samsonite suitcase; the power supply is in the other end of the bottom. The memory exerciser is mounted at the top and connected to the memory by two connectors. An external computer could also operate the memory through these connectors.

The total measured power of the assembly is 3.4 watts, when the ratio of write to read operations is 3:10, the clock rate is 1 megahertz, and temperature is between  $0^{\circ}$  and  $60^{\circ}$  C. Continuous writing of data that repeatedly changes the state of every storage element in a word requires considerably more power than continuous reading, of course. Such continuous writing involves the active driving of many circuits rather than merely the detection

of their various states.

The memory array itself dissipates slightly less than 1 watt, thanks to the restore-pulse technique. The exact figure is 930 milliwatts, or 30.3 microwatts per cell. Another 0.7 watt is dissipated in the 64 address driver circuits, of which only two are in operation at any one time; the smallness of this amount reflects, to a large extent, the special switching circuits.

The technique for cutting the dissipation can best be understood by comparing it with the straightforward driving technique. The address, digit, and restore lines in the memory array present relatively large capacitive loadings to their respective driving circuits. The energy, W, stored in this distributed capacitance is

#### $W = \frac{1}{2}CV^2$

where C is the total capacitance in farads and V is the voltage across the capacitance.

The energy stored in charging the capacitance is, of course, returned when the capacitance discharges, because the capacitance itself ideally dissipates no energy. However, energy equal to that stored is dissipated in the resistance through which the capacitance is charged (to demonstrate, square the exponential expression for the current in an RC circuit, multiply by R, and integrate), and this amount of energy is dissipated in both the charging and discharging processes. Therefore, the total amount of energy dissipated in a single chargedischarge cycle is

$$W = CV^2$$

Power is the average rate of energy dissipation



**Driving principle.** A resonant capacitance-inductance combination changes the voltage across the capacitance quickly without dissipating any power. The switches prevent ringing. Resultant pulse is in color.

per unit time, or

 $P = W/t = CV^2/t$ 

But time measured in seconds is the inverse of frequency in hertz. Therefore

 $P = CV^2 f$ 

The typical capacitance of an address line is 1,200 picofarads. If, in addition, V = 26 volts and f = 1 Mhz, the dissipation is 0.8 watt. And since the memory contains two sets of address drivers, the total dissipation is 1.6 watts—as compared with the 0.7 watt actually attained.

#### Stop the clock

The designers managed to attain this power dissipation by using a line driver with an inductive output impedance to form a resonant circuit with the distributed capacitance of the line. The driver also has nonlinear characteristics that prevent this resonance from ringing, as shown in the simplified schematic and waveform sketch above.

The initial voltage on the capacitor is  $V_c(0)$ . After switch  $S_1$  is closed at time  $t_0 = 0$ , the voltage across the capacitor is

$$V_c = V_1 + V_c(0) - V_1 \cos \omega_o t$$

where

$$\omega_{\circ} = \frac{1}{\sqrt{\mathrm{LC}}}$$

At time  $t_1 = \pi/\omega_0$ , that is, after one-half cycle of the resonant ringing voltage, the capacitor voltage has reached its negative maximum,  $2V_1 - V_e(0)$ . For example, if  $V_1 = -7$  and  $V_e(0) = +12$ , this negative maximum would be -26 volts. If switch  $S_1$  is opened at this instant, the capacitor remains charged to this value; no power has been dissipated, because all the components are lossless in this idealized example. Effectively, the clock has been stopped at this instant.

If switch  $S_2$  is closed at some later time,  $t_2$ , the clock starts again and the capacitor voltage is

$$V_e \equiv V_2 + V_e(t_2) - V_2 \cos \omega_o t$$

where  $V_{c}(t_{2})$  is the voltage just prior to the closing of switch  $S_{2}$ . Both switches open at  $t_{2} + \pi/\omega_{0}$ . In the diagram, the two voltage sources have equal magnitudes and signs, and because the circuit is lossless, the final voltage equals the initial, meaning no power has been dissipated. In the actual circuit there are power losses in components and voltage drops across semiconductor switches,



Line driver circuit. Transistor  $Q_2$  is analogous to the switch,  $S_1$  at the top of the page; transistor  $Q_1$  corresponds to  $S_2$ . Capacitance is distributed along the address line. The diodes prevent the recharging of the capacitance after the first half-cycle of the ringing that would otherwise occur.

and  $V_1$  must therefore be of greater magnitude than  $V_2$  to compensate.

The address driver, shown at the bottom of page 145, embodies the design principles illustrated in the idealized example. The line capacitance is initially charged to +12 through resistor  $R_4$ . The primary of the transformer is shunted by a capacitor that balances the stray capacitance of the network when the high-level driver is actuated and the low-level driver is not. When the high-level driver turns on, therefore, the voltage appears across the transformer, turning on transistor  $Q_2$ .

The saturated transistor connects the line capacitance through inductance  $L_1$  to the -7-volt supply, and the resonant circuit begins to oscillate. But after only half a cycle, diode  $D_4$  becomes reverse biased, thus effectively disconnecting  $Q_2$  from the output.

When the high-level driver turns off, the transformer input voltage drops quickly, turning on transistor  $Q_1$ . (Observe the polarity marks on the transformer windings.) The line capacitance charges up to its initial level through  $Q_1$ .

When circuit losses and semiconductor voltage drops are considered, the parameter values shown provide a 26-volt negative pulse on the address lines. The angular frequency given by a 2.7-microhenry inductance and 1,500-picofarad capacitance is  $15.8 \times 10^6$  radians per second, corresponding to address-pulse rise and fall times of about 0.2 microsecond each.

The same technique is also used in the restore drivers, but not in the write drivers. The high digit line capacitance would have made additional power supply voltages necessary for an inductorand-switch circuit. But the write drivers normally contribute very little to total system power because of their low duty cycle.

The sense amplifiers dissipate very little power because they are essentially shut off in the absence of any input signal or strobe.

#### Up the road

Advanced as this memory system is, further improvements are in sight. The list includes:

•Complexity. About four times the number of bits could be built on a single chip with today's technology if a tenth the speed of the present low-power memory, or less, is permissible. With such a design, the same flatpack could also contain peripheral and restore-pulse circuits.

• Speed. When metal-over-metal crossovers are developed to the point where they can replace the present junction crossovers, they will afford either double the speed or double the density of the present chip, and could permit a substantially reduced restore-pulse duty cycle. Complementary Mos devices could boost the present model's speed by a factor of 10 or more.

• Power. A lower-frequency restore pulse would reduce power dissipation even further, and by a significant amount.

• Cost. Volume production is bound to bring it

down. Duplicating the present model would cost something over \$2 per bit. A production run of 1,000 systems would cost perhaps 50 cents per bit.

• Size. Larger memories following the present design could be easily made by adding flatpacks. The limiting factors would be reduced readout signal-to-noise ratio because of crosstalk, and the additional capacitance on the digit lines, with the resultant loading on the driver circuits. The size of the present memory could probably be double or quadrupled with only minor modifications—new shielding, new inter-connection boards, an 11-bit decoder, and perhaps a bigger suitcase. Memories larger than 4,096 words are practical, but would require multiplexed driving and sensing circuits. and would therefore dissipate somewhat more power per bit.

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### **Probing the News**

### Space electronics

### Space-ground link hardware on schedule despite setbacks

Philco-Ford and Motorola will have S-band ground system ready next spring for Air Force satellites from six stations

### By Lawrence Curran

Los Angeles regional editor

**Despite the miseries** the Air Force has endured in developing the space-ground link subsystem and its follow on, the advanced version, hardware deliveries will begin late next spring—right on schedule.

The first space-ground link subsystem (SCLS) was designed to standardize and consolidate all of the tracking, telemetry, and command functions of all Air Force satellites. Using ultrawide bandwidth and high-speed pulse-codemodulation techniques, at least three separate communications links are integrated into a single multiplexed S-band channel: ultrahigh frequency for command, S band for tracking, and very high frequency for telemetry. The advanced version was designed to boost the capacity of the subsystem's data rate from 1 million to 20 million bits per second.

Season's greetings. Late last year, it was reported that someone connected with the program had accepted gratuities from representatives of a firm interested in securing a development contract [Electronics, Dec. 26, 1966, p. 49]. An Air Force investigation confirmed the allegation, but concluded that the gratuities did not represent an attempt to influence the service's decision [Electronics, Feb. 20, p. 54].

Then, TRW Inc.'s systems group, which built an sci.s prototype that passed orbital tests with flying colors, ran into cost problems. As a result the company lost the ground station hardware development contract to a team composed of the Philco-Ford Corp.'s Western Development Laboratories, Palo Alto, Calif., and Motorola Inc.'s Government Electronics division, Scottsdale, Ariz.

Second thoughts. The latest problem concerns the advanced subsystems. Last month the Air Force cancelled a request for proposals for ground-station tape recorders to store the 20-megabitper-second data stream that was to have been transmitted by certain satellites. Observers close to both programs single out two spacecraft that would need the high data rate provided by ASGLS-the Manned Orbiting Laboratory (MOL) and the supersecret reconnaissance satellite known only as Program 949 [Electronics, Oct. 2, p. 26]. However, an Air Force spokesman says the MOL probably won't need the 20-megabit data link, and that concellation of the tape recorder project suggests that the satellite program requiring the high data rate has either been cancelled or reoriented.

Whether or not there is a spacecraft that requires the ASGLS, an industry source says the Air Force still anticipates a need for the high bit rate it provides, and development work continues.

Hardware for the orbital portion

of the advanced link is shrouded by security requirements but almost all of the ground terminal equipment for both the sGLs and ASGLS is unclassified. Motorola engineers, working on the ground equipment for the advanced version, have been ordered to stop work on a pulse-code modulation decommutator and check-out equipment for the orbiting vehicle. However, they have also been told to get on with the development of the rest of the hardware and to "quit conjecturing about what the final version of the system is going to look like.'

Motorola, Philco-Ford's subcontractor, will supply most of the ground terminal equipment for both the sGLs and the advanced subsystem. Fred Kemmeries. Motorola's engineering project manager for both programs, says the scls receiver's big jobs are to autotrack Air Force satellites with 14-foot and 60-foot antennas from six sites, provide up-link command data, and handle down-link telemetry. "In this sense, the link is very similar to NASA's unified S-band system," he says.

There will be ground stations at Vandenberg Air Force Base, Calif., on Guam, Hawaii, at New Boston, N. H., Kodiak, Alaska, and one in the Indian Ocean. Kemmeries says the Hawaii, Guam, New Boston, and Vandenberg installations will be equipped with advanced space-



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### ... Motorola emitter-coupled logic is used in the digital ranging gear ...

ground link sub-system gear. Motorola's sGLs contract specifies that the firm will provide Philco-Ford with a ground receiver and analog ranging equipment, essentially a monopulse tracking system, according to Kemmeries; digital ranging equipment; a digital range rate extractor; a demodulator; a doppler frequency converter; a baseband separation unit; and a 1.7 megahertz biphase subcarrier demodulator. Motorola expects to finish its share of the sGLS work before the first site-Hawaii -goes operational.

#### I. Versatile receiver

The sgls antennas are slaved to the receiver. Motorola built a receiver for TRW for the developmental ground stations but the current model has been redesigned. A wideband autotracking mode, incorporating a frequency synthesizer for continuous tunability over the scis spacecraft transmitter range of 2,200 to 2,300 Mhz, has been added as has fault-isolation circuitry and indicators that permit tracing of malfunctions to any of the 50 individual subassemblies. The fault isolation feature gives a 15-minute mean time to repair, says Kemmeries. The wideband autotrack mode is required because the receiver is a monopulse unit, and has recently been given the job of pointing the 60-ft. antenna for the ASGLS carrier. The unit already had the antenna pointing job for the sGLs carriers.

The scLs has two down-link carrier waves. The first—carrier 1 provides return ranging and various low-data-rate subcarriers up to 1.7 megahertz. The second—carrier 2—provides telemetry data at rates up to 1 million bits per second.

**Pickup.** When SGLS carrier 1, the basic S-band carrier, is operating, the receiver provides two error outputs—one each for azimuth and elevation. The 60-ft. antennas have four feedhorns picking up signals from the spacecraft. The receiver processes the outputs from the horns, summing and differencing them to provide an error signal.

These are S-band signals, which the receiver converts to two analog d-c voltages—one each for azimuth and elevation.

The error is zero when the spacecraft "is dead center on the antenna," says Kemmeries. A plus error or minus error is generated if the spacecraft is off center, and the error is fed to the antenna servo system to position the antenna properly in azimuth and elevation. Kemmeries says this antenna signal error detection function is performed in either a phaselocked or wideband mode; the 60ft. antenna is monopulsed while the 14-ft. unit is conically scanned.

In addition to detecting antenna signal errors, the Motorola receiver also does data-demodulating for the principal carrier for range, range rate, and telemetry signals. The digital ranging equipment is connected to the receiver and the ground station transmitter. This apparatus provides a digital code word, which the transmitter sends to the spacecraft's transponder. The word is a pseudo-random noise signal with a length of more than 5 million bits and a duration of 5 seconds, giving the ranging equipment the ability to track spacecraft at lunar distances-even though the Air Force requires only a synchronous orbit ranging capability.

### II. Odd jobs

The retransmitted signal sent back by the spacecraft transponder is demodulated by the receiver and fed to the digital ranging equipment; the system's accuracy is approximately 100 yards. All active circuitry in the digital ranging equipment uses Motorola emittercoupled logic supplied by the company's Semiconductor Products division. Kemmeries says there are 31 cards in the ranging equipment, with about 500 MECL packages per system.

Range rate—the spacecraft's speed—is determined this way: analog doppler outputs from the receiver are fed to the doppler frequency converter, which processes them together with a sub-

multiple of the transmitted frequency, and provides a signal that contains exact two-way doppler information. This output is fed to the range-rate extractor, which converts the data to digital form and sends it along to a ground station computer that produces a digital value for range rate. The extractor also uses MECL eircuitry and has a clock rate of 30 Mhz.

The sGLS receiver also demodulates telemetry and voice subcarriers that are transmitted to the baseband separation unit. There is a 1.024-Mhz biphase modulated subcarrier for low-speed digital telemetry at rates up to 128,000 bits per second; a 1.25-Mhz wideband — 20 kilohertz — subcarrier that is frequency-modulated for voice and wideband analog signals; and a 1.7-Mhz subcarrier that is either frequency modulated or biphase modulated, depending on the spacecraft mission, providing a data rate up to 256,000 bits per second.

Megabit monitor. The scls receiver also processes signals on a second S-band carrier transmitted from the spacecraft simultaneously with carrier 1 and feeds them to the carrier 2 demodulator. Carrier 2 accommodates biphase pem digital telemetry data at rates from 128,000 bits per second to 1 million bits per second. It is 5 Mhz lower than the carrier 1 frequency to provide the 1 megabit capability plus a guard band.

A third carrier wave processed by the scills receiver is the advanced subsystem data carrier. Kemmeries says the receiver will be able to pinpoint the groundterminal antenna even if this carrier is the only one transmitted by the spacecraft. Carrier 3 relays the spacecraft's pem signal at a data rate between 2.5 million and 20 million bits per second. It could also be used for wideband f-m transmissions up to 10 mhz. One observer points out that the latter capacity would permit the link to relay television signals from an orbiting vehicle.

Off the air. Most of the time, carrier 3 will probably not be operating at the same time as carriers 1 and 2. If it is, Kemmeries says, a second scLs receiver will be assigned to it, eliminating the need for a guard band like that between



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carrier 1 and carrier 2.

**Receiver refinements.** A threshold improvement demodulator in the receiver demodulates carrier 3's f-m data, using a wideband modulation tracking phase-locked loop that yields a 4-decibel threshold improvement. "This means that you can have 4 db less signal before you reach the deterioration point where the f-m signal is lost in noise," Kemmeries explains. He says that this is equivalent to extending antenna diameter from 60 ft. to about 95 ft.

The most significant features in the scls receiver, say Motorola officials, are the 4-db threshold improvement, the wideband autocorrelation capability with spectrums up to 35-Mhz of bandwidth, and tunability across the band using a frequency synthesizer in the phaselocked mode. These are all state-ofthe-art developments, Kemmeries says. For wideband autocorrelation, the receiver compares the signal on a sum channel with signals on two angle channels, and puts out a d-c signal proportional to the antenna-pointing error.

Motorola has a line of standard radio-frequency components in the receiver called E, for extruded, and P, for potted, modules. The E module is a standard plug-in aluminum housing for all r-f packaging; the P modules fit inside. Motorola has 19 standard modules. including phase detectors, mixers, wideband amplifiers (100 to 200 Mhz with relatively flat response), variable gain amplifiers, power amplifiers, video amplifiers, and phase shifters. These units are epoxy potted and plated with tin for r-f shielding.

Two for one. A typical sGLS ground station will have one of each of the ground station subsystems plus a backup. "This redundancy, in effect, gives you two stations at each site," Kemmeries says.

#### III. Advanced link

A typical advanced space-ground link subsystem terminal will have three wideband receivers, each with an f-m demodulator. There will be three pcm demodulators and two pcm bit synchronizers. All of these units are connected in-line. In addition, there will be two pieces of automatic checkout equipment—a pcm simulator and a test transmitter—to make loop tests when there is no airborne transmitter in the loop. All this equipment will be in six racks.

Motorola's Government Electronies division makes everything but the pem demodulators and the test transmitter, which are being developed by Phileo-Ford.

Government-furnished tape recorders and a classified piece of hardware to maintain communications security will be integrated into the terminal complexes.

The advanced link equipment picks up the S-band signals on carrier 3 only, and goes to work after the sGLs receiver has pinpointed the antenna. It has a minimum data rate capacity of 2.5 million bits per second. "The ASCLS hardware adds a high data rate pem ability to the tracking sites," says Kemmeries. "There is a receiver in the ASCLS that is a functional repeat of the SGLS receiver, but it has only about one-fourth the hardware of the SGLS version."

Separate ASGLS receivers are needed so that carriers 1 and 2 the SGLS carriers—and carrier 3 can operate simultaneously. In this situation, carrier three would be relaying signals from a different spacecraft at a different frequency from carriers one and two.

**Busy signals.** The receiver output goes to the pem demodulator, essentially a quadraphase demodulator, and two wideband phase detectors. It has a loop that locks coherently to the carrier. The pem demodulator can operate either quadraphase or biphase.

Kemmeries explains that the S band has four possible phases representing one of four possible vectors. In the quadraphase mode, the pcm demodulator has half the r-f spectrum width it does in biphase mode for the same bit rate. "This is so the Air Force can put more spacecraft into the S-band frequency," says Kemmeries. "The system could handle two or three if they were all ASCLS vehicles."

From the pem demodulator, the signal goes to the pem bit synchronizer, which has a phase-lock loop that locks coherently to the data and yields matched filter detection of the data. The pem bit synchronizer operates either biphase or quadraphase and incorpo-





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### ... the bit stream will be sent to custom equipment ...

rates a signal combiner to delete ambiguity from the data.

Kemmeries says that a matched filter in the pcm bit synchonizer "makes the best decision possible as to what digital symbol was sent to the space vehicle in the presence of noise that is corrupting the whole channel. The bit synchronizer puts out a string of zeros and ones that is neither in word nor frame format."

Before the recent program change, Motorola was to have furnished a general-purpose pcm decommutator that would recognize individual words and frames in the data, and set it up for data processing equipment. It now appears that the bit stream will be passed to data-processing equipment peculiar to the airborne user program.

#### IV. Hybrid approach

Rupprecht, George project leader in Motorola's advanced development section, says all the pcm equipment in the advanced link ground hardware the company is building will use hybrid integrated circuits from a semistandard line developed by the Government Electronics division with its own funds. These devices have been proven in other Motorola equipment, and Rupprecht believes this demonstrated capability was a big factor in winning the advanced link contract.

"We have six kinds of wideband amplifiers that have different functions," Rupprecht says. "The hybrids are used mainly in the basemostlv equipment, band for multiplier functions. There are high-gain and low-gain amplifiers, and some d-c restoration amplifiers, plus three straight differential amplifiers with varying gains and power levels. All have bandwidths greater than 100 Mhz. We use hybrid amplifiers because they give us the speeds and bit rates we need." The pcm equipment specifications call for a maximum bit rate of 24 million per second, and Motorola engineers are attempting to hold differential delays to typical speeds of around 0.2 nanoseconds.



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### Broadcasting

### Uhf television on borrowed time

Medium faces economic eclipse at hands of cable system operators despite best efforts of the FCC to promote and protect its interests

### By Peter J. Schuyten Assistant editor

Two months ago the Federal Communications Commission handed down a decision in a community antenna television case that spotlighted the tenuous commercial position of ultrahigh-frequency broadcasting. Cable tv is potentially the most lethal threat to uhf telecasting, the medium the FCC chose to nurture as the best means of easing overcrowded conditions in the very-high-frequency spectrum. Despite superficial statistics to the contrary, uhf has never really taken hold, and now CATY has it under the gun.

Because cable operators alleviate the vhf spectrum's traffic jam by distributing ty and other signals over coaxial cable networks, what

may well happen is that the entire television industry will have to plan its future around it.

In the Sept. 12 decision, the FCC denied a petition from the Suburban Cable TV Co. Inc. to bring signals from three independent New York City stations into Philadelphia. Officially. Subur-

ban's request was turned down because copyright legislation that might have a profound impact on the CATV business is pending in Congress. However, cable operators and conventional broadcasters appear well on the way to settling this matter on their own. With the copyright issue resolved, CATV interests will inevitably press new petitions in Philadelphia as well as other major markets.

The FCC's stated intention in pro-

moting uhf is to open the airways to more stations and stimulate a greater variety of programs than can be accomodated in the vhf range. In the U.S. there are 2,000 to 2.200 extra channels available in the uhf belt. But the advent of large-scale CATV systems makes the problem of the crowded vhf spectrum less critical.

New ballgame. In addition, cable ty threatens to break down the traditional market structure of broadcasting. Since the lucrative economics of this business have been largely based on an artificial scarcity of stations, the FCC has been forced to referee a very rough among special-interest struggle groups while trying to protect its

suggests that this situation is not necessarily a bad one. Nicholas Johnson, an FCC commissioner, for example, is at odds with his agency's policy. He believes Philadelphia, where three commercial uhf stations are operating, would be as good a place as any to check the impact of imported signals.

#### I. Late, late show

The question of just how uhf would fare without FCC protection is being raised at the theoretical midpoint of its development cycle. In 1964, when the law specifying that all tv receivers must be equipped to receive uhf went into effect, observers predicted it would take at least eight years before con-



favored fledgling.

The commission assumed regulatory jurisdiction over cable operators early in 1966 and effectively froze them out of the top 100 metropolitan markets in the U.S. [Electronics, June 26, p. 143]. But waivers have been, and are being, granted in many key outlets, including New York City and Los Angeles. As a result, uhf broadcasting is still very much in jeopardy.

An increasingly vocal minority

version was completed. This so-called allchannel law had roots in a hasty decision made by the FCC during the 1940's.

World After War II, the commission decided that ty would operate in the vhf band at first, despite urgent recommendations to the

own staff engineers. They reasoned -correctly as it turned out-that vhf lacked the capacity to accommodate a nationwide tv system.

Vested interests. But vast amounts of money had been invested in television before and after the war. With a payoff in sight, many parties impatiently pres-sured the FCC to authorize vhf broadcasting immediately. At the time, the development work on uhf transmission and reception

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### ... uhf broadcasting is ill-served by those who minimize its problems ...

equipment was a couple of years behind vhf progress. Rather than risk criticism for further delays, the commission gave vhf a go-ahead in 1948.

By 1949 so many stations operating in the same channels were interfering with each other that a three-year freeze on allocations was necessary. While the commission was studying the situation, uhf boosters watched in dismay as millions of tv sets equipped to receive only vhf signals rolled off production lines.

In 1952 the FCC rescinded its ban and opened up the uhf band. But there was little incentive for broadeasters to build stations because the chances of set owners spending extra money for uhf equipment were nil.

Eventually, the vhf band became so crowded that Congress—at the behest of the rcc—passed the allchannel law in 1962 in an effort to stimulate investment in uhf stations. Statistically, the legislation has proved a big success: an estimated 50% of the sets now in use around the country are equipped to receive uhf. And as of October the number of on-the-air uhf stations totaled 204, as against 573 vhf installations.

Mournful numbers. For all their optimistic projections, uhf operators and FCC officials are well aware that sets with uhf receivers are one thing and sets with uhf antennas quite another. Good reception of uhf tv signals depends as much upon the quality of the antenna used as it does upon the effective radiated power level of the transmitter. Although no definitive data have been compiled, there is a significant discrepancy between the total of all-channel receivers in use and the number that can get a good uhf signal without being tied into a community antenna television operator's system.

A source in the FCC's broadcast bureau is philosophical about the disparity. He says: "It's up to the set owner. If he wants good uhf reception, he should invest in a quality yagi antenna." However, the commission is apparently content to permit this position to popularize itself among consumers.

#### II. Bad press

Controversy over the quality of uhf television signals has also proved something of a drag on the field's growth. Network spokesmen in particular insist that uhf transmission is inherently inferior to vhf. However, the evidence suggests that any disparity is the result of economic, rather than technical, factors.

Test case. In 1961 the FCC got \$2 million from Congress to check the quality of uhf signals in New York City. A 50-kilowatt transmitter and an antenna mounted atop the Empire State Building were used. The experiment, conducted in a metropolitan area with every con-ceivable type of interference, proved that uhf signals are virtually indistinguishable from vhf. And, concluded the final report, under ideal conditions, the picture, in both black and white and color, is clearer. In addition, engineers say that because there is less manmade noise in this band, a light signal—assuming power is adequate—is inherently better than vhf.

The FCC has established 5 megawatts as the maximum permissible effective radiated power level for uhf stations. While one broadcaster is known to have boosted his signal into the 4-megawatt range with 110-kilowatt transmitter and a 1,000-foot-high tower antenna, the majority of new uhf stations simply cannot afford the kind of investment involved in such facilities.

#### **III. Prose and Cons**

Nor is uhf's cause particularly helped by efforts to minimize its difficulties. For example, William Walker, director of broadcast management for the National Association of Broadcasters, frequently speaks of the industry's rosy prospects at the trade group's regional get-togethers. The only factors that could retard the growth of uhf, says Walker, are direct broadcast satellites and CATV.

Actually, satellites are well

within the realm of technical possibility and cable television is increasingly a fact of life. So much so, in fact, that the Columbia Broadcasting System, the Westinghouse Electric Corp., the Tele-Prompter Corp., and the National Broadcasting Co., among others, are scrambling to expand their stake in the fast-growing field.

Schools of thought. The truth is that CATV is an emotional issue with uhf operators. David M. Baltimore, president of uhf station WBRE-TV in Wilkes-Barre, Pa., says: "Cablemen are a bunch of pirates, stealing property that belongs to the broadcasters." He believes CATV should be a supplement to tv rather than its master. "The prospects for uhf are good, if CATV can be restrained." he says.

But Seymour Siegel, director of New York City's Municipal Broadcasting System and head of uhf station WNYC-TV, says: "Cable tv has built the better mousetrap, and the broadcasting industry should plan its future around the new technology." As far as WNYC is concerned, Siegel believes CATV can only help the station fulfill its role as a minority interest programer by bringing signals into homes with reception problems.

**Tripartite.** Baltimore and Siegel represent two segments of the uhf picture. Baltimore's station has network affiliation while Siegel's programs largely for cultural and ethnic minorities. A third kind of operation, like WPIL in Philadelphia, is oriented toward an independent programing format. Such facilities are most seriously threatened by the emergence of CATV.

In the Philadelphia case, which involved WPIL, attention focused on the importation of distant signals as perhaps the most immediate hazard for uhf operators. Leonard Stevens, president of WPIL, says: "It is unfair competition when I have to pay for programing while CATV can bring in the same format over its cables without a fee and compete for an audience."

In the eye of this storm is the problem of copyright payments. "This issue should be resolved through negotiation within the next 12 months," says Frederick Ford, president of the National Community Television Association. "Once CATV is paying its own way,

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### **Playing the field**

Cable tv operators are moving nimbly to exploit the opportunities available to their medium. Among the newest: a service that will use CATV facilities to pretest the impact of television commercials in consumers' homes. A joint venture of the H&B American Corp., a large cable system operator, and Audits & Surveys Inc., a marketing research firm, the new company, Television Testing, will go after advertising agency trade.

The demographic and brand preference characteristics of four medium-sized markets—Ventnor, N. J.; Lompoc, Calif.; Dubuque, Ia., and Walla Walla, Wash.—are being profiled for storage in computers. These data banks can be sampled to get the reactions of specific audience groups.

Viewers selected by the computer will be advised to watch a certain program when tests are scheduled. A monitoring device will determine how many sets were tuned in for how long. Phone calls will be made to test consumers' recall and the results verified later by market surveys of the test area. The service will start in January.

it will be up to the FCC to reevaluate its position concerning the industry's right to import signals."

Another difficulty for uhf operators centers about network affiliation. A spokesman at one of the big three puts it this way: "The networks prefer not to spill programing into uhf; they do so only when there are no other outlets in an area." This source cites two reasons for this policy: "There is at best a 50% penetration of uhf receivers in the television market, and even with a maximum effective radiated power the quality of a uhf picture is not as good as vhf."

Niche. Since uhf's future will be determined to a large extent by the fate of the vibrant CATV industry, many observers believe the whole broadcast field must reorient its goals to accommodate the upstart. Siegel, as well as several FCC commissioners, suggests that uhf operators should seek to provide viewers with programing unobtainable elsewhere. Shows keyed to self-improvement including cultural, educational, and communityinterest formats are among the possibilities.



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The pictures at the left represent rain on a 60-square-mile area in east-central New Jersey on November 28, 1966. Actually, they are four photos of a computer-generated display. The brightness of each little "patch" indicates the rainfall rate at each of 93 gauges spaced throughout the area.

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Voltage (V <sub>FB</sub> /V <sub>FT</sub> )	1500/ 1800	1300/ 1550	1300/ 1560
dv/dt			
(Exponential to full V <sub>F8</sub> )	300	200	200
$I_{gt}$ (T <sub>J</sub> = 25°C)	100	150	150
COMPARISON OF REPEOR			91179

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Applied Current			
(054=.44°C/W, TA=40°C	C) 40	35	35
Voltage (V <sub>FB</sub> /V <sub>FT</sub> )	1500/ 1800	1300/	1300/
dv/dt	1000	1000	1000
(Exponential to full V <sub>FB</sub> )	300	200	200
$I_{ot} (T_j = 25^{\circ}C)$	100	100	150

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## **Countdown begins on Intelsat's future**

Hallway talk at ITU conference centers on Comsat plan to revise ownership of consortium at 1969 parley and on big question of contract allocations

More prelude than climax, the twoweek planning conference of the 137-nation International Telecommunications Union ending Nov. 15 in Mexico City sets the stage for the 1969 renegotiation of the agreements covering worldwide satellite communications systems. Formal sessions at this month's get-together concentrated on projections of 1970-75 global telecommunications needs. But satellites proved the unbilled stars of the show—especially among delegates from the 60 member nations of the International Telecommunications Satellite (Intelsat) consortium.

Unofficially at issue in Mexico City were touchy questions raised by the Communications Satellite Corp.'s white paper outlining the U.S. position on the future of Intelsat [Electronics, Oct. 30, p. 52]. Resolution of these problems will not only shape the future of intelecommunications ternational systems but give foreign nations a greater voice in the management of the consortium. At stake, of course, is national pride as well as a bigger share of the procurement pie, which thus far has been largely the preserve of U.S. firms.

#### I. Counterrevolution

The initial Intelsat agreement signed by 13 nations in 1964 specified that the structure of the organization be subject to renegotiation in 1969. The Interim Communications Satellite Committee, established to hammer out recommendations for a permanent organization and global system, will hold its 29th meeting Nov. 29 in Washington, D. C.; six additional conferences are scheduled before the 1969 renegotiation sessions.

Last month, Comsat, Intelsat's manager and majority stockholder, began pushing for an expansion of the organization's communications role. In a proposal urging that the consortium continue in essentially its current form, the company seeks authorization for Intelsat to operate navigation, weather, aeronautic, and earth-resources satellites as well as spacecraft providing communications services.

**Gun shy.** In an effort to blunt charges that it dominates Intelsat, Comsat suggests that the maximum voting strength of a single nation be limited to 50%; each member's share would be determined by its use of consortium-supported facilities—excluding domestic satellites. This formula would reduce Comsat's share from the current level of 53.5% to perhaps 35% by the early 1970's.

The U.S. position paper takes no notice of independent regional satellite systems, but Comsat is known to be dead set against such projects. The paper outlines four plans for domestic satellite service —all within the Intelsat network.

Finally, Comsat recommends that it serve as Intelsat's manager under a formal contract with the interim group, meaning that it would continue to negotiate and administer all contracts. The com-

pany contends that this "would provide continuity and make use of the experience accumulated."

#### II. Yanqui no!

The question of who gets hardware contracts is potentially the biggest stumbling block to an Intelsat accord in 1969. The consortium's four present operational satellites—two over the Pacific and two over the Atlantic—were all built by the Hughes Aircraft Co. On order from the systems group of TRW Inc. are six 1,200-channel Intelsat 3's, the latest generation spacecraft; the first will be delivered next spring, about three months behind schedule.

Overseas contractors and foreign governments aren't particularly pleased with the made-in-America stamp on operational hardware. But a source at a West Coast concern with a large stake in communications satellite development claims the situation is changing. If the recent study contracts for Intelsat 4—a 10,000-channel multipurpose bird [Electronics, Aug. 21, p. 59]—are any criteria, he says, at least a third of the systems work

#### Share the wealth

While national feelings and simple economics are spurring foreign members of the International Telecommunications Satellite consortium to press for a better break on hardware awards, a successful U. S. contractor may, on its own, have broken the American grip on these orders. An estimated 35% to 40% of the work on two Intelsat 3 satellites being built by the systems group of TRW Inc. will be handled by firms from outside the U. S.

Officials at TRW say Comsat's request for proposals didn't mention foreign participation. But after TRW suggested using overseas contractors, Comsat took to the idea and wrote it into the contract, which covers six spacecraft and provides an option on 12 more.

As a result, the following outfits will furnish the designated support on the fifth and sixth satellites in the series: Britain's Hawker Siddeley Dynamics Ltd. (spacecraft structure); France's Société Anonyme de Télécommunications (solar array) and Engins Matra SA (attitude-determination subsystem); Japan's Mitsubishi Electric Corp. (power subsystem, excluding battery and solar array); Switzerland's Contraves AG (electrical integration assembly); and West Germany's Entwicklungsring Nord (positioning and orientation propulsion system). **PERMACOR®** powdered iron cores ...unequalled for design and prompt delivery !



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## ... Comsat's sweeping proposals for Intelsat were artfully timed ...

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Some of the more important members of the consortium would like an even bigger share of the contracts, however. Japan, a number of European nations, and Australia would like the 1969 agreement to stipulate that every third satellite be built outside the U.S. Such a provision is probably unrealistic, this official says, because most nations trail the U.S. in such key fields as reaction controls and apogee motors.

**Play for time.** But there may still be some international footdragging on Intelsat 4 in the hope of a better deal after the 1969 renegotiation. Intelsat has to get the interim committee's approval for the launch, scheduled for 1970. If a go-ahead could be put off, some reason, many countries could catch up technologically.

The U.S. executive believes the less developed nations won't put obstacles in the way of Intelsat 4 since they badly need the communications services it could provide. He also holds that Comsat should continue to oversee international operations, but that management of regional and domestic systems be delegated to area associations and individual countries.

#### **III. Skillful ploy**

Comsat's sweeping proposals for Intelsat's future were artfully timed. Most interested parties have had insufficient time to develop hard positions, and the company expects no substantive reaction before a mid-January meeting of the interim group. In the meantime, Comsat will have had the benefit of being able to gauge the potential response to its bombshell.

One thing is already clear: the formula linking votes to usage should bring some offbeat supporters into the American camp, where Japanese and British authorities profess to be already. Italy, for example, takes greater advantage of Intelsat-financed facilities than do either France or West Germany. The same may soon be true of Spain, which activates a ground station this month and expects an increase in its traffic with South America.

Such a prospect cannot help but vex France and Germany, which are planning to put a regional communications satellite system, called Symphonie, into service by 1971. Comsat opposes such efforts on the grounds that they will "drain the global organization."

However, neither France nor Germany appears particularly discomfited by Consat's stance; the French for their part have urged that communications satellite activities be autonomous in each of four geographical sectors of the globe, and that Intelsat's authority be reduced to coordinating overlapping efforts.

Home front. Domestic satellite systems also threaten international communications amity. Canada, for one, is determined to get an operational network-with or without U.S. cooperation—by the early 1970's [Electronics, Sept. 4, p. 131]. In proposing that domestic satellite programs without Intelsat blessing be proscribed, Comsat can fall back on the technological muscle of the U.S. Renegade nations would presumably get short shrift from the National Aeronauties and Space Administration should they seek launching facilities, boosters, and the like. However, the European Space Vehicle Launcher Development Organization may eventually offer an alternative to U.S. aid-albeit an expensive one-and Russia appears willing to support selective efforts. The Soviets have agreed to put up a French research satellite, and the two countries already exchange tv broadcasts over Russia's Molnya.

Ironically, Comsat's stringent proposals in this area are at odds with a recommendation it made last April for a pilot project. At this moment, the company is in the incongruous position of resisting domestic programs outside the Intelsat orbit while trying to get an independent project off the ground for the U.S.

Comsat officials point out that domestic satellites will be a necessity for certain countries. In Chile,

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for example, the Andes mountains constitute a communications barrier between north and south. And Brazil could use a satellite system for communications between its populous east coast and primitive interior regions.

#### IV. The big picture

James McCormack, Comsat's chairman, lists navigational aids for air traffic control, shipping assistance, rescue work, disaster warning, and earth-resources management as potential jobs for Intelsat. Although the company anticipated little opposition to such grandiose schemes, a division of opinion is already shaping up. German officials feel that the density of air traffic in Europe is not great enough to demand Intelsat control, so they plan no push for such services. France is also unenthusiastic about e x p a n d i n g applications within Intelsat's framework, but might go its own way, possibly with Russian help, to establish an independent system for areas it considers important—West Africa, Europe, and Canada. On the other hand, Italian sources back Comsat. "It's not the service but the means," says one.

Room at the top. Another problem, one of a technical nature, is sure to affect the outcome of the Intelsat renegotiations. The equatorial belt, the only space location that can accommodate communications satellites in synchronous orbit, has a finite capacity; just how finite has been the subject of feverish investigation. Last month, Comsat reported that two spaceeraft can operate within less than 2º of each other in a 23,000-milehigh orbit without interference (at this altitude, 2º equals about 1,000 miles). Before the latest experiment, estimates of the necessary separation ranged from 2° to 6°.

However, though there is more parking space up there than most observers had dared hope for, some locations are more attractive than others. For example, the optimum spot for a communications satellite linking London and Tokyo is 26.5° east longitude. Spacecraft more than 1° off either way would lose one of the cities. As a result, the number of satellites linking London and Tokyo will have to be held to two or three at the most.

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The odds against Surveyor 5's success jumped to 1000 to 1 when a loss of helium pressure was detected shortly after midcourse correction. Without sufficient pressure to move propellant to its three small vernier engines, the spacecraft could not be slowed and steadied to a soft landing on the moon.

Racing against time, a task force of NASA, Jet Propulsion Laboratory, and Hughes scientists worked around the clock to program a new landing sequence, telescoping 11 weeks of work into 40 hours. They verified their calculations on computers, tested duplicate vernier engines, then radioed the instructions that brought Surveyor 5 to a perfect soft landing.

When Surveyor 5 was turned off for the lunar night on September 24, it had returned 18,006 pictures of a new potential landing site for astronauts and had lowered a device to analyze the chemical composition of the moon's surface by radiation.

The new shipboard satellite communications sets Hughes is now delivering to the U.S. Navy promise to end the interruptions and blackouts caused by atmospheric and solar disturbances that have long plagued long-distance radio transmission. Shipboard or base commanders will be able to communicate with each other by voice or Teletype over vast distances. Messages will be relayed by DOD's random-orbiting satellites.

The birth of Hurricane Sarah was discovered in a cloud-pattern photo of the eastern Pacific taken September 6 by NASA's ATS-1 satellite. Succeeding photos showed Sarah's growth to a fullfledged hurricane on September 11 (its title was changed to "typhoon" when it crossed the international date line September 14). The 2,000 residents of Wake Island, warned days in advance, were safe in typhoon-proof buildings when Sarah's 140-mph winds left the outpost a shambles on September 16.

Full-color photos of the Atlantic cloud pattern will be taken by the ATS-C satellite scheduled to be launched this fall. The spin-scan cloud cameras for both ATS satellites were developed by Santa Barbara Research Center, a subsidiary of Hughes Aircraft Company, which is building the Applications Technology Satellites for NASA's Goddard Space Flight Test Center.

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The Apollo manned lunar landing vehicle and the Saturn booster will also be equipped with Hughes TWTs. Other spacecraft include Lunar Orbiter V, Venus-bound Mariner V, and Pioneer.



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Angeles, Calif. 90022. Or phone (213) 722-6810.

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under "Tape". Or write: The Borden Chemical Company, Mystik Tape Div., 1700 Winnetka Ave., Northfield, Illinois.



Electronics | November 13, 1967

## POLY-SIL PLASTIC MIL RECTIFIER At half the cost of glass

Popular 1N3611 series now available from IRC... off-the-shelf.

Up to now these units were available only from one source and at nearly twice the cost. Now, IRC (the resistor people) offers a Poly-Sil rectifier that's a real money saver for all your low-power MIL applications. Check these prices.

TYPE	1.99	100.999
JAN 1N3611	\$1.49	\$.99
JAN 1N3612	1.95	1.30
JAN 1N3613	2.70	1.85

Commercial versions at lower cost

#### These units have a single-cycle surge rating of 20 amps.

Tough and durable, Poly-Sil completely surrounds all internal parts. This solid construction is stronger than comparable glass packages. A great combination of low cost and superior performance, the 1N3611 series is available off-the-shelf in production quantities. See your IRC representative or write for data. IRC, Inc., Semiconductor Division, 727 Lynnway, Lynn, Mass. 01905.

SPECIFICATIONS			
ACTUA	LSIZE		
MIL	Meets MIL-S-19500/228D		
RATINGS	2A @ 25° C		
	1A @ 100° C		
	0.3A @ 150° C		
VOLTAGE	. 20 <mark>0, 400, 600</mark>		
TEMP. RANGE			
operating	65° C to 150° C		
storage	65° C to 175° C		



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## **New Products**

New computer equipment

## Massive core memory runs at lightning speed

Capacity of almost 20 million bits and cycle time of 2.7 microseconds can double computer productivity

This week at the Fall Joint Computer Conference in Anaheim, Calif., the Ampex Corp. introduces a memory with a speed-capacity combination that can double the productivity of computer systems using bulk core memories.

The model RM has a cycle time of 2.7 microseconds and a capacity of nearly 20 million bits, a double feature unique among memories of comparable cost. It will sell for less than three cents per bit, or about \$500,000. Smaller versions with one or two 5-million-bit sections will also be available.

"We expect high-speed mass memories to play a big role in new generations of large-scale computers," says Eugene E. Prince, Ampex vice president. "They will provide substantial programing and run-time economies."

In capacity and speed, a bulk core memory usually stands midway between a computer's main memory and its auxiliary storage units, such as magnetic disk files and magnetic drums.

A main memory has a cycle time that may range from 0.5 to 2.0  $\mu$ sec, but a capacity of no more than 2 million bits. Faster memories are considerably smaller. Disks and drums, on the other hand, can store 1,000 times more data. And, in some cases, they can deliver the data at dazzling speeds. Because they are electromechanical, however, they require milliseconds to locate stored data before they can produce it. Bulk core units store between 10 and 100 million bits, and most have cycle times between 5 and 10  $\mu$ sec.

The yardstick. Two main memories presently available on commercial computers exceed the performance of the new Ampex bulk core unit. One is on the General Electric Co.'s 635 computer, and the other on the Burroughs Corp.'s B-8500. The 635 memory, which is made by Ampex, has a 37-million-bit capacity and operates with a 1-µsec cycle; it consists of 32 one-million-bitplus modules operating in parallel, and is considerably more expensive to produce than the new memory. The B-8500 has a 12-million-bit capacity, and a 0.5-µsec cycle. But unlike ce's, Burroughs' memory is a thin-film type.

In comparing memories in size and speed, the yardstick is the quotient of number of bits in millions divided by the cycle time in microseconds. For most bulk core memories this comes out between 5 and 10; for the Ampex machine, it is 13.3; GE, 37; and Burroughs, 24.

Only one other commercially available memory approaches the speed of the Ampex RM, but it is only half the size. Fabri-Tek Inc. has a 10-million-bit memory with a 2.75- $\mu$ sec cycle time.

#### I. Interleaved sections

Ampex's RM is made up of four sections, each having almost 5 million bits. Each section has its own

decoding, driving, and sensing circuits, enabling it to be operated independently of the others. The memory is capable of accepting four different read or write commands from the computer 200 nanoseconds apart. After four commands have been received, a 1,900nsec pause is necessary before the first section can accept another command.

Called interleaving, this technique is commonly used in large memories. The 200-nsec limit is determined by the time required to load an address into a section's address register. Most computers cannot generate new memory requests that fast. The Ampex unit can operate continuously in the interleaved mode at an average cycle time of 675 nsec—one-fourth the complete cycle time for each section—which is a little more realistic for present-day systems.

Share technique. The four sections share two sets of input and output data and control paths, enabling the entire memory to operate as a common-data bank for two independent computers. Each section has its own auxiliary keyword memory, with which either computer can protect its own data from access or destruction by the other -a standard procedure without which no multiprocessing system would be feasible. With the auxiliary memory, access to the bulk memory must be accompanied by a keyword; keys stored in the auxiliary memory correspond to different blocks of storage in the bulk memory. Unless the keyword matches the corresponding key, the memory rejects the attempted access.

#### II. Two dimensions plus

The memory has a 2<sup>4</sup>-dimensional organization—that is, a single bit-wire threads 1,024 cores in one direction and 1,024 in the opposite direction. Selection of either set of cores is the termined by the direction of current in the 1,024



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Flat plane. A single five-million-bit section opens, like pages in a book, for maintenance and repair.

word windings that are common to each. One word-winding wire threads two corresponding cores, one in each set. For increased reliability, each wire passes through the fold in the array, thus reducing the number of solder connections that must be made during fabrication of the memory.

Data is stored in the form of 262, 144 words of 72 bits each. These 72 bits are written into or read out of the memory in parallel, and can represent eight standard computer bytes of nine bits each, or two 36bit words, or any other submultiple of 72. Each section of 65,536 words is mounted on its own folding ground plane, resembling a fourpage booklet having 16 square mats of cores on each page.

The memory's high speed was attained by minimizing the length of lines, and running the bit and word lines close to the ground plane, thus limiting inductance. The bit lines also go out and back, through adjacent rows of cores another way of minimizing inductance.

Double duty. Even higher speed would have been possible if the designers had not sacrificed some features to minimize costs. Only two wires thread each core; so the same wire is used for bit current when writing, and for sensing when reading. Every memory cycle consists of a read half-cycle followed by a write half-cycle. When reading, the write half-cycle restores the readout information. Because of the wiring's double duty, transients on the lines must be allowed to die out before bit current can be sent. This takes time.

There is also only one sense amplifier per bit, which cuts costs but increases the number of cores serviced by a single amplifier. This increases the amount of noise that a single amplifier must screen out.

Ampex Corp., Computer Products Div., Culver City, Calif. [338]

Electronics | November 13, 1967

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### **New Components Review**



The Modiflex capacitors, using a combination of synthetic film and a liquid plastic dielectric, are rated up to 250  $\mu$ f. Standard tolerance for nominal values of 0.1  $\mu$ f and higher is  $\pm 10\%$ ; under 0.1  $\mu$ f,  $\pm 20\%$ . Power factor is 0.004 at 60 hz and 25°C. Operating temperature without derating is  $-40^{\circ}$  to  $+125^{\circ}$ C. Industrial Condenser Corp., 3243 No. California Ave., Chicago 60618. [2341]



Double-triode-pentode compactrons are for color tv receivers. The 6AK9 has a heater voltage of 6.3  $\pm$ 0.6v, a heater current of 1.6 amps. The 16AK9 has a heater voltage of 16.4 v, a heater current of 0.6  $\pm$ 0.04 amp. The pentode section is suited for vertical deflection amplifier use; triode sections, for general purpose uses. General Electric Co., Owensboro, Ky. 42301. [345]



A fixed time delay relay encapsulated in epoxy is for p-c and aerospace uses. It is a spst, normally open unit with an input-output isolation resistance of 1,000 megohms at 100 v d-c. It operates from -40° to 60°C. Life expectancy is 15 million cycles. The unit is 1% t 1 $^{3}\%$  4 x % 16 in. Price starts at \$25.65. Universal Technology Corp., 107 New St., Pittston, Pa. 18640. [342]

Tuning-fork resonator TF600 is a

1/2-0z, 0.2-cu-in. unit that can be

provided with any fixed frequency

from 400 hz to 2,400 hz. Accu-

racy is 0.01% at 25°C. Operating

temperature range is -55° +

85°C. An input of 6 ma at 28 v

d-c is typical. Output is up to 5 v

rms into 20 kilohms when used

with proper drive. Bulova Watch

Co., 61-20 Woodside Ave., Wood-

side, N.Y. 11377. [346]



Metalized polycarbonate capacitors series 22E, in hermetically sealed tubular cases, come in 200, 400, and 600 v ratings in sizes from 0.174 x 0.500 in. to 0.750 x 1.875 in. Capacitance values are 0.001 to 5.0  $\mu$ f with tolerances from 20% to 1%. Temperature coefficient is 1.5% max. change from -55° to 25°C. SEI Mfg., 18800 Parthenia St., Northridge, Calif. 90324. [343]



Miniature axial fans series 7500 combine high air delivery and low noise level. They feature aerodynamic design of the pressure type blades. With a free air delivery of 275 cfm, the unit will sustain delivery as high as 225 cfm at 0.2 ln. of water back pressure. The venturi design limits noise factor to a low of 40.5 db at 3,350 rpm. Pamotor Inc., 312 Seventh St., San Francisco 94103. [344]



Size 8 synchros are available with over-all length of 1.015 in., which is 0.226 in. less than standard size 8's. Weight is also reduced to 1.15 oz. Standard accuracy of 7 minutes max. error is maintained. The line includes transmitters, control transformers, and differentials. Units have stainless steel housing. Clifton Div., Litton Industries, Marple at B'way, Clifton Heights, Pa. 19018. [347]



Enclosures known as Mini-Cool are constructed to contain a variety of precision devices. The line is available with integral heat sink walls. Made of lightweight aircraft alloy aluminum, they feature a lock joint at each corner which tightens when the screw fasteners are installed. Sizes range from 2 x 2 x  $1\frac{1}{2}$  to 2.6 x 2.6 x 10 in. Sarex Corp., 1001 Roosevelt Ave., Carteret, N.J. 07008. [348]

#### New components

## Avalanche brightens photodiode outlook

Detector combines high gain of photomultiplier tube with small size and power requirements of photodiode

**Combining the best** of two worlds is a silicon photodiode that operates in an avalanche mode. Developed by EG&G Inc. and designated the AV-102, the unit offers the lowvoltage and small-size advantages of solid state light detectors while providin r the hi h-rain and lownoise characteristics of photomultiplier tubes.

In photomultiplier tubes, which usually have 10 sections (dynodes), the emission from one section triggers the next so that a cumulative effect produces high gain. The disadvanta es of these tubes are that they are large and require both a high-voltage power supply and a high-impedance load. But at high frequencies, high impedance causes a noise problem.

Photodiodes, on the other hand, are small, low-voltage devices requiring low-impedance loads, thus avoiding the high-frequency noise problem. But they lack high gain. What EG&C engineers wanted was a device that incorporated the advantages of both a photodiode and a photomultiplier. The company considered such a product highly marketable, particularly for laser communications systems in which high gain and low noise at high



Unlike conventional relays that require a continual energizing of the coil to hold contacts open or closed, the RBM137 bistable relay transfers contacts on a momentary coil pulse, and contacts remain in a position of transferred state until coil is again pulsed. Unit is available in pole forms up to spdt, 12 amps at 115 v a-c. Essex Wire Corp., 131 Godfrey St., Logansport, Ind. 46947. [349]



Subminiature, snap-action switch series 15 features a self-cleaning, full-floating blade that dampens actuation shocks reducing contact bounce. It has a 360° enclosed high temperature housing of diallyl phthalate. The switches are guaranteed for 1,000,000 operations minimum. Fine silver contacts are rated at 5 amps. Hi-Tek Corp., 2220 S. Anne St., Santa Ana, Calif. 92704. [353]



Plug-in chopper model 75 features a transformer-coupled isolating drive network so that it can be driven from a 400 hz power line or from a drive source that is common to the d-c voltage being chopped. Sinusoidal or square wave drive may be utilized from 270 hz to 100 khz. Units withstand shock of 500 g for 11 msec. Solid State Electronics Co., 15321 Rayen St., Sepulveda, Calif. 91343. [350]



of single-ended analog signals, a solid state relay is adaptable for commutator input gates, choppers, dry circuit, a-to-d voltage comparators, and sample and hold amplifiers. Offset voltage is  $\pm 50 \ \mu v_i$ signal sensitivity, 1 $\mu v_i$  signal level,  $\pm 10 \ v$ . Units measure 0.6 x 0.6 x 0.8 in. WEMS Inc., 4650 W. Rosecrans Ave., Hawthorne, Calif. 90250. [354]



Industrial/commercial p-c transformers in the Deci-Miniature series are designed for control, instrumentation, audio, molded and other solid state applications. All have molded-in terminals that provide fixed mounting centers. Units measure  $\frac{3}{4} \times \frac{3}{4} \times \frac{19}{12}$  in., weigh  $\frac{1}{2}$  oz. Prices range from \$2.10 to \$3.50 in 100 lots. Microtran Co., 145 E. Mineola Ave., Valley Stream, N.Y. 11582. [351]



bise of white bolts at all critical terminations eliminates variable or high resistance connections in the EBA series aluminum-cased electrolytic capacitors. Capacitance ratings are from 1 to 1,000  $\mu$ f, with d-c nominal voltage ratings of 3, 6, 10, 15, 25, 35, 70, and 100 v. Units measure from  $\frac{1}{2}$  in. In diameter and  $\frac{4}{3}$  to  $\frac{1}{2}$  in. Iong. Aerovox Corp., New Bedford, Mass. 02741. [355]



Molded epoxy, solid tantalum capacitors, the Econotan E series, are for high volume commercial use where cost, space, and radial leads are important. Tolerances are  $\pm 20$  and  $\pm 10\%$ ; ratings, 35 and 50 wvdc. Capacitances range from 0.0047  $\mu$ f at 50 wvdc to 22  $\mu$ f at 6 wvdc. Leakage is 0.02  $\mu$ a/ $\mu$ f-v; impedance, less than 1 ohm at 1 Mhz. Components Inc., Smith St., Biddeford, Me. 04005. [352]



Dry reed relays series MRRK have a two-piece, molded thermoplastic case. Terminals and cover are welded ultrasonically to form a scaled, moisture-proof enclosure. The relay base holds up to 10 terminals with 0.1-in. grid spacing. Operating temperature range is  $-25^{\circ}$  to  $-1.85^{\circ}$ C. Insulation resistance exceeds  $10^{12}$  ohms. Struthers-Dunn Inc., Pitman, N.J. 08071. [356]

frequencies are necessary.

New tactic. The AV-102 ushers in another phase of EG&G's new marketing approach. Previously, the company would work on a new device only if it was needed for a system that EG&G was developing. The change in thinking stems from the company's diversification program which includes development of custom-made radiation-detection systems and components based on semiconductor technology. The Massachusetts company has been prime contractor to the Atomic Energy Commission for instrumentation of nuclear explosions since its founding 20 years ago. In addition



Peaked. Spectral response of the avalanche diode peaks at 0.9 microns.

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Shown below: commercial Model PL- $\frac{1}{2}$ , for systems up to 150 gallons. Others available for systems up to 12,000 gals, and larger.

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505 Rivermor Street Boston, Mass. 02132 ... avalanche mode boosts gain ...

to diversifying through acquisition of smaller companies, it is designing lines of high-speed devices to detect and measure nuclear events. The new diode is a further extension of this program into special semiconductor devices.

The avalanche diode's spectral range is from 0.35 to 1.13 microns, with its response peaked at 0.9 the wavelength of light emitted from gallium-arsenide lasers. The major problem with laser systems is that because the beam has to travel long distances, the amplitude of the signal portion of the beam gets lost in noise. To reduce the effects of noise, the detector's impedance must be low and its signal-to-noise ratio, high. The AV-102 satisfies both conditions.

Avalanche threshold. If the AV-102 is operated below 11 volts the point at which it goes into avalanche—its gain would be that of a conventional photodiode. But when operated in the avalanche mode, with a cumulative multiplication of carriers taking place, the diode's gain is increased 300 times. This increase is caused by the entire junction area being active. In conventional photodiodes, only part of the junction is active.

Memory systems is another application in which the AV-102 could be teamed with a laser. Reading out information after it has been recorded on photographic film, for example, requires a highly sensitive detector because much of the light is lost to the film. Also, the detector requires the capability of rapid response to a wide range of frequencies. This type of memory has applications where a large quantity of read-only data is to be stored for future recall.

#### Specifications

Signal·to-noise improvement	300 to 1 for 50- ohm load
Sensitivity at 0.9 microns	0.5 µa/µw
Spectral range	0.35 to 1.13 mi-
	crons
Frequency response	d-c to 1 Ghz
Operating avalanche voltage	8 to 15 v
Junction capacitance	1.5 pf
Dark current at 1 v	0.001 µa
Active area	2 x 10 <sup>-5</sup> cm <sup>2</sup>
Package	TO-18
Price	\$275

EG&G Inc., 160 Brookline Ave., Boston, Mass. 02215 [357]

## RCA's high-density memory stacks are tested and proved to military specifications

These military-type high-density stacks are available in various capacities up to  $4k \times 32...$  operating temperature range from -55°C to +125°C. And we can provide fast delivery of most configurations... just let us know your requirements!

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RCA "building-block" construction provides wide flexibility of electrical capacities, ruggedized construction, improved reliability and faster delivery.

Greater reliability is assured because core mats are continuously wound—solder joints are kept to a bare minimum. Fewer frames result in smaller size, lighter weight, tighter, more compact package. The RCA 30/18 lithium ferrite cores provide wide-temperature operation. The complete package withstands vibrations up to 15G's.

Backed by more than two years of manufacturing experience and strict quality control, these RCA High-Density stacks are proved to MIL specs before you order them. In many cases we can make initial deliveries in eight to ten weeks.

May we have one of our salesmen arrange for a demonstration for your specific military applications? Contact your RCA Field Representatives for details and availability for your requirements. Or call Marketing Dept. (617-444-7200), RCA Memory Products Division, Needham Heights, Mass. 02194. For Technical Bulletin MP317, write RCA Commercial Engineering, Section FN11-2, Harrison, N.J. 07029.

Designed to meet requirements of MIL Specifications MIL-E-5400, MIL-T-5422

30/18 High-Density Stack	
Capacity: 4096 words 25 bits	Shock: 50g
Temp. Range: -55°C to +125°C	Altitude: 0 to 70,000 ft.
Vibration: 10-500 cps 15g	Humidity: 10 days



### New components

## Walls of bulb are color-full

Pilot lights can be used to color-code information on electronic equipment

**Electronic equipment** may soon blossom out with tiny fluorescent pilot bulbs in different shades of the rainbow. Manufacture of the cold-cathode gas-filled bulbs has been started by Toyo Musen Co.

Conventional neons work on the principle of an electric potential exciting gas molecules. When the molecules are excited, electrons jump from one energy level to another. This change in state of internal electrons causes energy to be released in the form of light. The colored bulbs operate on a completely different principle, similar to a cathode ray tube. The potential across the electrodes causes the gas in the envelope to emit electrons, not photons. These electrons strike the fluorescent coating on the inner wall of the bulb, causing the coating to emit photons. Changing the color of the bulbs necessitates changing only the fluorescent material, not the gas.

The bulbs are similar in electrical



#### Lighting the way. Colored fluorescent bulbs make for easier reading on instrument panels.

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Designed and shielded to isolate and terminate high frequency signal data in the form of pulses. AM and FM modulated carriers, multiplexed signals, and other low to high frequency data.

#### ELECTRO-GUARD TRANSFORMERS

Power (1 watt to 100VA)

Electrostatically shielded for use in signal conditioners, bridge supplies, and Zener reference supplies to isolate circuits from noise transients and undesirable common mode voltage commonly carried on power lines.



208 Circle 208 on reader service card

Electronics | November 13, 1967



A new technology developed by Sperry scientists is making significant improvement in the identification of radar targets.

Its name? Picosecond technology, the generation and analysis of impulse-like illuminations. The backscatter signatures for these illuminations are more easily analyzed and permit the identification of target shapes, such as flat plates, cylinders, spheres, etc.

Some typical target scattering data are shown in the accompanying traces at a time scale of 100 picoseconds per division.

In addition, Sperry's work in picosecond technology is providing the basis for improved wide-band microwave components.

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## . . . color bulbs help computer debugging . . .

and mechanical specifications to high-brightness NE-2 neon bulbs. The big difference is that the Japanese units have fluorescent material on the side walls of the bulb, and use an unidentified gas that is not neon. Colored light is emitted from the entire wall surface, not just from a small region around the electrodes. The brightness of the new bulbs is of the same magnitude as high-brightness neon units.

In computers, where neon bulbs are used on front panels to indicate the logic state of different sections of the memory, the colored units will make debugging an easier chore. Neons are now used because there is no filament to burn out, they require very little current, and there is no initial current surge that could damage the logic circuitry that drives them.

If a program doesn't work, or if the computer stops at some point, the only clue to the trouble comes from the neons, telling the operator about each section of the memory. To look at a maze of orange lamps is almost as confusing as looking at the memory cores themselves. Using the three colors for different sections simplifies the process of finding out what went wrong.

The first bulbs being produced are red, yellow, or green. Other colors have been manufactured experimentally. The units (in Japan) are priced at about 15 cents each in small quantities. This compares with about 10 cents for highbrightness NE-2's and 6 cents for standard NE-2's.

A major American manufacturer of indicator lamps says that it could have built colored neon bulbs years ago, but the demand for such devices is not as great as the demand for multicolored alphanumeric readouts. The color approach to alphanumeric readouts is not going the gas tube route, but rather to solid state electroluminescent panels, according to the U.S. company. The ideal result of the electroluminescent panel research would be an alphanumeric readout that can change its color by changing the frequency of the applied voltage.

Toyo Musen Co., Tokyo [358]

Electronics | November 13, 1967

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Circle 211 on reader service card



Actual Size

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For literature write Bramco Controls Division, Ledex Inc., College and South Streets, Piqua, Ohio, or call 513-773-8271.



BRAMCO CONTROLS DIVISION, LEDEX INC. College and South Streets, Piqua, Ohio 45356 New components

## Double feature pickup tube

Can view laser patterns; short decay time permits detection of motion

A pickup tube that operates like a vidicon but has an unusual double feature has been developed by Tokyo Shibaura Electric Co. It is highly sensitive to long infrared wavelengths yet has a short decay time. Other infrared detectors offer one feature or the other but seldom both. The range of sensitivity widens the applications of the tube. The short decay time makes it useful for viewing moving objects.

Toshiba's tube has a lead oxide target similar to those in its Sensicon tube and in the Plumbicon developed by Holland's NV Philips Gloeilampenfabricken. The addition of antimony sulphide to the lead oxide provides the sensitivity to infrared. Toshiba hints that it mixes the two while the lead oxide material is being evaporated.

Plumbicon, like vidicon, is based on the principle of photoconduction. However, Philips engineers claim that performance of the Plumbicon is better because it uses a large-area p-i-n photodiode as the light-sensing target mechanism. This, they say, gives it the advantages of an extended linear transfer characteristic, no discernible dark current, and a very small photoconductive lag.

The sensitivity range runs from visible light to wavelengths up to two microns. The tube can detect objects heated at 200°C or more.

Toshiba expects the tube to be used to view infrared laser mode patterns and to observe dislocations in germanium and silicon crystals; also for supervision of dark rooms in photographic film plants, and for remote measurement of temperature distributions in hot objects. The tube also has security and military applications.

Tokyo Shibaura Electric Co., Tokyo [359]






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Circle 131 on reader service card

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### **New Semiconductor Review**



Germanium power transistor series SDT2700 is a 15-amp device in a TO-36 case. Collector-to-base voltage is 40 to 60 v; collector-toemitter voltage, 25 to 50 v. The general purpose unit is for use in industrial and commercial power amplifier and switching applications. The series is available from stock. Solitron Devices Inc., 1177 Blue Heron Blvd., Riviera Beach, Fla. 33404. [436]



Safe operating area specified, plastic power transistor B-5001 provides TO-66 mounting compatibility and isolated collector without using extra hardware or washers. Maximum ratings: collector-toemitter breakdown voltage, 35 v; collector current, 3 amps; junction temperature, -65° to +150°C. It features betas from 20 to 250. Semiconductor Div., Bendix Corp., Holmdel, N.J. 07733. [440]



Molded block silicon rectifiers in the RHP series offer a forward current of 2.25 to 2.5 amps at 50°C ambient and a piv rating of 3,000 to 50,000 v with a recovery time of 300 nsec when measured from 1 amp forward current to 30 v blocking. Surge rating is 150 amps. Price is \$82.75 each in 100 lots. Electronic Devices Inc., 21 Gray Oaks Ave., Yonkers, N.Y. 10710. **[437]** 



High power SCR's, with voltage ratings to 1,200 piv, come in two styles. Both feature high surge current capability for optimum coordination of load characteristics with fuse or other protection systems. One series, rated 275 amps rms, conforms to Jedec outline TO-93; the other, rated 110 amps rms, Jedec TO-94. IRC Inc., 401 N. Broad St., Philadelphia, Pa. 19108. [438]



Monolithic dual TTL, JK masterslave flip-flop DM7501 is for highspeed control and counting uses where multiple data inputs are not required. The unit has a toggle rate of 25 Mhz, 1-v noise immunity, a guaranteed clock skew of 15 nsec; and meets all requirements of the SN5473 dual flipflop. National Semiconductor Corp., 2950 San Ysidro Way, Santa Clara, Calif. 95051. [439]



MLV line are electrically interchangeable with Jedec types 1N-437A-1N4372A and 1N746-1N-757. They are available for regulation at voltages as low as 0.3 v. Units come in a package 0.100 x 0.060 in. They have power dissipation ratings of 750 or 250 mw depending on the leads. Computer Diode Corp., Pollitt Dr. South, Fair Lawn, N.J. 07410. [441]



Transistors in the K disk package are for amplifier and oscillator circuits operating above 1 Ghz. For amplifier circuits, the K disk, made from beryllium oxide, provides increased power gain and lower system noise figure. Oscillator circuits get greater power output at higher frequencies and temperatures. KMC Semiconductor Corp., Parker Rd., Long Valley, N.J. 07853. [442]



Silicon rectifier stacks come in 3 families: OSB-, OSM- and OSS-9210. OSB can be used in 1-phase full circuits or 2-phase half-wave circuits; OSM, in 1-or 3-phase bridges or in voltage doublers. Both have prv's from 2 to 15 kv in 1 kv steps. OSS can be used in 1-phase half-way circuits and has prv's from 3 to 30 kv. Amperex Electronic Corp., Slatersville, R.I. 02876. [443]

### New semiconductors

## Linear IC's take baby step toward LSI

Monolithic circuits range from amplifiers to complete f-m front ends with a minimum of external connections

**Borrowing a technique** used in LSI interconnection, Ameleo Semiconductor has developed a linear integrated circuit that, depending on how many are used, can operate as either a simple amplifier or a multifunction radio-frequency receiver. The monolithic circuit, designated the 911, is made up of three diodes, three transistors, and two resistors. Other IC's in the series are merely two or more 911's interconnected on the wafer.

Instead of using a universal chip having 35 or more elements,



Bias. Arrangement of resistors allows proper selection of bias voltage.

Amelco, a division of Teledyne Inc., follows the same course taken for digital circuits in large-scale integration: different master inter-



Access. Component placement enables simple external connection.

connection patterns are used on the wafers containing the basic structures.

Versatility. Aimed at the consumer entertainment equipment market, the 911 was designed to be versatile yet sell for \$2.55. It is an npn differential amplifier with an npn current source. D-c biasing is achieved by a self-contained bias chain that is made up of the resistors R1 and R2, and diodes D1,  $D_2$ , and  $D_3$ . To establish a desired operating current, R1, or a combination of R1 and R2, forces a current from the positive supply, through the diodes, to ground. Because the diode characteristics are known, the current causes a predictable voltage drop across cach diode. When the voltage is applied to the base-emitter junction of a transistor, and if the transistor is matched to the characteristics of the diode, a current will flow in the transistor's emitter equal to the current forced in the diode. This matching is accomplished because  $D_1$  is actually a transistor, identical to Q<sub>3</sub> in geometry, with its collector-base junction shorted.

Circuit designers accustomed to choosing r-f transistors for highfrequency applications, and audio transistors for d-e and low-frequency applications, will find that there is no difference between the two types in the monolithic construction of the 911. For example, collector-emitter breakdown voltages better than 30 volts, typical d-c current gain of 100 at 1 milliamp, and current gain-bandwidth products from 500 to 800 megahertz are common to monolithic IC's.

Combinations. Four interconnected combinations of the 911



Smaller and smaller and smaller parts... tighter and tighter tolerances... in larger and larger quantities...this is the story of microceramics. Regular production includes substrates so tiny that a teaspoon holds more than 8,000 parts! Coors offers a complete facility for creating small, consistent, ceramic substrates – in several Coors Alumina and Beryllia ceramics, metallized or unmetallized. To assure economy, "as-fired" parts are produced in quantity, to extremely close tolerances (as shown at right). Let Coors provide the special help you need. Write for Data Sheet No. 7002. Get on-the-spot answers. Dial Coors–303/279-6565, Ext. 361. For complete design criteria, write for Coors Alumina and Beryllia Properties Handbook No. 952.



Circle 217 on reader service card





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Try it yourself! Using a Bissett-Berman E-CELL\* in the power-switching circuit shown below, a signal current of 200 microamps or less will fire the SCR and light the 100-watt lamp exactly 72 hours after you throw the switch. You get a complete time integration function performed virtually power-free. (Actually, 600 microwatts are consumed by the timing circuit shown.) To get the equivalent time delay using conventional microcircuitry would increase both the power drain and the cost by several orders of magnitude.



🐺 The Bissett-Berman E-CELL<sup>®</sup> is a unique "liquid state" electrochemical timing and integrating component now being manufactured in high volume on fully automatic production lines. E-CELLs are designed for single use or re-cycling, can be set or re-set in the field, and are furnished in wirelead or plug-in versions. A multipleelectrode E-CELL enables complex functions such as two-phase timing - or subtotaling and totaling - with

For technical information and application notes, contact: Components Division. The Bissett-Berman Corporation, 3860 Centinela Avenue, Los Angeles, California 90066; Telephone: Area Code 213, 394-3270.

Actual size



signal outputs at each step. E-CELLs can generate accurate time delays ranging from a fraction of one second to months; can integrate events from one to infinity; and can operate in the nanowatt range. Operating/ storage temperature is -55°C to 75°C. E-CELLs have been tested and approved by users for severe shock and vibration tolerance in accordance with military specifications. Patents applied for.



### ... complete r-f sections on one monolithic chip ....

and the 911 itself are being offered initially. These range from the 912, a dual emitter-coupled amplifier, to the 915, a complete amplitudeinodulation intermediate-frequency strip, with built-in automatic gain control (agc).

In designing the 912 as a singlefunction device, the packaging cost is minimized by requiring only eight pins for the two independent stages. Since each stage has its own bias chain, the need for external biasing components is reduced. When two 912's are connected, for example, in a 10.7-Mhz frequencymodulated i-f strip with conventional transformers, there is an over-all gain of about 100 decibels. This combination, offered as the 914, is a complete f-m i-f strip, with only external transformers and bypass capacitors required.

While the 912 trades flexibility for package pin reduction, the 913 -two connected 911's-requires a 16-pin package, but performs a variety of functions. Each half of a 913 can be used independently as a cascode, emitter-coupled, or selfcontained d-c amplifier.

The most complex configuration is the 915, a 16-pin package that is made up of four basic modules. Three cascode amplifiers, capable of 30 to 40 db power gain per stage, and a self-contained age loop are connected. Components from the fourth module form a diode detector, an emitter-follower age buffer, and an emitter-follower output buffer. The accessibility of various internal points, in the 16pin package, allows external control of the agc threshold, determination by external capacitor values of detector response, age time constants (fast attack, slow decay characteristics are possible), and shaping of the i-f bandpass characteristics.

According to a company spokesman, no insurmountable system problems have been encountered with the four-module chips, indicating that further increases in complexity to six or eight modules per chip are currently possible in r-f systems.

Amelco Semiconductor Inc., Box 1030, Mountain View, Calif. 94042 [444]

# COMBINATIONS

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# Still another IC for television

Single-coil winding minimizes tuning of detector-limiter

**Trying to get** integrated circuits designed into television sets is a kind of mating game.

The IC maker will tailor the characteristics of his device to make it highly compatible with existing circuitry—to minimize redesign problems for the set manufacturer; and he will pack as much function into the chip as economics will permit —to lessen the number of external interfacing components and the number of adjustments.

Above all this, however, the paramount consideration is cost. If the IC price is not right, the mating game is off. So the IC maker will usually hedge his product investment by including features attractive to the easier-to-sell industrial and military market. Such seems to be the approach followed by Sprague Electric Co., latest member of the IC club to enter the lucrative consumer market [Electronics, Aug. 7, p. 88].

Sprague has developed a linear ic frequency-modulation detector and limiter, aimed at tv channels and f-m receivers. The device is also suited for automatic-frequencycontrol system telemetry and for



Chipfull, Circuit includes 25 active elements and 18 diffused resistors.

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division of Hamilton Watch Company, Lancaster, Pa. 17604

### ... balance network lowers distortion ...

radar applications.

Designated the ULX-2111A, the complex chip contains 19 transistor elements, 6 diodes, and 18 resistors. It requires only one singlewinding coil for tuning, so a screwdriver is all that is needed to tune the detector. Most counterparts in discrete semiconductor networks and in 1C's require complex phaseshift networks.

Some competing devices also offer simplified tuning, but they do not provide the limiting action associated with the balanced phase detector.

On the Sprague chip is a threestage amplifier, a limiter, and a balanced detector, all of which work in tandem to provide linear gating. Filtering out of unwanted signals is high—the a-m rejection of signals riding on the f-m carrier is 45 decibels. The circuit's capture ratio is 1.4 db, and its distortion products are 1.5% maximum.

The IC's bandwidth extends from 5 kilohertz to 50 Mhz. Its output is sufficient to drive either vacuum tube or transistor power amplifiers in tv sets directly. An output-connection option is provided, so the IC may be used as a 60-db broadband amplifier. In nearly all applications for the device, only a 12volt power supply is required.

Sprague says the price of the device cannot be determined until the process is moved from its research laboratory to production facilities in Worcester, Mass. The unit is the first of a series of consumeroriented IC's to be introduced on a one-a-month basis during 1968.

During the past six months, at least six major competitors have been introducing IC's aimed at the same tv and f-m receiver sockets [Electronics, June 12, p. 38; June 26, p. 163].

Specifications (tv application)

fo	4.5 Mhz
Deviation	土 25 khz
Vc	+12 v
Pdis	200 mw
Vout	0.60 V rms
Limiting threshold	400 µv rms
A-m suppression	46 db
Distortion, maximum	1.5%

Sprague Electric Co., North Adams, Mass. [445]

222 Circle 222 on reader service card





The name of the game is versatility.

Formal designation Model PG-32 probably the most versatile pulse generator ever designed. A single PG-32 can do just about everything two conventional pulsers can do and do it better, much more economically, reliably and simply.

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Please note: you can control independently for each channel, rise and fall time (10 ns to 1 sec), width (independently for each pulse — 30 ns to 1 sec) and delay (50 ns to 1 sec), all over the widest dynamic ranges available. The two outputs are simultaneous and can be used separately or in combination: the combined mode makes possible DC-offsets or bipolar pulses of up to 10V. All of this comes in a  $3\frac{1}{2}$ " high solid-state package.

With the output parameter control provided, the PG-32 is capable of pro-

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### **New Instruments Review**



Two-component blender model 99C is available in 2 configurations: to ratio one flow to the other or to ratio one flow to the total flow. It will accept high-frequency turbine meter inputs or low-frequency meter inputs. Equipped with memory capability, the 99C produces a 10-15 ma signal to control the ratioed flow. Foxboro Co., Mechanic St., Foxboro, Mass. 02035. [361]



DS-2 sorts or grades up to 1,200 components per hour into several categories (5%, 10%, 20% or 4 to 8 pf, 8 to 11 pf, etc.) with 0.1% absolute accuracy. Components are inserted into a guarded test fixture or test jig, with capacitance indicated on a 4-digit readout. Micro Instruments Co., 12901 Crenshaw Blvd., Hawthorne, Calif. 90250. [362]



High-pressure transducer model GT-24 is designed for dynamic measurements. Pressure range is 0-20,000 through 0-100,000 psig; sensitivity, 3.0 mv/v minimum; natural frequency, 50 khz; non-linearity,  $\pm 0.5\%$  full scale max; repeatability, 0.1% full scale max; operating temperature, cryogenic to 300°F. General Transducer Co., Corvin Dr., Santa Clara, Calif. 95051. [363]



Digital voltmeter series 6250 mounts magnetically to the top of computers. It provides 4-digit readout of analog voltage signals. Voltage ranges (1 and 10 v) are push-button selected. Input impedance of the dvm is 10 megohms; conversion time, 100 msec. Accuracy is  $\pm 0.1\%$  of full scale  $\pm 1$  digit. Price is \$495. Electronic Associates Inc., West Long Branch, N.J. 07764. [367]



F-m communications monitor CE-3 makes off-the-air measurements of base stations up to 50 miles away. It offers a choice of 3 r-f preselector plug-ins—20-80, 120-180, and 450-512 Mhz—or a broadband r-f mixer plug-in for close-in monitoring and in-shop measurements. The instrument weighs 38 lbs. Cushman Electronics Inc., 166 San Lazaro Ave., Sunnyvale, Calif. 94086. [364]



Automatic noise figure meter model 792A offers variable impedance and balanced outputs. It provides complete measurements up to 26.5 Ghz and metered noise figure ranges of 5 to 30 db for waveguide and diode sources and 0 to 20 db for hot wire and diode sources. Input sensitivity is 0 to 75 dbm; input impedance, 50 ohms nominal. Kay Electric Co., Pine Brook, N.J. 07058. [368]



Pressure-to-frequency transducer PF-1001 is for missile, spacecraft, aircraft, and industrial f-m telemetering. Pressure ranges are from 0 to 200 psig up to 0 to 5,000 psig. Any center frequency from 400 hz to 12 khz with a deviation of  $\pm$ 7.5% is available. IRIG channels from 1 to 12 can be specified. Solid State Electronics Corp., 15321 Rayen St., Sepulveda, Calif. 91343. [365]



Short stroke, d-c/d-c linear motion transducer model 15 delivers 5 v d-c output for 0.010-in. travel with better than  $\frac{1}{2}$ % linearity. It incorporates a linear variable differential transformer with a completely integrated oscillatordemodulator-amplifier built into the potted enclosure. Prices start at \$145. C-E Electronics Inc., 363 W. Glenside Ave., Glenside, Pa. 19038. [366]

### New instruments

### Hands-off frequency sweeping

Plug-in checks range from 0.1 hz through 100 khz; can be teamed with new log converter to make Bode plots

For different categories of electronic devices, frequency-response tests are key stages in the design and manufacturing processes. A hearing aid, for example, must amplify only those frequencies which the wearer cannot hear well. A hi-fi speaker must be carefully tested with variable-frequency input signals. The servocontrol system on an aircraft can go into oscillation if wrong-frequency signals are let loose.

To meet these differing needs, a new sweep plug-in built by Hewlett-Packard Co. permits frequencyresponse checks to be made over a range from 0.1 hertz to 100 khz quickly and accurately. It sweeps over these measurement ranges without the need for any knobtwiddling between ranges or for switching from one instrument to another.

Designed to work with the company's 3300A function generator and to provide it with both wideand narrow-band capabilities, the model 3305A plug-in sweeps from 0.1 hz to 100 khz in three overlapping four-decade ranges.

Any part or all of one range can be swept by setting calibrated start-frequency and stop-frequency



Surface temperature transducer R-104 has a base resistance of 10,000 ohms. Measuring from  $-100^{\circ}$  to  $+350^{\circ}$ F, the unit, when used with a suitable bridge network, yields a high level output of more than 10 mv/°F as a linear function of temperature. The unit is 36 in. in diameter X 0.050 in. thick. Eon Instrumentation Inc., 15547 Cabrito Road, Van Nuys, Calif. 91406. [369]



Portable 1,024-channel pulse analyzer model 1010 has a 12.5-Mhz digitizing rate and 15- $\mu$ sec memory cycle. Count capacity of the memory is 10<sup>0</sup>-1 count per address. Operating modes are provided for pulse height analysis, multiscaling (at count rates up to 1 Mhz) and analog sampling. Technical Measurement Corp., 441 Washington Ave., North Haven, Conn. 06473. [373]



Incremental strip chart recorders series IR-100 provide up to 6 analog plotting pens, each accurate to within  $\pm 0.25\%$  of full scale, and have an incremental paper drive. They are suited for applications where the data is event-dependent rather than timedependent. The drive motor can operate at up to 200 steps/sec. Compat Corp., 52 Bethpage Rd., Hicksville, N.Y. 11801. [370]



A-c/d-c differential voltmeters reduce the dependence on a highly accurate d-c voltmeter to achieve good a-c performance. Model A-45 has  $\pm 0.25\%$  a-c accuracy; model A-45A,  $\pm 0.15\%$  a-c accuracy. Prices are \$595 and \$695, respectively. D-c accuracy is  $\pm 0.1\%$  for either model. Both units use FET's. Medistor Instrument Co., 4503-8th Ave., NW, Seattle, Wash. 98107. [371]



Temperature controller model 52-B is designed for rugged duty on packaging, plastics, sealing, and other machines. Temperatures to 600°F and higher are sensed by a stainless steel sheathed thermistor probe. Output power to the heater load of up to 3,000 watts is smoothly modulated by a solid state triac. Athena Controls Inc., 314 West Ridge Pike, Consho-hocken, Pa. 19428. [372]



Multiple-wave function generator 9010 provides sinusoidal, square, and triangular signal waveforms. All outputs are available at the front panel, with continuously variable frequencies from 0.005 hz to 1 Mhz in 8 ranges. A selectable, 30-v output is provided, with continuously variable level and d-c offset. Beckman Instruments Inc., 2200 Wright Ave., Richmond, Calif. 94804. [374]



TR-220 series event recorders simultaneously record 20 or 40 separate on-off events. They feature deflection-type presentation with 3-msec response time. The stylus is designed to operate through more than 5 million events without failure. The recorders take a 200-ft-long chart roll. Up to 18 speeds are available. Techni-Rite Electronics Inc., Industrial Park, Warwick, R.I. 02887. [375]



Frequency selective voltmeter model 2006 directly measures voltages in a-m/f-m, single sideband, and tv frequency ranges. The battery-powered unit features 7 overlapping ranges from 100 khz to 230 Mhz. It performs a number of selective r-f voltage measurements within a 2-mv to 50-v range. B&K Instruments Inc., 5111 W. 164th St., Cleveland, Ohio 44142. [376]

dials on the front panel. The time taken to sweep from the start frequency to the stop frequency is selected from the front panel and is adjustable from 100 seconds to 10 milliseconds. Sweep time is independent of the frequencies or range being swept. This feature provides better resolution and accuracy for narrow-band sweeps than previously obtainable, according to H-P.

**Teamwork.** The 3305A is ideal for use with either x-y recorders or oscilloseopes. An automatic penlift feature is provided for x-y recorder operation. When teamed with H-P's Moseley division's new model 7562A log converter, a Bode plot of a system can be made directly over a four-decade frequency range with a dynamic range of 80 decibels.

Because the sweep limits are easily set to any frequency within a range and are independent of each other, the 3305A is also suited for narrow-band up or down sweeping. For example, the steep skirts of an active filter can be displayed on a scope or x-y recorder.

A manual sweep control adds flexibility by permitting the user to sweep manually with one turn of the control from the start-frequency setting to the stop-frequency setting. It may be used to set up the display limits, locate frequencies of interest in the sweep, or add reference frequency marks on an x-y plot.

A constant sweep-output voltage, independent of frequency range, sweep width, or the start and stop frequency settings, eliminates the need to readjust the x-axis display even if the sweep width, frequency range, or start or stop settings are changed. This also permits magnifying a small portion of a wideband sweep to cover the entire width of the display without any sweep output adjustments.

Other features include a local or

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your Winchester Electronics distributor. You'll find him close as your phone – make the connection now. Winchester Electronics, Main St. & Hillside Avenue, Oakville, Conn. 06779.





Teaming up. H-P's sweep plug-in provides logarithmic frequency control over more than four decades to simplify testing such devices as a Butterworth bandpass filter. Bode plot is obtained on x-y recorder directly by using Moseley division's new logarithmic converter.

remote triggered single-sweep, and normal 3300A main frame operation without the need to remove or change plug-ins.

**Ramp control.** The sweep control is a ramp generated by a Miller integrator, a current source, and two voltage comparators to sense the peak-to-peak levels.

The ramp is applied to the stopfrequency potentiometer, to the start potentiometer through an inverter, and to the sweep-output amplifier. The potentiometer outputs are summed to produce a ramp proportional to the difference of the start and stop frequency settings. To produce log-arithmic plots directly, the ramp is shaped into an exponential curve using a piece-wise linear technique. Sixteen segments are needed to produce the desired two-decade exponential. This operation is performed by a log shaper which synthesizes the exponential curve with biased diodes. Excellent stability at low voltage levels is achieved by H-P's integrated circuit diodes designed especially to reject wide ambient temperature changes.

Two for one. A voltage comparator causes the shaper's output to go through two excursions for a single ramp excursion. At the beginning of the second shaper excursion, the 3300A's integrating capacitor is switched to a value 100 times smaller than before. Thus, two decades are swept, the capacitor is changed and two additional decades are swept. By changing two frequency-determining elements in combination, the ability to sweep four decades of frequency is achieved with improved accuracy and stability. Phase continuity is preserved with capacitors.

In the worst case, the switching time required is two orders of magnitude shorter than one period of signal. The overlapping ranges permit narrow-band systems with a critical point at the switch frequency to be swept without losing data.

The shaper output is fed to two

#### Specifications

Price

Frequency range	0 1 by to 100 kby in 2		
Sweep width	apping ranges. Limits adjustable 0 to 4 decades in any of three 4-decade bands;0.1 hz to 1 khz, 1 hz		
Start-stop dial accuracy	$\pm 5\%$ of setting, 0.1 hz to 20 khz; $\pm 7\%$ of setting, 20 khz to 100 khz.		
Sweep modes			
Automatic	Repetitive logarithmic sweep between start and		
Manual	Vernier adjustments of		
Trigger	and stop frequency set- tings. Sweep between start and stop frequency settings and retrace with applica- tion of external trigger voltage or by depressing front-panel trigger but- ton.		
External frequency control			
Sensitivity	6v/decade (referenced to		
	start setting), ±24 v max.		
V-to-f conversion accuracy	For each 6 v change in programing voltage, fre- quency changes 1 decade =5% of final fraguency		
Input impedance	400 k		

\$975

# HOW CAN YOU USE THIS NEW WRINKLE IN PLASTIC TUBING?

FLEXITE SHRINKDOWN TUBING is fast becoming an "indispensable" to design engineers. It shrinks 50% in diameter, upon application of moderate heat, to form a tough, tightfitting sheath of plastic around objects of irregular shape. Primarily intended for insulation, it is also being used in many other ingenious ways. Like binding things together - adding strength and rigidity protecting against abrasion, wear. breakage --- resisting corrosion, heat, moisture - preventing vibration and noise --- etc. How can you use it? We'll be glad to send you our "Hot Idea" experimental sample kit of all 3 types of Markel Shrinkdown. Just write for it. No cost or obligation.



L. FRANK MARKEL & SONS Norristown, Pa. 19404 • 215-272-8960 INSULATING TUBINGS AND SLEEVINGS HIGH TEMPERATURE WIRE AND CABLE voltage-to-current converters which supply the currents necessary to sweep the main oscillator—the 3300Å. Precision converters insure less than a 1% symmetry error for the full range of frequencies and environmental temperatures from  $0^{\circ}$  to  $+55^{\circ}$ C.

At the end of the sweep a multivibrator is triggered, blanking the main-frame's sine and triangle outputs. When the sweep output is reset to zero, blanking is removed and the 3300A begins to oscillate at the start frequency. After a short delay, the multivibrator again changes state, and the frequency is swept again. This delay provides for system recovery between sweeps.

Hewlett-Packard Co., Loveland Division, Loveland, Colo. [377]

New instruments

## Materials sensor measures heat flow

No-contact device operates on convection principle instead of measuring infrared

**No-contact** temperature sensing of materials, once the exclusive domain of infrared equipment, is now being accomplished by measuring heat flow instead of thermal radiation.

Called Nontact, the technique avoids some problems of infrared systems, such as having to compensate for different colors which radiate different amounts of energy, or looking through the material and picking up radiation from some other material behind it.

Nontact was developed by David Hornbaker and Dieter Rall, consulting engineers specializing in heat transfer and temperature measurement. They established a new company, Trans-Met Engineering, to produce the system.

**Balances heat.** The equipment consists of a sensing head and a temperature readout and control unit. It operates on a null-heat-balance principle employing convective heat exchange between the





What was so tough about the isolator spec? Among other things were power handling capability (400W CW, 4kW peak); isolation VSWR limited to 1.18:1; insertion loss (only 1 db permitted), and RFI shielding to prevent interference with other aircraft systems. All parameters had to be met at altitudes up to 60,000 feet and over the temperature range of  $-55^{\circ}$ C to  $+55^{\circ}$ C without cooling.

Sperry met the challenge with Model No. D-44S9, a specially engineered isolator that helps assure the reliability of B-52 ECM.

Is there a particularly difficult isolator problem Sperry can solve for you? There's a broad line of standard items, plus plenty of engineering talent if you need it. For full details, contact your Cain & Co. man or write Sperry Microwave Electronics Division, Sperry Rand Corporation, Box 4648, Clearwater, Florida 33518.

SPERRY

MICROWAVE ELECTRONICS AND ELECTRONIC TUBE DIVISIONS SPERRY RAND CORPORATION CLEARWATER AND GAINESVILLE, FLORIDA



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For detailed specifications, write for Data Bulletin 3124.

PITMAN, NEW JERSEY 08071





Standoffish. Sensor measures heat flow without touching surface of material.

sensing head and the material being studied.

The system can be used either to monitor temperature or to control the temperature of the material being processed, such as a hot plastic strip. In monitoring, the sensor head detects the heat flow from the hot strip. If the material is hotter than the head, a servo signal triggers an electric heater in the head assembly which heats the sensor assembly until its temperature is the same as that of the material. At this point there is no heat flow between the head and the material, the system is in null balance, and there is no output signal.

If the head is hotter than the material, output signals trigger a water- or air-cooling system and the coolant is circulated through passages in the sensor assembly until its temperature is the same as that of the material.

The sensor head measures about  $2 \ge 2^{1/2}$  inches and is embedded in the center of a flat aluminum plate measuring about 6 inches in diameter. The sensor is a solid, potted assembly and is covered with a special reflective coating to cut out all radiant energy.

Sink plus sensor. Rall says the sensor assembly is basically a heat sink or heat reservoir, with a heat-flow sensor in the face to detect whether heat is flowing in or out. Included in the assembly are a potted electric heater and passages for air or water coolant. A thermocouple in the head monitors the temperature, which is read out on a meter.

When heat flows into the sensor, a positive d-c signal proportional to the rate of heat flow is generated for the control unit. When heat is flowing out, the voltage is negative. In simple temperature tracking,

230 Circle 230 on reader service card





Sperry Rand Corporation has solved a unique oscillator application problem for multi-mode radars on the RF-4C and the A-7A. Texas Instruments Incorporated, prime contractor for both radar systems, needed a dual function tube — one which could serve as local oscillator in the radar, and would also work in the test and check-out circuit.

Sperry suggested the SRU-2161, and tests proved they were right. Today every AN/APQ-99 (for the RF-4C) and AN/APQ-116 (for the A-7A) system carries two of these Sperry reflex klystron oscillators.

The SRU-2161 delivers 50 mW at Ku band, while operating from a 300 V power supply. Since the oscillator has Sperry's unique adjustable reflector voltage, both tubes in the system can be driven from a single power supply. Mode shapes can be controlled to comply with the exacting tolerances of both systems.

If you need unusual performance from klystron oscillators, Sperry is the place to look. Contact your Cain & Co. representative, or write Sperry Electronic Tube Division, Sperry Rand Corporation, Gainesville, Florida 32601.

SPERRY MICROWAVE ELECTRONICS AND ELECTRONIC TUBE DIVISIONS CLEARWATER AND GAINESVILLE, FLORIDA





## Why multi-mode radars for RF-4C and A-7A depend on dual-purpose oscillators from Sperry...the first name in microwaves.

Electronics | November 13, 1967

# Order Compack Controllers from Stock/Save Space, Time, Money



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Select upright-type Compack I or edge-reading Compack II, whichever suits you better. Both contain reliable solid-state circuitry, rugged taut-band meter movement and other outstanding features that add up to the easiest approach to controlling any common variable.

> Ask for: Bulletin 48 (non-temperature) Bulletin 49 (pyrometer models)



## ... output signals control process ...

the voltage—approximately 0.5 millivolt per degree F—goes to the solid state control unit where it is used to turn on either the heater or coolant to drive the sensor back to the null condition, equal to the temperature of the material being monitored. The sensor tracks at a rate of up to 10°F per minute, according to Trans-Met.

When the system is being used to control the temperature of material being processed, it is preset at the desired temperature and, as the temperature varies, the output signals are used to switch on controls to heat or cool the material.

In this mode, an indicator on the galvanometer is set at the required temperature. If the material is not at the right temperature, signals from the sensor head operate through a 5-amp relay to switch on controls to heat or cool the material.

When the galvanometer's temperature readout needle reaches the correct temperature, the needle vane shuts off light which has been passing through the set point indicator to a photoelectric cell inside the unit. This imbalances a bridge circuit, cutting off power.

**Container application.** A prototype unit is in operation at a plastics company in the Los Angeles area, where it monitors the temperature of styrene plastic sheet and controls a bank of heaters in an oven to keep the sheet at the right temperature. This is done just before the sheet enters a thermoforming press, where it is made into containers for cottage cheese. The plastic will not form properly if it is not at the right temperature.

Trans-Met is marketing two versions of the NCT 4,000 series system, one with a range from 75 to 300°F and one with a 75-400°F range. Accuracy is  $\pm 2\%$  of full scale.

Price is \$1,875, including sensor head and mounting bracket with positioning mechanism, controller, readout system, and 10 feet of cabling. Rall says a comparable infrared system would cost \$2,000 to \$2,500.

Trans-Met Engineering, P.O. Box 56, . Whittier, Calif. 90608. [378]

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*Output voltage ranges:	10-V Range: 0 to 11.11110 volts (10μV steps) 100-V Range: 0 to 111.1110 volts (100μV steps) 1000-V Range: 0 to 1111.110 volts (1mV steps)		
Output current capability:	O to 25 milliamperes nominal at any voltage setting.		
Accuracy:	0.01% of setting.		
Stability:	Within 30 PPM for 24 hours, 50 PPM for 30 days.		
Visual display:	In-line readout, automatic decimal point positioning.		
Dimensions:	Cabinet: 10½" W x 5¼" H x 15½" <mark>D</mark> . Rackmount: 19" W x 5¼" H x 15½" <mark>D</mark> .		
Price:	Cabinet (324A): \$995. Rackmount (3 <mark>24</mark> AR): \$1050. F.O.B. San Diego. Additional export charge.		
Delivery:	Immediate, from stock.		

For illustrated brochure on how this instrument is applied in the auto repair industry, write for Bulletin E 5-29.



Box 623 San Diego, California 92112 Phone: 714-277-6700

For full details, contact your Cohu engineering representative.

Circle 233 on reader service card 233

### **New Subassemblies Review**



Stepping commutator type 1724 Digicom is designed for multichannel telemetry. It provides up to 30 break-before-make signal channels with as many as two separate differential input sets of poles. Stepping rates as high as 200 samples/sec are reliably achieved. Production quantities sell for about \$1,100 each. General Devices Inc., P.O. Box 253, Princeton, N.J. 08540. [381]



D-c voltage regulators series 803 permit  $\pm 0.05\%$  regulation for line and load variations. Standard models offer fixed outputs of 24, 28 or 32 v. They supply up to 7.6 w to load at  $+25^{\circ}$ C in free air, or 16 w with a heat sink. Operating temperature range is  $-55^{\circ}$  to  $+125^{\circ}$ C. Units measure 0.990 x 0.490 x 0.170 in. Beckman Instruments Inc., 2500 Harbor Blvd., Fullerton, Calif. 92634. [382]



A delay line providing 16 combinations of nsec delays in 10-nsec steps is for installation in telemetry code and de-code circuits, computers and automation equipment, as well as on p-c boards. It has a maximum attenuation of 1 db, 510-ohm impedance, and a maximum 55-nsec output rise time. PCA Electronics Inc., 16799 Schoenborn St., Sepulveda, Calif. 91343. [383]



Instrumentation preamplifiers offer continuous operation for over a year from internal mercury cells. They are for use in upgrading the sensitivity and input impedance of scopes, counters, and vtvm's. Specs include input impedances up to 1,000 megohms, gains up to 40 db, and noise levels of 3 µv broadband. Applied Cybernetics Systems Inc., 880 Bonfant St., Silver Spring, Md. 20900. [384]



Keyboard communications buffers series 608E-1000 are adaptable to fill almost any buffer memory requirement for asynchronous input or output character rates of up to 500 khz or for synchronous rates up to 4 Mhz. The basic system provides storage of 4,096 8-bit characters and can be expanded to 131,072 characters. Digital Devices Inc., 200 Michael Dr., Syosset, N.Y. 11791. [385]



Digital tape transport GTM-14 generates computer - compatible data and features tape speeds up to 105 in./sec. It is designed for land-mobile and shipboard use in such applications as geophysical data gathering, oceanography, and reconnaissance. The unit is 14 x 25 x 12 in., weighs 90 lbs. Price ranges from \$16,000 to \$22,000. Ampex Corp., 401 Broadway, Redwood City, Calif. 94063. [386]



Core memory ICM-500 uses IC's in all electronic functions, including sensing and direct drive of selection lines. Full-cycle time is 600 nsec; access time, under 300 nsec. Capacities are from 4,096 to 32,-768 words. Mean time between failure is over 25,000 hours for an 8,192-word, 28-bit-per-word memory at 35°C. Honeywell Inc., Old Connecticut Path, Framingham, Mass. 01701. [387]



Decimal-to-binary converter card Z-253 is for use in transforming decade thumbwheel switch outputs to straight binary. It accepts 3 BCD digits on 12 lines and delivers a 10-bit output. Conversion is accomplished by a parallel decoder matrix providing continuous output information. Price is \$226. Metric Systems Corp., 736 N. Beal St., Ft. Walton Beach, Fla. 32548. [388]

#### New subassemblies

### Making sure of dotted i's and crossed t's

Magnetic deflection amplifier gives fast, undistorted readout for computer displays, electronic typesetting

When a ransom note or a love letter appears blurry on the television screen, you can usually guess the contents from the context of the story.

This is not good enough in computer-driven alphanumeric displays, nor in electronic typesetting. If letters and figures become rounded at the corners and plotted points become smears, computer speed must be sacrificed to improve resolution or the equipment loses its usefulness.

For fast, undistorted readout in any cathode ray tube or storage tube display using magnetic deflection, the speed of the deflection amplifiers is crucial. A new line of amplifiers introduced by Beta Instrument Corp. provides very high speed deflection performance. The all-silicon solid state modular packages are d-c coupled operationaltype difference amplifiers designed for any magnetic deflection system.

"The market is not a big one, about \$250,000 a year, but due for a quick rise when electronic typesetting gets off and running," says Norman Fine, president of Beta.

Fine says the new Beta line, available in three models, offers a 1-megahertz small-signal band-



Modular and rack power supplies in the D and H series operate all types of IC's. Response to overvoltage is less than 10 #sec and maximum voltage overshoot is 0.5 v above the overvoltage set point. Supplies have fixed overvoltage protection and output resolution as low as 1 mv. Prices start at \$130 each with quantity discounts. Dynage Inc., 1331 Blue Hills Ave., Bloomfield, Conn. 06002. [389]



Totalizing counter series 710830 Digi-Con contains from 3 to 7 Veeder Decade single wheel counters with necessary input, drive and reset circuitry. BCD or decimal output is standard. The unit has a speed of 2400 counts per minute and a minimum reset time of 300 msec. Reset is by panel push button, or remote connection if desired. Veeder-Root, Danvers, Mass. 01923. [393]



Data entry keyboard KN-10 is supplied assembled and wired to a single p-c edge for a mating connector or for hard wiring to external circuitry. Keybuttons are spaced on 5/a-in. centers, having momentary contact, with single or double output from a single commón. The unit measures 3 x 4 x 1<sup>1</sup>/4 in. Price is \$1.75 per button in quantity. Nutronics, Box 72, Paranus, N.J. 07652. [390]



Dual in-line filters come in 2 series (7127, -8, -9 and 7130, -31, -32), each consisting of low-pass, high-pass and bandpass units in 10 Mhz and 30 Mhz frequencies. Miniature packaging conforms with IC configurations. Interconnection pins are located on 0.100-in. centers with 0.300 in. between pin contact rows. Cambridge Thermionic Corp., 445 Concord Ave., Cambridge, Mass. 02138. [391]



Differential d-c operational amplifier model 440 is intended for use as a servo motor or d-c through audio power amplifier. It may be used in audio applications with either a single polarity or bipolar power supply. Output capability is 60 w rms. Size is  $434 \times 5\sqrt{2} \times 25\%$ in. Price for 1 to 99 is \$60 each. 100 to 999, \$55. Opamp Labs, 172 So. Alta Vista Blvd., Los Angeles 90036. [392]



141A features maximum initial bias current of 50 pa and 75  $\mu\nu\ell'^{\circ}$ C voltage drift. Models 141B and 141C feature reduced bias current of 25 pa maximum, and voltage drifts of 40  $\mu\nu\ell'^{\circ}$ C and 25  $\mu\nu\ell'^{\circ}$ C respectively. Prices of the 141A/B/C are \$25, \$30, and \$35 each in lots of 1 to 9. Analog Devices Inc., 221 Fifth St., Cambridge, Mass. 02142. [394]



Nondispersive infrared analyzers models 215A, 315A, and 415A are for use in the process industries. All use a transistorized amplifier that converts millivolt output to current signals that are compatible with all miniature electronic recorders, controllers and data acquisition systems. Process Instruments Div., Beckman Instruments Inc., 2500 Harbor P. vd., Fullerton, Calif. 92634. [39]



Hernietically sealed style M overspeed monitor conforms to MIL-T-16049 specs. As an rpm monitor, it can be used in overspeed measurements and in warning/shutdown applications for alarm switching. It is a single set-point device adjustable over a  $\pm 5\%$  span. Connectors for power, pickup, and output leads are on the unit's face. Airpax Electronics, Box 8488, Ft. Lauderdale, Fla. 33310. [396]

width, compared to 250-500 kilohertz generally available. This bandwidth is proportional to writing speed in small deflection operations, such as point plotting or character generation. With one of the new amplifiers retrofitted to an electronic typesetter, says Fine, the equipment might be able to work at two to four times its previous rate.

**Settling time.** The high-speed capability of the Beta amplifiers is also defined in terms of settling time—the time it takes an amplifier to reach a given percentage of a desired final voltage. "If you want a spot in the middle of a crt screen,"



**C**lear steer. Amplifier provides fast, precise deflection for alphanumeric readout.

says Fine, "it will take so many microseconds for the amplifier to reach the proper deflection voltage to within 1%, and then to within 0.1%. The 1% figure has been used to specify such amplifiers. But now, with higher-resolution displays needed for typesetting and computer systems, the settling time from one per cent to a tenth of a per cent is a more useful measure. Also, settling time to 1% is controlled more by constants of the ert deflection yoke and associated circuitry than by the speed of the deflection amplifier."

Beta's amplifiers settle from one to one-tenth of a per cent in 1 to 2 microseconds, says Fine. This is up to  $1\frac{1}{2}$  times as fast as competing units, he asserts.

Symmetrical. Fine says the fast

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Current ratings are available up to 400 amps at 1 mc., capacitance to 30,000 mmf, and safety gap settings to 85 kv peak. These characteristics fill a broad range of needs. May we send you more information? Ask for Bulletin 302. Lapp Insulator Co., Inc., LeRoy, N.Y. 14482.

## ... device symmetry adds bandwidth ...

settling time and broadbandedness are achieved by means of the transistor output arrangement in the amplifier. This complementary symmetry output (npn-pnp) keeps the output impedance constant in both sweep directions, and therefore the settling time is equal in both directions.

In some deflection amplifiers, the yoke sees a different impedance depending on deflection direction. Thus settling occurs at a different rate in each direction. This type uses dual npn transistors and can be coupled through the emitter in only one sweep direction. When the output is from the collectors, impedance is higher than it is when the emitters are emitting. The circuit in the Beta amplifiers gives low-impedance emitter output in both directions, and this is a major reason for achievement of the 1megahertz small-signal bandwidth and high speed.

The three models—priced from \$1,000 to \$2,000—can supply up to  $\pm 2$ ,  $\pm 4$ , or  $\pm 6$  amperes of deflection current respectively to each axis of a directly-coupled deflection yoke. They offer maximum performance in bandwidth and settling time when operated from  $\pm 35$  volt power supplies.

Most deflection amplifiers use a potentiometer across the yoke to adjusting damping. But this costs power. The Beta devices incorporate the pot—adjustable by screwdriver—in the feedback loop. In this way, gain can be optimized for a given yoke without power loss due to a paralleled resistance across the yoke.

#### Specifications (Model DA 225)

Inputs			
a-c power (for fan)	115 v 60hz		
d.c power (for full output)	±35 v. 14 amp		
signal			
amplitude*	±5 v		
impedance	1 kohm		
Output			
deflection coil current			
(each axis)	±6 amp		
Linearity (deviation from			
best straight line)			
class AB	-+-0.04% max		
class A	+0.02 % max		
01000 / 1			

<sup>a</sup> Input signal may be d-c, sawtooth, random positioning, sine, square, pulse, resolved sweeps, and/or complex waveforms.

Beta Instrument Corp., 377 Elliot St., Newton Upper Falls, Mass. 02164 [397]





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New subassemblies

## Color tv camera sells for \$9,850

Simplified optics lower cost of unit for schools, hospitals

The insides of the color television camera introduced this month at the National Association of Educational Broadcasters convention in Denver are so bare that the trick of producing a good picture is seemingly done with mirrors.

And it is. The International Video Corp. says the biggest single factor in getting the cost of its camera below \$10,000 was a radically redesigned optics system. The camera will sell for \$9,850.

Closed-circuit television in color has been a big-ticket item mainly because of camera cost. A broadcast-quality model can easily run \$75,000, and even the strippeddown model introduced by Cohu Electronics, Inc., last spring sells for about \$30,000. CBS Laboratories has built a \$10,000 camera using field-sequential techniques [Electronics, June 12, p. 33], but it does not produce a National Television Standards Committee signal and thus requires a special monitor.

International Video, founded two years ago by two graduates of Ampex Corp. and Memorex Corp., is marketing a complete ccrv system—camera, color tape recorder, and standard monitor—for \$15,-000. President Donald F. Eldridge stresses that the camera does not produce a broadcast-quality signal. Its principal market, he believes, will be in hospital and educational ccrv systems.

Called the IVC 100, the camera has a self-contained encoder and a sync generator with integrated circuits. It is intended for use with the IVC 800 color recorder, introduced last spring.

One obvious difference between the IVC 100 and broadcast cameras is that the signal in the closed-circuit camera has a resolution of only 400 lines; broadcasters specify 525. Yet a broadcast signal is degraded,

# When ordinary methods of observing and recording don't deliver



We have a very large staff of photographic engineers qualified to provide photographic solutions to previously unsolvable problems. Together, you and they can probably work out solutions. A few challenges presented to us recently...

A rescarch team needed a way to study the combustion of metal droplets. Kodak was able to provide a film just right for high-speed cameras to record exactly what happens at 4000°C ... and in what sequence (see picture above).

Another group, concerned with impact testing, faced the problem of oscillograph traces which intermixed

# <mark>call Kod</mark>ak

hopelessly at the point showing impact. They called Kodak. And found that we had a paper that, when exposed through appropriate filters, would provide multicolored traces. These could be interpreted even with large amplitude variations on narrow paper.

A third group had the problem of projecting computer output on a screen in color. Particularly troublesome was the fact that these data had to be updated and changed every few scconds. They called Kodak. Our engineers answered their problem with an embossed lenticular film originally intended for color kinescope recording. This film not only developed in 20 seconds to stay within their time requirements, but, with appropriate shooting and projecting techniques, produced the necessary color images.

Right now, you may be facing a datacollection problem that seems to defy solution. It may be quite different from those we mentioned. Your best bet could be a conversation with one of our photographic experts. Call Kodak. Dial (716) 325-2000, Ext. 3257. Or write: Instrumentation Sales, Eastman Kodak Company, Rochester, N. Y. 14650. Kodak

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# ... only 4 mirrors in optics system ...

in some cases down to 300 lines, by the time it reaches a home set; and Eldridge says that the IVC 100 picture appears to be equal in resolution and hue to one on a home receiver.

**Zoom lens.** Merely relaxing specs did not bring about the big cost reduction. The company developed a simplified optics system, consisting of a Nikon 50- to 300-millimeter zoom taking lens, relay lenses, and a system of plate beam-splitters. The relay lenses are necessary in order to shorten the back plane focal length of the taking lens.

The light from the relay lens passes first through a red-reflector dichroic mirror that reflects the long-wavelength portion of the spectrum to one side; another mirror redirects the reflected beam so that it is parallel to the main optical axis and imaged on the red vidicon. The main beam then passes through a blue-reflector dichroic surface that reflects to one side the shortwavelength portion of the spectrum. This beam is then redirected and imaged on the blue pickup tube. What is left of the main beam goes onto the green vidicon.

Doubling trouble. Plate beamsplitters are cheaper than solid glass block beam-splitters, but they can produce a double image-one from the front of the plate and one from the back. Skipworth Athey, a consultant to IVC and a director of the corporation, who designed the optics, says that the blue channel is most bothered by this double vision, because blue is low in luminosity. The blue channel thus has special circuitry to trim out the undesired reflection. Also, the backs of both dichroic mirrors have a coating the thickness of which is computer-calculated to suppress the undesired reflection.

The entire optics system thus requires only four fixed mirrors. These mirrors and the relay lenses are mounted in a subassembly sealed in a plastic case and mounted on the camera chassis. It never needs adjustment, according to IVC.

Thus, the camera consists of optics, three vidicons, deflection circuits, an integrated circuit sync

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generator, and an NTSC encoder. There are no external racks of equipment. The encoder is on a single printed circuit board about 8 by 10 inches.

To obtain registration of the three signals, IVC says it uses "considerable feedback" in the deflection circuits. The company asserts that component stability is such that the camera will operate for eight hours without adjustment.

Athey says that color tv is usually encoded by a method in which two different bandwidths are used. The color subcarrier is modulated in quadrature with the narrow-band Q-channel, corresponding to colors along the orange-blue axis, and the wideband I-channel, corresponding to colors along the redgreen channel. But decoding is on the R-minus-Y and B-minus-Y axes (Y being luminance), which are in quadrature. The ivc camera uses R-Y and B-Y encoding as well, which Athey says is much simpler and requires fewer components.

The sync generator is simplified. It does not lock the color signal to the horizontal sync. No one would know it by looking at the picture, says IVC.

Ronald Freid, ivc marketing manager, says he already has a \$500,-000 backlog from "two of the largest electronic manufacturers in the CCTV area." One is interested in audio-visual training, and the other in computer-aided education. International Video Corp., Mountain View, Calif. [398]

New subassemblies

# 2-minute detector of water pollution

Carbon analyzer system operates on-line for process control uses

Water pollution, according to recent government reports, is killing fish and spoiling recreation areas at an alarming rate.

Present systems for detecting organic pollution require hours or even days to determine the exact



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Sampler. System measures carbon content for pollution detection or process control.

carbon content-and hence organic content-of a sample. This is just too slow. In most cases, if the pollution is detected fast enough, it can be stopped.

A carbon analyzer built by Union Carbide Corp. completes the pollution check in two minutes. Designated the model 1212, the unit can detect organic pollution as small as a few parts per million.

Its rapid response also suits it for process control applications. In the treatment of chemical waste, continuous monitoring of both influent and effluent streams accurately measures efficiency of the process and permits regulation of operations to avoid upsets. Continuous monitoring of sewers or cooling water detects spills and leaks within moments. Circuitry can be added to sound an alarm when the quantity of organic matter rises above a preset level.

The analyzer consists of two sections: the preparation equipment and the analyzing equipment. A 40microliter sample is introduced in the test chamber in either a batch or continuous process. Through a hot-wire catalytic system, the organic sample is changed to carbon dioxide which is carried to an infrared analyzer by a nitrogen gas stream. By measuring the amount of infrared energy absorbed by the CO<sub>2</sub>, the carbon content of the sample is determined.

Two readout devices, a panel meter and a strip-chart recorder, are provided in full scale ranges from 0 to 100 through 0 to 3,000 parts per



Electronics | November 13, 1967



John Manning, Missiles Systems Division, Raytheon Company, Bedford, Mass., has installed 4 VSMF Files: Defense Design, Documentation, Mil Specs and Mil Standards.



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## Giant pulses easily obtained with revolutionary new PLASTIC LASER Q-SWITCH



The Mitsubishi plastic Q-Switch is a plastic version of the reversible, bleachable-dye Q-switch. When placed on the laser resonator, it automatically controls the Q of the resonator, offering a simple and repeatable means of obtaining ruby laser giant pulses of  $1 \sim 3$ MW. The device is a flat, transparent plastic plate in which bleachable-dye molecules are suspended.

Using closely coupled lamp reflector with a diffused reflecting surface, the device has successfully generated more than a hundred giant pulses with a peak power of a few megawatts. It can produce any desired contour and is stable for UV radiations. Since it can be used repeatedly, maintenance is minimal, and it saves space and weight in laser design.



#### **Specifications:**

Wavelength	6,943 Å (for ruby lasers)			
Absorption	30~50% at 6,943 Å			
Active dimensions	1½ x 1½ x ½ inches (thickness governs absorption)			
Alignment	No precise alignment required			

For full technical information, write to: Mitsubishi International Corporation 277 Park Avenue, New York, N.Y. 10017 Phone: 922-3700



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You never had a black book like it. Over 1,500 pages. And those phone numbers! More than 100,000 telling you who to call/where to go, for the over 4,000 different product categories listed and advertised in the yellow pages of the Electronics Buyers' Guide. There's never been a buyer's directory like it. The new '68 edition will be coming your way in October. Look for the book in the black box. EBG for '68...bigger, better and more useful than ever before. Electronics Buyers' Guide A McGraw-Hill Market Directed Publication, 30 West 42nd Street, New York, N.Y. 10036 million. Both units have a repeatability to within  $\pm 2\%$ . The tester, priced at \$8,600, operates at ambient temperatures from 32° to 120°F. In process stream installations, it requires a sample flow rate of 5 gallons an hour.

Union Carbide Corp., Electronics Div., 5 New St., White Plains, N.Y. [399]

New subassemblies

## The price is right -- even with cores

Japanese firm produces \$900 desk calculator with new techniques

In the U.S., it's considered uneconomic to use magnetic core memory registers in electronic desk calculators. Acoustic delay lines are employed instead. Cores are rarely designed into data processing systems which store less than about 10,000 bits.

Not so in Japan. Casio Computer Co. of Tokyo adds to the growing list of electronic calculators with an entry which will sell for \$900 in Japan. Like the Hayakawa Electric Co. unit [Electronics, Aug. 21, p. 189] all its internal registers are made of magnetic cores.

Masakatsu Ara, Casio's submanager for new product development, says the low price is possible partly because of the magnetic core registers.

The limiting factor in core memories lies in the electronic circuitry which decodes addresses, drives current through the wires in the memory, and senses the output signals. Casio has used several techniques to help keep these costs down and make the use of cores economically feasible.

Noise dies. For one thing, the memory is designed to operate at very low speeds; at these speeds the pulse signals have relatively slow rise and fall times, and therefore generate little noise. In fact, capacitively-coupled crosstalk is virtually nonexistent. There is also plenty of time for the noise that is

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## **NEW:** <u>smallest</u> axial <u>shielded</u> <u>inductor</u> <u>available</u> the "**'NANO-RED''**

0.250 ±0.010 #24 0.100 ±0.010 ACTUAL SIZE

Range:  $0.10\mu$ h to  $1,000\mu$ h in 49 stock values Size:  $\frac{1}{10}$  dia. by  $\frac{1}{4}$  lg. Inductance Tolerance:  $\pm 10\%$ 

This new "NANO-RED" offers the highest inductance to size ratio available in an axial shielded inductor. Exceptional "Q" and self-resonance characteristics. Max. coupling 2% units side by side. Non-flammable envelope. Designed to MIL-C-15305C. Operating temperature  $-55^{\circ}$ C to 125°C.

Other Lenox-Fugle Subminiature Shielded Inductors:



MICRO-RED The "Micro-Red" is a shielded inductor that offers the largest inductance range in its size: 0.10µh to 10,000µh. "Q" to "L" ratio unsurpassed, with excellent distributed capacity. Inductance tolerance ±10%. Designed to MIL-C-15305C. Stocked in 61 predesigned values.

The "Mini-Red" offers the highest "Q" to "L" ratio available over inductance range  $0.10\mu$ h to  $100,000\mu$ h in its size. Inductance tolerance  $\pm 10\%$  measured per MIL-C-15305C. Stocked in 73 predesigned values.

**DURA-RED** The "Dura-Red" is designed to MS-90537 with inductance range  $0.10\mu$ h to  $100,000\mu$ h with tolerance  $\pm 10\%$ . Stocked in 73 predesigned values.





Teamed. Programed mode permits semiautomatic coupling to typewriter.

generated to die away; the sensing circuits need not have a high noiserejection capability. Thus the circuits themselves can be simpler and can be built with wide-tolerance components.

Another important design feature is the serial loading and unloading of registers, one digit, or four bits, at a time. The memory has only four sense amplifiers and four write drivers, compared to the dozen or two of each found even in small computer memories.

Up to 14 digits. Using these techniques for a small core-memory unit, the Casio machine works with numbers of up to 14 digits. It stores them in four 14-digit registers, and two 7-digit registers. It also has a 30-digit program register, each digit corresponding to a single instruction.

The machine has a 14-instruction repertoire, any of which can be stored in a single digit position; ten decimal digits require four bits for a binary-code representation, and the four bits can represent up to 16 different symbols—the 10 digits and six others. The machine's output is through indicator tubes; its input is from its keyboard or from a typewriter.

The operator enters a program of up to 30 steps. He then enters data into the various registers and the program makes its calculations on this data; results appear in the indicator tubes above the keyboard. A semiautomatic mode, using a typewriter, is also available.

#### Specifications

Instruction repertoire		Add, subtract, multiply, divide Clear memory, clear keyboard Set memory registers 1, 2, 3, 4 Set minus sign Square root			
Size Weight Power		17½ 5 lbs 30 w	x 15	x 9 in.	
Casio (	Com	puter	Co.,	Tokyo	[400]

Electronics | November 13, 1967


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## **New Microwave Review**



Microwave sweep oscillator model 221 features remote symmetrical sweep control, remote power level control, manual sweep mode, and a time delay at the beginning of each sweep to stabilize r-f power. Frequency coverage of the sweeper, utilizing various available oscillator plug-ins is 200 Mhz to 40 Ghz. Micro-Power Inc., 25-14 Broadway, Long Island City, N.Y. 11106. [401]



Log periodic antenna AN112, covering the 1-12.5 Ghz range, is for use with wideband, electronically scanned microwave receivers. It is suited for rfi/emc surveillance. The assembly can withstand the continued flexing of a heavy coaxial cable attached to it such as RG-8. Dimensions are 8 x 61/4 x 61/2 in. Price is \$195. Electro/ Data Inc., 3121 Benton St., Garland, Texas. 75040. [405]



Backward-wave oscillator SE-218, covering 18 to 26.5 Ghz, has applications as a local oscillator in radar receivers, as a master oscillator in frequency diversity transmitters and in electronic countermeasure equipment. It features permanent-magnet focusing. The unit is  $2V_2 \times 2V_2 \times 5$  in. over-all, and weighs 4 lbs. Watkins-Johnson Co., 3333 Hillview Ave., Palo Alto, Calif. 94304. [402]



Type 4673-35 OSM Hybridge reflectometer has a residual swr under 1.055 over the range of 7.0 to 12.4 Ghz. No special storage oscilloscope or X-Y recorder is required since the entire swr vs frequency characteristic of the device under test can be determined in a single sweep cycle of the r-f source. Price is from \$470 to \$570. Alford Mfg. Co., 120 Cross St., Winchester, Mass. 01890. [403]



TR/limiter cell type BS808 is for X-band radars. It consists of a gas discharge TR cell and a solid state limiter fitted together. The limiter is self biasing, unlike p-i-n diodes, and thus requires no power supply. Frequency range is 9 to 10 Ghz. Peak operating power is 200 kw, and insertion loss is less than 0.8 db. Calvert Electronics Inc., 220 E. 23rd St., New York. 10010. [404]



dar system applications is rated at 1.0 kw output. Operation is rated at 1.0 kw output. Operation is class B, linear. Frequency range is 400 to 800 Mhz with manual tuning. The unit has a bandwidth of 6 Mhz, a gain of 13 db, and is rated at 50% efficiency. Power input is 50 w; maximum input vswr, 2:1. Microwave Cavity Laboratories Inc., 10 N. Beach Ave., LaGrange, In. 60525. [406]



Four-section, gang-tuned coaxial filter G450T has direct frequency readout. It features a compact tape drive coupled to a low-torque precision geartrain. Tuning range is 4.4 to 5.0 Ghz. Insertion loss is 0.85 db max. Calibration accuracy is  $\pm 2$  Mhz. Direct tape readout available on all standard models (1-12 Ghz) upon request. Gombos Microwave Inc., Webro Rd., Clifton, N.J. 07012. [407]



Directional detector model 3142 is an integrated package that combines a maximally flat directional coupler with a matched high sensitivity crystal detector. Frequency sensitivity is limited to  $\pm 0.2$  db from 0.950 to 2.11 Ghz with a minimum directivity of 25 db. Total  $\pm 2$  db flatness is guaranteed. Narda Microwave Corp., Engineers Hill, Plainview, L.I., N.Y. 11803. [408]

#### New microwave

# Ultrafast switching--it's a snap

Uhf stripline device switches in 0.8 nsec,

twice as fast as mathematics says it should

A mathematical oddity, that's what Microwave Associates Inc. has come up with in a diode switch that turns on or off twice as fast as it should.

In building its 800-inegahertz single-pole, single-throw switch, the company found the device turns on or off in only 0.5 to 0.8 nanosecond. This wasn't possible —according to an impressive technical paper presented last year in which the mathematics proved switching time cannot be less than 1.24 divided by the operating frequency. Based on that paper's



Speeder. Impulse from driver turns on diodes that conduct microwave energy to ground.

equation, the stripline device should turn on or off in about 1.8 nsec.

Paul Bascon, who headed the company's design effort, can demonstrate the mysterious speed on

# may account for switching speed . . .

the test bench, but can't explain it mathematically.

With a snap. The device uses two of the company's snap varactor diodes to do the switching. Bandpass filters at input and output keep both switching transients and drive power out of the microwave transmission line. They seem to do their job—drive-signal attenuation reaches 50 decibels just below about 150 Mhz and keeps increasing as frequency decreases. Attenuation above the passband is almost as steep.

A third filter stands between the driver terminals and the transmission line as added interference protection for the microwave signal. This filter presented a knotty tradeoff problem. To keep the microwave energy from entering the driver circuitry and thus keep insertion loss low, the filter's impedance had to be high. That meant a low cutoff frequency.

But to get a fast-risctime switching pulse through the filter to the diodes, a high cutoff frequency was necessary—about 700-Mhz bandwidth was needed to get the required pulse and the bulk of its Fourier components to the diodes.

The compromise was a sevenelement Chebyschev stopband filter with 40-db attenuation between 600 and 900 Mhz; above and below



Stripped down. Both faces of stripline circuit boards are shown with filter stubs and interconnections.

the stopband, attenuation drops off rapidly.

The compromise seems to have worked. Across a 200-Mhz bandwidth centered at 800 Mhz, there is less than 1.5-db insertion loss when the switch is turned on; isolation exceeds 40 db when the switch is off. Input and output voltage standing-wave ratio is a maximum of 1.67.

**Bootstrapping hinted.** Bascon believes the varactor diodes' frequency-multiplication characteristic may account for the speed. Perhaps the diodes are multiplying the Fourier components of the switching pulse to even higher frequencies, thus bootstrapping their way to ultrafast switching speeds. On oscilloscope traces, the switching signal was found to have frequency components well above 1,000 Mhz after it had passed through the diodes.

But Bascon also found that the diodes changed between the on and off states long before the switching pulse had completed even a small part of its 2-nsec rise to peak amplitude. It may be that the diodes need little power to switch and are being overdriven to high speed performance.

Preliminary applications are in military and research programs. The switch, designated the MA-8306-ILIN, was built for the Hughes Aircraft Co. for use in a classified system. Bell Telephone Laboratories, interested in switches that can stop a radio-frequency signal in mid-cycle, seeks a 300-Mhz switch with 2-nsec speed -another impossible combination of speed and frequency. And the Air Force wants an ultrahigh speed switch for an S-band application.

#### **Specifications**

Switching speed Bandwidth to 1.5-db attenuation points Bandwidth to 3-db attenuation points Drive voltage Drive-pulse risetime Drive-pulse falltime Power capability 0.5-0.8 nsec 700-900 Mhz 650-950 Mhz +1, -2 v 2 nsec 1.5 nsec

more than 700 mw continuous

Microwave Associates Inc., Burlington, Mass. 01803 [409]

# Some other ENGELHARD products

**PRECISION-DRAWN TAPE** is supplied to specification in bimetals or solid precious metals. ECON-O-TAPE is available in any thickness, length or width (from .0095"). Shaped or rectangular sections. Excellent material for electrical contacts subject to corrosion.

E-70 BRIGHT GOLD PROCESS produces mirror bright electroplates from flash deposits to 500 microinches in thickness. This highly efficient, neutral bath produces hard, wear resistant finishes suitable for the complete range of decorative applications.

**CLAD CONTACT PARTS** provide a precious metal layer essentially pore free and durable, with an extremely strong bond to the base metal. These parts are supplied usually in the form of blades and spring assemblies.

ACID GOLD PLATING PROCESS provides high purity gold electrodeposits (24 Karat) that are smooth, lustrous, free from porosity, highly ductile, relatively hard. Excellent deposits up to several mils in either still or barrel plating. Highly stable and simple to handle over long periods. Adaptable to plating wide variety of electronic components.

**SEMICONDUCTOR MATERIALS** are supplied in a wide range of precious and base metals and their alloys. These include solid sheet, wire, tape, base tab materials and clad products, fine gold wire, and ribbon. New materials are constantly under development. Technical assistance is available.

**PRECIOUS METAL CONTACTS** in pure or alloyed forms of silver, platinum, palladium and gold provide unmatched resistance to atmospheric corrosion and electrical pitting. Engelhard will manufacture to specifications or provide material in wire, rod or sheet form.

THIN WIRE AND FOIL are produced by Engelhard Industries to meet rigid electronic design requirements. Both extruded and Taylor Process thin wire are available in diameters as small as .001". Thin-gauge foil is supplied in sheets up to 8" to 18".

MILL PRODUCTS include sheet, thin foils, wire, seamless tubing, gauze, platinum clad and fabricated items. All are precision made using skills resulting from over seventy-five years experience in the working, drawing, machining, spinning, forging, and weaving of basic forms of platinum metals and alloys.



# **ENCELHARD** gold and silver on relay contacts assure only one miss in ten million cycles!

Electro-Tec Corp. faced one of its toughest problems develop electromechanical relays to meet the extraordinary reliability requirements of missiles, manned aircraft and space craft, and computers. The solution: new Wedge-Action relays using Engelhard 24K gold and fine silver for contacts.

These remarkable relays have the highest confidence level ever achieved in any electromechanical relay only one miss in 10 million cycles. Engelhard impurityfree gold and silver, electrodeposited to both moving and stationary switching contacts, helped do the trick. Contact resistance is an extremely low 0.012 ohms to 0.015 ohms. And remains constant to within 15 milliohms for more than 100,000 operations.

This is just one more example of the problem-solving capabilities of Engelhard precious metals—capabilities that result from our constant search and development of the precious metals. When you have a precious metals problem, call on Engelhard Industries, working wonders with wonder-working metals!



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New microwave

# Coaxial connector for fast crimping

Uniform contacts assured by mechanical process including cable preparation

There was a time when the installation of solder-type coaxial connectors, with their many loose parts, was difficult and time-consuming. Stray braid strands were a common cause of trouble. This situation was somewhat alleviated by crimp-type connectors but the process still took too much time especially when it came to stripping subminiature cable.

To eliminate these problems, AMP Incorporated has developed a system—including connectors and installation equipment—that does the job in 20 seconds. The contact exhibits a voltage standing wave ratio of less than 1.5:1 at 500 megahertz.

Designed for high-density, multiple-circuit connector applications, the subminature, 0.11-inch contact fits into any AMP connector housing that accepts size 16 pinand-socket contacts. Either pinand-socket or coaxial contacts will fit into any of the 14 to 156 positions of the 19 connector styles available.

The contact body is stamped from strip brass conforming to MIL-B-50. A polypropylene dielectric surrounds and supports the inner contact for accurate mating alignment, and a tin-plated copper retention spring attached to the outer contact surface secures the crimped contact from axial pullout.

Application tooling for the stripfed connector includes two electrically operated bench machines —an applicator and a crimping press—that complete the assembly in 20 seconds.

**Collared.** Operation of the applicator tool is simple. A piece of cable is inserted through a funnel-like opening, a button pushed, and the stripped cable removed with a crimping collar put in place. Inside the machine, a vibratory hop-



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- All Lambda power supplies are guaranteed for 5 years.

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Model	Range	30°C	40°C	50°C	60°C	Prices
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LP 411	0-20 VDC	1.2A	1.1A	1.0A	0.8A	119
LP 412	0.40 VDC*	0.70A	0.65A	0.60A	0.50A	114
LP 413	0-60 VDC*	0.45A	0.41A	0.37A	0.33A	129
LP 414	0-120 VDC	0.20A	0.18A	0.16A	0.12A	149
LP 415	0-250 VDC	80MA	72MA	65MA	60MA	164

\*Overvoltage Protection available as an accessory - \$40.00 each.

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# **New Production Equipment Review**



Weld head model 820-IWW is designed for welding insulated wire to terminals, without prestripping. Equipped with water-cooled electrodes, the head will operate for hours at high production rates. It has a force range of 8 oz to 20 lbs and a digital force readout. Throat depth is 25/8 in. Price is \$495. Wells Electronics Inc., 1701 S. Main St., South Bend, Ind. 46623. [421]



Ultrasonic scrubber 020 cleans semiconductor wafers in the process steps leading to making epitaxial slices. It includes a 150-w, 6-x 10- x 4-in. tank system. Its transducers are lead titanate. The power supply driving them is oversized by 300%, giving long life and eliminating need for a fan. Pittsburgh Materials & Chemicals Corp., 3400 Old Wm. Penn H'way, Murrysville, Pa. 15668. [425]



Long-life sapphire capillaries are for the precision flameoff of bonding wire used in the manufacture of IC's. Bore sizes are 0.002, 0.003, and 0.004 in. Bores are accurate to 0.0005 in., assuring accurate reproducibility of flame levels from capillary to capillary with little if any pressure compensation. Specialty Glass Products Inc., 147 Terwood Rd., Willow Grove, Pa. 19090. [422]



vacuum evaporator VE-30 is automatic and has built-in fail-safe features. Working vacuum is in the  $10^{-5}$  torr range, with 7-minute pumpdown to  $10^{-6}$  torr. Features include an 18 x 30 in. work area; 1,440 liter per sec diffusion pump; and 2 kva filament power supply. Uses include thin film deposition work and r-f sputtering. Varian Associates, N.W. Science Park Dr., Portland, Ore. 97229. [423]



Model 300 Autopulse soldering system places all critical aspects of hand soldering under fully automatic programed control. It generates temperatures higher than 1,000°F in as little as 100 msec, and permits soldering of insulated wires smaller than 0.001 in. The system is suited for IC production. Browne Engineering Co., 2003 State St., Santa Barbara, Calif. 93105. [424]



vields of 99% plus. It uses fine diameter steel wires combined with an abrasive slurry to saw through materials such as glass, silicon and germanium. Wafers with center-to-center spacing as little as 0.010 in. can be cut at rates of 1½ minutes each including wafer loading and unloading. Micro Tech Mfg. Inc., 703 Plantation St., Worcester, Mass. 01605. [426]



Die bonder model 1212 accommodates dual-in-line (DIL) IC's. Its carrier holds 4 tiers of 15/8-inwide indexing belts and cach belt holds 16 lineal inches of DIL strips. A bonding needle is contained in an air bearing. Vacuum creates the bonding force. A horizontal movement of the needle provides scrubbing motion. Sola Basic Industries, 2450 W. Hubbard St., Chicago. 60612. [427]



A conveyor furnace offers precise process control and high production yields for thick-film firing of semiconductors. It can be adapted for soldering, alloying, brazing, and sintering. Solid state controls hold set temperatures of up to 1,000° within  $\pm 2^{\circ}$ C. The belt drive provides accurate speeds from 1 to 10 in./minute. Sola Basic Industries, 2450 W. Hubbard St., Chicago. 60612. [428]

#### New production equipment

# Controlled overloading tunes up resistors

Applying excessive current to thin-film devices produces an adjustment tolerance of 0.02%

**Overloading** a resistor can blow or degrade a circuit.

But controlled overloading is the heart of a new technique for adjusting thin-film resistors to tolerances as tight as  $\pm 0.02\%$ . A precision resistor adjustment machine designed at the Bunker-Ramo Corp. is said to be the first commercially available machine of its kind which works on an electrical-thermal principle. Most use mechanical or chemical means to adjust thin-film resistors.

The new equipment, which is being offered for lease, emerged from



Settable. Operator selects the desired resistance and attaches the probes. The rest of the operation is automatic.



... process slow, so no hot spots ...

a program to develop equipment for in-house use by Bunker-Ramo, a major supplier of custom-designed hybrid thin-film circuits. The machine is used with a digital voltmeter, which reads out resistance values.

No hot spots. According to Jack W. Ireland, director of the company's microelectronics and advanced technology operations, the controlled, relatively slow nature of the new process eliminates the hot spots and noise that are characteristic of chemical and mechanical adjustment techniques.

The new technique alters the temperature coefficient of resistance (TCR) of resistors. This is not true of incchanical adjustment techniques such as scribing or the use of shorting bars. "When you ad-just with our equipment," Ireland says, "you get a TCR change at a predictable rate with respect to the change in resistance. This TCR change can be advantageous for tracking purposes-where you have two adjacent resistors that have to remain identical in resistance over a wide temperature range. For every degree of heat, you add maybe 10 to 50 parts per million, depending on the TCR factor of the material."

Balancing the bridge. The equipment consists of a Wheatstone bridge, power supplies and associated circuitry to selectively energize and de-energize the bridge arrangement. The bridge has four arms, two of which have the resistors to be adjusted-and standard wire-wound resistors against which they'll be checked—sequentially switched into them. The resistors and the standards are so arranged that when a switch positions the resistor to be adjusted into the Wheatstone bridge, the standard resistor is placed in the adjacent arm of the bridge. A current from a secondary winding of a transformer in the circuitry flows through the bridge arrangement, including both the resistor and the standard. Current flowing through the resistor to be adjusted is controlled by the setting of an autotransformer in the circuitry, and a reading of the current is provided by a milliameter in series with the autotransformer.

When the resistance value of the resistor to be adjusted equals that of the standard, a detector functions to de-energize the circuit. A stepping switch can then be advanced to the next position, bringing another resistor and its standard reference into the bridge arrangement. The standard resistors are much larger than the resistors that must be adjusted. They easily dissipate the heat and their values remain unchanged.

The resistance tolerance of the equipment is adjustable, "but there's a practical value beyond which you don't need to go," says Ireland. "A good practical limit for repeatable production rates is  $\pm 0.01\%$ ." A typical production rate at this accuracy, Ireland says, is 10 resistors per hour, using single probes and depending on the accuracy of the DVM used.

**Up or down.** Some typical resistance changes accomplished with the equipment in an oxidizing atmosphere show that the resistance of uncoated chromium resistors was boosted from 1,927 ohms to 2,156 ohms in 13 seconds at 570 watts per square inch; coated chromel-C resistance was lowered from 1,950 ohms to 1,879 ohms in two seconds with 565 watts per square inch.

Ireland says the advent of hybrid circuits has created the market for precision resistor adjustment equipment. "This equipment should assist major users of hybrid microcircuits on make or buy decisions at a minimum outlay," he says. "The major aerospace companies are going the hybrid route with their own research and development efforts. Our equipment comes into play in this subsystems work."

A typical customer, Ireland believes, might be a large-volume user of analog circuits such as a manufacturer of analog computers. Such a customer could use the equipment for prototype work, then let out production specifications for resistors to a volume vendor.

The company has identified an initial market potential of about 100 units, and will lease the equipment for \$300 a month plus one cent per pulse.

Bunker-Ramo Corp., Western Technical Center, 8433 Fallbrook Ave., Canoga Park, Calif. 91304 **[429]**  You're a yearbehind the timesif you think ourF1 vacuum relayis just for theomunicationsindustry.

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operation (10 ms maximum). For complete information on the RF1 and a copy of our new vacuum relay catalog, write to ITT Jennings, a division of International Telephone and Telegraph Corporation, 970 McLaughlin Avenue, San Jose, California 95108

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New production equipment

# Welding fasteners quick as a flash

High-speed stud welding unit numerically controlled for parts production

Numerical control, used extensively to run drilling machines, boring mills and punch presses, has been coupled to stud welding techniques for mass-production of parts for the electronics industry.

Stud welding is the joining of metal fasteners of various dimensions. The use of a tape-fed numerical control machine means that intricate welding patterns can be accomplished on items ranging from electronic housings to appliance panels without the need for auxiliary tooling or multiple welding heads, according to KSM division of Omark Industries Inc.

The company coupled its production welding unit to a numerical control system and positioning table made by Hughes Aircraft Co. The resulting system permits about 30 welds per minute, in virtually any pattern and within 0.001 inch of the desired location. The company sees primary applications in electronic parts production, where precisely-positioned fasteners are often needed in a small area to secure components.

Studs of up to one-quarter inch in diameter can be attached by the welding unit, which can be stocked with more than 15,000 fasteners. A weld is completed in a few milliseconds, so quickly that there is no burning on the reverse side of the thinnest-gauge materials, KSM says. The capacitor-discharge method of welding is used. A steel stud with a small, protruding tip is placed on the workpiece. Electrical energy stored in the capacitors is then released, instantly melting the projection and the surface of the material, and permanently joining the stud and the piece. The process can be used on a variety of metals, including aluminum.

Omark Industries, Inc., KSM Division, Moorestown, N.J. 08057 [430]

# Mold-A-Terms cut terminal insulating costs to 50%!



This technique consists of encapsulating any desired portion of the standard open barrel terminals after they are crimped onto wire leads. PVC and various other thermoplastic materials have been found equally adaptable.

Beman refined "MOLD-A-TERMS" to overcome price inequities found in comparable cost studies with preinsulated and post-insulating methods.

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Circle 263 on reader service card



TRIPLETT ELECTRICAL INSTRUMENT COMPANY, BLUFFTON, OHIO

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# **New Books**

#### Less guesswork

Handbook of filter synthesis Anatol I. Zverev John Wiley and Sons, Inc., 576 pp. \$19.95

Today a systems engineer can specify almost any type of filter response as a subsystem on a block diagram and be reasonably sure that it can be approximated and built into an operating electronic filter. This handbook makes it easier for filter designers to satisfy such specifications. It combines the best features of a theoretical text with those of a practical filter design manual.

Performance and design data for all possible filter types—inductance/capacitance, crystal, and coupled resonators—are given in both the time and frequency domains. Designed primarily as a guide to solving filter problems, the book also covers basic network synthesis.

Zverev starts with the underlying theory, concepts, and techniques of selective networks and then moves to the responses that are provided by passive, linear, bilateral filtering structures. These are illustrated by specialized networks such as crystal and helical filters.

Other sections cover polynomial filters with monotonic attenuation curves, design tables for lowpass element values, normalized coupling coefficients, quality factors, and network-transformation techniques.

Although the author does an excellent, comprehensive job of describing passive filters, the reader will not find an extensive treatment of active networks and microwave structures.

#### A for effort

Introduction to Quantum Mechanics for Electrical Engineers P.A. Linsay McGraw-Hill Book Co., 240 pp., \$9.50

Few books have been aimed at making quantum mechanics palatable to electrical engineers. Any that try to are like coeds at Princeton—on the basis of rarity alone they demand attention. This book tries and partially succeeds.

The importance of quantum mechanics to today's inventive electrical engineer is summed up by Rudolf Kompfner of Bell Telephone Laboratories in his introduction: "I expect to see a reversal of a trend . . . that the major inventions in the recent past in the sciences of communications and electronics have been made by physicists." Presumably, notes Kompfner, the physicists studied quantum mechanics at school.

In a discussion of waves Lindsay glosses over the first experiments that suggested the wave properties of matter and omits illustrations that might be helpful. He assumes the reader is familiar with wave equations, and points out the similarities between Heisenberg's uncertainty principle and the timefrequency domain correspondence. Liberal use is made of transmission line theory throughout to support the author's presentations.

The book concludes with a discussion of the concept of energy bands in crystals. Most readers would expect, and profit by, a discussion of the relationship between this concept and semiconductor physics—but it is lacking. Instead the reader must refer to texts on solid state physics, for which Lindsay's book is an excellent introduction.

For those who are seriously interested in the subject, he includes problems at the close of each chapter. Some instruct the reader to "discuss" specific areas. One wonders with whom the solitary student will discuss such problems; wives, for example, are notoriously poor conversationalists when it comes to quantum mechanics.

#### Two in one

Tunnel Diodes M.A. Lee, B. Easter, H.A. Bell, Chapman and Hall Ltd., Distributed in the U.S. by Barnes & Noble Inc., 196 pp., \$6.25

As one of a series of brief, inexpensive monographs on selected topics in electronics, it's easy to see why this book has been published. The

# How to keep relay contact forces balanced at 30 G's.

Picking a relay for an extreme shock/vibration environment is a tough problem for many a circuit designer. Few relays are designed to meet the problem head on. There is now one notable exception -a 4PDT, 10 ampere relay in a one-

inch cube. Using a new design principle balanced-force-this relay withstands severe shock. vibration or acceleration while maintaining high contact and overload capabilities. It will take more than 30 G's to 3000 Hz vibration, a shock of 100 G's and has a minimum life of 100,000 cycles. This one-inch cube is all welded, weighs 2.5 ounces, and is rated at 2.9 watts coil power.

#### EFFICIENT MAGNETIC CIRCUIT

In the conventional relay motor, forces for open and closed contacts are unequal. Energized coil power causes the armature to close the normally open contacts. But, when the coil power is removed and the contacts return to the normally closed position, only the spring forces of the contacts and the return spring provide the force. These combined spring forces are usually low, allowing the contacts to bounce. In addition, the low spring force allows the armature to rebound off the armature stop, again knocking the contacts open sometimes, for as long as several milliseconds after they have initially closed.



Force-Stroke Curve of Typical Relay

condition is to balance the armature forces exactly. This is Curve A'C' -- Balanced-Force Relay normally open contacts. Curve DEFGH-Typical Relay. achieved in the

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getting rid

of a bounce

Leach Balanced Force Relay by use of an extremely efficient magnetic design. It has to be to keep the forces balanced while ignoring 30 G's.

Basically it is a controlled application of magnet and coil flux. In the de-energized position, a permanent magnet flux flows between the armature and the tip of the adjacent pole piece, resulting in a high holding force. The motor is, therefore, relatively immune to shock and vibration. When coil power is applied, the flux from the permanent magnet is nullified by the coil flux flowing in an opposite direction. The armature closes with a rapid build-up of magnetic force driving it against the contact overtravel forces and into a sealed position.



When coil power is removed and the armature returns.

the

Balanced-Force Motor De-Energized

restoring force of the permanent magnet builds up quickly. The armature is then driven against the overtravel forces of the normally closed contacts and into its de-energized sealed position. With this type of forcedisplacement, the armature isn't about to rebound.



The moving contacts are mounted to an armature, which is held firmly at the end of each stroke by high magnetic forces. Since the armature can't move during shock

or vibration, undesirable contact opening is eliminated.



Reinforcing the moving contact is a buffer strip which assumes a

variety of chores. It has a bow in the center to act as a spring load while serving as a rivet plate. It works as a heat sink. It will break the contact strip free from a weld if one occurs because of excessive overload. It makes contact with the moving blade which results in excellent low contact drop. It serves as an electrical contact between the moving blade system and the header. And, as the name implies, it buffers the contact blade against extreme shocks and vibrations.

WELDED ASSEMBLY

In assembling the relay all detail parts are welded. No part is solder assembled. There is no possibility of contamination from solder flux. The unit is then pressed into a can and electron-beam sealed, leaving only an evacuation hole. After a high temperature bake, the relay is filled with a dried inert gas, and the hole is welded shut. Here, ready for shipment, is a relay with a magnetic circuit designed so the force without coil power applied is equal to the force with coil power applied, but in exactly the opposite direction. And you can rest assured those forces stay balanced no matter how you shake them.





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### New Books

topic of tunnel diodes is narrow and lends itself to coverage in less than 200 pages.

Tunnel diodes, today, are useful in only two applications: microwave amplifiers and high-speed logic circuits. This book covers both areas. But a reader interested in logic circuits would care little about microwave amplifiers, and vice versa. Thus, either reader, if he buys the book, is also paying for information that will probably be useless to him in his work.

One wonders, in fact, why two books were not prepared for the series, one on each major application area. This would have allowed deeper coverage of each type circuit and made each one more useful to a particular reader.

The best section in the book is the first one, on physical aspects of tunnel diodes. This is a well-written discussion of the tunneling phenomenon and the construction and metallurgy of the devices.

#### Bright hope

The Physics of Electroluminescent Devices P.R. Thornton E&F.N. Spon Ltd., 382 pp., \$14.50

After candidly indicating the breadth of topics needed to cover the subject in his very first sentence—"The study of electroluminescent devices is not one for faint hearts"—the author goes on to deliver one of the best books yet published on the subject. It is complete, well written, and will be useful for a long time as this embryonic segment of electronics grows to major importance.

It highlights the changing nature of electronics engineering. With the advent of new devices, today's engineer must be part metallurgist, part thermodynamicist, part optics specialist, and still be all engineer.

As a primer for the understanding of the basic mechanisms of electroluminescence, the first two chapters are devoted to excitation and recombination processes. The author then moves on to avalanche breakdown and reverse-bias light emission, and then zeroes in on

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## New Books

electroluminescent behavior in zinc sulfide, cadmium sulfide, gallium arsenide, and gallium phosphide. He winds up with a discussion of injection lasers and points out in detail the many applications for electroluminescent devices.

In his section on applications, the author has looked far enough ahead to areas that are only theoretical today. Since the most likely applications for injection lasers will be in room temperature devices where cryogenic cooling will not be required—the author discusses the thermal effects in detail. To minimize the contact resistance and provide better heat sinking, he points up the need to improve laser materials. Applications of noncoherent electroluminescent devices in optical coupling, x-y displays, and electrical scanning are also discussed.

The book concludes with the physics of failure. The author cites the built-in effects, such as mechanical defects, variations in doping levels, and surface contamination, and the operational effects, such as ionic movement, and thermal effects.

#### Why bother?

Servomechanisms L.J. Bulliet Addison-Wesley Publishing Co., 276 pp., \$9.95

A major technical advance during World War II occurred in servomechanisms and, shortly thereafter, several basic books appeared on the subject. Two notable texts were by Brown and Campbell, and by Lauer, Lesnik, and Matson. The first treated servomechanisms on an analytical basis, the second described servo components and system design.

This duo was in the vanguard of a variety of works by others in the field of servos. For years, industry has not suffered from a lack of servomechanism textbooks. And, except for treating very specialized aspects, most authors have had the good grace not to produce additional readings.

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view except for one thing—the author's admirable intention is to educate technicians among others. To accomplish this he "avoids the deeper theoretical subtleties which can be appreciated only through the use of higher mathematics."

Such a statement cannot acquit, in advance, the failure of a book to come to grips with its subject at the required level. Technicians are better educated than the author implies. Were they not, the book would be of little use to technicianreaders, for the author doesn't spare the mathematics anyway. He just avoids mathematics to give a real insight into servomechanism principles.

For example, Bulliet overlooks a fundamental servomechanism concept—that of stability—and his insistence on eschewing mathematics is probably the reason. Any technician who thinks he can understand servomechanisms from this book will be in for a mighty big surprise when the real servomechanism on which he's working with a development engineer suddenly starts oscillating. Unfortunately, he won't have time to read another book on servos to discover why that's happening.

Perhaps to compensate for leaving out thorough treatment of stability, the author dwells at great length on ideas like saturation, isolation, and time constant. After defining time constant in a complex paragraph, Bulliet uses the term vaguely—parenthetically stating that the time constant is the "time to settle down." Settling time does relate to time constant, but the two are not the same.

#### **Recently Published**

Handbook of Numerical Methods and Applications, Louis G. Kelley, Addison-Wesley Publishing Company, 354 pp., \$14.50

Designed mainly as a handbook, this volume is also a reference for engineers and scientists who program their own problems. The author discusses numerical analysis, curve fitting and data smoothing, nonlinear algebraic equations, Eigenvectors, and the Gram-Schmidt orthogonalization procedure.

Modern Transistor Electronics Analysis and Design, Fred K. Manasse, John A. Ekiss, and Charles R. Gray, Prentice-Hall, Inc., 555 pp., \$12.95

Primarily for the electronics design engineer, this book focuses on development and analysis of semiconductors. Included are several

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### **New Books**

new areas of development—integrated circuits, avalanching and Gunn-effect diodes, charge-control models, and choppers.

Reusable Protective Packaging, Steven E. Mautner, Kayar Publishing Co., 101 pp., \$8.50

Protecting electronic equipment during shipment and storage has become a problem that the electronic designer has to face. This book attempts to lead him through the maze of military specifications for shock, vibration, and hostile environments.

Magnetism and Magnetic Materials 1967 Digest, Edited by W.D. Doyle and A.B. Harris, Academic Press, 278 pp., \$11

A concise review of papers on magnetism and magnetic materials published in 1966, designed as a reference for the graduate student or the practicing engineer.

Electric Power Systems, B.M. Weedy, John Wiley and Sons, 302 pp., \$8.50

This introductory text provides students with the basic essentials of power system operation and analysis. Equivalent circuits, d-c transmission, and the limitations of transmittable power are discussed.

Handbook of Analog Computation, Maxwell C. Gilliand, Systron-Donner Corp., 40 pp., \$5

Provides students as well as experienced computer users with up-to-date analog computer software. Basic fundamentals and advanced programing techniques are presented.

Marks' Mechanical Engineers Handbook, Seventh Edition, Edited by Theodore Baumeister, McGraw-Hill Book Co., \$29.50

Latest edition of a standard work, most useful for electrical engineers in the areas of cryogenics, ultrasonics, optics, and thermal properties of materials.

Basic Analog Computation, Gerald R. Peterson, The Macmillan Co.,  $124\ \text{pp.},\ \$3.95$ 

How an analog computer functions and what makes it function are covered in this undergraduate text. Simple linear, high-order linear, and nonlinear and time-varying systems programing are included.

Digital Logic and Computer Operations, Robert C. Baron and Albert T. Piccirilli, McGraw-Hill Book Co., 321 pp., \$13.50

Beginning with a general introduction to the computer field, this textbook covers Boolean algebra, computer logic, storage, input and output functions, and control elements. Timesharing, and multiaccess systems are also included.

High Frequency Communications, J.A. Betts, American Elsevier Publishing Co., 98 pp., \$5

The application of error detection and correction is explained, showing the difference between systems used on one-way and two-way circuits. Also included are methods of ionospheric forecasting.

Electric Circuit Problems With Solutions, F.A. Benson, Barnes and Noble, 257 pp., \$4.95

Aimed at the laboratory technician, this book contains a wide variety of problems in a-c, d-c, and polyphase circuits provides the reader with detailed solutions.

Characteristics and Operation of MOS Field Effect Devices, Paul Richman, McGraw-Hill Book Co., 146 pp., \$10

The book covers the electrical characteristics of MOS transistors, MOS technology, fabrication techniques, and linear and digital MOS circuit applications. Included are recent developments in the fabrication of low power MOS complementary integrated circuits.

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Heat Distortion Temp. @ 66 PSI	°F.	285	308
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# **Technical Abstracts**

#### Large repertoire

An LSI variable function register Robert J. Lesniewski Goddard Space Flight Center Greenbelt, Md.

Although large-scale integrated circuits are usually designed for just one purpose, the true value of LSI may be in more versatile arrays such as those that can be electrically programed to perform many different functions.

Such circuit versatility will soon be almost mandatory in sophisticated spacecraft with on-board data processing. As an example, a variable function register capable of four different operations has been built using metal oxide semiconductor technology, and 500 active devices on a chip.

A second-generation register, capable of parallel processing with 18 different operations using 1,300 active devices, also has been designed, but not yet built. The complementary MOS technology makes such design possible by reducing power dissipation and element count.

The variable-function repertoire includes seven basic operations parallel loading and outputting, rotating data, shifting data to the right and left, and complementing the register's contents. The shifting and rotating operations can be electrically programed by setting MOS switches between the shift-register stages.

The register chips also can be cascaded to form large registers. With a bypass switch, information can be shifted past a register while it continues to operate.

Presented at Eastcon, Washington, Oct. 16-18.

#### Two-way etch

Anisotropic etching for forming isolation slots H.A. Waggener, R.C. Kragness, and A.L. Tyler, Bell Telephone Laboratories, Allentown, Pa.

A technique that etches downward into a silicon wafer much more rapidly than it etches sideways gives narrow, precisely defined isolation slots. As a result, more beamleaded integrated circuits can be fabricated in a silicon slice than is possible with standard etching techniques. The new method requires a unique orientation of the etching mask on a specific lattice plane of the silicon crystal, and an etchant that attacks one plane more than the others. Etchants now being investigated for silicon consist of strong alkaline solutions, such as a mixture of potassium hydroxide, propanol, and water.

To fully exploit the difference in etch rates, two conditions are required: the face of the silicon disk to be etched is made parallel to the lattice planes having a high etch rate; and the edges of masked areas are aligned parallel to a second lattice plane with a negligible etch rate. Under these conditions, slots are formed with slanted sides, in the shape of flat-bottomed wedges. Each slot steadily becomes narrower as the etching progresses, and thus the slot's depth and width are precisely defined by the etching mask and etching rate. Etching terminates when the two sloping sides of the deepening slot meet, or when it etches through the slide, whichever occurs first.

During the fabrication of beamleaded integrated circuits, slots are etched out of the semiconductor slice to separate the many individual circuits and/or to isolate components within each integrated circuit. Standard (nonpreferential) etchants result in fewer integrated circuits because variations in the thickness of silicon slices cannot be reduced economically to less than a few tenths of a mil. To insure complete penetration at the thickest parts of the slice, considerable over-etching must be tolerated at the thinner portions. Since the isotropic, nonpreferential solutions etch as fast sideways as downward, the active devices on the opposite side of the slice must be spaced three to four time farther apart than the average slice thickness to protect them against over-etching during separation.

With preferential ctching, the masking operation is done after the desired devices have been fabricated on one side of the slice. A silicon dioxide mask then is applied

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Technical Abstracts

to the opposite side to delineate the slots for etching. Because the sides of the slots are stationary, only relatively simple etching controls are required.

An important feature of the improved etching technique is that the mask shape is altered to compensate for undercutting at the outside corners of the mask, where the third main lattice plane of silicon is exposed. The etch rate of this third plane can be made much slower than that of the primary etching plane, but it is still significant. Therefore, enlarged corner areas of calculated size and shape are added to the etch mask to compensate for the undercutting at these corners.

Presented at the International Electron Devices Meeting, Washington, Oct. 18-20.

#### Featherweights

A digitally implemented microelectronic i-f decoder Richard S. Ocheret General Instrument Corp., Radio Receptor Division, Brooklyn, N.Y.

Metal oxide semiconductor technology may slash the size and price of delay lines. Beaconry and interrogation-friend-or-foe (IFF) systems use delay lines for passive decoding of a pulse train to see if it agrees with a preselected code. The new digital equivalent for the IFF passive decoder-a shift register-is built on a single silicon chip with mos technology that is easy to design and simple to make.

With the mos device, transconductance can be determined by geometry so that all chip devices can be simultaneously diffused in a single step. Since both drain and source are reverse-biased with respect to the substrate, no isolation is required between devices, and, because the input impedance of each device is high, increased fanout is possible.

The single chip holds a 43-bit shift register, decoding logic, and input circuitry. The circuitry can operate down to d-c but if this is not needed, four-phase logic can be used. With the four-phase scheme, power is dissipated only during switching.

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## **Technical Abstracts**

clocked at 2.069 megahertz with three bits provided for every pulse interval in the IFF reply train. The decoding logic on the chip compares incoming trains with a code selected by external switches.

The input video signal is fed to a strobe circuit, which clocks the signal into the shift register. The outputs of every third stage are fed to logic circuits, NAND and NOR gates, and compared with the coded input.

Presented at Eastcon, Washington, Oct. 16-18.

#### Sound design

Monolithic limiter and balanced discriminator for f-m and tv receivers A. Bilotti and R.S. Pepper Sprague Electric Co., North Adams, Mass.

Quadrature detectors have found widespread use in f-m receivers and tv audio sections because they are simple to design and provide excellent performance. Less costly than other types such as ratio detectors and discriminators, they require inexpensive single-tuned coils rather than costlier double-tuned transformers. A design, based on the quadrature approach, for a monolithic limiter and balanced discriminator for f-m and tv receivers using full-wave coincidence gates offers even lower cost to manufacturers of television sets.

Basically, f-m detectors fall into three broad categories—slope, phase shift, and pulse averaging.

In the slope detector, the frequency deviation is transformed into a variable amplitude voltage by a reactive circuit's amplitude versus frequency slope. In the phase-shift detector, a reactive circuit's phase versus frequency characteristic transforms the instantaneous frequency deviation into a relative phase deviation, which is then detected by either a vector addition- or coincidence-type phase detector. In the pulse-averaging detector, single-polarity pulses are generated at each zero crossing of the signal. The resulting pulses of constant area are integrated and demodulated.

Of the three, a strong case can be made for an LC-type phaseNow Available... Power Supply Manual From Transformer Electronics Company



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## **Technical Abstracts**

shift network used in conjunction with a quadrature detector. Phase shifts can be transformed into amplitude variations without regard to the amplitude characteristics of the reactive circuit in which it is used. Complete linearity between the phase-shift deviation and the resulting output signal is also exhibited.

To enhance performance, a wideband limiter precedes the detector circuit.

F-m and tv applications require a high a-m rejection. Since wideband limiters tend to convert a-m signals to pulse-width asymmetries, rejection of these signals can be seriously degraded by the amplifier. This, however, is overcome by a full-wave quadrature circuit. This type of circuit has an added advantage: it can be used as either a high-performance synchronous demodulator or a double-balanced mixer.

Fresented at the International Electronic Devices Meeting, Washington, D. C., Oct. 18-20.

#### A new image

Electron-beam-accessed silicon diode arrays for image-sensing applications M. H. Crowell and E. F. Labuda, Bell Telephone Labs, Murray Hill, N.J.

Semiconductor diodes outshine thin-film photoconductive targets in vidicon applications. And a planar array of reverse-biased silicon p-n diodes can afford advantages over evaporated photoconductors as image-sensing elements in television camera tubes. Among these advantages:

 photoconductive lag problems don't arise;

spectral response is broader;

sensitivity is higher;

 there are no associated optical and electron-beam "burn-in" effects;

• higher temperatures can be tolerated during vacuum processing.

A 1-centimeter-square matrix containing a 660-by-660 diode pattern constitutes the array; the diodes are fabricated by photolithographic techniques. An optical image is focused on the laterally homogeneous n-type substrate, The sky is no limit for design engineers and designers at Lockheed



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There is no limit on individual achievement and recognition at Lockheed. An engineer's responsibility for a design package continues from initial concept through manufacturing and successful operation. Nothing is static. Demand for rapid response to changing requirements continually creates new challenges, opens new avenues of opportunity for advancement. □ At present, design openings include development of hydraulic and pneumatic components, mechanical/structural design of missiles and aircraft, mechanisms and antennas, ground support equipment, reentry vehicles, automotive design, conceptual design, missile basic and secondary structures, material-handling equipment and analysis of material usage and producibility. 
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## **Technical Abstracts**

which is typically 1 mil thick.

The diode side of the array serves as a p-type target and is scanned by an electron beam. Resolution capability and spectral sensitivity are functions of the minority carrier lifetime in the substrate and of recombination velocity of the light-incident surface.

Collection efficiencies—the ratio of holes collected at the diode depletion regions to the photons absorbed in the substrate—have topped 50%, better than twice the level achieved by conventional means. Useful spectral range is 4,500 to 9,500 angstroms, and dark currents are kept below 10 nanoamperes.

Presented at the International Electronic Devices Meeting, Washington, D. C., Oct. 18-20.

#### **Noisy light**

Pulse interval modulation laser communications Monte Ross McDonnell Douglas Corp., St. Louis, Mo.

Darkened somewhat by the problem of interfering quantum noise from stray photons at light frequencies—the prospect of laser communications now appears brighter. A proposed pulse-interval modulation (pim) system takes into account the probability of stray photons ending up at the receiver by sending short, high peak power laser pulses in one of several possible coded time intervals.

Because the system's detector must only sample transmitted pulses for a short time period, there is less chance of its also seeing stray photons. Such a system would pack a lot of power into each pulse, making it possible to raise the detector's threshold so that it could easily distinguish between signals and quantum noise.

The number of bits one pulse could carry would depend on the number of possible time intervals in each time slot, because the number of time intervals determine the number of combinations of binary ones and zeros.

Pim laser systems might find application in space communications where it's particularly important to send the most information per watt





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## **Technical Abstracts**

of power. For example, assume a data link between Mars and the Earth. A pim system with a 150 watt input would require a four inch focusing lens and a 40 foot receiving antenna to send 1,000,000 bits per second using 1-nanosecond pulses. In contrast, an r-f system operating under the same power would require an eight foot transmitting antenna and a 210 foot receiving antenna and would only send 10,000 bits per second.

Presented at Eastcon, Washington, Oct. 16-18.

### Semiconductor tube

A germanium space-charge-limited triode, A. Shumka. Jet Propulsion Laboratory Pasadena, Calif.

A solid state triode that behaves like a vacuum-tube triode offers a low level of sensitivity to thermal change, high input impedance, and tube-like transfer characteristics. The first of these features is new to semiconductor devices; the latter two are more pronounced in the triode than in field effect transistors. until now considered the semiconductors most similar to tubes.

The new device, fabricated from germanium, has an electrode that controls and modulates the flow of space-charge-limited electron currents and is analogous to the vacuum tube's grid. The p<sup>+</sup> stripes forming this grid electrode are inserted in an  $n^+ - \pi n^{\dagger} =$  type diode structure. The closely spaced stripes are capacitively coupled to the diode's terminals to establish emitter and collector regions analogous to a plate and anode.

Currents follow the three-halves power law when an electric field is impressed between the control electrode and the emitter. Over-all current-voltage characteristics show high transconductance, a large amplification factor, and an input impedance exceeding 1 megaohm.

Noise figures are a few decibels lower than those of conventional bipolar semiconductors, and susceptibility to temperature change is at least an order of magnitude less.

Presented at International Electron Devices Meeting, Washington, D. C., Oct. 18-20.



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### **New Literature**

Microwave glossary. Alfred Electronics, 3176 Porter Drive, Palo Alto, Calif., has published a four-page application note entitled "Glossary of Microwave Terms" that lists 115 microwave definitions. Circle 446 on reader service card.

**R-f test instruments.** Kay Electric Co., Maple Ave., Pine Brook, N.J. 07058, has released a 32-page brochure illustrating and describing a line of r-f test instruments. [447]

**Capacitance probes.** Wayne Kerr Corp., 22 Frink St., Montclair, N.J. 07042. A two-page, illustrated bulletin describes the company's capacitance probes. [448]

Slip ring capsules. Collectron Corp., 304 E. 45th St., New York 10017, offers a brochure describing a simplified method in designing a completely functional and highly reliable miniature and subminiature slip ring capsule. [449]

Tape reel drive motors. General Electric Co., Schenectady, N.Y. 12305. Technical data sheet GEC-1795 describes direct-current, fractional h-p motors for use as computer tape transport drives. [450]

Ultrasonic cleaning equipment. Delta Sonics Inc., 12918 Cerise Ave., Hawthorne, Calif. 90250, has released a 12-page brochure on ultrasonic cleaning equipment. Detailed specifications for tank sizes from 3- to 90-gallon capacity and 300 to 4,000 w are listed. [451]

Avalanche diode oscillator. Sylvania Electric Products Inc., 1100 Main St., Buffalo, N.Y. 14209, offers a brochure describing the SYA-3200, an X-band avalanche diode oscillator that simplifies construction of parametic amplifiers. [452]

Instrument motors. Amphenol Controls Division, Amphenol Corp., 120 S. Main St., Janesville, Wis. 53545. An eightpage catalog covers servocontrol, induction, reluctance and hysteresis synchronous motors. [453]

Vacuum coaxial switching. ITT Jennings Division, ITT Corp., P.O. Box 1278, San Jose, Calif. 95108. Brochure 108 describes the characteristics, construction, and application of vacuum coaxial switching systems. [454]

Emi/rfi shielding. Technical Wire Products Inc., 129D Dermody St., Cranford, N.J. 07016, has published an eightpage booklet containing information on its emi/rfi shielding products and services. [455]

Random data generator. Datapulse Inc., 10150 W. Jefferson Blvd., Culver City, Calif. 90230, offers a technical bul-



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**New Literature** 

letin on the model 213 random data generator for data error analysis and pattern sensitivity detection in transmission-medium systems and storage elements. [456]

Parametric amplifier systems. TRG Division, Control Data Corp., 535 Broad Hollow Road, Melville, N.Y. 11746, has issued brochures describing models 4-500 and 7-120 parametric amplifier systems. [457]

Motors. A.W. Haydon Co., 232 North Elm St., Waterbury, Conn. 06720. A four-page bulletin contains information on 16 types of d-c motors, synchronous motors, stepper motors and drives, and gearheads for timing, driving and positioning applications. [458]

**Diode reliability.** Unitrode Corp., 580 Pleasant St., Watertown, Mass. 02172, has available reliability report TR-129 covering rectifiers, zeners, and assemblies. [459]

Metal-to-ceramic components. Advac Division, GTI Corp., Stamford, Conn., offers a metal-to-ceramic components and assemblies folder. [460]

Dynamic bridge amplifier. Redcor Corp., 7800 Deering Ave., Canoga Park, Calif. 91304, has issued a booklet containing numerous applications for a dynamic bridge amplifier module designed for use in low level data acquisition and instrumentation systems. [461]

**Pressure actuated switch.** Electro Marine Corp., 4 Robbins Road, Falmouth, Mass. 02540. Bulletin 800 describes a pressure actuated switch for oceanographic instrumentation applications. **[462]** 

Laser components. Oriel Optics Corp., 1 Market St., Stamford, Conn. 06902, has published a data sheet on carbondioxide-laser end reflectors made from germanium and silicon with high efficiency multilayer dielectric coatings. [463]

Card reader. Scientific Data Systems, 1649 Seventeenth St., Santa Monica, Calif. 90404. Model 7140 card reader, a high-speed peripheral device that reads punched cards at a rate of 1,500 cards per minute, is described in data sheet 64-24-16A. [464]

Synchro converters. Natel Engineering Co., 7129 Gerald Ave., Van Nuys, Calif. 91406, has issued catalog 101 on a family of synchro converters including synchro-to-sine/cosine converters, synchro-to-linear d-c converters, synchroto-digital converters, and angle position indicators. **[465]** 

Time-sharing computers. Scientific Data Systems, 1649 Seventeenth St., Santa Monica, Calif. 90404. The SDS940



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TL-6D11 (A)	6 kHz 11	kHz T1-40055 (	40 kHz	55 kHz
TL-8D14 (A)	8 kHz 14	kHz T1-45D65 (	45 kHz	65 kHz
TL-10D16 (A)	10 kHz 16	kHz TL-50D75 (	3) 50 kHz	75 kHz
TL-16D25 (A)	16 kHz 25	kHz	•, ••••••••	
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### Biased amplifier. Hamner Electronics Co., Box 531, Princeton, N.J. 08540,

offers a technical bulletin covering the NA-18 biased amplifier that permits a section of the spectrum to be spread over a larger number of channels of a multichannel analyzer. [468]

time-sharing computer system is the

subject of brochure 64-03-29A. [466]

Audio interference suppressor. Narda Microwave Corp., Plainview, L.I., N.Y.

11803, has available a technical bul-

letin on the model 562 audio inter-

ference suppressor. [467]

**New Literature** 

Semiconductor products. Westinghouse Semiconductor Division, Youngwood, Pa., 15697. Condensed catalog B-9418 describes a wide variety of semiconductor devices ranging from a 250-amp transistor to a full line of low-cost plastic-case rectifiers. [469]

Computers on campus. Scientific Data Systems, 1649 Seventeenth St., Santa Monica, Calif. 90404. Interface 12, the latest issue of the company's quarterly magazine, contains a feature article describing the use of SDS computers in some 40 colleges and universities. [470]

Vacuum systems. Consolidated Vacuum Corp., 1775 Mt. Read Blvd., Rochester, N.Y. 14603. Two bulletins describe new vacuum systems that feature AutoMate control. [471]

Interchangeable thermistors. Victory Engineering Corp., 128 Springfield Ave., Springfield, N.J. 07081. Product bulletin MTM141 describes Isotherm interchangeable thermistors and contains a comprehensive resistance vs temperature table. [472]

Wire marking. W.H. Brady Co., 727 W. Glendale Ave., Milwaukee, Wis. 53209. A 20-page catalog lists over 5,000 different self-sticking wire markers and several dispensing methods to speed wire identification. [473]

Operational amplifier, National Semiconductor Corp., 2950 San Ysidro Way, Santa Clara, Calif. 95051. Bulletin SC-103 describes and illustrates the LM101 general-purpose operational amplifier. [474]

Thermal relays. G-V Controls Inc., Okner Parkway, Livingston, N.J. 07039, has available a file folder including information on two series of commercial thermal relays. [475]

potentiometers. Conelco Trimming Components, 465 W. Fifth St., San Bernardino, Calif. 92401. A four-page brochure details the Midgi-Trim line of precision wirewound/slidewire trimming potentiometers. [476]



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### New Literature

Temperature-humidity chambers. Tenney Engineering Inc., 1090 Springfield Road, Union, N.J. 07083, offers bulletin 106 describing an advanced version of its temperature and temperaturehumidity chambers. [477]

RC networks. Electro Cube Inc., 1710 S. DelMar Ave., San Gabriel, Calif. 91776, has published a brochure on precision RC networks for contact protection and noise suppression. [478]

Vibration meter. Wayne Kerr Corp., 22 Frink St., Montclair, N.J. Three-color literature describes the B731B vibration meter that features linear output characteristics. [479]

Solderless terminals. Hollingsworth Solderless Terminal Co., Nutt & French Creek Roads, Phoenixville, Pa. 19460. A complete line of solderless terminals, splices and tools is described and illustrated in a 30-page catalog. [480]

Versatile digital instrument. Technology/Versatronics Inc., 506 S. High St., Yellow Springs, Ohio 45387. Three instruments in one-digital voltmeter, electronic counter, and electronic integrator-are provided by the model DM5000 Versa/meter described in bulletin 701-B. [481]

Plastic-encapsulated transistors. Motorola Semiconductor Products Inc., Box 955, Phoenix, Ariz. 85001. A 12-page brochure presents a reliability report on small-signal, plastic-encapsulated transistors. [482]

Casting system. Hysol Corp., Franklin St., Olean, N.Y. 14760. Bulletin E3-225 describes water white hardener H-3840, a room-temperature-cure casting system for electrical and electronic applications, [483]

Wirewound resistors. RCL Electronics Inc., 700 So. 21st St., Irvington, N.J. 07111. Engineering catalog 678 lists hundreds of types of wirewound resistors, together with complete engineering information. [484]

Ceramic capacitors. Gulton Industries Inc., 212 Durham Ave., Metuchen, N.J. 08840. High capacitance subminiature ceramic capacitors are described in bulletin H29. [485]

Electronic timers. Brooks Instrument Division, Emerson Electric Co., Hatfield, Pa. 19440. Digital-readout electronic timers that maintain accuracy regardless of power line frequency variations are discussed in technical bulletin DS-4580. [486]

High-vacuum system. Ultek Division, Perkin-Elmer Corp., P.O. Box 10920, Palo Alto, Calif. 94303. A bakeable, tabletop high-vacuum system is the subject of a six-page bulletin. [487]

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### **Newsletter from Abroad**

#### November 13, 1967

### British government funds CAD project

Britain's Ministry of Technology believes the country's electronics industry needs computer aid in designing circuits, and is backing this conviction with money.

Over the next three years, the ministry will pick up half the tab for a CAD project started two years ago by Racal Electronics, a leading British producer of high-frequency communications equipment and electronic instruments. Cost of the project next year is estimated at \$365,000 and subsequent rises are expected. In return for the ministry's help, Racal will offer CAD services to the electronics industry at commercial rates.

Racal already has developed CAD programs for relatively simple cirsuits such as gated carrier amplifiers. Along with circuit parameters, the programs develop information on cost, life, and reliability. With the government money, Racal will tackle more complicated devices, particularly integrated circuits.

### Color-tv spurs mergers in France

A wave of mergers among small set makers in France seems inevitable. Few of the 100-plus companies now producing radio and tv receivers have the financial strength to go into color-tv production alone or to weather the expected drop in black-and-white set sales now that color-tv has arrived.

A big merger already is in sight. Compagnie Generale d'Electricite, France's largest electrical-electronics firm, and two smaller companies are well along in negotiations for lumping the consumer electronics operations of all three together. CGE would combine its subsidiary, Continental Edison, with Compagnie Centrale d'Electronique et d'Appareils de Mesure. Cocelam is jointly owned by Lebon et Cie. and the Societe Lyonnaise des Eaux et de l'Eclairage.

Consumer electronics sales of Continental Edison and Cocelam this year will run about \$60 million. Merged, they'd rank as the third largest set maker in France behind Compagnie Francaise Thomson Houston-Hotckiss Brandt and La Radiotechnique, an affiliate of Philips' Gloeilampenfabrieken of the Netherlands.

Taiwan may get big tube plant The Westinghouse Electric Corp. says it's negotiating a deal to supply the Industrial Development Corp. of Boston with more than \$1 million worth of equipment for the manufacture of receiving tubes. The Boston firm apparently wants to use the equipment to produce replacement tubes in Taiwan in conjunction with Taipei interests.

> Westinghouse insists the sale would not affect production capacity at its plant at Elmira, N.Y. Officials say the equipment is surplus and has been in storage for some time.

### Telefunken bolsters its computer effort

AEG-Telefunken has readied a new family of small computers in a bid to get a better foothold in the German data processing market. Although Telefunken is Germany's number two electronics producer, its share of the computer market is less than 1% and there has been speculation that the company was on its way out as a contender in computers.

Telefunken is expected to announce the new family of computersthe TR 8 series-before the end of the year. Price tag for the basic commercial machine will run about \$87,000. It will have nine input-output

### **Newsletter from Abroad**

channels, a core memory with a capacity of 64,000 words of 24 bits, and a cycle time of 900 nanoseconds.

The TR 8 series will also include a computer for military applications. This version will be smaller and have fewer channels than the commercial machine.

### Tide of IC imports is rising in Japan

Japan is braced for a surge of integrated-circuit imports during the next few months. Such imports—all but a handful from the U.S.—totaled 270,000 packages in September but are expected to climb to about 500, 000 this month and hold at that level through the rest of the year.

The industry guess is that Nippon Electric, Fujitsu, and Hitachi are gobbling up more than half the IC's coming into the country. Both Nippon Electric and Fujitsu are major producers of IC logic but their production schedules will keep them heavy importers of computer circuits for some time to come. Hitachi, which has put initial in-house emphasis on IC packages for calculators and consumer electronics, imports logic circuits for the RCA Spectra 70 computer it produces under license.

So sharp is the projected import rise that the flood of foreign IC's may temporarily top domestic production. But by early next year, Japanese producers figure to dominate their home market even though there's little prospect of a drop in imports.

Nippon Electric, currently the top Japanese IC producer, turned out 250,000 packages in September and expects a 600,000 monthly output rate by March. Mitsubishi production is close to 200,000 circuits a month; but the other two major producers, Fujitsu and Tokyo Shibaura Electric, are still below the 100,000-a-month mark.

Defensive maneuvers by Associated Electrical Industries have so far blocked efforts by Britain's General Electric Co. to take over the firm.

Since its first bid of \$330 million last month [Electronics, Oct. 16, p. 225], GEC has upped the ante twice. Arnold Weinstock, head of GEC (not connected with General Electric in the U.S.), describes the present offer of \$450 million—rejected by AEI's management—as "final." But there's speculation he may go higher since the latest bid is still some \$80 million shy of AEI's total assets.

Meanwhile, AEI has acquired a new chairman and come up with a plan to put its telecommunications equipment business into a joint venture with Standard Telephones and Cables, an ITT subsidiary. These moves have helped AEI hold the fort, but insiders say the battle could still go either way.

Kremlin programs tv production boost

**AEI resists** 

takeover bid

New emphasis on consumer goods in Soviet economic plans will push television-set production to record levels next year. The target is 5.7 million sets, up nearly 20% from this year's estimated output of 4.8 million.

Most of the sets will be black and white. Although nationwide colorcasts started last week with a live showing of the Red Square festivities marking the 50th anniversary of the Bolshevik revolution, volume production of color sets won't come until 1970.

The stepped-up tv-set production apparently won't be at the expense of other electronic sectors. Despite the secrecy surrounding sophisticated technology, there are indications that the Soviets have plotted a solid boost in automatic controls and computers over the next three years.



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Circle 301 on reader service card

# IBM Circuit Design and Packaging Topics

- packaging cost reductions
- high-speed switching
- 🗆 reed switch application data

### packaging cost reductions

Performance Measurements Co., Detroit, Michigan, reports significant savings in packaging their new electronic recording system. The packaging method previously employed required two gates to mount the components in the main console. Now, with IBM's modular packaging as pictured below, only one gate is needed. That's because the IBM technique makes the most efficient use of console space with compactly mounted and connected circuit boards, relays and hardware.

Mounting time has been saved too. Pluggable components, low-cost card receptacles and interlocking card guides have so simplified the packaging job, that Performance Measurements now saves 70% on the cost of mounting

hardware. Fewer and shorter wires are needed in the compact console — eliminating three feet of 1<sup>1</sup>/<sub>2</sub>-inch cable and shortening a second cable by eight inches. The modular chassis gave designers freedom to experiment freely with various mounting configurations. It also permits easy access for servicing and diagnostic analysis.

The same design freedom, plus significant hardware and labor savings are available in many applications. IBM components and packaging can help you in timing control, digital logic testing, telemetering, process or numerical control.

### high-speed switching

IBM wire contact relays were originally designed for data processing use. Now they are being used extensively in machine tool and assembly applications. One of these assembly applications is a numerically-controlled component insertion machine. It sequentially inserts random combinations of up to 24 different types of axial lead resistors and diodes into printed circuit boards. Such machines have been widely used, often on a round-the-clock, three-shift basis, in IBM's electronic assembly operations.

Insertion rates range from 3,000 to

4,500 components per hour, depending upon the type of components being inserted.

Instructions from an 8-channel punched paper tape provide the logic input to the relay gate. The gate employs three rows of 6- and 12-pole IBM wire contact relays. These relays control the movement of each printed circuit board through the X and Y axis positioning of the board for each component insertion. They also control the component feed, component insert, and cut-and-clinch cycles for each insertion operation.



IBM wire contact relays can perform in excess of 200 million operations with an operate speed as fast as 4.5 ms, a release time of 5 ms maximum. The product line includes 4-, 6-, and 12-pole Form C relays, 4- and 6-pole latch models, all with compact, solderless, pluggable mountings--with coil-voltages up to 100 VDC.

### 🗌 reed switch application data

Data on the magnetic switching characteristics of miniature dry reed switches is available to design engineers on request. The data was compiled from extensive tests conducted by IBM to help the design engineer use these switches most effectively. It can also help him determine the motion and position of the magnet required.

Simply described, a miniature dry reed switch operates under the influence of a permanent magnet. When the magnet is adjacent to the reed switch,



the flux of the magnet flows through the cantilever beams, as illustrated. While this magnetic flux is being carried by the beams, a polarity exists across the beams. Look at the overlap area of the beams. The north pole of one beam and south pole of the other beam are in proximity. Since unlike poles of a magnet attract each other, when the magnetic force becomes great enough to overcome the physical mass of the beams, they "snap" together, thus switching.

On the graph the X axis represents the displacement (in degrees for rotary motion, inches for lateral motion) of a magnet's center with reference to the center of the reed switch. The Y axis represents displacement (in inches) of the magnet from the outer edge of the



dry reed switch glass envelope. Dimensions shown along both axes represent displacement from the center of the magnet in alignment with the center of the reed switch.

There are some "gray areas" where performance varies due to minor differ-

ences in the characteristics of each switch. In these areas the status of each switch is not completely predictable.

Assume the zero point on the X axis is the magnetic center of an IBM reed switch. The magnet is positioned with its center at  $\pm$ .5 on the X axis, and .04 inches above the glass envelope. If the magnet is set in motion along the X axis toward the center of the switch, some reeds will pick when the center of the magnet reaches the point  $\pm$ .12 on the X axis. (The magnet has then reached the "gray area"). If motion is continued toward the center of the switch, all reeds will pick when the center of the magnet reaches the point  $\pm$ .09 on the X axis.

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# **Electronics Abroad**

Volume 40 Number 23

### Soviet Union

### Red glow in space

The packet of sophisticated hardware put into orbit by the Soviet Union in recent weeks added up to a stunning celestial celebration of the 50th anniversary of the Bolshevik revolution. And with their November space spectacular, the Soviets demonstrated dramatically that electronic controls is no longer a soft spot in their space effort.

Most space specialists rate the automatic docking of the Cosmos 186 and Cosmos 188 spacecraft as an achievement the U.S. would be hard put to match. Although American Gemini spacecraft scored nine dockings before the Russian feat, in each case an astronaut was at the controls for the final, delicate maneuvers.

In the Soviet view, expressed by Georgi Petrov, director of the Space Exploration Institute of the Soviet Academy of Sciences, "automatic linkup will always be more economical" than manual docking.

**Radio and radar.** The Russians used a combination of ground commands through a radio link and radar on the spacecraft to bring the Cosmos together under computer control. During the docking maneuver, the Cosmos 186, which was launched first, worked as the active partner with Cosmos 186 as the target. Both were Soyuz spacecraft, the latest Soviet capsules designed to carry cosmonauts.

The target vehicle went into orbit a scant 15 miles from Cosmos 186, which caught up with it and locked on before it had made its first orbit. Just before the docking, Cosmos 186 sent a signal to the target that caused it to point its docking socket toward the approaching craft.

The docking, say the Soviets, was shockless. The two spacecraft remained linked, with their electrical circuits connected for 3<sup>1</sup>/<sub>2</sub> hours. On ground command, the two separated and Cosmos 188 came down to a soft landing.

The race. The successful landing indicates the Russians have corrected the fault that caused a Soyuz to tumble and crash last summer, killing cosmonaut Vladimir Komarov. And the automatic docking proves the Russians can assemble heavy packages in an earth orbit with existing rockets. Such a heavy space station could then continue on to the moon.

Like the U.S. with its Saturn 5, the Soviet Union is apparently ready to test a rocket that could put a heavy lunar spacecraft into earth orbit. On balance, then, the USSR seems to be running neckand-neck with the U.S. in the race to put a man on the moon.

**Nationwide.** Space also figured in the pomp and ceremony last week that marked the anniversary celebration. The military parade through Moscow's Red Square was televised live for the first time to the farthest reaches of the country by the Soviet satellite communications network, Orbita.

For the network, the Soviets have built 20 ground stations, stretching from Moscow to Siberia and on to the Pacific regions. Antenna dishes of the stations measure 39 feet in diameter. The receivers operate at liquid nitrogen temperature and have a maximum noise temperature of 30°K.

Up there. The stations work with second-generation versions of the Soviet communications satellite called Molnya 1 [Electronics, Nov. 1, 1965, p. 158]. Although the Russians refer to the satellite in the singular, Western space specialists think that four second-generation Molyna-1's have been launched and that two still are operating. These satellites have 12-hour orbits. The more-sophisticated U.S. communications satellites have stationary 24-hour orbits.

### The Netherlands

### Filling the blanks

There's so little room to spare in the broadcast frequency spectrum these days that anyone who wants to put a new service like facsimile transmission on the air has to snatch at snippets. One snippet still up for grabs is the 1.3-millisecond blanking interval between successive fields in television transmission.

Since there are 50 or 60 blanking intervals per second, depending on whether you're using the European or U.S. standard, considerable information can be slipped in without disturbing the tv picture that regular viewers see.

In the U.S., the Radio Corp. of America last summer reported it had developed an experimental system to transmit printed material over regular television broadcasts. RCA since has been running on-the-



Still life. Pickup unit of Philips' system that transmits still photos, drawings and the like during the vertical blanking periods of regular tv broadcasts.

### **Electronics Abroad**

air tests during the early-morning hours when there are no programs and will report the results to the Federal Communications Commission early next year.

Market bound. N.V. Philips' Gloeilampenfabrieken, too, has developed a system that fills in the blanks between tv scanning fields and hopes to start marketing the equipment perhaps late next year. But where RCA's receiver reproduces the transmitted graphic material with an electrostatic printer, Philips' receiver photographs the image that appears on a cathoderay-tube.

With the European tv broadcasting setup of 625 lines per frame and 25 frames per second (there are two fields in a frame), it takes as little as 2.5 seconds to transmit graphic material—a photo, for example, or a printed text. Because of the time it takes for the scan, only still material can be handled.

Philips thinks the Dutch police will be among the first to use the system. They may use the equipment to broadcast pictures of wanted criminals and missing persons to stations throughout the country.

The lineup. The vertical blanking period lasts long enough to transmit between 20 and 28 lines, but because of the time it takes to switch the auxiliary circuit in and out—and to provide a safety margin—Philips designed its equipment to transmit a maximum of 5 lines per interval. Any number of lines from 1 to 5 can be chosen.

The pickup equipment, which has its own camera, is tied into the regular tv video path by means of a relay. It switches on when the operator pushes a start button, and it develops a pulse that initiates transmission of the still material.

Vertical synchronization pulses of the normal tv signal are used to trigger a pulse generator that gates out lines scanned by the auxiliary camera. The camera's horizontal deflection circuits get normal drive pulses, also from a special pulse generator.

Vertical deflection circuits, though, are set up so the scan for a field is reduced from the normal 312.5 lines to 310 lines or 312 lines. That way, the reduced scanning pattern shifts gradually down, compared with the normal scan pattern, as each group of 1 to 5 lines is transmitted during the vertical blanking period. The reduced number of lines for the auxiliary camera's scan is obtained by slightly increasing the frequency of vertical deflection pulses by means of a frequency divider.

**Receiver.** Vidco information inserted into the vertical blanking interval is picked up on a receiver whose front end is identical to a normal receiver except that there's no sound channel.

Deflection circuits for the cathode ray tube are set up to match the horizontal and vertical pulse trains in the pickup equipment. The camera that photographs the crt display has its shutter opened and closed automatically.

### **Great Britain**

### New beat

Thus far, consumer radio set designers have played it conservative with integrated circuits. To be sure, there's many a set with Ic's on the market. All, however, merely use IC's as a new kind of hardware to build an old circuit—the superheterodyne with an envelope detector.

This state of affairs won't last much longer, thinks R.C.V. Marcario of the University of Wales. Marcario maintains it's high time that designers revive a couple of circuit concepts that have been around for some time but weren't practical for domestic sets before low-cost IC's came along.

The concepts Marcario has in mind are homodyne reception and the single-span receiver. In the homodyne technique, a suppressed carrier is reconstituted in the receiver and added to the broadcast signal at the detecting diode. In the single-span receiver, the intermediate frequency is set higher than the highest carrier frequency to be received. Thus both the long-wave and medium-wave bands used in Europe for popular broadcasting can be covered by tuning the local oscillator with one variable condenser.

**Off-the-shelf.** Marcario already has breadboarded a homodyne circuit using standard linear Ic's produced by Fairchild Semiconductor for the crucial circuits. He currently is putting together a single-span receiver whose kingpin component is a dual-gate field effect transistor.

And since the single-span receiver needs a broadband antenna, Marcario has designed one that can be tucked into the cabinet of a lineoperated table set. A few feet of plain wire would serve the purpose equally as well, but Marcario is convinced that few consumers would buy a set that needed a living-room aerial.

This trio of developments, Marcario says, together add up to a receiver that would outperform conventional a-m superhets, especially for long-distance reception. Fading would no longer plague, as it now does, a Londoner listening to a station in Rome. That's because the coherent detection used in the homodyne concept adds the signals but not the noise—in the two sidebands. This improves the signal-tonoise ratio by 3 decibels, a big advantage when the signal deteriorates during a fade.

Zeroed in. For homodyne reception, one obvious way to supply the demodulating frequency is to lock a local oscillator in phase onto the signal carrier. But unless the set were tuned more carefully than most consumers are in the habit of doing, the oscillator would tend to jump out of lock on a fade. Automatic frequency correction to prevent jump-out would cost too much for a consumer set.

Marcario's homodyne develops a demodulating frequency precisely matched to the carrier frequency by tying a Schmitt trigger circuit to a zero-crossing detector. The basis of the arrangement is that if a station can be picked up at all, the carrier will appear at the detector and will change polarity regularly at twice the carrier frequency. Because the zero-crossing detector drives the Schmitt trigger, then, its square-wave output stays locked to



Coherent. Adding square-wave signal from Schmitt trigger to input from r-f stages turns diode  $D_i$  into a coherent detector.

the carrier frequency.

For the crossing detector, Marcario uses a Fairchild  $\mu A$  702 wideband linear IC amplifier; the Schmitt trigger is a  $\mu L$  914 package.

The square-wave output signal is applied, along with the amplified radio-frequency signal, to a detecting diode  $(D_1)$ . The square-wave also is applied to a second diode  $(D_2)$  which in effect measures the enhanced carrier. The outputs from both diodes pass through a differential amplifier and then go to conventional audio filtering and amplifying stages. The second detecting diode and the differential amplifier prevent an audible step waveform from developing when the Schmitt trigger switches off, as it would during a very deep fade.

Up and down. In Marcario's scheme of things, the homodyne detection system would have upstream of it an r-f front end that could cover the long-wave and medium-wave broadcast bands with no band-switching. For practical purposes, this means a pair of local oscillators, one working well above 1,600 kilohertz and a second to bring the i-f down to an easily handled frequency not in the antenna band, something like 100 khz. The problem here is spurious heterodyning between the two oscillators. Marcario believes balanced mixing with the dual gate field effect transistor should bring an economic answer.

The other major design problem for a single-span receiver—an aperiodic antenna that can be packaged into the set—has been solved. The antenna consists of a pair of parallel unetched copper printed circuit boards, one at the top of the set and the other at the bottom.

Each board has an area of 50 square inches and the two lie about 4 inches apart.

### France

### Foresight

For the Jaguar jet that will be the mainstay trainer of the French and British air arms in the early 1970's, the French air force divided the contracts for the fire control equipment in what it considered a logical fashion.

To CSF-Compagnie Générale de Télégraphie sans Fil, France's top avionics producer, went the job of developing the fire-control computer and the target-sighting gear. And to the Compagnie Générale d'Electricité, the country's frontrunner in laser research, went the contract for building an airborne laser rangefinder for precision bombing.

Csr's top brass, though, figured it would be logical for the company to develop a laser rangefinder on its own. That way, csr could offer complete fire-control systems to potential buyers of Jaguars other than the French air force.

The edge. Csr, in fact, managed

to get its laser telemetry hardware ready before cce. The French air force already has completed tests on csF's laser and is currently checking out cce's.

Although there's only an outside chance that the air force will adopt the csr laser, the company thinks it can win out in export deals for Jaguars because of its edge in technology. Instead of a rotating prism and complicated synchronizing circuitry to Q-switch the ruby laser so that it builds up giant pulses for ranging, csr uses a fixed slab of dark red glass. At an energy level of about 100 millijoules, the glass becomes transparent and releases the pent-up laser energy.

**Relatively rapid.** The Mitsubishi Electric Corp. put a laser rangefinder with similar passive Qswitching on the market 15 months ago [Electronics, Aug. 8, 1966, p. 300], but CSF apparently is one of the first to adapt the technique for airborne fire control, where the repetition rate of the laser pulses has to be high.

The CSF laser can put out bursts of 5 ranging pulses at a rate of 1 per second or 10 pulses at a rate of one every 2 seconds. But after a burst, it then needs 40 seconds to recoup. Alternatively, the unit can pulse without recovery intervals at a rate of 12 pulses per minute. The pulse length is about 30 nanoseconds.

Maximum range of the laser is 10,000 meters and accuracy within 5 meters. The pilot aims the beam of the nose-mounted laser through a sight incorporated in the head-up display of the fire-control system. Range to the target is measured by a quartz-oscillator clock circuit operating at 30 megahertz. The clocking is started by a fast photodiode that picks up part of the outgoing pulse and continues until the reflected beam hits a photomultiplier.

The receiver optics have a 10angstrom passband and limit the field of reception to an angle of 3 milliradians. The divergence of the outgoing beam is 1 milliradian.

**Even faster.** Although the laser pulses are fast enough for air-toground bombing or strafing runs, CSF now is trying to develop a ver-

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sion suitable for air-to-air weapons. "What we need," says the engineer who headed the Jaguar fire-control project, "is a laser with a muchhigher firing rate."

### West Germany

### New geometry

In long-distance broadcasting, radical improvements in antenna design are rare happenings now.

A few years ago, American antenna designers bettered transmission characteristics significantly by rigging a log-periodic half-rhombic array of dipole elements vertically between supporting masts. Another step forward, says AEG-Telefunken, is the full-rhombic vertical array its designers came up with for an antenna field now going up at Usingen, near Frankfurt.

The full rhombus arrangement keeps the elevation angle of the radiation pattern down low and thus well-suited for long-distance transmission. Further, the pattern is independent of frequency and can be highly directional. A frequency range of 6:1 can be handled without any tuning.

Five by five. The Usingen field, scheduled to go into full service by early 1968, will air intercontinental broadcasts at frequencies from 3 to 30 megahertz. All told, Usingen will have five arrays, each made up of five dipole curtains extending out from a center mast. One array, designed for transmission in the 3 to 18 Mhz range, will have a center mast 230 feet high. The other four arrays, for 5 to 30 Mhz broadcasting, will have center masts 130 feet high.

A typical antenna curtain has a vertical radiation pattern whose main lobe lies between 4° and 12° in elevation. This relatively low angle makes for optimum transmission characteristics at distances

Weighted antenna. Lower ends of rhombic dipole elements in West German antenna are held down by weights that can move up and down. from 900 to 1,200 miles. The elevation angle isn't changed appreciably for greater distances. They are covered by "skips" between the earth's surface and the ionosphere.

**Curtain time.** Since the horizontal radiation pattern of each dipole curtain is about 72° at the halfpower width, five curtains are required to get omnidirectional transmission characteristics for an array. Any of the curtains can be switched by remote control onto the transmitter to select the one best matched to the propagation conditions.

Each curtain is made up of 19 vertically rigged and vertically polarized rhombic half-wave dipole elements. At the top, the elements hang from an isolator attached to a guy wire; at the bottom the dipoles are joined to an isolator tied to a weight. The arrangement lets the rhombic elements "give" under high wind loads.

Energy feed to the array is by a two-conductor cable that runs through the center of each dipole. The dipoles are alternately connected to the conductors so that the energy in adjacent dipoles is 180° out of phase. Excitation, by means of a wire running parallel to the energy cable, starts with the



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shortest dipole and progresses along the array toward the center mast.

**Reflections.** Much as in a Yagi antenna, the larger dipoles immediately behind the one that's radiating act as a reflector. And the smaller dipoles next in front act as a director. As seen from the excitation feed-in point at the smallest dipole, the dipole elements before the one that's radiating present a reactive load to the energy cable.

The voltage standing wave ratio, at a 60-ohm input impedance, is less than 2. Gain of the individual dipole curtain depends somewhat on frequency. But compared to a  $\lambda/2$  radiator in free space, gain is approximately 12 decibels. Transmitting power is 20 kilowatts.

### Where away?

Specialists in wave propagation don't have any particular trouble checking total atmospheric noise in the very-low-frequency band. Finding out where the noise is coming from, though, is another matter. The usual methods of measurement can't sort out the individual contributions from various directions.

But at a radio-frequency propagation conference held by the Institution of Electrical Engineers in London last week, a trio of West German scientists reported on a method of plotting both the direction and spectral amplitude of incoming atmospheric noise. The work was done jointly by Guenter Heydt and Joachim Frisius of the Heinrich Hertz Radio Frequency Institute in West Berlin and Hans Volland of the Radioastronomy Institute of Bonn University.

**Pinpointed.** The system picks up atmospheric noise on a vertical rod antenna and a pair of cross-loop antennas. Each incident atmospheric thus induces three voltage pulses, and these are processed in a narrowband direction-finding circuit to obtain a direct-current pulse whose amplitude indicates the azimuth angle from which the noise came. This pulse drives the vertical amplifier of an oscilloscope.

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### **Electronics Abroad**

of the oscilloscope comes from a narrowband amplifier linked only to the vertical rod antenna. The amplifier, whose resonant frequency can be set from 5 to 50 kilohertz, measures the spectral amplitude of the atmospheric. Its output is also fed to a differentiating network that derives a short, highamplitude pulse that controls the oscilloscope's electron gun.

The screen is photographed with a long exposure. The result is a pattern of light spots distributed according to the direction and amplitude of incoming atmospheric noise.

Variations. The scientists have also come up with equipment modifications that make it possible to spot different noise sources lying on the same azimuth. In one variation, the pulse outputs of two narrowband amplifiers set at different frequencies are compared. In another, a combination of narrowband circuits develops a pulse proportional to the difference in the group delay times of the noise spectrum at two different frequencies in the range from 4 to 10 khz.

#### Japan

### Tuned IC

Cost-conscious radio and televisionset makers are always on the lookout for ways to do away with tuned transformers in intermediate-frequency amplifiers. Aligning i-f strips after a set is built adds a significant chunk to its labor cost.

Murata Manufacturing Co. thinks it has a way—hybrid integrated circuits incorporating ceramic filters. Although the company says the hybrids are still under development, it already has them available in sample quantities.

Murata's lead-zirconate-titanate piezoelectric filters have been used previously by the Sony Corp. as discrete components in a 455-kilohertz i-f amplifier for portable radios [Electronics, Nov. 14, 1966, p. 160]. As could be expected, a 455khz i-f amplifier turns up in Murata's hybrid line. But the company feels its eventual best sellers will be 4.5-megahertz i-f amplifier modules for tv-sound channels and 10.7-Mhz units for f-m receivers.

The trap. When its first discrete 455-khz filter was under development several years ago, Murata felt it had gone about as far as it could in standard i-f frequencies. At 4.5 and 10.7 Mhz, the filters showed intolerable spurious responses because of coupling between the several modes of vibration that can exist simultaneously in ceramic wafers.

Then William Shockley, best known as one of the inventors of



Hybrid. I-f amplifier module for tv-sound channel substitutes three energy-trap ceramic filters (large dark rectangles) for the transformers used to tune conventional i-f strips.

the transistor, discovered the energy-trap mode. In this mode, the frequency band is set by the thickness of the wafer and its electrodes. Only the energy trapped between the electrodes is effective; energy at other frequencies escapes so that spurious response cannot occur.

In the U.S., the Clevite Corp. produces high-quality crystal filters based on the energy-trap mode, largely for military equipment. Murata, however, claims to be the first to develop low-cost ceramic versions for consumer sets.

In the package. For its 4.5-Mhz module, Murata uses two energytrap filters in the amplifier and one Can your executives and their wives find happiness in "the sticks"? (impossible!)



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### **Electronics Abroad**

for the discriminator. On the substrate with the filters are three transistor chips, a pair of diodes, a dozen resistors and five capacitors. The diodes are used with the third filter in the discriminator circuit. Gain ranges between 40 and 46 decibels.

The 10.7-Mhz unit is similar to the 4.5-Mhz module, but does not include a discriminator circuit. Murata, however, is developing a filter that can be used as a discriminator at 10.7 Mhz.

### Inside job

With much fanfare, Matsushita Electrical Industrial Co. and N.V. Philips' Gloeilampenfabricken last month signed a pact extending for another 10 years their long-standing joint venture in Japan—the Matsushita Electronics Corp.

In view of such close cooperation, observers wondered why Matsushita Electric has quietly set up a semiconductor group in its central research laboratory to develop integrated circuits. Until now, the job has been handled by the joint venture.

**Competing.** Matsushita vicepresident Tetsujiro Nakao says there's nothing sinister in the development, even though the new group is led by the former director of research at Matsushita Electronics.

Under the joint agreement, Nakao points out, Philips has access to any Matsushita Electric semiconductor developments. And he adds that there's no plan to set up separate semiconductor production facilities in which Philips won't share. Nakao insists the move was made mainly because the Japanese company likes some internal competition among its researchers and development groups.

Outsiders, though, feel there's another reason behind the new IC research group: a freer hand for Matsushita Electric. Apparently Matsushita has had trouble selling its partner on some research projects that look promising from a Japanese standpoint but nonetheless seem unattractive to Philips, whose prime market is Europe.



Here's a common-source FET amplifier, with a current-limiter diode as a source resistor and a VCR FET gain control. With  $V_C = 0$ , the gain is 32 dB. Gain decreases as  $V_C$  approaches pinchoff for the VCR. Maximum gain depends on  $r_{ds}$  at  $V_{GS} = 0$  for the VCR6P. Gain with full AGC ( $V_C = V_P$ ) is controlled by the current limiter. Variations in maximum gain are due to variations in  $r_{ds}$ .

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\* VCR - Voltage Controlled Resistor - a FET bilateral resistance whose value is voltage controlled from one high-impedance terminal.



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